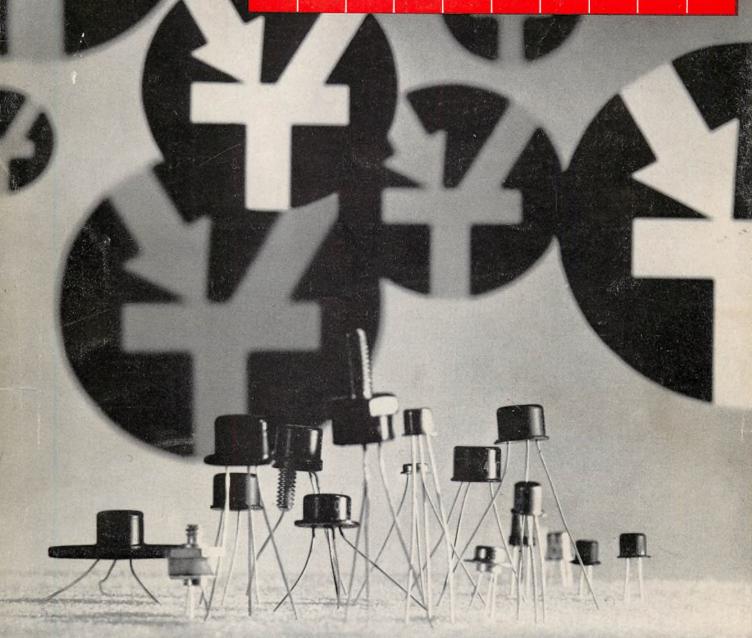


E L E C T R O N I C D E S I G N



ELEVENTH ANNUAL
TRANSISTOR DATA CHART

FASTEST TRANSISTORS EQUIREMENTS

FASTEST LOW LEVEL LOGIC

2N709 (NPN)

TIME -

6 nsec max @ 5/5/5mA

• V_{sat} - 0.3V max @ I_c = 3mA I_B = .15mA

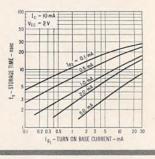
● h_{FE} —

20 min @ I_C=10mA V_{CE}=0.5V

f_T —

600 MC min @ $I_c=5mA$ $V_{CE}=4V$

Package: TO-18



FASTEST LOGIC

2N2369 (NPN)

13 nsec max @ 10/10/10mA

• V_{sat} - 0.25V max @ I_c =10mA I_B =1mA

20 min @ I=100mA V_{CE}=2V

500 MC min @ Ic=10mA VcE=10V

Package: TO-18



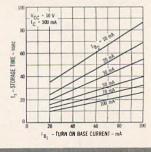
FASTEST CORE DRIVER

20 nsec @ 50/50/50mA

• V_{sat} - 1.0V max @ I_c = 500mA I_B = 50mA

• h_{FE} - 20 min @ I_{C} = 500mA V_{CE} = 10V • f_T - 250 MC @ I_C = 50mA V_{CE} = 10V

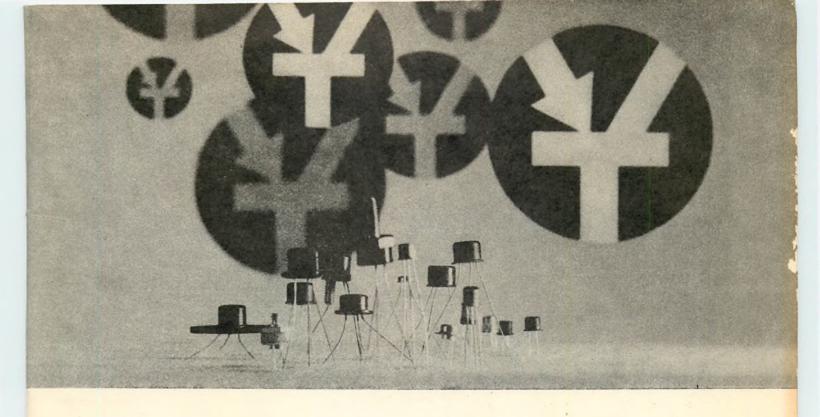
Package: TO-18, TO-5



2N2845 SERIES (NPN)

> FAIRCHIL SEMICONDUC

A DIVISION OF FAIRCHILD CAMERA AND INSTRUMENT CORPORATION



ELECTRONIC DESIGN'S ELEVENTH ANNUAL

TRANSISTOR DATA CHART

1963

Donald Christiansen Technical Editor

ELECTRONIC DESIGN'S 11th Annual Transistor Data Chart includes more than 3,000 listings, of which about 375 appear for the first time.

Transistors are classified according to seven application categories: Audio and General Purpose (page T4), High-Frequency (page T16), Power (page T40), Low-Level Switching (page T62), High-Level Switching (page T77) and, for the first time, Field-Effect (page T85) and Unijunction (page T86).

Within each category, types are arranged in order of increasing value of a key design parameter. This also permits quick identification of close substitutes.

Alternate suppliers are listed in the "Remarks" column. The manufacturer whose data are listed is identified in the "Mfr." column. He is not necessarily the original registrant.

A cross index (page T88) identifies types in numerical sequence. Each type in the cross index carries a code that identifies its application category and specifies the block of 10 types in which it appears. A3, for example, means the type can be found in the third block of the Audio section.

Many manufacturers, upon request, provide detailed application notes and data sheets to the design engineer. Where this is true, it is noted next to the manufacturer's name in the list of manufacturers (page T1).

Update Your Transistor File



Step 1. Send for your personal copy of the 1963 Transistor Data Chart, Reader-Service No. 549. It has been tailored to meet your needs as a design engineer—to guide you in the rapid selection of transistors for a particular circuit need.

Step 2. Having narrowed the field to a number of similar types, your next step is to refer to manufacturers' specification sheets for exact test conditions, application details and other pertinent information.

But unless you have invested much time and effort on your transistor file, it is bound to contain obsolete types and overlook new ones.

So, to supplement the Data Chart, ELECTRONIC DESIGN has made special arrangements with semiconductor manufacturers to provide specification sheets and application notes to readers requesting this material. Merely circle the number alongside each manufacturer's name on the special Reader-Service card at the end of this section.

Transistor Manufacturers

| | | Further Information Av | ailable |
|------|--|--|-------------------------------------|
| Code | Сомрапу | Туре | Ĉircle Reader- Service No. |
| Al | Amelco, Inc. 341 Moffett Blvd. Mountain View, Calif. | FET application notes, 20- page data folder, and other brochures | 400 |
| AMF | American Machine and Foundry Co. Leland Airborne Products Div. AMF Semiconductor Dept. Vandalia, Ohio | Data sheets on 38 transistor types | 401 |
| AMP | Amperex Electronic Corp. 230 Duffy Ave. Hicksville, L.I., N.Y. | Several condensed catalogs and application notes | 402 |
| BE | Bendix Semiconductor Div. South St. Holmdel, N.J. | Two guides to silicon and germanium transistors | 403 |
| CS | Clark Semiconductor Corp. Div. of National Semiconductor Walnut Ave. Clark, N.J. | Data sheets on transistors | 404 |
| CL | Clevite Transistor 200 Smith St. Waltham 54, Mass. | Condensed catalog and application notes | 405 |
| СТ | Crystalonics, Inc. 249 Fifth St. Cambridge 42, Mass. | 3-ring folder of data sheets and application notes | 406 |
| DE | Delco Radio Div. GM Corp. Kokomo, Ind. | Condensed catalog, data sheets, application notes and test data | 407 |
| FA | Fairchild Semiconductor 545 Whisman Road Mountain View, Calif. | Condensed catalog and data sheets | 408 |
| GE | General Electric Co. Semiconductor Products Dept. Electronics Park Syracuse 1, N.Y. | Condensed catalog, data sheets and application notes | 409 |
| GI | General Instrument Corp. 18 East 41st Street New York 17, N.Y. | Data sheets, tentative specifications and application notes | 410 |
| н₩ | Honeywell Semiconductor Products 2747 Fourth Ave. South Minneapolis 8, Minn. | Application notes, lab reports and data | 411 |
| HU | Hughes Semiconductor Div. 500 Superior Ave. Newport Beach, Calif. | Application selection guide, data sheets and brochures | 412 |
| IND | Industro Transistor Corp. 35-10 36th Ave. Long Island City 6, N.Y. | Condensed catalog, data sheets and application notes | 413 |
| KF | Kearfott Semiconductor Corp. 437 Cherry St. West Newton 65, Mass. | Loose leaf binder of semi- conductor engineering data | 414 |
| МО | Motorola Semiconductor Products, Inc. 5005 E. McDowell Road Phoenix 8, Ariz. | Condensed catalog, data sheets and reliability brochure | 415 |
| NA | National Semiconductor Corp. 90 Rose Hill Ave. Danbury, Conn. | Condensed catalog, data sheets, engineering memos, application notes | 416 |

| | | Further Information Av | ailable |
|------|--|---|-------------------------------------|
| Code | Company | Туре | Circle Reader- Service No. |
| PSI | Pacific Semiconductor, Inc. (TRW Electronics) 12955 Chadron Ave. Hawthome, Calif. | Condensed catalog and data sheets | 417 |
| PH | Philco Corp. Lansdale Div. 504 Church Road Lansdale, Pa. | Transistor reference chart and planar reliability report | 418 |
| RCA | Radio Corp. of America Semiconductor Div. Somerville, N.J. | Condensed catalog, data sheets and application notes on many devices | 419 |
| RRD | Radio Development & Research Corp. 100 Pennsylvania Ave. Paterson 3, N.J. | Will not manufacture after 1963 | |
| RA | Raytheon Co. Semiconductor Div. 350 Ellis St. Mountain View, Calif. | Condensed catalog | 421 |
| STC | Silicon Transistor Corp. 150 Glen Cove Road Carle Place, L.I., N.Y. | Condensed catalog | 422 |
| SI | Siliconix, Inc. Sunnyvale, Calif. | Application notes, data sheets and articles on FET devices | 423 |
| SSE | Solid State Electronics Corp. 15321 Rayen St. Sepulveda, Calif. | Data sheet on SST610 transistor | 424 |
| SSP | Solid State Products, Inc. One Pingree St. Salem, Mass. | Folder of data sheets and comparison chart | 425 |
| SSD | Sperry Semiconductor Div. Norwalk, Conn. | Data sheets and tentative specifications | 426 |
| SPR | Sprague Electric Co. 347 Marshall St. North Adams, Mass. | Condensed catalog | 427 |
| SY | Sylvania Semiconductor Div. 100 Sylvan Road Woburn, Mass. | Full catalog, data sheets and Circuit Loops brochures | 428 |
| ΤI | Texas Instruments Inc. 13500 North Central Expressway Dallas 22, Texas | Data sheets, application notes and theory of FET devices brochure | 429 |
| TR | Transitron Electronic Com. 168 - 182 Albion St. Wakefield, Mass. | Data sheets, application notes, condensed catalog and an article reprint | 430 |
| TS | Tung-Sol Electric, Inc. One Summer Ave. Newark 4, N.J. | Condensed catalog, FET. brochure and silicon double diffused brochure | 431 |
| WE | Western Electric Co., Inc. Marion and Vine St. Laureldale, Pa. | Available only to agencies of the U.S. Govt, and their subcontractors | |
| WH | Westinghouse Electric Corp. 3 Gateway Center Pittsburgh 30, Pa. | Condensed catalog, data sheets, application and design notes | 433 |

May 24, 1963 T1

HOW TO USE THE CHARTS

A color code pairs the transistor type with the value of its key parameter. Types are listed in order of increasing value of key parameter. Note, however, that since various manufacturers may characterize their types differently, some "jumps" may take place in the sequence. Consider, for example, a type in the high-frequency category. Its key characteristic will be $f_{\alpha e}$, f_T , or $f_{\alpha b}$ (values of f_T are preceded by a single asterisk; values of f_{ab} , by a double asterisk). But f_{ae} is the frequency at which h_{fe} drops to 0.707 of its low frequency value, and f_T is the gain-bandwidth product, or the product of h_{fe} and frequency at a point where h_{fe} is dropping by 6 db per octave. Thus, f_T is about h_{fe} times greater than $f_{\alpha e}$ for a given transistor.

Under maximum ratings, manufacturers were asked to specify collector power dissipation at 25 C case temperature, this generally being the most meaningful single dissipation rating. The derating factor can then be used to estimate P_c for other operating temperatures.

Either V_{CEO} or V_{CBO} is listed as a maximum voltage rating. V_{CEO} is related to collector-emitter diode breakdown and V_{CBO} to collector-base diode breakdown. But bear in mind that many manufacturers' data sheets will list other important voltage ratings, such as V_{CES} or V_{CER} .

Under characteristics, ELECTRONIC DESIGN asked manufacturers to supply typical values rather than maxs or mins. Where deviations from this occur they are noted.

Finally, it must be cautioned that the characteristics listed are primarily a guide and generally cannot be used for direct comparison of types. This is because it is impossible to list the wide variety of test conditions under which characteristics have been measured. V_{ceo} , for example, can differ considerably for comparable devices when measured at a collector current of 100 μ a in one case and 1 ma in another. The best bet is to consult the manufacturers' data sheets before making the final selection.

Key to Symbols

 $f_{\alpha e}$ = small-signal short-circuit forward current transfer ratio cutoff frequency (common-emitter)

 f_{ab} = small-signal short-circuit forward current transfer

ratio cutoff frequency (common-base)

 f_T = gain-bandwidth product

P_c = collector power dissipation (average)

 T_i = junction temperature deg C

mw/°C = derating factor

 V_{CEO} = max collector voltage, collector to emitter, base

open

 V_{CBO} = max collector voltage, collector to base, emitter

open

1_c = max collector current

Ip = max collector current (peak)

h fe = small-signal short-circuit forward current transfer

ratio (common-emitter)

h FE = dc short-circuit forward current transfer ratio (com-

mon-emitter)

Ico = collector cutoff current (dc) emitter open

C_{oe} = output capacitance (common-emitter)

C_{ob} = output capacitance (common-base)

 t_r = rise time

t_s = storage time

 $V_{CE(sat)} = collector-to-emitter saturation voltage$

g_m = transconductanceV_P = pinch-off voltage

I_{DSS} = zero-bias drain current

BV_{DGO} = drain-gate breakdown voltage with gate-source

open-circuited

BV_{DGS} = breakdown voltage from drain to gate with drain

shorted to source

C_{is} = common source short-circuit input capacitance

N.F. = noise figure

n = intrinsic standoff ratio

I_{EO} = max emitter reverse current

Ip = max peak point emitter current

 $V_{E(sat)}$ = max emitter saturation voltage

V_{EB2} = min emitter reverse voltage

 V_{OB1} = min base one peak pulse voltage

Key to Transistor Types

| | Construction | GD | Grown diffused |
|-----|----------------------|-----|--------------------------|
| AJ | Alloy junction | GJ | Grown junction |
| AD | Alloy diffused | GR | Rate grown |
| DD | Double diffused | МВ | Meltback |
| DG | Grown diffused | MD | Micro-alloy diffused |
| DJ | Diffused junction | | base |
| DM | Diffused mesa | MS | Mesa |
| DDM | Double-diffused mesa | PE | Planar epitaxial |
| DP | Diffused planar | PL | Planar |
| DR | Drift | SBT | Surface barrier |
| ED | Electro-chemical | SP | Surface precision alloy |
| | diffused - collector | TDP | Triple - diffused planar |
| EM | Epitaxial mesa | | p.dilai |
| EP | Epitaxial | | Materials |
| FA | Fused alloy | ge | germanium |
| FJ | Fused junction | si | silicon |

Manufacturers and their Lines

| Manufacturer | Audio (A) | High- Frequency (HF) | Power (P) | Low-Level Switching (LL) | High-Level Switching (HL) | Field- Effect (FE) | Uni- junction (LNJ) |
|-------------------------|--------------|----------------------------|-----------|--|---------------------------------|--------------------------|---------------------------|
| Amelco | | | | • | , , | | |
| AMF | | | • | | 1 | | |
| Amperex | | • | | • | • | | |
| Bendix | • | | | • | • | | |
| Clark | | | • | | | | |
| Clevite | | • | • | • | • | | |
| Crystalonics | | | | • | | • | |
| Delco | | | • | | • | | Jan 19 |
| Fairchild | | • | • | • | • | | |
| General Electric | • | • | • | • | • | | • |
| General Instrument | • | • | • | | • | | No. |
| Honeywell | | • | • | The Control | | | |
| Hughes | • | • | | • | • | | |
| Industro | • | • | • | • | • | | |
| Kearfott | • | • | • | • | • | | |
| Motorola | • | • | • | • | • | • | |
| National Semiconductor | • | • | • | • | | | |
| Philco | • | • | | • | • | | |
| PSI | 1 | • | • | | | | |
| Radio Development | • | | | The State of the S | | | |
| Raytheon | • | • | • | • | • | | |
| RCA | • | • | • | • | • | • | |
| Silicon Transistor | | | • | | • | | |
| Siliconix | 1.15 | | | | | • | |
| Solid State Electronics | • | | | • | | | |
| Solid State Products | | | | | • | | |
| Sperry | • | • | | • | | | |
| Sprague | • | • | | • | | | |
| Sylvania | • | • | • | • | | | |
| Texas Instruments | • | • | • | • | • | | • |
| Transitron | | • | • | • | • | | |
| Tung-Sol | • | • | | • | • | • | |
| Western Electric | • | • | • | • | • | | |
| Westinghouse | | | • | | • | | |

AUDIO AND GENERAL PURPOSE

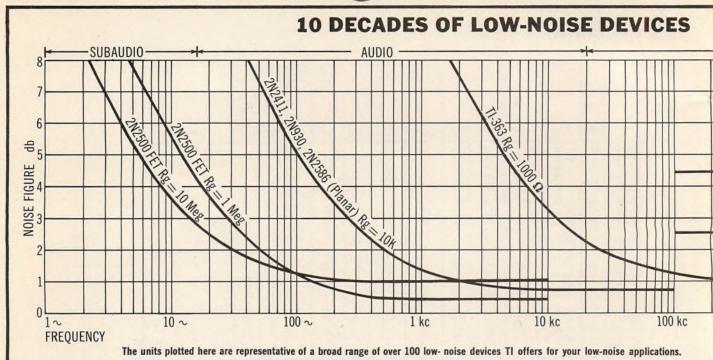
Mostly audio and general-purpose types below one watt. In order of increasing forward-current transfer ratio.

| | | | E T | | MAX. RATINGS CHARACTERISTICS | | | | | | CS | | | |
|-----------------------|---|---------------------------------|---|---|---|--|--------------------------------------|----------------------------------|----------------------------------|--|---------------------------------|--------------------------|-----------------------------|---|
| Cross Index Key | Type No. | Mfr. | Туре | hfe *hFE **G _m | P _c (mw) | T _i | mw/°C | VCEO *VCBO (v) | l C (ma) | ¹ CO (μα) | ME (9P) | Coe *Cob (pf) | fae *fT **fab (mc) | Remarks |
| A 1 | 2N160 2N160A 2N349 2N161 2N161A | RRD RRD RRD RRD RRD | npn,GJ,si npn,GJ,si npn,GJ,si npn,GJ,si npn,GJ,si | 0.93 0.93 0.95 0.96 0.96 | 150 150 750 150 150 | 175 175 175 175 175 175 | 11111 | *40 *40 *125 *40 *40 | 25 25 40 25 25 | 0.2 0.2 10 0.2 0.2 | 25 25 - 25 25 25 | 7 - 7 7 | 4 3 5 5 | |
| A 2 | 2N348 2N1096 2N347 2N1095 2N163 | RRD RRD RRD RRD RRD | npn,G1,si is,L0,nqn is,L0,nqn is,L0,nqn | 0.96 0.96 0.98 0.98 0.99 | 750 500 750 500 150 | 175 175 175 175 175 175 | 11111 | *90 *90 *60 *60 *40 | 50 30 60 40 25 | 10 6 10 5 0.2 | - 18 - 25 | - 7 - 7 | 3 3 3 6 | |
| A 2 | 2N163A 2N1566 2N2673 2N1154 2N1155 | RRD TI GE NA NA | npn,GJ,si npn,MS,si npn,GD,si npn,DM,si npn,DM,si | 0.99 1.2 •8-22 9 | 150 - 250 750 750 | 175 175 185 150 150 | - 80 1.66 5 5 | *40 60 *60 50 80 | 25 100 25 60 50 | 0.2 1 0.004 5 6 | 25 50 11 - | 7 - 4 - - | 6 - 10 - - | TR, NA TI TI |
| | 2N1156 2N117 2N332 2N332A 2N333A | NA TI TI NA NA | npn, DM, si npn, GR, si npn, GR, si npn, MS, si npn, MS, si | 9 9·20 9·20 9·20 9·20 | 750 150 150 150 150 500 | 150 175 175 175 175 175 | 5 1 0.86 2.8 | 120 *30 45 45 45 | 40 25 25 - - | 8 2 2 2 0.5 | 20 20 - - | - - 30 15 | - 4 6 - | TI TR,USN GE,TR,RRO,NA,RA,AMP GE, TI GE, TI |
| A 3 | 2N1149 2N243 2N470 2N471 2N472 | TR TI TR TR TR | is, LD, nqn is, LD, nqn is, LD, nqn is, LD, nqn is, LD, nqn | 9-20 9-32 10-25 10-25 10-25 | 150 750 200 200 200 | 150 150 200 200 200 | 6 | *45 60 15 30 45 | 25 60 25 25 25 25 | 0.1 1 0.02 0.02 0.02 0.02 | 25 - 22 22 22 22 | 7 - 7 7 | 7 7 8 8 8 | NA, TI NA, SO NA, TI, AMP NA, TI, AMP NA, TI, AMP |
| | 2N472A 2N102/13 2N144/13 2N1439 2N756 | TR SY SY NA NA | npn,DG,si npn,AJ,ge npn,AJ,ge pnp,AJ,si npn,DM,si | 10-25 10.5 10.5 12 12-20 | .200 1w 1w 400 500 | 200 75 75 200 200 | 20 20 2.28 2.5 | 45 •30 •60 50 45 | 25 1.5a 0.8a 100 | 0.02 5ma 5ma 0.01 9.2 | 22 - 12 - | 7 - - 25 - | 8 - 1 - | NA, T! audio/med.power |
| A 4 | 2N756A 2N2674 CK64B CK64C 2N935 | NA GE RA RA SSD | npn,DM,si npn,GD,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,si | 12-20 •12-40 13.5 13.5 | 500 250 75 75 385 | 200 185 85 85 160 | 2.5 1.66 1.25 1.25 2.85 | 60 •60 45 45 40 | 25 100 100 50 | 0.1 0.004 10 10 0.005 | 11 - - 18 | - 4 - - 70 | - 11 - - 2 | Sub min Sub min NA |
| A 6 | 2N284 2N284A 2N339A 2N340A 2N341A | AMP AMP TR TR TR | pnp,AJ,ge pnp,AJ,ge npn,DJ,si npn,DJ,si npn,DJ,si | 15 15 15 15 15 | 125 125 1000 1000 1000 | 75 75 200 200 200 | 2.5 2.5 8 8 8 | *32 *60 55 85 *125 | 125 125 1 0.1 0.1 | 4.5 4.5 1 1 | 11111 | | 11111 | |
| A 5 | 2N927 2N938 2N1247 2N1249 2N1440 | NA SSD NA TR NA | pnp,AJ,si pnp,AJ,si npn,DM,si N-GJ pnp,AJ,si | 15 15 15 15 15 | 150 250 30 30 400 | 200 175 150 - 200 | 2.5 1.7 0.2 - 2.28 | 70 35 6 6 50 | - 100 5 5 100 | .005 .001 1.5 0.002 0.01 | - - - 12 | 12 7 12 8 25 | .8 1 - 5 1 | NA TR audio/med. power |
| | 2N1623 2N1655 BCZ12 TR34 2N2391 | RA RA AMP IND TI | pnp,AJ,si pnp,AJ,si si pnp,AJ,ge P,si | 15 15 15 15 *15-*45 | 250 250 250 250 120 1000 | 160 160 150 85 | 0.54 0.54 2 3 - | 20 •125 •60 40 20 | 50 50 50 150 30 | .005 .005 0.01 10 | 18 18 8 15 - | 70 70 50 15 | .1 .2 1 1.6 | AMP |
| A 6 | TS601 TS603 2N925 2N529 2N756A | TS TS NA GI TR | pnp,AJ,ge pnp,AJ,ge pnp,AJ,si • N-M | *15-*60 *15-*60 16 17 17 | 200 200 150 100 500 | 100 100 200 85 | 2.5 2 0.30 | *12 *20 50 *15 60 | 400 400 - - 100 | 20 20 .005 3 0.1 | - - 14 - | - 12 14 5 | - .8 - 100 | matched pnp,npn |
| | 2N1277 2N1584 2N1586 2N1587 2N1588 | TR TR TR TR TR | N-GJ N-GJ npn,GJ,si N-GJ npn,GJ,si | *18 18 *18 18 *18 | 150 150 150 150 150 150 | - 150 - 150 | 1.00 1.00 1.33 1.00 1.33 | *40 60 15 30 60 | 25 25 50 25 50 | - 0.5 - 0.5 | - 20 - 20 | 5 5 •2 5 •2 | 15 5 15 5 15 | |
| A 7 | 2N334A 2N757 2N757A 2N118 2N333 | NA NA NA TI TI | npn,MS,si npn,MS,si npn,MS,si npn,GR,si npn,GR,si | 18-36 18-36 18-36 18-40 18-40 | 500 500 500 150 150 | 175 200 200 175 175 | 2.8 2.5 2.5 1 | 45 45 60 •30 45 | - - 25 25 | 0.5 0.2 0.1 2 | 15 - - 20 20 | 11111 | - - 5 8 | TR GE,TR,NA,RA,AMP |

| | | | | | MAX. RATINGS | | | | | CHA | RACT | ERISTI | CS | |
|-----------------------|---|-------------------------------|---|---|---|-----------------------------------|----------------------------------|---------------------------------|---------------------------------|-------------------------------------|----------------------------|---|-----------------------------------|---|
| Cross Index Key | Type No. | Mfr. | Туре | h _{fe} *hFE **G _m | P _c (mw) | T _i | mw/°C | VCEO | 1 C (ma) | 「CO (m) | NF (db) | C _{oe} *C _{ob} (pf) | fae *fT **fab (mc) | Remarks |
| | 2N1150 2N334 2N758 2N758A 2N1151 | NA TI NA NA NA | npn,DM,si npn,GR,si npn,MS,si npn,DM,si npn,DM,si | 18-40 18-90 18-90 18-90 18-90 | 150 150 500 500 150 | 175 175 200 200 175 | 0.86 1 2.5 2.5 0.86 | 45 45 45 60 *45 | 25 25 - - 25 | 2 2 0.2 0.1 2 | 20 - - - | 7 - - - 7 | 1 10 - - 8 | TI GE,TR,NA,RA,AMP TR,TI |
| A 8 | 2N129 2N923 2N1051 2N1248 2N1670 | SPR NA WE TR GI | pnp,AJ,ge pnp,AJ,si npn,DD,si N-GJ pnp,DR,ge | 20 20 20 20 20 20 | 30 150 600 30 120 | 85 200 150 - 85 | 2.5 0.25 - 2 | *3 40 60 6 *100 | 5 - 5 - | - .005 0.1 0.002 3 | 11111 | - 12 8 8 3 | 30 .8 70 5 | US,MIL only NA Hi-volt switch |
| | 2N2551 BCZ10 ST1506 ST1543 TNT839 | HU AMP TR TR TR | pnp,A,si si N·M N·M npn,MESA,s | *20 20 *20 20 20 20 | 400 250 300 30 100amb | 160 150 - - 175 | 3.0 2 0.50 - 0.66 | . 150 *25 30 6 45 | 200 50 - 5 5 | 0.1 0.001 - 0.002 0.1µa | 6 8 | 90 50 - 8 *8 | 1.0 1 - 5 50 | |
| A 9 | 2N475A 2N2042 2N2042A 2N761 TMT2427 | TR MO MO NA TR | npn,DG,si pnp,AJ,ge pnp,AJ,ge npn,DM,si npn,PL,si | 20-50 20-50 20-50 20-55 •20-60 | 200 200 200 200 500 150amb | 200 100 100 200 175 | 2.67 2.67 2.5 1.0 | 45 *105 *105 45 40 | 25 200 200 - 50 | 0.02 25 25 .2 0.010µa | 20 - - - 4 | 7 25 25 - *6 | 10 0.5 0.5 - 50 | TI TI "Meg·A-Life", TI |
| | 2N406 2N530 TR722 CK22A CK64A | SY GI IND RA RA | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 20-80 22 22 22.5 22.5 22.5 | 150 100 150 80 80 | 75 85 2.5 85 85 | 3 2 3 - - | *20 *15 45 20 .29 | 35 - 200 100 100 | 14 3 10 2 2 | - 14 15 6-5 22 | 3 20 - | 250 - 2.5 1.2 0.8 | •matched pnp,npn micromin micromin |
| A 10 | 2N2675 2N186A 2N189 2N1150 2N1476 | GE GE GE TR SSD | npn,GD,si pnp,AJ,ge pnp,AJ,ge npn,GJ,si pnp,AJ,si | *22-76 24 24 *24 *24 24 | 250 200 75 150 250 | 185 85 85 150 175 | 1.66 4 2 1.33 1.7 | *60 25 25 45 100 | 25 200 50 50 100 | 0.004 16 16 0.5 .05 | 11 - 15 20 - | *4 40 40 •2 7 | 13 0.8 0.8 15 1 | |
| | 2N381 2N44 2N229 2N330A 2N460 | SY GE SY SSD TS | pnp,AJ,ge pnp,AJ,ge npn,AJ,ge pnp,AJ,si pnp,AJ,ge | 24-45 25 25 25 25 25 | 200 240 180 385 200 | 85 100 85 2.85 100 | 3.3 4 3 0.3 | *25 45 10 30 *45 | 200 300 - 50 400 | 20 16 100 .005 | 6 8 | 40 | 10 1 600 0.5 | TI MIL, GI NA 71 |
| A 11 | 2N564 2N592 2N726 2N1265 2N1441 | IND GI TI SY NA | pnp, AJ, ge pnp, AJ, ge pnp, DM, si pnp, AJ, ge pnp, AJ, si | 25 25 25 25 25 25 | 150 150 1w 50 400 | 85 100 175 85 200 | 2.5 0.2 - 0.9 2.28 | 30 *20 25 *10 50 | 300 - 50 100 100 | 3 5 .007 100 0.01 | 12 116 - - 12 | 20 35 - - 25 | 0.8 0.4 - 600 1 | US,GI Bilateral, TI audio/med power |
| A 12 | 2N524A 2N1101 2N1102 2N34 2N35 | MO SY SY SY SY | pnp,AJ,ge npn,AJ,ge npn,AJ,ge pnp,AJ,ge npn,AJ,ge | 25-42 25-50 25-50 25-125 25-125 | 225 180 180 150 180 | 100 75 75 75 75 85 | 3 3.6 3.6 3 | *45 *20 *40 *40 *40 | 500 100 100 100 100 | 10 50 50 50 50 | 15 - - - | 40 | 5 0.01 0.01 0.01 0.01 | "Meg-A-Life" RCA Driver, TI Driver, TI |
| N.12 | 2N306 2N464 2N1474 2N531 CK65B | SY MO SSD GI RA | npn,AJ,ge pnp,AJ,si pnp,AJ,si | 25-125 26 26 27 27 | 180 200 250 100 75 | 85 100 175 85 85 | 3 2.5 1.7 2 1.25 | *20 *45 60 *15 45 | 100 100 100 - 100 | 100 6 .005 3 10 | - - 14 - | - 7 14 | 0.6 0.7 1 | IND, RA, US, GI, TI NA *matched pnp, npn Sub min |
| A 13 | CK65C 2N936 2N244 2N757A 2N279 | RA SSD TI TR AMP | pnp,AJ,ge pnp,AJ,si npn,GJ,si N-M pnp,AJ,ge | 27 28 28-90 29 30 | 75 385 750 500 125 | 85 160 160 - 75 | 1.25 2.85 6 0.30 2.5 | 45 35 60 60 •30 | 100 50 60 100 | 10 .005 1 0.1 110 | - 18 - - 10 | 70 - 5 - | - .3 8 100 0.15 | Sub min NA NA |
| A 13 | 2N524 2N594 2N939 2N1446 2N1474A | SY GI SSD IND SSD | pnp,AJ,ge npn,AJ,ge pnp,AJ,si pnp,AJ,ge pnp,AJ,si | 30 30 30 30 30 | 225 150 250 200 250 | 100 85 175 85 175 | 3 1.67 1.7 3.33 1.7 | *45 *20 35 45 60 | 500 - 100 400 100 | 10 2 .001 5 .005 | 16 - 6 - | - 15 7 20 7 | 2 2 2 2 2 2 | GE, MO, TI Bilateral, TI |
| A 14 | 2N1654 2N1656 2N2428 2N331 2N727 | RA RA AMP MO TI | pnp,AJ,si pnp,AJ,si pnp,ge pnp,AJ,ge pnp,PE,si | 30 30 30 30-70 *30-*90 | 250 250 165 75 1000 | 160 160 75 85 | 0.54 0.54 0.3 1.2 | *80 *125 *32 *30 20 | 50 50 100 - 50 | .005 5 - 1 | 18 18 4 20 | 70 70 - 50 | .2 .2 1.7 .4 | |
| | 2N1372 2N1373 2N2392 2N2711 ST1242 | SY SY TI GE TR | pnp, AJ, ge pnp, AJ, ge P, si npn, P, si N-GJ | 30-90 30-90 *30-*90 *30-*90 30 | 150 150 1000 200 200 | 100 100 - 100 - | 2 2 2.67 0.80 | *25 *45 20 *18 *40 | 200 200 30 100 50 | 100 100 - 0.05µ2a 75 | - - 2.8 - | - - - 9 4 | - - - 10 | KF, TI KF, TI |

May 24, 1963 T5

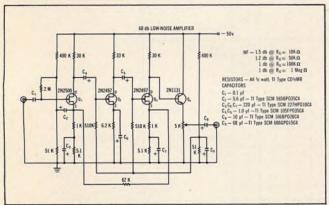
Now 1~ to 14gc low-noise



Low-noise devices for your

SUBAUDIO CIRCUITS

Texas Instruments 2N2497-2500 series field-effect transistors give the design engineer extremely low-noise characteristics — as low as 5 db at 10 cycles. They are ideal for such low-frequency equipment as null-detection apparatus, medical research equipment, oscillographic and magnetic tape recorders, oscilloscopes and all types of low-level transducers. ■ The circuit below illustrates how Texas Instruments 2N2500 silicon field-effect transistors are used to achieve low-noise, low-frequency operation.



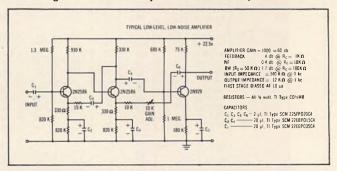
This circuit gives you a maximum voltage gain of 60 db ± 0.5 db from -55° C to 125° C with built-in gain adjustment. You also get good low-frequency response and stable circuit operation. Write for your technical information file on low-noise Tl devices for your subaudio applications.

TI cannot assume any responsibility for any circuits shown or represent that they are free from patent infringement.

Low-noise devices for your

AUDIO CIRCUITS

Now you can design the low-level, high-gain amplifier shown below with typical noise figure as low as 1 db. Advanced low-level planar technology of Texas Instruments 2N929 and 2N2586 transistors makes possible high gain at low current levels, plus the extremely low leakage currents necessary for true low-noise performance.

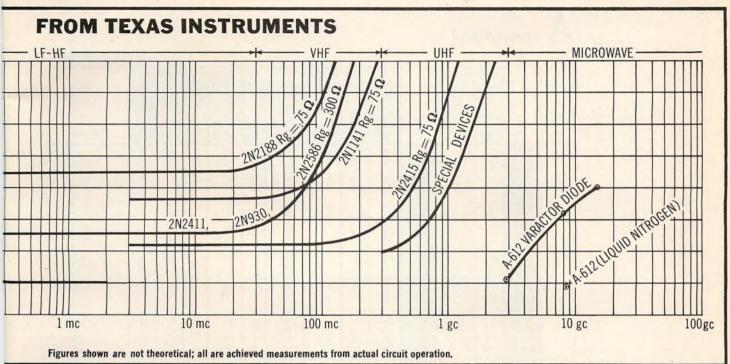


For high-impedance transducer applications, TI 2N930 and 2N2586 devices permit typical 1 db noise figure at emitter currents below 1 microampere, and generator resistances over 1 megohm. These special characteristics allow direct coupling of low-level, high-impedance sources... advantages previously available only with vacuum tubes and field-effect transistors. High gain at low levels plus very thin regions in these units combine to offer low power consumption and high radiation resistance to make the 2N930 and 2N2586 ideal for space applications. A technical information file on almost 50 TI low-noise devices for audio circuits is yours upon request.

SEMICONDUCTOR-COMPONENTS
DIVISION



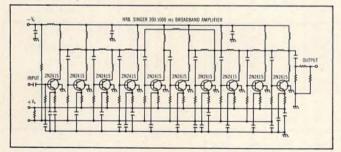
solid-state amplification



Low-noise devices for your

LF-UHF CIRCUITS

For your low-noise, high-frequency receiver and preamplifier applications, $71\ 2N2415$ germanium mesa transistors give you a typical noise figure of 2.4 db at 200 mc, maximum available gain of 15.5 db at 500 mc with a f_{MAX} of 3 gc. In the following circuit, HRB-Singer, Inc. utilizes 2N2415 transistors and "multiple feedback" techniques to achieve a uniform low noise figure, nominally 6 db, over the entire frequency range of 300 to 1000 mc with an average gain of 35 db. Unique design provides stable operation over a temperature range of -30° to $+70^{\circ}$ C and eliminates the need for RF tuning capacitors.



Another line of TI low-noise communications devices is the Dalmesa 2N2188 and TI363 series of germanium alloy diffused mesa transistors. These advanced units offer you ultra-high performance from dc to 100 mc, typical mid-frequency noise figures of less than 2 db, and increased high-frequency stability through guaranteed maximum output capacitance of 2.8 pf at 9 volts. ■ Investigate TI's wide selection of low-noise transistors for LF-UHF circuits by writing for a free fact file on these devices.

TEXAS INSTRUMENTS

I N C O R P O R A T E D 13500 N. CENTRAL EXPRESSWAY P. O. BOX 5012 • DALLAS 22, TEXAS Low-noise devices for your

MICROWAVE CIRCUITS

Now you can design microwave circuits for highest frequencies at lowest noise with the new GaAs Pill Varactor Diode from Texas Instruments. These new subminiature devices offer you minimum cutoff frequency of 90 gc to 150 gc at -2 volts with low junction capacitance - CJ @ 0 bias from 0.15 to 0.75 pf. Your production-line requirements for identical plug-in units are met through tight control of junction and package characteristics. These features offer you the lowest package capacitance and inductance in industry today — backed up with Tl varactor manufacturing capacity to meet your tightest production schedules. Tl GaAs Pill Varactor Diodes are particularly applicable to low-noise parametric amplifiers, harmonic generators, microwave switches, sub-harmonic oscillators, phase shifters and parametric limiters.

FOR FULL INFORMATION ...

... write for a fact-filled file of technical data on low-noise TI devices designed for application in your frequency range. Please address your card or letter to Department 605 and specify which of these four information files you desire.

1. SUBAUDIO
2. AUDIO
3. LF-UHF
4. MICROWAVE

Ask your authorized TI distributor about "Transistor Circuit Design," an informative new hardbound book for circuit designers authored by 32 TI engineers and published by McGraw-Hill.

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| 1 | | | | Yan | | MAX. RATINGS | | | CHARACTERISTICS | | | | CS | | |
|---|-----------------------|--|--------------------------------|---|---|-------------------------------------|---------------------------------|--------------------------------------|-----------------------------------|---------------------------------|---|-------------------------|---|-------------------------------|---|
| | Cross Index Key | Type No. | Mfr. | Туре | h _{fe} *hFE **G _m | P _c (mw) | т _і (°с) | mw/°C | V CEO *V CBO (v) | 1 C (ma) | l co (µa) | NF (db) | C _{oe} *C _{ob} (pf) | fae *fT **fab (mc) | Remarks |
| | | ST1243 2N2715 2N1432 2N1380 2N1381 | TR GE SY SY | N-GJ npn,P,si pnp,DD,ge pnp,AJ,ge pnp,AJ,ge | *30 *30-90 30-120 30-300 30-300 | 200 200 80 150 150 | 100 85 100 100 | 0.80 2.67 1.3 2 | *40 *18 *35 *15 *25 | 50 25 10 200 200 | 75 0.05µa 15 14 100 | 2.8 - - - | 4 *5 - - | 10 - 250 - - | T) Ti |
| | A 15 | 2N532 /N319 2N44A 2N525A 2N405 | GE GE MO RCA | pnp,AJ,ge pnp,A,ge pnp,AJ,ge pnp,AJ,ge | 32 34 34-65 34-65 35 | 100 225 240 225 150 | 85 85 100 71 | 2 4 3 | *15 20 *45 *20 | - 200 500 35 | 3 16 10 14 | 14 - 15 - | 14 25 40 •35 | 5.5 | * matched pnp, npn MO, TI "Meg-A-Life" |
| | | 2N406 2N734 2N738 2N926 2N928 | RCA TR TR NA NA | pnp,AJ,ge npn,MS,si npn,DM,si pnp,AJ,si pnp,AJ,si | 35 35 35 35 35 35 | 150 1.0 1w 150 150 | 71 175 175 200 200 | - - 2.5 2.5 | *20 *80 *125 50 70 | 35 50 35 - | 14 1 1 .005 | - 20 - - | *35 5 - 12 12 | - 50 - 0.8 0.8 | TO-18, NA NA |
| | A 16 | 2N1010 2N1564 2N1572 2N2617 BCZ11 | RCA TI TR AMP AMP | npn,AJ,ge npn,MS,si npn,DM,si pnp,si si | 35 35 35 35 35 35 | 20 1.2 1.2w 250 250 | 175 175 150 150 | - - 2 2 | *10 *80 *125 *-25 *25 | 2 50 50 50 50 | 10 1 1 0.001 0.001 | 5 20 - - 6 | 5 - - 50 | *2 50 - 3.0 3 | TO-5 TR, NA |
| | 4.17 | OC57 2N383 2N190 2N187A 2N119 | AMP SY GE GE TI | pnp,PADT,g pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,GR,si | e 35 35-110 36 36 36-90 | 10 200 75 200 150 | 55 85 85 85 175 | 3.3 2 4 1 | •7 •30 25 25 *30 | 10 200 50 200 25 | 1.5 20 16 16 2 | - 15 - 20 | - 40 40 - | 1.4 10 1 1 6 | TS.KF, TI TR, USN |
| | A 17 | 2N335 2N335A 2N759 2N759A 2N1152 | TI NA NA NA NA | npn,GR,si npn,MS,si npn,DM,si npn,DM,si npn,DM,si | 36-90 36-90 36-90 36-90 36-90 | 150 500 500 500 150 | 175 175 200 200 175 | 1 2.8 2.5 2.5 0.86 | 45 45 45 60 45 | 25 - - - 25 | 2 0.5 0.2 0.1 2 | 20 - - - - | - - - 7 | 11 - - - 1 | TR, GE, NA, RA, AMP GE, TI TR, TI |
| | | 2N533 2N1278 2N742 2N1009 2N1176 | GI TR NA SY BE | N·GJ npn,MS,si pnp,AJ,ge pnp,AJ,ge | 37 * 37 40 40 40 | 100 150 - 150 300 | 85 - 200 85 85 | 1.00 1.71 2.5 6.6 | *15 *40 60 *25 15 | - 25 100 20 300 | 3 - 0.1 1 10 | 14 | 14 5 5 - | - 15 200 - - | • matched pnp, npn, Tl Switch |
| | A 18 | 2N1176A 2N1176B 2N1191 2N1566 2N1678 | BE BE MO TI GI | pnp,AJ.ge pnp,AJ.ge pnp,AJ.ge npn,DM,si pnp,DR,ge | 40 40 40 40 40 | 300 300 200 1200 120 | 85 85 100 175 85 | 6.6 6.6 2.7 8.0 2 | 40 60 •40 60 •60 | 300 300 200 50 | 10 15 2 1µ2 3 | - 10 5 - | - - *5 3 | - 1.5 150 - | TI Trixie Driver |
| | A 19 | BCY11 BCY12 CK4A TR-650 TR-653 | AMP AMP RA IND IND | si si pnp, AJ, ge pnp, AJ, ge pnp, AJ, ge | 40 40 40 40 40 | 312 312 80 150 | 150 150 85 85 85 | 2.5 2.5 - 2.5 2.5 2.5 | *60 *32 24 45 30 | 500 500 100 400 400 | 0.02 0.02 2 1.0 1.0 | 7 7 - 10 10 | 90 90 14 20 20 | 1.5 2 6 2 2 | micromin RF switch 2N650 |
| | V 13 | 2N382 TNT840 2N480A 2N929 2N2387 | SY TR TR TI TI | pnp,AJ,ge npn,MESA,s npn,DG,si npn,PL,si n pn,PL,si | | 200 100amb 200 600 1200 | 85 175 200 175 175 | 3.3 0.66 - 4.0 8.0 | *25 45 45 45 45 | 200 50 25 30 30 | 20 0.1µa 0.02 0.01µa 0.01µa | - 20 2 2 | - *8 7 *6 6 | 10 50 11 60 60 | KF, TI TI |
| | A 20 | ST1244 2N43 OC79 2N104 2N215 | TR GE AMP RCA RCA | npn,GJ,si pnp,AJ,ge pnp,PADT, pnp,AJ,ge pnp,AJ,ge | *40-125 42 ge 42 44 44 | 200 240 550 150 | 150 100 75 - | 1.33 4 - - - | 20 45 • 26 30 30 | 50 300 300 *10 *10 | 0.8 16 10 - 10 | 20 6 - 12 - | *2 40 - *.7 12 | 20 1.3 1.2 50 *.7 | ті |
| | | 2N525 2N1924 2N322 2N465 2N595 | GE GE GE IND GI | pnp, AJ, ge pnp, AJ, ge pnp, AJ, ge pnp, AJ, ge npn, AJ, ge | 44 44 45 45 45 | 225 225 140 150 150 | 100 85 85 85 85 | 4 - 4 2.5 1.67 | *45 40 18 *45 *20 | 500 500 100 200 | 10 4 16 6 2 | 6 - - 15 16 | 25 - 25 20 15 | 2.5 - 2.0 0.8 4 | MO, SY, TI MO, TI Driver, MO, TI MO, RA, US, GI, SY, TI Bilateral, TI |
| | A 21 | 2N924 2N1098 2N1145 2N1372 2N1373 | NA GE GE TI | pnp,AJ,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 45 45 45 45 45 | 150 140 140 250 250 | 200 85 85 100 100 | 2.5 4 4 3.3 3.3 | 40 16 16 25 45 | 100 100 200 200 | .005 16 16 3 3 | - - 7 7 | 12 25 40 - | 0.8 - - 1.5 1.5 | Driver, TI Driver KF KF |
| | A 21 | 2N1442 2N1447 2N1451 2N1477 CK65A | NA IND IND SSD RA | pnp,AJ,si, pnp,AJ,ge pnp,AJ,ge pnp,AJ,si pnp,AJ,ge | 45 45 45 45 45 | 400 200 200 250 80 | 200 85 85 175 85 | 2.28 3.3 3.3 1.7 | 50 45 45 100 24 | 100 400 400 100 100 | 0.01 5 7.5 2 2 | 12 6 9 - 22 | 25 20 20 7 - | 1 3 1.5 1 1.0 | audio/med. power micromin |

| | | Min | | | | MAX. | RATINGS | | | СН | ARACT | ERISTI | CS | |
|-----------------------|--|-------------------------------|---|--|--|---------------------------------|---|----------------------------------|---------------------------------|---|---------------------------|------------------------------|---------------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | hfe *hFE **G _m | P _c (mw) | T _i | mw/°C | V CEO *V CBO (v) | 1 C (ma) | l CO (µa) | NF (db) | Coe *Cob (pf) | fae *fT **fab (mc) | Remarks |
| | TR721 2N762 2N2676 2N280 OC71N | IND NA GE AMP AMP | pnp,AJ,ge npn,DM,si npn,GD,si pnp,AJ,ge pnp,ge | 45 45-150 *45-290 47 47 | 150 500 250 125 110 | 2.5 200 185 75 75 | 3 2.5 1.66 2.5 0.45 | 30 45 *60 *20 *-30 | 200 - 25 10 10 | 10 0.2 0.004 150 | 15 - 11 10 10 | 20 - *4 - | 3 - 15 0.1 | |
| A 22 | TR320 2N650 2N650A 2N653 2N1186 | MO MO MO MO MO | pnp, AJ, ge pnp, AJ, ge pnp, AJ, ge pnp, AJ, ge pnp, AJ, ge | 48 49 49 49 49 | 150 200 200 200 200 200 | 85 100 100 100 100 | 3 2.7 2.8 2.8 2.7 | 25 *45 *45 *30 *60 | 100 500 500 250 500 | 10 3 10 5 5 | 5 15 10 5 | 25 - 25 20 - | 2.5 1.5 1.5 1.5 1.5 | 2N320 US, TI Mega life, TI SY, US |
| | 2N43A* 2N320 2N331 2N363 2N422 | GI GE BE IND RA | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,FA,ge | 50 50 50 50 50 | 150 225 200 150 150 | 100 85 85 85 85 | 2 4 - 2.5 - | *45 20 *30 30 | 200 200 200 200 100 | 10 16 16 10 6 | 18 - 9 - 6.5 | 40 25 - - | 3.5 2.5 1.16 - | *MIL, GE, TI MO, TI IND, MO, GI RA, US |
| A 23 | 2N917 2N918 2N941 2N942 2N1173 | FA FA SSD SSD WE | npn,DP,si npn,DP,si pnp,AJ,si pnp,AJ,si npn,A,ge | *50 *50 50 50 50 | 300 300 250 250 | 200 200 175 175 100 | 1.71 1.71 1.7 1.7 1.7 3.3 | 15 15 8 8 *20 | 50 50 200 | 0.0004 0.0004 .001 .001 150 | - - - 3.0 | *1.0 *1.0 7 7 25 | *800 *900 16 10 | MO TO-18 |
| A 24 | 2N1174 2N1273 2N1274 2N1383 2N1589 | WE TI TI TI TR | pnp,A,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge N-G-5 | 50 50 50 50 50 | 150 150 200 150 | 100 85 85 85 - | 3.3 2.5 2.5 3.3 1.00 | *20 *15 *25 *25 *15 | 200 150 150 200 25 | 100 3 3 14 | 3.0 6.5 6.5 7.0 | 25 - - - - 5 | - - 1.5 5 | |
| A 24 | 2N1590 2N1591 2N1917 2N1918 2N2271 | TR TR SSD SSD SY | N-G-5 N-G-5 pnp,AJ,si pnp,AJ,si pnp,AJ,ge | 50 50 50 50 50 | 150 150 250 250 250 250 | - 175 175 100°C | 1.00 1.00 1.7 1.7 3.3 | *30 *60 8 8 *20 | 25 25 50 50 500 | - .001 .001 10 | 11111 | 5 5 7 7 - | 5 5 16 10 0.01 | KF KF |
| 4.05 | 2N2354 BCY10 TR-320 2N214 2N228 | SY AMP IND SY SY | npn,AJ,ge si pnp,AJ,ge npn,AJ,ge npn,AJ,ge | 50 50 50 50-100 50-100 | 180 312 150 180 180 | 85 150 85 85 85 | 3.0 2.5 2.5 3 | *20 *32 30 *40 *40 | 150 500 200 100 100 | 10 0.02 7.5 50 100 | 7 | 100 20 - | 1.5 2.5 0.01 0.01 | 2N320 Matched |
| A 25 | 2N241A 2N270 2N321 2N1059 2N408 | Y2 Y2 Y2 Y2 Y2 | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,AJ,ge pnp,AJ,ge | 50-100 50-100 50-100 50-100 50-135 | 200 150 200 180 150 | 85 85 85 75 85 | 3.3 2.5 3.3 3.6 2.5 | *30 *25 *25 *20 *20 | 200 75 200 100 70 | 16 12 16 50 14 | 101.00.00 | 11111 | 10 0,01 10 0,01 | ТІ |
| | 2N109 2N217 2N323 2N1374 2N1375 | Y2 Y2 Y2 Y2 Y2 | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 50-150 50-150 50-150 50-150 50-150 | 50 - 140 150 150 | 85 85 85 100 100 | 0.9 - 2.3 2 | *25 *25 *16 *25 *45 | 75 75 100 200 200 | 12 12 16 100 100 | 111111 | 11111 | - 10 800 - - | TI, KF TI,KF |
| A 26 | 2N526A 2N188A 2N191 2N758A CK22B | MO GE GE TR RA | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge N-M pnp,AJ,ge | 53-90 54 54 54 54 | 225 200 75 500 75 | 100 85 85 - 65 | 3 4 2 0.30 1.25 | *45 25 25 60 35 | 500 200 50 100 100 | 10 16 16 0.1 10 | 15 - 15 - 6.5 | 40 40 40 5 | 6.5 1.2 1.2 100 | "Meg-A-Life" Driver Submin. |
| A 07 | CK66B CK66C CK261 CK262 2N566 | RA RA RA RA IND | pnp,AJ,ge pnp,AJ,ge npn,AJ,ge npn,AJ,ge pnp,AJ,ge | 54 54 54 54 55 | 75 75 75 75 75 150 | 85 85 85 85 85 | 1,25 1,25 1,25 1,25 1,25 2,5 | 35 35 35 35 35 30 | 100 100 100 100 300 | 10 10 10 - | - - - 12 | - - - 20 | 11111 | Submin. Submin. Submin. Submin. US, GI |
| A 27 | 2N10S7 2N1144 CK27A OC58 2N596 | GE GE RA AMP GI | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,PADT,g npn,AJ,ge | 55 55 55 55 se 55 60 | 140 140 80 10 150 | 85 85 85 55 85 | 4 4 - - 1.67 | 16 16 15 •7 20 | 100 100 400 10 | 16 16 2 1.5 2 | - - - 16 | 25 40 14 - 15 | - 11 1.6 6 | Driver, TI Driver micromin RF switch Bilateral , TI |
| A 28 | 2N633 2N937 2N940 2N957 2N1475 | SSD FA SSD | pnp,AJ,ge pnp,AJ,si pnp,AJ,si npn,DD,si pnp,AJ,si | 60 60 60 *60 | 150 385 250 800 250 | 85 160 175 150 175 | 2.5 2.85 1.7 6.5 1.7 | 35 30 35 20 60 | 200 50 100 - | 10 .005 .001 1.0 .005 | - 18 - - - | 70 7 *4.0 | 0.8 0.5 2 *400 | RA, US NA |
| A 20 | OC60 TS602 TS604 AC107 2N220 | AMP TS TS AMP RCA | pnp,PADT,g pnp,AJ,ge pnp,AJ,ge pnp,gc pnp,AJ,ge | *60 *60 *60 60 65 | 10 200 200 80 20 | 55 100 100 75 | - - - 0.6 - | *7 *12 *20 *-15 *10 | 10 400 400 5 2 | 1.5 20 20 2.0 12 | - - 3 6 | 11111 | 1.6 - - 2 *0.85 | |

May 24, 1963

| | | | 200 | | MAX. RATINGS | | | | CHA | RACT | ERISTIC | ZS 2 | | |
|-----------------------|--|--------------------------------|---|---|---------------------------------------|--------------------------------|-----------------------------------|-----------------------------------|-----------------------------------|---------------------------------------|-------------------------------|----------------------------|--------------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | hfe *hFE **G _m | P _c (mw) | T _i | mw/°C | VCEO -VCBO (v) | 1 C (ma) | ι co (μα) | NF (db) | Coe *Cob (pf) | fae *fT **fab (mc) | Remarks |
| 4.20 | 2N175 2N398A 2N407 2N408 2N649 | RCA MO RCA RCA RCA | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,AJ,ge | 65 65 65 65 65 | 20 150 150 150 100 | - 100 71 71 - | - 2 - - - | *10 105 *20 *20 *20 | 2 200 70 70 50 | 12 12 14 14 14 | 6 | | *0.85 1 - - | GI, TI SY |
| A 29 | 2N759A 2N1448 2N1452 OC74 2N2043 | TR IND IND AMP MO | N·M pnp,AJ,ge pnp,AJ,ge pnp,PADT, pnp,AJ,ge | 65 65 65 65 65-100 | 500 200 200 550 200 | 85 85 75 100 | 0.30 3.33 3.33 - 2.67 | 60 45 45 20 105 | 1 00 400 400 300 2 00 | 0.1 5 7.5 10 25 | 6 9 - | 5 20 20 - 25 | 100 4 2.2 1.5 0.75 | ті |
| | 2N2043A 2N323 2N281 2N282 2N361 | MO GE AMP AMP IND | pnp.AJ.ge pnp.AJ.ge pnp.PADT. pnp.ge pnp.AJ.ge | 65-100 68 10 70 70 70 | 200 140 165 167 150 | 100 85 75 75 85 | 2.67 4 - 2.5 | 105 18 *32 *-32 45 | 200 100 250 250 200 | 25 16 4.5 4.5 10 | 11111 | 25 25 - - | 0.75 2.5 0.9 0.9 | "Meg-A-Life", TI Driver, MO RA, US |
| A 30 | 2N591 2N647 2N735 2N739 2N1352 | RCA RCA TI TI IND | pnp,AJ,ge npn,AJ,ge npn,MS,si npn,DM,si npn,AJ,ge | 70 70 70 70 70 | 100 100 1.0 1w 150 | - 175 175 85 | - - - - 2.5 | *32 *25 80 *125 30 | 40 50 50 70 200 | 7 14 1 1 2.5 | - 20 - - | - 5 - 18 | 0.7 - 50 - 2.5 | SY TO-18, TR, NA NA KF |
| | 2N1565 2N1573 2N213 2N1251 TR-383 | TI TI SY SY IND | npn,MS,si npn,DM,si npn,AJ,ge npn,AJ,ge npn,AJ,ge | 70 70 70-250 70-250 72 | 1.2 1.2w 150 150 200 | 175 175 85 85 85 | 2.3 2.5 3.33 | *80 *125 *40 *20 25 | 50 50 100 100 200 | 1 1 50 50 7.5 | 20 - - - - | 5 - - 20 | 50 - 0.01 7.5 1.8 | NA 2N383 |
| A 31 | 2N527A 2N241 2N109 2N192 2N217 | MO GE RCA GE RCA | ag, LA, qnq ag, LA, qnq ag, LA, qnq ag, LA, qnq ag, LA, qnq | 72-121 73 75 75 75 75 | 225 100 150 75 150 | 100 85 - 85 - | 3 3 - 2 - | *45 25 25 25 25 25 | 500 200 70 50 70 | 10 16 14 16 14 | 15 - - 15 - | 40 40 - 40 - | 7.0 1.3 - 1.5 | "Meg-A-Life" SO |
| | 2N361 2N1192 2N1443 2N1672 C620 | US MO NA GI CT | pnp,AJ,ge pnp,AJ,ge pnp,AJ,si pnp,AJ,ge pnp,AJ,si | *75 75 75 75 75 **75 | 150 200 400 120 250 | 85 100 200 85 160 | 2.7 2.28 0.5 2 | 30 *40 50 *40 10 | 200 200 100 - 50 | 10 2 0.01 5 | 13 10 12 - 3.5 | - 25 - 15 | 1.5 2 1 - | TI audio/med. power Trixie driver Ig FE |
| A 32 | C622 C624 GT-74 GT-81 TR-323 | CT CT GI GI IND | iz, LA, qnq iz, LA, qnq eg, LA, qnq eg, LA, qnq eg, LA, qnq | **75 **75 75 75 75 | 250 250 150 150 150 | 160 160 100 100 85 | 2 2 2 2 2 2.5 | 10 10 25 25 25 16 | 50 50 - 200 | - 5 5 7.5 | 1.5 0.4 6 16 | 15 15 35 35 20 | - - - - 2.5 | tg FE 1g FE 2N323 |
| | 2N1376 2N1431 2N2712 2N2716 2N1950 | SY SY GE GE IND | pnp,AJ,ge npn,AJ,ge npn,P,si npn,P,si npn,DM,si | 75-150 75-150 *75-225 75-225 75-250 | 150 180 200 200 600 | 100 75 100 100 175 | 2 3.6 2.67 2.67 4 | *25 *25 *18 *18 20 | 200 100 100 25 | 100 50 0.05µa 0.05µa 0.01 | | - *9 5 | 10 | ТІ |
| A 33 | 2N1951 2N1952 2N1279 2N120 2N336 | IND IND TR TI TI | npn,DM,si npn,DM,si N-GJ npn,GR,si npn,GR,si | 75-250 75-250 *76 76-333 76-333 | 600 600 150 150 150 | 175 175 - 175 175 | 4 4 1.00 1 | 30 40 *40 *30 45 | - 25 25 25 25 | 0.01 0.01 - 2 2 | - - 20 20 | - 5 - | - 15 7 13 | TR TR, GE, NA, RA, AMP |
| | 2N336A 2N760 2N760A 2N1153 2N321 | NA NA NA GE | npn,MS,si npn,DM,si npn,DM,si npn,DM,si npn,AJ,ge | 76-333 76-333 76-333 76-333 80 | 500 500 500 150 225 | 175 200 200 175 85 | 2.8 2.5 2.5 0.86 4 | 45 45 60 45 20 | - - 25 200 | 0.5 0.2 0.1 2 16 | 1111 | - - 7 25 | - - 1 3 | TI TI TI, TR TR, TI MO |
| A 34 | 2N527 2N651 2N651A 2N654 2N780 | SY MO MO MO TI | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,DM,si | 80 80 80 80 80 | 225 200 200 200 200 1w | 85 100 100 100 175 | 3.7 2.8 2.8 2.8 | *45 *45 *45 *30 45 | 500 500 500 250 50 | 10 3 10 5 | 5 15 10 | 111111 | 3.3 2 2.0 2.0 | TS, TI US, SY, TI TI US, TI/ |
| A 25 | 2N1187 2N1370 2N1371 2N1374 2N1375 | MO TI TI TI | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 80 80 80 80 80 | 200 150 150 250 250 | 100 85 85 100 100 | 2.7 2.5 2.5 3.3 3.3 | *60 25 25 25 25 45 | 500 150 150 200 200 | 5 3 3 3 3 | 5 6.5 6.5 6.5 6.5 | 31111 | 2 2.0 2.0 2 2 | GI, KF KF KF KF |
| A 35 | 2N1382 2N1449 2N1926 CK28A OC59 | TI IND GE RA AMP | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,PADT, | 80 80 80 80 80 | 200 200 225 80 10 | 85 85 85 85 55 | 3.33 - - - | 25 45 40 12 *7 | 200 400 500 400 10 | 14 5 4 80 1.5 | 6.5 6 - - - | 20 - 14 | 2 5 - 17 2.2 | MO micromin RF switch |

SHOCKLEY SEMICONDUCTOR DEVICES

TYPE E 4-LAYER DIODES

1-N SERIES

| | Switching Voltage (V_s) in volts | | | urrent (I _b) liamps | | | y Voltage (V _s) volts | Holding Current (I _b) in milliamps | |
|--------|--------------------------------------|--------------|--------|------------------------------------|--------|----------|--------------------------------------|---|---------------|
| Type | 25°C | -40° to 85°C | 25°C | -40°C | Туре | 25°C | -40° to 85°C | 25°C | 85°C |
| 1N3831 | 20±4 | 14-25 | 0.5-15 | 40 max | 1N3839 | 20±4 | 14-25 | 14-50 | 5 min |
| 1N3832 | 25±4 | 19-30 | 0.5-15 | 40 max | 1N3840 | 25 ± 4 | 19-30 | 14-50 | 5 min |
| 1N3833 | 30 ± 4 | 23-36 | 0.5-15 | 40 max | 1N3841 | 30 ± 4 | 23–36 | 14-50 | 5 mi n |
| 1N3834 | 35±4 | 28-41 | 0.5-15 | 40 max | 1N3842 | 35 ± 4 | 28-41 | 14-50 | 5 min |
| 1N3835 | 40±4 | 32-46 | 0.5-15 | 40 max | 1N3843 | 40 ± 4 | 32–46 | 14-50 | 5 min |
| 1N3836 | 45±4 | 37-51 | 0.5-15 | 40 max | 1N3844 | 45 ± 4 | 37-51 | 14-50 | 5 min |
| 1N3837 | 50±4 | 41-57 | 0.5-15 | 40 max | 1N3845 | 50 ± 4 | 41–57 | 14-50 | 5 min |
| 1N3838 | 100±10 | 80–115 | 0.5–15 | 40 max | 1N3846 | 100 ± 10 | 80-115 | 14-50 | 5 min |

| COMMER | CIAL SERIES | | MIL-LINE | SERIES | | | SERIES A (BROAD SPEC) | | | |
|----------|---|--|-----------|--------------|--|--|-----------------------|--|--|--|
| Туре | Switching Voltage (V _s) in volts | Holding Current (I _b) in milliamps | Туре | i | ng Voltage (V _s) n volts —60° to 125°C | Holding Current (I _b) in milliamps | Туре | Switching Voltage (V _s) in volts | Holding Current (I _h) in milliamps | |
| 4E20-8 | 20±4 | 1–15 | 4E20M-8 | 20±4 | 14-25 | 1-15 | 4E20A | 20 ± 6 | 0.5-60 | |
| 4E20-28 | 20±4 | 14-45 | 4E20M-28 | 20 ± 4 | 14-25 | 14–45 | 4E30A | 30 ± 6 | 0.5–60 | |
| 4E30-8 | 30 ± 4 | 1-15 | 4E30M-8 | 30 ± 4 | 23-36 | 1-15 | 4E40A | 40 ± 6 | 0.5–60 | |
| 4E30-28 | 30 ± 4 | 14-45 | 4E30M-28 | 30 ± 4 | 23-36 | 14-45 | 4E50A | 50±6 | 0.5-60 | |
| 4E40-8 | 40 ± 4 | 1-15 | 4E40M-8 | 40 ± 4 | 32-46 | 1-15 | | | | |
| 4E40-28 | 40 ± 4 | 14-45 | 4E40M-28 | 40±4 | 32-46 | 14-45 | | | | |
| 4E50-8 | 50±4 | 1–15 | 4E50M-8 | 50 ± 4 | 41-57 | 1-15 | | | | |
| 4E50-28 | 50±4 | 14-45 | 4E50M-28 | 50±4 | 41-57 | 14-45 | | | | |
| 4E100-8 | 100 ± 10 | 1-15 | 4E100M-8 | 100 ± 10 | 80-115 | 1–15 | | | | |
| 4E100-28 | 100±10 | 14-45 | 4E100M-28 | 100 ± 10 | 80-115 | 14-45 | | | | |
| 4E200-8 | 200 ± 20 | 1-15 | 4E200M-8 | 200 ± 20 | 160-230 | 1-15 | | | | |
| 4E200-28 | 200 ± 20 | 14-45 | 4E200M-28 | 200 ± 20 | 160-230 | 14-45 | | | | |

1

TYPE J 4-LAYER DIODES

COMMERCIAL SERIES

MIL-LINE SERIES for extended temperature ranges

| Туре | Switching Voltage (V _s) in volts | Holding Current (I _h) in milliamps | Туре | Holding Current (I _h) in milliamps | | |
|----------|---|--|-----------|---|---------|------|
| 4J50-5 | 50±5 | 1-10 | 4J50M-5 | 50±5 | 41-57 | 1-10 |
| 4J50-25 | 50±5 | 9-45 | 4J50M-25 | 50 ± 5 | 41-57 | 9–45 |
| 4J100-5 | 100 ± 10 | 1-10 | 4J100M-5 | 100 ± 10 | 80-115 | 1-10 |
| 4J100-25 | 100 ± 10 | 9-45 | 4J100M-25 | 100 ± 10 | 80-115 | 9–45 |
| 4J200-5 | 200 ± 20 | 1-10 | 4J200M-5 | 200 ± 20 | 160-230 | 1-10 |
| 4J200-25 | 200 ± 20 | 9-45 | 4J200M-25 | 200 ± 20 | 160-230 | 9–45 |



TYPE G 4-LAYER DIODES

COMMERCIAL SERIES

MIL-LINE SERIES for extended temperature ranges

| Туре | Switching Voltage (Vs) in volts | Holding Current (I _h) in milliamps | Туре | Switching \in v in v 25°C | /oltage (V _s) rolts 60° to 105°C | Holding Current (I _h) in milliamps |
|-------|---------------------------------|--|--------|---------------------------------|--|--|
| 4G50 | 50±5 | 1–50 | 4G50M | 50 ± 5 | 41–57 | 1-50 |
| 4G100 | 100±10 | 1–50 | 4G100M | 100 ± 10 | 80–115 | 1-50 |
| 4G200 | 200±20 | 1–50 | 4G200M | 200 ± 20 | 160–230 | 1-50 |



New! NPN HIGH FREQUENCY SILICON POWER TRANSISTOR

MAXIMUM RATINGS at 25°C base temperature unless otherwise stated

CHARACTERISTICS at 25°C unless otherwise stated

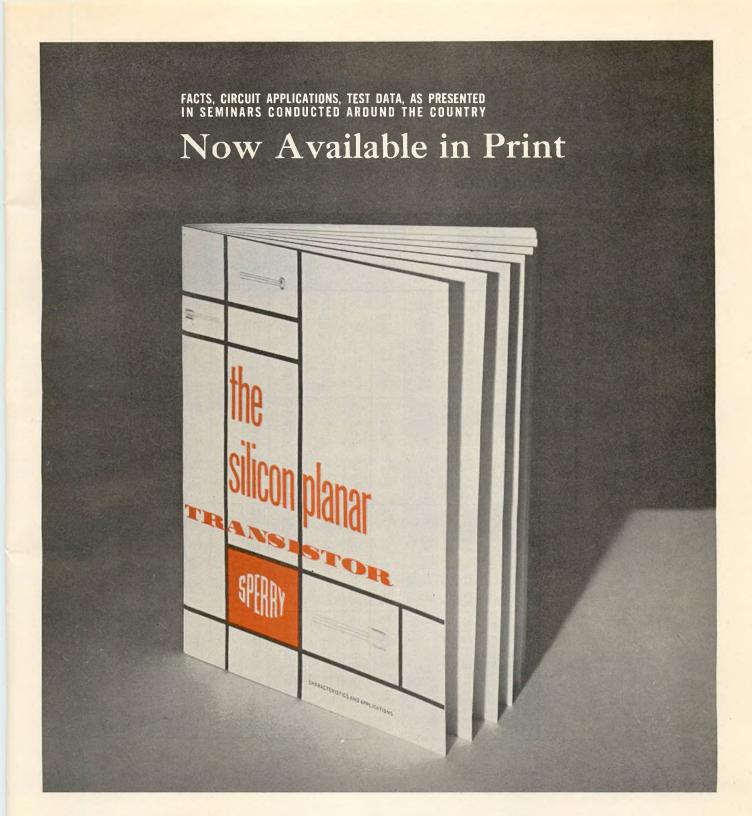
| | 3TX002 | 3TX003 | 3TX004 | | Condition | 3TX002 | 3TX003 | 3TX004 |
|-----------------------|--------------|--------------|--------------|--------------------|---------------------|--------|--------|--------|
| BVCBO | 100 V | 100 V | 60 V | F _T min | 10 V, 2.5 A | 150 MC | 150 MC | 150 MC |
| 1c | 5 A | 5 A | 5 A | Beta min | 5 V, 5 A | 30 | 10 | 10 |
| PAVERAGE | 60 W | 45 W | 45 W | VCE max | 5 A, 0.5 A | 1V | 2V | 3V |
| Rт | 2.5°C/W | 3.3°C/W | 3.3°C/W | ICBO max | 150°C 3TX002 - 80 V | 10 MA | 10 MA | 10 MA |
| Temperature-Storage | −65 to 200°C | -65 to 200°C | −65 to 200°C | | 3TX003 - 80 V | 10 MA | 10 MA | 10 MA |
| Temperature-Operating | −65 to 175°C | -65 to 175°C | −65 to 175°C | | 3TX004 - 50 V | 10 MA | 10 MA | 10 MA |

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| | | B | | | | MAX. | RATINGS | | | CHA | RACT | ERISTI | cs | |
|-----------------------|--|---------------------------------|---|--|--|---------------------------------------|-----------------------------------|---------------------------------|--------------------------------|--------------------------------------|------------------------------|----------------------------|---------------------------------------|---|
| Cross Index Key | Type Na. | Mfr. | Туре | ^h f., * ^h F E ** G _n | P _c (mw) | T _i | mw/°C | V CEO *V CBO (v) | l C (ma) | ا (س) | NF (db) | Coe *Cob (pf) | fae *fT **fab (mc) | Remarks |
| A 20 | TR-321 2N543A 2N736A 2N1566A TNT841 | IND TR TI TI TR | pnp,AJ,ge npn,DG,si M,si M,si npn,MESA,si | 80-201 80-201 80-201 80-331 | 150 200 1000 1200 100amb | 85 200 - 175 | 2.5 - - - 0.66 | 30 45 80 80 45 | 2 00 25 100 100 50 | 7.5 0.02 - - 0.1µa | 20 - - | 20 7 - - *8 | 3.1 15 - - 50 | 2N 321 |
| A 36 | 2N2648 2N527 2N324 2N466 2N1247 | GI GE GE MO TI | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,PL,si | 80-500 81 85 90 *90 | 250 225 140 200 600 | 100 100 85 100 175 | 3.3 4 4 2.5 4.0 | *35 *45 18 *35 6 | 1 50 100 100 30 | 3µ2 10 16 6 0.005µ2 | - 6 - 15 4 | *18 25 25 - 7 | *10 3.3 3 1 60 | MO Driver , MO, TI US, GI, RA, SY, TI |
| | 2N1706 2N1707 CK66A OC75 OC75N | TS TS RA AMP AMP | - pnp,AJ,ge pnp.AJ,ge pnp,ge | 90 90 90 90 90 | 200 200 80 125 110 | 100 100 85 75 75 | - - 0.45 | *25 *30 20 *30 *-30 | 400 400 100 50 10 | 10 15 2 5 4.5 | - 22 - 15 | 11111 | 3 3 1.2 0.75 | TI TI micromin |
| A 37 | 2N2171 2N1376 2N1377 2N2375 2N207 | TS TI TI PH PH | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | *90-*250 95 95 95 100 | 500 250 250 250 250 50 | 100 100 100 100 65 | 6.7 25 3.3 3.3 1.25 | *50 45 45 *35 *12 | 400 200 200 500 20 | 10 7 3 2 4 | 3.5 5.5 5.5 - 5 | *20 40 - *14 - | **7.5 2 2 *15 **2 | KF KF Output |
| | 2N207A 2N207B 2N360 2N362 2N362 2N534 | PH PH RA IND PH | pnp.AJ.ge pnp.AJ.ge pnp.AJ.ge pnp.AJ.ge pnp.AJ.ge | 100 100 100 100 100 | 50 50 150 150 25 | 65 65 85 85 65 | 1.25 1.25 2.5 2.5 | *12 *12 20 20 *50 | 20 20 400 100 25 | 4 4 10 200 8 | 2 2 - - | 11111 | **2 **2 1,2 - - | IND, US RA, US |
| A 38 | 2N535 2N535A 2N535B 2N568 2N632 | PH PH PH IND IND | ag, LA, qnq ag, LA, qnq ag, LA, qnq ag, LA, qnq ag, LA, qnq | 100 100 100 100 100 | 50 50 50 150 150 | 85 85 85 85 85 | - - 2:5 2.5 | *20 *20 *20 30 30 | 20 20 20 300 200 | 6 6 6 3 10 | 10 5 0 12 | - - - 20 - | **2 **2 **2 1.5 | US, GI RA, US, GI |
| | 2N736 2N740 2N1380 2N1381 C621 | TI TI TI TI CT | npn,MS,si npn,DM,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,si | 100 100 100 100 100 **1)0 | 1.0 1w 250 250 250 | 175 175 100 100 160 | - 3,3 3,3 2 | *80 *125 12 25 10 | 50 100 200 200 50 | 1 1 3 3 | 20 - 5.5 5.5 3.5 | 5 - 40 40 15 | 50 - 2 2 | TO-18, TR, FA, NA TR, NA |
| A 39 | C623 C625 2N1574 TR383 4JX1A547 | CT CT TI IND GE | pnp,AJ,si sa,LA,qnq is,DM,nqn gg,LA,qnq gg,LA,qnq | **100 **100 10(10(*1(0-*200 | 250 250 1.2w 150 150 | 160 160 175 85 75 | 2 2 - 3 3.0 | 10 10 *125 25 *-20 | 50 50 50 200 100 | - 1 10 6µа | 1.5 0.4 - 6 | 15 15 - 50 *12 | - - 1.8 *10 | Ig FE Ig FE TR 2N383 |
| | 2N213A 2N930 2N1944 2N1945 2N1946 | SY TI IND IND IND | npn,AJ,ge npn,PL,si npn,DM,si npn,DM,si npn,DM,si | 101-250 *1 00 300 10 +300 10 +300 10 +300 10 +300 | 180 600 600 600 600 | 85 175 175 175 175 | 2.5 4.0 4 4 4 | *40 45 20 30 40 | 100 30 - - - | 50 0.01μα 0.01 0.01 0.01 | 2 - | *6 | 10 60 - - | |
| A 40 | 2N1947 2N1948 2N1949 2N2388 CK67B | IND IND IND TI RA | npn,DM,si npn,DM,si npn,DM,si n pn,PL,si pnp,AJ,ge | 10)-300 10)-300 10)-300 *:00-300 1(8 | 600 600 600 1200 75 | 175 175 175 175 175 85 | 4 4 8.0 1.25 | 20 30 40 45 35 | 0.01 - - 30 100 | 0.01 0.01 0.01µa 10 | - - 2 - | - - *6 - | - - 60 - | Submin. |
| A 43 | CK67C 2N265 2N1705 GT-109 2N508 | RA GE TS GI GE | pnp,AJ,ge pnp,AJ,ge - pnp,AJ,ge pnp,AJ,ge | 1(8 1 0 1 0 1 0 1 2 | 75 75 200 150 140 | 85 85 100 100 85 | 1.25 2 - 2 4 | 35 25 *18 *25 18 | 100 50 400 - 100 | 10 16 10 6 16 | 15 - 16 - | 40 - 35 25 | 1.5 4 - 3.5 | Submin. Driver T! Driver, MO, T1 |
| A 41 | 2N1018 2N2431 ST1290 2N2586 2N2430 | KF AMP TR TI AMP | pnp,AJ,ge pnp.ge N-GJ npn,PL,si npn,ge | 1 10 120 120 *120-360 125 | 80 165 200 600 280 | 85 75 - 175 90 | 3.3 0.80 4.0 3.3 | 8 *32 20 45 *32 | 400 150 50 30 30 | 2 10 75 0.002μα – | - - 1.5 - | 14 - 4 *6 - | 25 1.7 10 60 25 | micromin RF switch |
| A 42 | 2N2614 2N2706 2N2707 AC127 TR-508 | RCA AMP AMP AMP IND | pnp,AJ,ge pnp,ge np,ge npn,ge pnp,AJ,ge | 25 25 25 .25 .25 | 100 280 280 280 280 150 | 100 90 90 90 90 85 | 2.2 0.37 0.37 3.3 2.5 | *20 *-32 *32 *32 16 | 50 200 200 30 200 | 6.5 | - 4 4 - - | - - - - 20 | 10 2.5 2.5 2.5 2.5 3.5 | 2N508 |
| A 42 | 2N652 2N652A 2N655 2N1188 2N1248 | MO MO MO MO TI | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,PL,si | 130 130 130 130 *130 | 200 200 200 200 200 600 | 100 100 100 100 175 | 2.7 2.8 2.8 2.7 4.0 | *45 *45 *30 *60 6 | 500 500 250 500 30 | 3 10 5 5 0.010μa | 5 15 10 5 4 | - - - 7 | 2.5 2.5 2.5 2.5 60 | SY, US, TI T! US, TI |



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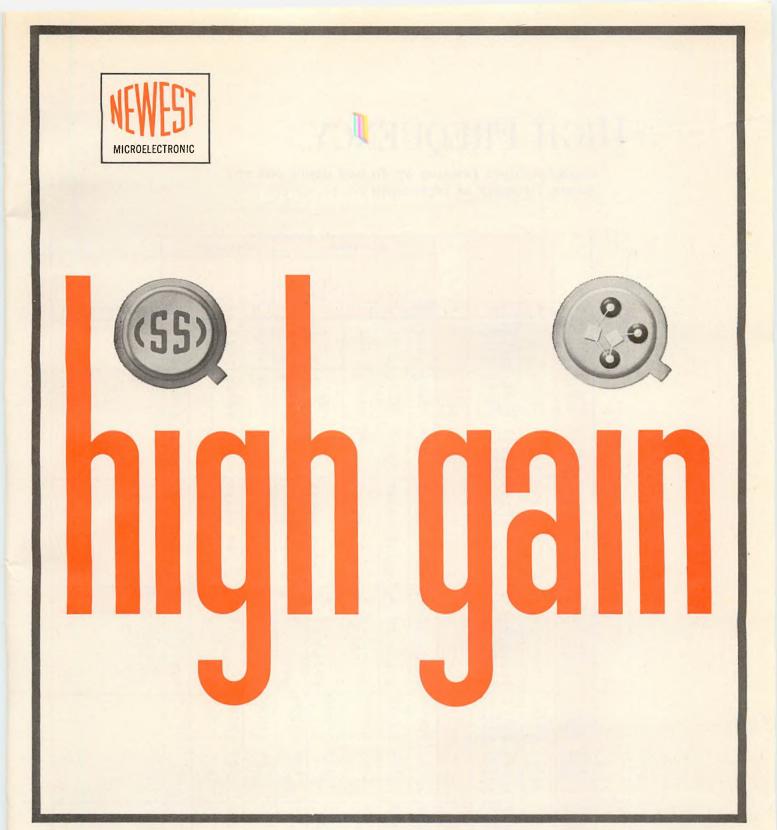
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| | | | | | | MAX. | RATINGS | ENAS | PAG | CHA | RACT | ERISTI | cs | |
|-----------------------|---|---------------------------------------|--|---|---|---|---|------------------------------------|--|-----------------------------|-----------------------------|------------------------------|-------------------------------|---|
| Cross Index Key | Type No. | Mfr. | Type | hfe *hFE **G _m | P _c (mw) | T _i (°c) | mw/°C | V CEO *V CBO (v) | l C (ma) | ا (س) | NF (db) | Coe *Cob | fae *fT **fab (mc) | Remarks |
| | 2N78 2N78 A 2N1592 2N1593 2N1594 | GE GE TR TR TR | npn,RG,ge npn,RG,ge N-G5 N-GJ N-GJ | *135 *135 140 140 140 | 65 65 150 150 150 | 85 85 - - - | 1.1 1.1 1.00 1.00 1.00 | 15v 20 •15 30 •60 | 20 20 25 25 25 25 | 0.7 0.7 - - | 12 12 - - | *3 3 5 5 | *9 9 5 5 | |
| A 43 | 2N359 2N570 2N631 2N1008A 2N1471 | RA IND IND SY IND | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 150 150 150 150 150 | 150 150 150 400 200 | 85 1T 85 85 85 | 2.5 2.5 2.5 6.6 3.33 | 45 30 25 • 40 12 | 200 300 200 300 200 | 10 3 10 500 2.5 | - 12 - - | 20 - - 18 | 1 2 1.2 25 5 | IND, US GI RA BE |
| | 2N1193 2N2613 C632 C633 2N467 | MO RCA CT CT MO | e, LA, qnq la, LA, qnq is, LA, qnq si, LA, qnq pnp, AJ, ge | 160 160 **175 **175 180 | 200 1 00 2 50 2 50 2 00 | 100 100 160 160 100 | 2.7 2.2 2 2 2.5 | *40 *13 250 350 *35 | 200 10 50 50 100 | 2 4 - - 6 | 10 5 - - | - 2 2 | 2.5 *10 - - 1.2 | TI tg FE tg FE IND, SY, US, TI |
| A 44 | CK67A 2N467 2N169A 2N572 2N1378 | RA GI GE IND TI | pnp,AJ,ge pnp,AJ,ge npn,RG,ge pnp,AJ,ge pnp,AJ,ge | 180 200 •200 200 200 200 | 80 120 75 150 250 | 85 85 85 85 100 | 2 1.25 2.5 3.3 | 15 •35 •25 30 12 | 100 - 25 300 200 | 2 10 0.9 3 3 | 22 16 6 12 4 | - 40 *2.4 20 40 | - 0.5 *9 3 3 | micromin MO, RA, US GI |
| | 2N1379 C631 2N2374 2N2429 2N1185 | TI CT PH AMP MO | pnp,AJ,ge pnp,AJ,si pnp,AJ,ge pnp,ge pnp,AJ,ge | 200 **201 210 220 260 | 250 250 250 165 200 | 100 160 100 75 100 | 3.3 2 3.3 3.3 2.7 | 25 150 *35 *32 *45 | 200 50 500 30 500 | 3 - 2 - 5 | 4 - - 4 5 | 40 2 *14 - | 3 - ••15 2.3 3 | tg FE Output, TI |
| A 45 | 2N1194 C640 C641 C642 C643 | MO CT CT CT CT | pnp,AJ,ge pnp,AJ,si pnp,AJ,si pnp,AJ,si pnp,AJ,si | 280 **20 IC **40 IC **60 IC **90 IO | 200 675 675 675 675 | 100 160 160 160 160 | 2.7 5 5 5 5 | *40 35 35 35 35 35 | 200 50 50 50 50 50 | 2 | 10 | - 8 8 8 8 | 3 20 30 40 50 | TI tg FE tg FE tg FE tg FE |
| | C644 SST610 2N461 2N943 2N944 2N945 | CT SSE MO SSD SSD SSD | pnp,AJ,si npn,DM,si pnp,AJ,ge pnp,AJ,si pnp,AJ,si pnp,AJ,si | 12,0 0 12,0 0 - - - - | 675 500 200 250 250 250 | 160 150 100 175 175 175 | 5 4 2.8 1.7 1.7 | 35 *60 *45 18 18 50 | 50 500 100 50 50 50 | - 0.3ma 10 | - 8 20 - - - | 8 20 - 7 7 7 | 60 *0.120 0.7 1 1 | tg FE USAF, 'TI |
| A 46 | 2N946 2N1919 2N1920 2N1921 2N1922 2N2376 | SSD SSD SSD SSD SSD PH | pnp,AJ,si pnp,AJ,si pnp,AJ,si pnp,AJ,si pnp,AJ,se pnp,AJ,ge | 111111 | 250 250 250 250 250 250 250 | 175 175 175 175 175 175 100 | 1.7 1.7 1.7 1.7 1.7 1.7 3.3 | 80 18 18 50 80 *35 | 50 50 50 50 50 50 50 | - - - - 2 | | 7 7 7 7 7 *14 | 1 1 1 1 •••15 | m. pair 2N2375, TI |

ELECTRONIC DESIGN



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HIGH FREQUENCY

Includes types ranging up to and above the vhf range. In order of increasing $f_{\alpha e}$, $f_{\alpha b}$, or f_{τ} .

| | | | | | | MA | X. RATIN | IGS | | СНА | RACTE | RISTIC | cs | |
|-----------------------|--|---------------------------------|---|------------------------------------|--|--|---------------------------------|---------------------------------|-----------------------------------|---------------------------------------|-----------------------------------|---------------------|------------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P c (mw) | T _i (°C) | mw/°C | °CEO °V CBO (v) | 1 C (ma) | h _{fe} *h _{FE} | ¹ co (μα) | NF (db) | Coe *Cob (pf) | Remarks |
| HF 1 | 2N444A 2N707 2N988 2N989 2N1024 | GI PSI PSI PSI SSD | npn,AJ,ge npn,TDP,si npn,TDP,si npn,TDP,si pnp,AJ,si | 1 1 1 1 **1 | 150 .006 .006 .006 .006 250 | 100 175 175 175 175 175 | 2 56 20 20 1.7 | - 40 15 | 12 70 70 100 | 25 .005 .05 .05 | 2 300 250 250 0.025 | 12 6 8 11 | .2 .32 .63 7 | TI NA, KF |
| | 2N 1025 2N916 2N2656 PT720 PT886 | SSD PSI PSI PSI PSI | pnp,AJ,si npn,TOP,si npn,TOP,si npn,TOP,si npn,TOP,si | 1.2 1.2 1.2 1.6 | 250 .006 .006 .006 .01 | 175 200 200 200 200 175 | 1.7 45 25 25 22 | 35 - 200 200 - | 100 120 50 80 | 9-22 .001 .01 5 | 0.025 300 250 250 180 | - 10 15 - | 7 - .05 .05 .150 | NA, KF |
| HF 2 | PT887 PT888 2N94 2N139 2N193 | PSI PSI SY SY | npn,TDP,si npn,TDP,si npn,AJ,ge pnp,AJ,ge npn,AJ,ge | 1.6 1.6 2 2(min.) 2 | .01 .01 150 80 150 | 175 175 85 85 85 | 45 45 2.5 .75 2.5 | - - *20 *18 | - - 50 15 50 | .3 .3 50 22-110 9 | 180 180 50 50 50 | 6 4 - - | .750 1.000 - - - | |
| | 2N194 2N194A 2N211 2N233A 2N413A | Y2 Y2 Y2 Y2 Y2 | ag, LA, nqn pg, LA, nqn gg, LA, nqn gg, LA, nqn gg, LA, qnq | 2 2 2 2 2 2 | 150 150 50 150 150 | 85 85 70 85 85 | 2.5 2.5 1.1 2.5 2.5 | *18 *18 *10 *18 *15 | 50 50 50 50 50 200 | 10 10 5-15 30 | 50 50 20 50 10 | 11111 | 11111 | Mixer Converter GI |
| HF 3 | 2N515 2N516 2N517 2N519A 2N1026 | Y2 Y2 Y2 G1 G22 | ga, LA, nqn npn, AJ, ge npn, AJ, ge np, AJ, si sa, LA, nqn | 2 2 2 ·2 ·*2 | 50 50 50 150 250 | 75 75 75 100 175 | 1 1 1 2 1.7 | *18 *18 *18 *25 35 | 10 10 10 - | 25-50 5-15 10-60 25 18-44 | 50 50 50 1 0.025 | - - 12 - | - - 14 7 | IND, KF KF, NA |
| | 2N1469 2N1840 2N413 2N1342 2N356 | SSD PSI RA PSI RCA | pnp, AJ, si npn, TDP, si pnp, FA, ge npn, TDP, si pnp, AJ, ge | **2 2 2.5 2.8 3 | 150 .013 150 .018 100 | 150 175 85 175 85 | 1.2 25 - 150 1.67 | 35 500 18 300 20 | 100 15 200 12 | 36 .3 30 .01 | 25 180 2.0 190 5 | - 7 8 - | 7 - .7 12 | KF IND, US, KF, GI GI, SY, TI |
| HF 4 | 2N438 2N438A 2N445A 2N481 2N1302 | GI GI US TI | npn,AJ,ge npn,AJ,ge npn,AJ,ge pnp,AJ,ge npn,ge | 3 3 3 3 | 100 150 150 200 150 | 85 85 100 85 100 | 1.67 2.5 2 3 2.0 | *30 *30 *30 30 *25 | - - 20 300 | - 70 50 20* | 10 10 2 3 3 | - 12 - 3.6 | 12 12 14 14 12 | TI RA, TI TI |
| | 2N1564 2N1565 2N1566 2N1889 2N1890 | PSI PSI PSI PSI PSI | npn,TDP,si npn,TDP,si npn,TDP,si npn,TDP,si npn,TDP,si | 3 3 3 3 | .02 .02 .02 .017 .017 | 175 175 175 200 200 | 80 80 80 100 100 | 50 50 50 | 30 60 130 80 200 | .01 .01 .01 .001 | 190 190 190 190 190 | | 1111 | |
| HF 5 | 2N1893 2N1893A 2N1506A 2N482 TR-482 | PSI PSI PSI IND IND | npn,TDP,si npn,TDP,si npn,TDP,si pnp,AJ,ge pnp,AJ,ge | 3 3 3.5 3.5 3.5 3.5 | .017 .017 .02 150 150 | 200 200 200 85 85 | 120 140 80 2.5 2.5 | 500 500 500 *14 14 | 80 90 60 200 200 | .001 .001 .005 50 20 | 190 190 190 3 3 | - 10 - - | - 1.3 12 12 | US, TI |
| lesi, | PT1558 2N212 2N385 2N414A 2N1027 | PSI SY SY SY SY | Page (And Page) And Page (And Page) And Page Page Page Page Page Page Page Page | 4 4 4 | .023 150 150 150 250 | 200 85 100 85 175 | 80 2.5 2.0 2.5 1.7 | - *18 *25 *15 15 | 40 50 - 200 100 | .005 20 - - 18 | 210 50 35 20 0.025 | 10 | 1 - 4 - 7 | Converter GI, TI KF,GI,AMP KF |
| HF 6 | 2 N 1058 2N94A 2N292 2N388A 2N395 | SY SY GE RCA RA | eg, LA, nqn ag, LA, nqn ag, LA, nqn ag, nqn ag, LA, qnq | 4 5 5 5 5 | 50 151 65 151 151 | 75 85 85 - 85 | 1 2.5 .9 - - | *18 *20 15 *40 25 | 50 20 200 - | 15 19 6-44 30* 40 | 50 50 5 - 2.0 | | - - - - 12 | Converter TI TO-5 RF Switch, TI, RCA |
| | 2 N 439 2N 439 A 2N 448 2N 520 A 2N 634 | GT RA GE GI GE | npn,AJ,ge npn,AJ,ge npn,RG,ge pnp,AJ,ge npn,AJ,ge | 5 5 5 5 5 | 10(15) 65 15) 15) | 85 85 85 100 85 | 1.67 2.5 1.1 2 2.5 | *30 *30 15 *25 *20 | - 20 - - | - 25 100 - | 10 10 5 1 5 | - - 12 - | 12 12 2.4 14 12 | SY, TI TI IND, KF, TV TI |
| HF 7 | 2 N 483 2 N 357 2 N 377 2 N 446A 2 N 483 | IND RCA SY GI US | pnp,FA,ge npn,AJ,ge npn,AJ,ge npn,AJ,ge pnp,AJ,ge | 5.5 6 6 6 | 15(10(15(15() 15) | 85 85 100 100 85 | 1.67 2.0 2 2.5 | *12 *20 *25 *30 12 | 20 - - - 20 | 60 - - 120 65 | 3.0 5 5 2 1.5 | - - 12 10 | - 12 12 14 *12 | US, TI GI, SY, TI TI TI |



9 New Differential Amplifier Transistors feature close matching of characteristics: \triangle V_{BE} as low as 5 mV maximum. \square Other features include: temperature tracking of V_{BE} \longrightarrow \triangle (V_{BE1} \longrightarrow -V_{BE2})/ \triangle T as low as 10μ V/° C.; extremely high beta — up to 50 min. at 1μ A matched to within 10%; and low noise typically 2db. Extremely low leakage — as low as 1nA max. at 30 volts. \square Because

typically 2db. Extremely low leakage — as low as 1nA max. at 30 volts.

Because these devices eliminate common-mode signals and allow use of balanced inputs to minimize input drift, they find application in low drift DC amplifiers, operational amplifiers, telemetry, comparators and analog-digital converters. These new microelectronic devices have two closely matched low-level NPN silicon planar transistors, electrically isolated but thermally connected, in a single 6-lead TO-5 package. Production quantities are presently available.

Sales Offices: Chicago, Illinois; Los Angeles, California; Oakland, New Jersey; Medford, Massachusetts; Sykesville, Maryland; Bethpage, L. I., New York.

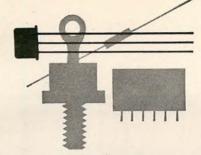
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|---|-----------------------|--|---------------------------------|---|----------------------------------|--|--|-------------------------------|--|-----------------------------------|--|--|----------------------------------|--------------------------------|---|
| | Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P _c (mw) | Ť i (°C) | mw/°C | V _{CEO} *V _{CBO} (v) | 1 _C | hfe *hFE | l CO (μα) | NF (db) | Coe *Cob (pf) | Remarks |
| | 35.0 | OC45 2N139 2N218 2N409 2N410 | AMP RCA RCA RCA RCA | pnp,PADT,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 6 6.8 6.8 6.8 6.8 | 83 80 80 80 80 | 75 85 85 85 85 | 1 | *15 16 16 13 13 | 10 15 15 15 15 | 100 48 48 48 48 75 | 0.5 6 6 10 10 | 8 | 11111 | SY YZ |
| | HF 8 | 2N414 2N439 2N1090 CK14 2N485 | RA Gi RA RA IND | pnp,FA,ge npn,AJ,ge npn,AJ,ge pnp,FA,ge pnp,AJ,ge | 7 7 7 7 7.5 | 150 100 150 80 200 | 85 85 85 85 85 | - - - 3 | *15 *20 18 15 30 | 200 400 100 200 20 | 60 45 50 60 50 | 2.0 3 3 2.0 3 | 6 - 6 - | 9 9 - 12 | IND, US, TS, GE, RCA, AMP, TI TO-5 RF Switch, SY TO-5 RF Switch US |
| | | 2N 168A 2N 169 2N 293 2N 388 2N 396 | GE GE GE RA | npn,RG,ge npn,RG,ge npn,RG,ge npn,AJ,ge pnp,AJ,ge | 8 8 8 | 65 65 65 150 | 85 85 85 100 85 | 1.1 1.1 1.1 2.0 | 15 15 15 *25 20 | 20 20 20 - - | 40 72 25 - 60 | 5 5 5 5 2.0 | 11111 | 2.4 2.4 2.4 12 12 | SY, TI |
| | HF 9 | 2N 449 2N 471A 2N 472A 2N 581 2N 957 | GE TR TR RA PSI | npn,RG,ge npn,GJ,si npn,GJ,si pnp,AJ,ge npn,TDP,si | 8 8 8 8 | 65 200 200 100 .006 | 85 200 200 85 150 | 1.1 30 45 - 40 | 15 30 45 15 | 20 25 25 100 •45 | 72 10-25 10-25 30 .01 | 5 .02 .02 3 250 | - 22 22 - | 2.4 7 7 12 | TI TI TO-5 RF Switch, RCA |
| | | 2N1086 2N1086A 2N1087 2N1121 2N1478 | GE GE GE GI | npn,RG,ge npn,RG,ge npn,RG,ge npn,RG,ge pnp,fe | 8 8 8 8 | 65 65 65 65 150 | 85 85 85 85 100 | 1.1 1.1 1.1 1.1 2 | 9 9 9 15 *1 | 20 20 20 20 20 100 | 40 40 40 72 70 | 3 3 5 5 | 1111 | 2.4 2.4 2.4 2.4 15 | |
| | HF 10 | 2N1624 2N2085 2N358 2N521A 2N140 | GI GI GI RCA | npn,ge npn,ge npn,AJ,ge pnp,AJ,ge pnp,AJ,ge | 8 9 9 10 | 150 150 100 150 80 | 10 0 100 85 100 85 | 2 2 1.67 2 | *0.5 *0.25 *20 *25 16 | 30 10 - - 15 | 120 100 - 150 75 | 5 5 1 6 | - - 12 8 | 20 20 12 14 - | SY, TI SY |
| | | 2N219 2N411 2N414B 2N416 2N440 | RCA RCA IND RA GI | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,FA,ge npn,AJ,ge | 10 10 10 10 10 | 80 80 200 150 100 | 85 85 85 85 85 | - 2.5 · - 1.67 | 16 13 14 *12 *30 | 15 15 200 200 – | 75 75 90 80 | 6 10 3 2.0 10 | - - 4 - | - 12 - 12 | SY IND, KF IND, US, GI, TS, KF,AMP SY, TI |
| | HF 11 | 2N440A 2N447A ST905 2N473 2N474 | GI GI TR TR TR | npn,AJ,ge npn,AJ,ge npn,GR,si npn,GR,si npn,GR,si | 10 10 10 10 10 | 150 150 150 200 200 | 85 100 150 200 200 | 2.5 2 1.0 - | *30 *30 *30 *15 *30 | - - - 25 25 | 150 65 20-50 20-50 | 10 2 0.1 .02 .02 | 12 25 20 20 | 12 14 7 7 7 | RA, TI TI TI |
| | | 2N474A 2N475 2N484 2N2425 2N118A | TR TR US KF TR | npn,GJ,si npn,GR,si pnp,FA,ge pnp,AJ,si npn,GR,si | 10 10 10 10 10 | 200 200 150 375 150 | 200 200 85 200 175 | 11111 | 30 *45 *12 50 *30 | 25 25 20 50 25 | 20-50 20-50 90 60 19-90 | .02 .02 3.0 0.1 0.1 | 20 20 - 10 27 | 7 7 - 7 7 | TI TI TI JAN, TI |
| | HF 12 | 2N478 2N479 2N479A 2N480 2N1417 | TR TR TR TR TR | npn,GR,si npn,GR,si npn,GJ,si npn,GR,si npn,GR,si | 11 11 11 11 11 | 200 200 200 200 200 150 | 200 200 200 200 200 150 | - | *15 30 30 45 *15 | 25 25 25 25 25 25 | 40-100 40-100 40-100 40-100 30-200 | 0.2 .02 .02 .02 .02 0.1 | 20 20 20 20 20 19 | 7 7 7 7 | TI TI TI TI AMP |
| | 115.12 | 2N1418 ST15 ST35 ST45 ST904A | TR TR TR TR TR | npn,GR,si npn,GR,si npn,GR,si npn,GR,si npn,GR,si | 11 11 11 11 11 | 150 200 200 200 200 150 | 150 200 200 200 200 150 | - - - 1.0 | 30 15 30 45 30 | 25 25 25 25 25 | 30-200 10-100 10-100 10-100 60 | 0.1 .02 .02 .02 .02 0.1 | 19 22 22 22 22 25 | 7 7 7 7 7 | NA 2N332 |
| | HF 13 | ST910 2N397 2N486 2N751 4C28 | TR RA IND RA GE | npn,GR,si pnp,AJ,ge pnp,AJ,ge npn,DJ,si npn,GD,si | 11 12 12 12 12 12 | 15(15(- 15(150 | 150 85 85 175 125 | 1.0 - 3 0.75 | *30 15 30 20 *40 | - 20 50 25 | 140 80 100 4 15 | 0.1 2.0 3 0.01 2 | 20 - - - 20 | 7 12 12 6 •20 | TO-5, RF Switch, KF, TI, RCA RA, US |
| | DE 14 | 4C29 4C30 4C31 2N541 2N542 | GE GE GE TR TR | npn,GD,si npn,GD,si npn,GD,si npn,GR,si npn,GR,si | 12 12 12 15 15 | 150 150 150 200 200 | 125 125 125 200 200 | 11111 | *40 *40 *40 *15 *30 | 25 25 25 25 25 25 | 30 55 115 80-200 80-200 | 2 2 2 0.2 0.2 | 20 20 20 20 20 20 | *20 *20 *20 7 7 | NA. TI NA. TĪ |
| | HF 14 | 2N542A 2N543 2N602A 2N1091 2N2424 | TR TR GI RA KF | npn,GJ,si npn,GR,si pnp,DR,ft npn,AJ,ge pnp,AJ,si | 15 15 15 15 15 15 | 200 200 120 150 37! | 200 200 85 85 200 | - 2 - | 30 *45 *30 15 40 | 25 25 50 100 50 | 80-200 80-200 50 70 80 | 0.2 0.2 5 3 0.1 | 20 20 25 - | 7 7 7 9 7 | NA, TI TO-5 RF switch |

HUGHES SEMICONDUCTOR BUYERS' GUIDE



HUGHES® DIODES

Silicon MICROSEAL* Diodes — Zener and Computer Types With or without welded leads, or in circuit arrays (0.062" dia.x 0.030" thick). Rated 150 mW free air (minimum), 500 mW mounted in circuit boards, to 1 watt infinite heat sink. Microminiature devices for high density circuit applications. Representative Types are E.I.A. equivalents: 1N46-59, 1N625-27, 1N903-08, 1N914, 1N916, 1N1934-37, 1N3064 and †N3067.

Silicon Zener Diodes Power Dissipation up to 500 mW. Hard backs with extremely low noise and dynamic impedance. Stable alloy process. Excellent voltage regulation as low as ±3% at low current level. Representative Types: 1N702-726A, 1N746-759A, 1N957-975B, 1N761-769, 1N1929-1937.

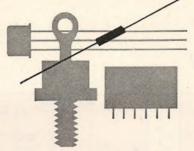
Silicon Capacitor Diodes Medium Q devices with good stability and low leakage. Capacitance ranges from 20 to 100 pf (tolerance as low as ±5%) with maximum bias voltage variations up to 150 volts. Representative Types: 1N950-956.

Silicon Computer Diodes Diffused planar passivated. Inversive working voltages to 100 volts. Recovery times as low as 2 nsec using a sampling scope circuit. Representative Types: 1N903-08, 1N914, 1N916, 1N3064 and 1N3067.

Germanium Point Contact Diodes The first industry standard subminiature glass general purpose and computer diode. Proven stability with inverse working voltages to 190 volts. Recovery times as low as 0.75 nsec using a sampling scope. Representative Types: 1N198B, 1N933, HPS, 1600 series.

Germanium Gold Bonded Diodes General purpose and computer applications. Recovery times as low as 3.5 nsec. Improved rugged mechanical stability withstands 30,000 G's centrifuge and 3,000 G's shock. Representative Types: 1N270, 1N276, 1N277 and HD1800 series.

Silicon General Purpose Alloy Diodes and Rectifiers Power Dissipation to 250 mW. Forward currents to 0.2 amps. Oxide-coated (surface passivated) units with working inverse voltages up to 1,000 volts. Representative Types: 1N456-459, 1N482B-488B, 1N846-889.



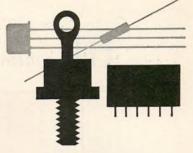
HUGHES TRANSISTORS

PNP Silicon Alloy Junction Transistors 2N1034, 2N1035, 2N1036, 2N1037. 2N1228 through 2N1234, 2N1238 through 2N1244, 2N327A, 2N328A, (also USA 2N328A), 2N329A, HA7597, HA7598, HA7599, HA7520 through HA7529, HA7530, through HA7539... available in the standard TO-5 package or the Hughes coaxial package with up to 5 watts power dissipation. Manufactured by the evaporative-fusion technique which creates unusually low saturation resistance. Retain highly uniform characteristics from batch to batch, making possible much closer tolerances in the design of small-signal, high-temperature and amplifier circuits.

PNP Silicon Double Diffused Planar Transistors 2N1254, 2N1255, 2N1256, 2N1257, 2N1258, 2N1259, HA9048, HA9049, 2N1196, 2N1197, (also USA 2N1197), 2N869, 2N995 . . . most types available in any package configuration...TO-5, TO-18, TO-46, the Hughes MICROSEAL transistor...or any industry standard package. Offer many outstanding features: low collector capacitance, good low- and high-level gain characteristics, low leakage currents, low stored base charge, typical ft of 75 mc. High breakdown voltages in combination with gains, plus exceptionally fast-switching capabilities, make these superior general purpose units. 2N1131, 2N1131A, 2N1132, 2N1132A, 2N1132B, 2N1991 . . . available in any package configuration...TO-5, TO-18, TO-46, the Hughes MICROSEAL transistor . . . or any industry standard package. Used extensively in advanced missile, satellite and computer applications. Feature high breakdown voltages, exceptionally low leakage currents, typically 20 nanoamps, measured at stringent bias conditions, Most types offer guaranteed switching times of less than 50 nanoseconds.

NPN Silicon Double Diffused Planar Transistors 2N706, 2N706A, 2N706B, 2N707, 2N726, 2N753 Planar, 2N1613, 2N708 Planar, 2N744 Epitaxial, 2N913, 2N914 Planar Epitaxial...available in any package configuration... TO-5, TO-18, TO-46, the Hughes MICROSEAL transistor...or any industry standard package.

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HUGHES RECTIFIERS

Miniature High-Power Rectifiers These 1 amp devices are available from 50 to 3,000 volts PIV in the DO-7 package.

Standard Metal Package Rectifiers Available at ratings of 6, 12, 20 and 35 amps. PIV ratings are from 50 to 1,000 volts for the 6 and 12 amp packages. (DO-4 and DO-10), and from 50 to 600 volts in the 20 and 35 amp packages (DO-5 and DO-11).

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|-----------------------|--|---------------------------------|--|--------------------------------------|---|------------------------------------|----------------------------------|-----------------------------------|---------------------------------|---|-----------------------------------|-------------------------|---------------------------------------|---|
| Cross Index Key | Type No. | Mfr. | Туре | fae -*fT **fab (mc) | P (m v) | T _i (°C) | mw∕ °C | V CBO (v) | 1 _C (ma) | h _{fe} *hFE | l (pa) | NF (db) | C _{oe} *C _{ob} (pf) | Remarks |
| | OC44 2N388A 2N476 2N477 2N522A | AMP TI TR TR GI | pnp,PADT,ge npn,AJ,ge npn,GJ,si npn,GJ,si pnp,AJ,ge | 15 **16 17 17 17 | 83 150 200 200 150 | 75 - 200 200 100 | - - - 2 | *15 40 *15 *30 *25 | 10 200 25 25 - | 100 *60-180 30-60 30-60 200 | 0.5 5 .02 .02 | - 19 19 12 | 20° 8 8 | TI TI KF, TI |
| HF 15 | 2N582 2N1118 2N1118A 2N232 2N417 | RA PH PH PH RA | pnp,AJ,ge pnp,SAT,si pnp,SAT,si pnp,SBT,ge pnp,FA,ge | 18 18 18 20 20 | 100 150 150 9 150 | 85 140 140 55 85 | 1.3 1.3 0.9 | *14 *25 *25 *4.5 *10 | 100 50 50 4.5 200 | 60 20 2 ⁶ 39 140 | 3 - - 6 2.0 | - - - - 4 | 12 *6 *6 *6 -6 | TO-5 RF switch, TI SPR, KF, MIL SPR SPR IND, US, GI, TS, KF, TI |
| | 2N602 2N1899 2N1902 2N1903 2N1904 | GI PSI PSI PSI PSI | pnp,Dr,ge npn,DM,si npn,DM,si npn,DM,si npn,DM,si | 20 20 20 20 20 20 | 120 125 ** 125 125 125 | 85 150 150 150 150 | 2 1000 1 1 1 | *20 140 140 140 140 | 10a 10a 10a 10a 10a | - 10 10 10 10 | 3 20ma 20 20 20 | 14 - - - - | 4 600 - - | TI hi freq., hi pwr |
| HF 16 | 2N1907 2N1908 2N2551 PT900 PT901 | TI TI HU PSI PSI | pnp,AD,ge pnp,AD,ge pnp,A,si npn,DM,si npn,Ms,si | *20 *20 *20 *20 20 20 | 150 N 150 N 400 125 N 125 N | - 160 150 150 | - 3.0 1000 1000 | 100 130 .150 80 140 | 20a 20a .1 10a 10a | *10 *10 *90 3 10 | 0.3ma 0.3ma 6 40 30 | - •1.0 - | - 200 600 600 | hi freq., hi powr. Hi frequency, |
| | 2N495 2N523A 2N1428 2N1429 2N1677 | PH G1 PH PH PH | pnp,SA,si pnp,AJ,ge pnp,SAT,si pnp,SAT,si pnp,SAT,si | 21 23 23 23 23 23 | 150 150 100 100 100 | 140 100 140 140 140 | 1.3 2 0.86 0.86 0.87 | *25 *20 *6 *6 *4.5 | 50 50 50 50 | 30 300 45 45 50 | .002 1 .001 .001 .001 | - 12 - - - | *6 14 *7 *7 *7 | MIL IND,KF SPR, chapper |
| HF 17 | 2N1065. 2N1900 2N1901 2N274 2N370 | GI PSI PSI RCA RCA | pnp,Dr,ge npn,DM,si npn,DM,si pnp,Dr,ge pnp,Dr,ge | 25 25 25 30 30 | 120 125 w 125 w 120 24 | 85 150 150 85 85 | 2 1000 1000 - - | *40 140 140 *40 *40 | - 5a a 10 10 | - 10 15 60 60 | 20ma 20ma 16 20 | 12 | 3 600 600 - | hi freq., hi pwr. hi freq., hi pwr. SY |
| | 2N371 2N372 2N373 2N374 2N1224 | RCA RCA RCA RCA RCA | pnp,Dr,ge pnp,Dr,ge pnp,Dr,ge pnp,Dr,ge pnp,Dr,ge | 30 30 30 30 30 | 80 80 80 80 120 | 85 85 85 85 85 | 11111 | 20 20 25 25 25 *40 | 10 10 10 10 10 | - 60 60 60 60 | 20 20 8 8 | | | SY Mixer, SY SY converter, SY GI, AMP, SY |
| HF 18 | 2N1226 2N1395 2N1709 2N1710 2N1750 | RCA RCA PSI PSI PH | pnp,Dr,ge pnp,Dr,ge npn,DM,si npn,DM,si pnp,SBT,ge | 30 30 30 30 30 | 12(12(13\/ 13\/ 15 | 85 85 175 175 75 | 86.7 86.7 0.5 | *60 *40 75 60 *14 | 10 10 1.2a 1.2a 5 | 60 90 - - *18 | 16 16 50 2 | | - 40 40 •6 | AMP AMP Hi freq., hi pwr. Hi freq., hi pwr. |
| | 2N2225 2N2595 2N2598 MHT-6001 2N1425 | KF SSD SSD MH RCA | pnp,AJ,ge pnp,DP,si pnp,DP,si npn,DP,si pnp,Dr,ge | 30 *30 *30 30 33 | 22! 4.0 4.0 40.7 80 | 100 200 200 175 71 | 2.3 2.3 270 | 15 60 80 *100 24 | 500 - - 5a 10 | 300 15-60 15-60 10-120 50 | - 25na 25na 1 12 | 3 - - | 10 *6 6 - | |
| HF 19 | 2N1426 2N1524 2N1525 2N1526 2N1527 | RCA RCA RCA RCA RCA | pnp,Dr,ge pnp,Dr,ge pnp,Dr,ge pnp,Dr,ge pnp,Dr,ge | 33 33 33 33 33 | 80 80 80 80 80 | 71 71 71 71 71 | - 0.4 0.4 0.4 0.4 | 24 24 24 24 24 | 10 10 10 10 10 | 130 60 60 130 130 | 12 16 16 16 16 | | - 2 2 - - | GI GI GI |
| | 2N934 2N603 2N603A 2N750 2N1633 | RCA GI GI RA RCA | pnp.ge pnp.Dr,ge pnp.DR,ft npn,DJ,si pnp,Dr,ge | *35 40 40 40 40 | 151 121 121 151 80 | - 85 85 175 71 | - 2 2 0.75 0.4 | 13 *30 *30 50 34 | 200 - 50 50 10 | *60 60 7 75 | - 3 5 10 16 | - 14 25 - - | - 3 5 6 - | T1 |
| HF 20 | 2N1634 2N1638 2N3746 2N640 2N641 | RCA RCA RCA RCA RCA | pnp,Dr,ge pnp,Dr,ge pnp,Dr,ge pnp,Dr,ge pnp,Dr,ge | 40 40 40 42 42 | 80 80 80 80 80 | 71 71 71 85 85 | 0.4 0.4 - 0.75 0.75 | 34 34 34 34 34 | 10 10 20 10 | 75 75 .985 60 60 | 16 7 16 5 7 | | - 2 3.8 - - | GI GI GI |
| | 2N642 2N754 2N755 2N839 2N840 | RCA TR TR TR TR | pnp,Dr,ge npn,DJ,si npn,DJ,si npn,DJ,si npn,DJ,si | 42 44 44 44 44 | 80 300 300 300 300 | 85 175 175 175 175 | 0.75 - - - - | 34 *60 *100 *45 *45 | 10 50 50 25 25 | 60 20-80 20-80 20-45 40-90 | 7 1 1 0.1 0.1 | - - 15 15 | - 8 8 - 8 | GI TMT839 (150mw) TMT840 (150mw) |
| HF 21 | TMT842 2N1196 2N1631 2N1632 2N1635 | TR HU RCA RCA RCA | npn,DJ,si pnp,MS,si pnp,Dr,ge pnp,Dr,ge pnp,Dr,ge | 44 45 45 45 45 | 1:0 3:5 8(8(8(| 175 200 71 71 71 71 | 2 0.4 0.4 0.4 | *45 70 34 34 34 | 25 - 10 10 10 | 20 - 80 80 75 | 0.1 - 16 16 16 | | 6 4 2 2 - | GI GI GI |

TEKTRONIX TRANSISTOR-CURVE TRACER

INVALUABLE TOOL FOR EVALUATING SEMICONDUCTOR DEVICES

With a Type 575, you can plot and measure 7 different transistor characteristics. You can display 4 to 12 curves per family—with input current from 1 microampere/step to 200 milliamperes/step or input voltage from 10 millivolts/step to 200 millivolts/step—in repetitive or single-family presentations. You can select either common-emitter or common-base configurations.

The Type 575 provides 20-ampere collector displays (10-ampere average supply current), two ranges of collector supply (0 to 20 volts, 0 to 200 volts), and 2.4-ampere base supply (positive or negative base stepping).

Add a Type 175 Adapter and you extend the range of collector displays 10 times and the range of base supply 5 times.

You can also test diodes under a wide variety of conditions and observe waveform characteristics on the 5-inch crt with a high degree of accuracy.

Type 575 Calibrated Displays

Vertical Axis—Collector Current, 16 steps from 0.01 ma/div to 1000 ma/div. Pushbuttons are provided for multiplying each current step by 2 and dividing by 10, increasing the current range to 0.001 ma/div to 2000 ma/div.

Horizontal Axis—Collector Voltage, 11 steps from 0.01 v/div to 20 v/div.

Both Axes—Base Voltage, 6 steps from 0.01 v/div to 0.5 v/div. Base Current, 17 steps from 0.001 ma/div to 200 ma/div. Base Source Voltage, 5 steps from 0.01 v/div to 0.2 v/div.

Type 575 Transistor: Curve Tracer \$1075

U.S. Sales Prices f.o.b. Beaverton, Oregon



HIGH-CURRENT ADAPTER

For measuring high-powered semiconductor devices which exceed the current capabilities of a Type 575, ask your Tektronix Field Engineer about the Type 175 High-Current Adapter. Not intended for separate use, the Type 175 depends upon the circuitry and crt of a Type 575 to provide 200-ampere collector displays, three ranges of collector supply, and 12-ampere base supply—for calibrated displays with Collector Current on the Vertical Axis and either Collector Voltage or Base Voltage on the Horizontal Axis.

Type 175 Transistor-Curve Tracer
High-Current Adapter \$1475



HIGH-VOLTAGE TYPE 575

Supplied on order from your Tektronix Field Engineer is a special model of the Type 575 Transistor-Curve Tracer. Although similar to the Type 575, the special model provides much higher diode breakdown test voltage (variable from zero to 1500 volts at a maximum current of 1 milliampere) and also much higher Collector Supply (up to 400 volts, at 0.5 ampere).

For complete specifications of this special model—call your Tektronix Field Engineer.

Type 575 Mod 122C \$1325

. . . for more information about evaluating semiconductor devices with a Type 575 or other Tektronix test equipment, please call your Tektronix Field Engineer. He will be glad to assist you.

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ON READER-SERVICE CARD CIRCLE 446

| | | | and the | | MAX. RATINGS | | | | | | ARACTE | RIST | ICS | |
|-----------------------|--|---------------------------------|---|--------------------------------------|---|------------------------------|-----------------------------------|-------------------------------------|----------------------------|---|-------------------------------------|------------------------|---------------------------------------|---|
| Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P c (n w) | T _i (°C) | mw/°C | V CEO *V CBO (v) | 1 _C | hfe *hFE | l CO (μα) | NF (db) | C _{oe} *C _{ob} (pf) | Remarks |
| | 2N1636 2N1637 2N1639 2N344 2N345 | RCA RCA RCA PH PH | pnp,Di,ge pnp,Di,ge pnp,Di,ge pnp,SB,ge pnp,SA,ge | 45 45 45 50 50 | 80 80 80 20 20 | 71 71 71 55 55 | 0.4 0.4 0.4 1.33 1.33 | 34 34 34 *5 *5 | 10 10 10 5 5 | 75 80 75 22 35 | 16 5 7 0.7 0.7 | 11111 | - 2 *3 *3 | GI GI SPR SPR |
| HF 22 | 2N393 2N604 2N738 2N739 2N740 | PH GI AI AI | pnp,MA,ge pnp,Dr,ge npn,P,si npn,P,si npn,P,si | 50 50 **50 **50 **50 | 25 120 1.0w 1.0w 1.0w | 100 85 - - | 0.63 2 - - - | *6 *30 *125 *125 *125 | 50 - - - - | 155 •15 •30 •60 | 5 4 .01 .01 1.0 | 14 - - | *2 3 *8.0 *8.0 *8.0 | SPR,GI TI |
| | 2N759 2N760 2N760A 2N870 2N871 | GE GE AI AI | npn, si npn,si npn,P,si npn,P,si npn,P,si | **50 **50 **50 **50 **50 | 500 500 1.50 w 1.8v 1.8v | 200 200 - - - | 11111 | 45 45 •60 •100 •100 | 11111 | 36 76 •205 •200 •200 | 0.2 0.2 0.01 .01 0.01 | 11111 | 8 *8.0 *8.0 | Planar Passivated Planar Passivated |
| HF 23 | 2N910 2N911 2N912 2N956 2N998 | AI AI AI AI | npn,P,si npn,P,si npn,P,si npn,P,si npn,P,si | **50 **50 **50 **50 **50 | 1.8v 1.8v 1.8v 1.8v 1.8v | 111111 | 11111 | *100 *100 *100 *75 *100 | 61111 | *75 *35 *15 *200 *5000 | 2.05 2.05 2.05 0.01 .01 | 11111 | *8.0 *8.0 *8.0 *8 | |
| | 2N1564 2N1565 2N1566 2N1572 2N1573 | AI AI AI AI | npn,P,si npn,P,si npn,P,si npn,P,si npn,P,si | **50 **50 **50 **50 **50 | 1.2v 1.2v 1.2v 1.2v 1.2v | 1111 | | *80 *80 *80 *125 *125 | 11111 | *15 *30 *60 *15 *30 | 1.0 .01 .01 1.0 1.0 | 11111 | *8.0 *8.0 *8.0 *8.0 *8.0 | |
| HF 24 | 2N1574 2N1889 2N1890 2N1972 2N1973 | AI AI AI AI | npn,P,si npn,P,si npn,P,si npn,P,si npn,P,si | **50 **50 **50 **50 **50 | 1.2v 3.0v 3.0v | 1111 | 11811 | *125 *100 *100 - *100 | | *60 *200 *200 -200 - *75 | 1.0 0.01 0.01 - 2.5 | 1111 | *8.0 *8 *8 *8.0 | |
| | 2N1974 2N1975 2N1983 2N1984 2N1985 | AI AI AI AI | npn,P,si npn,P,si npn,P,si npn,P,si npn,P,si | **50 **50 **50 **50 **50 | 3.0 / 3.0 / 2.0 / 2.0 / | 11111 | 1111 | *100 *100 *50 *50 *50 | | *35 *15 2.0 2.0 *85 | 2.5 2.05 5.0 5.0 5.0 | 11111 | *8.0 *8.0 *8.0 *8.0 | |
| HF 25 | 2N1986 2N1987 2N1988 2N1989 2N1990 | AI AI AI AI | npn,P,si npn,P,si npn,P,si npn,P,si npn,P,si | **50 **50 **50 **50 **50 | 2.0 / 2.0 / 2.0 / 2.0 / 2.0 / | 411111 | 91111 | *50 *50 *100 *100 *100 | | *130 *60 *85 *40 *20 | 5.0 5.0 5.0 5.0 | 11111 | *8.0 *8.0 *8.0 *8.0 *8.0 | |
| | 2N2060 2N2223 2N2223A 2N2223A 2N2453 2N2483 | AI AI AI AI | npn,P,si npn,P,si npn,P,si npn,P,si npn,P,si | **50 **50 **50 **50 **50 | 1.5)w 1.6 v 1.6 v 0.6)w 1.2 v | 11111 | 11111 | *100 *100 *100 *60 *60 | | *50 *150 *150 *80 | | 11111 | *8.0 *8.0 *8.0 *8.0 *8.0 | |
| HF 26 | 2N2484 2N2590 3N36 ASA-2 ASA-31 | AI SSD GE AI AI | npn,P,si pnp,DP,si npn,MB,ge npn,P,si npn,P,si | **50 *50 50 **50 **50 | 1.2 v 4.0 30 75v | 200 85 - | 2.3 0.5 - | *60 60 6 *60 | - 20 - - | *30 30-80 2,2 *45 | .01 25na 3 .01 | 11111 | *8.0 *5 2 *8.0 *8.0 | tetrode |
| | ASA-51 ASA-100 ASA-1000 ASA-1003 ASA-1004 | A1 AI AI AI | npn,P,si npn,P,si npn,P,si npn,P,si npn,P,si | **50 **50 **50 **50 **50 | 11111 | 11111 | | 11111 | 11111 | 11111 | | 11111 | *8.0 *8.0 *8.0 *8.0 *8.0 | |
| HF 27 | 2N1197 2N604A TRS100 TRS101 TRS301 | HU GI IND IND IND | pnp,Ms,si pnp,DR,ft npn,DM,si npn,DM,si npn,DM,si | 55 60 *60 *60 *60 | 385 120 600-25 C 600-25 C | 300 | 2 2 4 4 4 | 70 *30 *150 *180 *300 | 50 500 500 500 | 70 *30 *25 *30 | 5 0.01 0.01 0.01 | _ 25 _ - - | 4 5 10 15 25 | |
| | 2N128 2N841 TMT843 2N929 2N930 | PH TR TR AI AI | pnp,SB,ge npn,DJ,si npn,DJ,si npn,P,si npn,P,si | 60 64 64 ••70 ••70 | 25 300 150 0.1 w 0.1 w | 85 175 175 - - | 0.82 - - - - | *10 45 45 *45 *45 | 5. 25 25 - - | 40 80-330 40 •200 •200 | 0.6 0.1 0.1 .01 | 10 15 - - | *2.5 8 6 *8.0 *8.0 | SPR, MIL TMT841 (150 mw) |
| HF 28 | 2N990 2N991 2N992 2N1335 2N1336 | AMP AMP AMP PSI PSI | pnp,PADT,ge pnp,PADT,ge pnp,PADT,ge npn,MS,si npn,MS,si | 70 70 70 70 70 70 | 67 67 67 2. }w 2. }w | 75 75 75 150 150 | 1.33 1.33 1.33 24 24 | 20 * 20 * 20 120 120 | 10 10 10 75 75 | 75 75 75 13 13 | - - 8 8 | 11111 | - - 4 4 | RF, Mixer, Oscillator RF, Mixer, Oscillator RF, Mixer, Oscillator High freq., high power High freq., high power |



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advantage of Avnet's on-time delivery of STC products, featuring miniaturized power transistors without heat sink; isolated collector; PNP with NPN complements. Stocks in depth on either standard or hard-to-get items are part of Avnet's comprehensive marketing assistance. There are 10 Local Avnet Headquarters.

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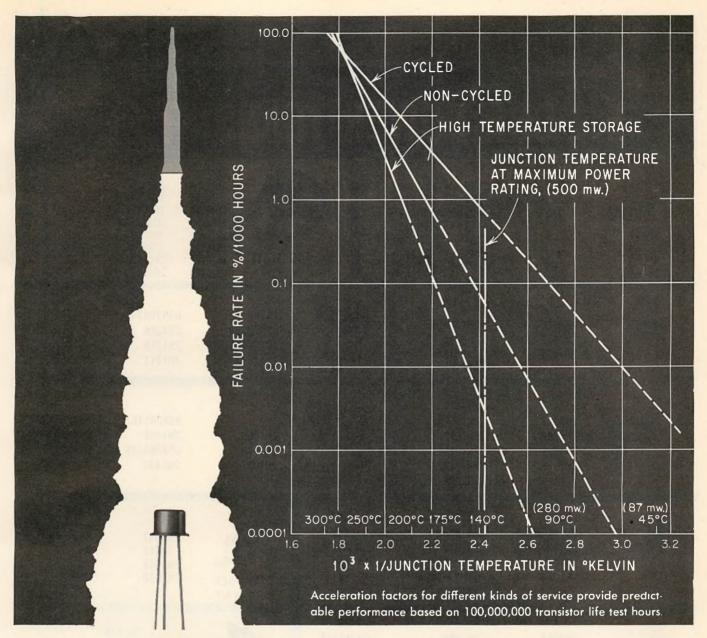


THE AVNET SYSTEM
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AVNET ELECTRONICS CORP.

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| Γ | 7 | | 000 | E SEE | | | MAX. RATINGS | | | | СНА | RACTE | RISTI | CS | Ro Company |
|---|-----------------------|---|---------------------------------------|---|-------------------------------------|--|--|-------------------------------------|---------------------------------------|-------------------------------|--|--|--------------------|---------------------------------------|---|
| | Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P c (mw) | T _i (°C) | mw/°C | V CEO *V CBO (v) | (ma) | hfe *hFE | ¹ CO (μα) | NF (db) | C _{oe} *C _{ob} (pf) | Remarks |
| | | 2N1337 2N1339 2N1340 2N1341 2N1505 | PSI PSI PSI PSI PSI | npn,MS,si npn,MS,si npn,MS,si npn,MS,si npn,MS,si | 70 70 70 70 70 70 | 2.8w 2.8w 2.8w 2.8w 2.8w 3w | 150 150 150 150 175 | 24 24 24 24 0.2 | 120 120 120 120 120 50 | 75 75 75 75 75 | 13 - - - 7 | 8 8 8 8 | 11111 | 4 4 4 4 20 | High freq., high power High freq., high power High freq., high power High freq., high power high freq., high power |
| | HF 29 | 2N1506 2N1516 2N1517A 2N2509 2N2510 | PSI AMP AMP A1 AI | npn,MS,si pnp,PADT,ge pnp,PADT,ge npn,P,si npn,P,si | 70 *70 *70 *70 **70 | 3w 83 100 1.20w 1,20w | 175 - - - - | .2 1.7 1.7 - - | 60 *20 *40 *125 *100 | 9 10 10 - | 100 150 - | - - .001 .005 | 11111 | 8 - - *8.0 *8.0 | High freq., high power RF-IF |
| | | 2N2591 2N346 2N993 2N2671 2N2672 | SSD PH AMP AMP AMP | pnp,DP,si pnp,SB,ge pnp,PADT,ge pnp,AD,ge pnp,AD,ge | *70 75 75 75 75 | 4.0 20 83 100 100 | 200 55 75 75 75 85 | 2.3 1.3 1.7 0.6 0.6 | 60 *5 *20 *32 *32 | 5 10 10 10 | 50-135 35 75 150 15 | 25na 0.7 - - 1.2 | - - - 1.5 | *5 *3 - - | SPR RF, Mixer, Osc., IF AM rec. |
| | HF 30 | 2N2089 2N2090 2N2091 2N2092 2N2093 | AMP AMP AMP AMP AMP | pnp,PADT,ge pnp,PADT,ge pnp,PADT,ge pnp,PADT,ge pnp,PADT,ge | 75 75 75 75 75 75 | 100 67 83 100 100 | 85 75 75 85 85 | 0.6 .75 1.7 0.6 1.7 | *32 *32 *20 *32 *25 | 10 10 10 10 10 | 150 150 150 150 150 | 1111 | 11111 | | RF, Mixer, Osc., IF AM rec. RF, Mixer, Osc., IF AM rec. RF, Mixer, Osc., IF AM rec. IF, Mixer FM rec. RF in FM rec. |
| | UE 21 | 2N696 2N698 2N699 2N706 2N1252 | FA FA FA FA | npn,DP,si npn,DP,si npn,DP,si npn,DP,si npn,DP,si | 80 80 80 80 80 | 2w 2w 2w 1w 2w | 175 175 175 175 175 | 13.3 13.3 13.3 6.7 13.3 | 40 *80 80 25 20 | 11111 | 40 30 65 12 35 | 0.1 0.1 .01 .005 0.1 | 11111 | 18 12 12 5 30 | RA,MO,PSI,TR,TI,IND,SY,GI,US RA, IND, TR, NA, GI, TI, PSI RA, NA, MH, GI, TI, US, PSI RA, NA, CL, GI, TI, TR, GE, MO RA, TR. TI |
| | HF 31 | 2N2511 2N2596 2N2597 2N2599 2N2600 | 1A 022 022 022 022 | npn,P,si pnp, DP, si pnp, DP, si pnp, DP, si pnp, DP, si | **80 *80 *80 *80 *80 | 1.20w 4.0 4.0 4.0 4.0 | 200 200 200 200 200 | 2.3 2.3 2.3 2.3 | *80 60 60 80 80 | 11111 | *80 40-100 80-200 40-100 80-200 | .005 25na 25na 25na 25na 25na | 11111 | *8.0 *6 *6 *6 | |
| | | MHT-4401 MHT-4402 MHT-4501 MHT-4502 2N844 | MH MH MH MH TR | npn,EP,si npn,EP,si npn,EP,si npn,EP,si npn,DJ,si | 80 80 80 80 86 | 4w 4w 10w 10w 300 | 200 200 200 200 200 175 | 23 23 57 57 | *60 *120 *60 *120 *60 | 500 500 1a 1a 50 | 20-120 20-120 20-120 20-120 40-120 | 1 2 1 2 1 | 11111 | 30 20 25 29 8 | |
| | HF 32 | 2N845 2N2592 3N37 2N384 2N697 | TR SSD GE RCA FA | npn,DJ,si pnp,DP,si npn,MB,ge pnp,Dr,ge npn,DP,si | 86 *90 90 100 100 | 300 4.0 30 80 2w | 175 200 85 85 175 | 2.3 0.5 - 13.3 | *100 60 6 30 40 | 50 - 20 10 75 | 40-120 100-200 1.1 60 0.01 | 1 25na 3 16 | - - - 18 | 8 *5 1.5 - - | letrode RA,PSI,TR,US,MO,SY,NA,GI,TI |
| | | 2N702 2N703 2N735A 2N736B 2N739A | GI GI SSD SSD SSD | npn,si npn,si npn, DP, si npn, DP, si npn, DP, si | 100 100 *100 *100 *100 | 360 360 4. 0 4. 0 4. 0 | 175 175 200 200 200 | 2.4 2.4 2.3 2.3 2.3 | *5 *5 60 60 80 | 10 10 - - - | 40 70 40-100 80-200 40-100 | 0.05 0.5 5na 5na 5na | 1111 | 9.9.01 | CL CL |
| | HF 33 | 2N740A 2N758B 2N759B 2N760B 2N920 | 22D 22D 22D 22D 22D GI | npn, DP, si npn, DP, si npn, DP, si npn, DP, si npn, DM, si | *100 *100 *100 *100 100 | 4. 0 4. 0 4. 0 4. 0 1.2w | 200 200 200 200 200 200 | 2.3 2.3 2.3 2.3 6.7 | 80 60 60 60 25 | - - - - 220 | 80-200 18-90 36-90 76-333 4 | 5na 5na 5na 5na .005 | 11111 | *6 *6 *6 5 | (CL, Epitaxial) |
| | | 2N921 2N922 2N929A 2N930A 2N979 | GI GI SSD SSD SPR | npn,DM,si npn,DM,si npn, DP, si npn, DP, si pnp,MD,ge | 100 100 *100 *100 *100 | 1.2w 1.2w 4.0 4.0 60 | 200 200 200 200 200 100 | 6.7 6.7 2.3 2.3 0.8 | 50 50 45 45 *20 | 200 200 - 100 | 4 4 60-350 150-600 50* | .005 .005 2na 2na 18 | - 4 3 - | 4 4 *6 *6 *2.5 | (CL, Epitaxial) (CL, Epitaxial) |
| | HF 34 | 2N980 2N987 2N1180 2N1224 2N1226 | SPR AMP RCA GI GI | pnp,MD,ge pnp,PADT,ge pnp,Dr,ge DR,ft DR,ft | *100 100 100 100 100 | 60 86 80 120 120 | 100°c 90 71 85 85 | 0.8 1.33 - 2 2 | *12 *40 30 *12 *12 | 100 10 10 1.5 1.5 | *70 100 80 60 60 | 1 | 11111 | *1.5 - - 5 5 | RF, Mixer, Osc. |
| | UE ac | 2N1225 2N1253 2N1396 2N1420 2N1427 | RCA FA RCA FA GI | pnp,Dr,ge npn,DP,si onp,Dr,ge npn,DP,si MAD f | 100 100 100 •100 100 | 120 2w 120 2 60 | 85 175 85 175 100 | 13.3 0.013 0.8 | *40 20 *40 30 *6 | 10 - 10 - 10 | 60 45 90 130 25 | 12 0.1 16 0.01 3 | 11111 | 30 - - 3.5 | AMP RH, TI AMP GI, PSI |
| | HF 35 | 2N1499A 2N1613 2N1748 2N1748A 2N1749 | GI FA PH PH PH | MADT npn,DP,si pnp,MD,ge pnp,MD,ge pnp,MD,ge | 100 100 100 100 100 | 60 3w 60 60 75 | 100 200 100 100 100 | 0.8 17.2 .8 0.8 | *20 75 *25 25 *40 | 40 - - 50 10 | 50 80 45 70 45 | 3 .0004 1.5 1.5 1.5 | | 3 18 •1.3 1.3 •1.3 | SPR RA, GI, TI, MO, GE, PSI |



General Electric transistors exceed Minuteman 99.999% reliability objective

General Electric has completed a silicon transistor reliability improvement program for the MINUTEMAN airborne guidance and control system where data on a single product has been accumulated for over 100,000,000 life test hours . . . unsurpassed in the semiconductor industry. The result is reliability without parallel. For instance, final-phase testing of 4,650 G.E. MINUTEMAN transistors to approximately 24,000,000 transistor hours at 288 mw resulted in ZERO failures. The

| Transistor Minuteman Part No. | Silicon Transistor Description | Maximum Dissipation | V _{B2} E | Nearest EIA Type No. | "Additional Minuteman Types"* |
|-------------------------------------|--------------------------------------|------------------------|-------------------|----------------------------|--|
| 551B | Unijunction | 600 mw | 60 | 2N489 | MM/2N490/M MM/2N491/M MM/2N492/M MM/2N493/M |
| 703B | Fixed-Bed Grown-diffused | 500 mw | 60 | 2N335A | MM/2N494/M MM/2N332/M MM/2N333/M MM/2N336/M |
| 801B * Furnished | Grown-diffused to either A, B or | 250 mw M MINUTE | 45 MAN 1 | 2N337 evel units. | MM/2N338 |

MINUTEMAN Part transistor made by General Electric substantially exceeds the MINUTEMAN objective of an average failure rate of 0.001%/1000 hours in continuous operation at 87 mw (25°C ambient) (see graph).

You can have this kind of reliability in *your* military and commercial applications. Just check the chart for MINUTE-MAN Part Numbers, similar EIA Types, and additional MINUTEMAN Types, all produced simultaneously on the same production lines and under the same exacting conditions.

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GENERAL & ELECTRIC



SILICON POWER TRANSISTORS



7/8" HEX **200 WATT**

2N1936 2N2820 2N1937 2N2821 STC1728 2N2815 2N2822 STC1731 2N2823 2N2816 STC1733 2N2817 2N2824 STC1736 STC1738 2N2818 2N2825 STC1726 STC1750 2N2819



150 WATT

2N1015 2N1015A 2N1015B 2N1015C 2N1015D 2N1015E

USN2N1016C 2N1016D USN2N1016D 2N1016E 2N1016 STC1015 STC1015A 2N1016A 2N1016B STC1015B

USN2N1016B

2N1016C

STC1015C STC1015D STC1015E STC1016 STC1016A STC1016B STC1016C STC1016D STC1016E



TO-36 75 WATE

2N1514 2N1511 2N2015 2N1512 2N2016 2N1513



T0 - 5385 WATT

2N389 **USN2N389** 2N389A 2N424

USN2N424 2N424A 2N1210 2N1211

2N1250 2N1620 2N1722 2N2383



11/16" HEX 85 WATT

2N1208 2N1209 2N1212 2N1616 2N1616A



TO-3 75 WATT



2N1070 2N1487

USA2N1487 2N1488 **USA2N1488** 2N1489

USA2N1489 2N1490 USA2N1490 2N1702



40 WATT

2N1047 2N1047A **USN2N1047A** 2N1047B 2N1048 **USN2N1048A** 2N1048A 2N1048B 2N1049 2N1049A **USN2N1049A** 2N1049B

2N2384

2N1050 2N1050A USN2N1050A 2N1050B 2N1768 2N1769



7/16" HEX 40 WATT



2N2150 2N2151 2N2828 2N2829



TO-8 25 WATT

2N1067 2N1068 2N1483 **USA2N1483**

2N1484 USA2N1484 2N1485 **USA2N1485** 2N1486 **USA2N1486** 2N1701 2N2035 2N2308



2N2036 STC1800 STC1810 STC1850



5 WATT

2N497 2N498 2N547 2N548 2N549 2N550 2N551 2N552

2N656 2N656A 2N657 2N657A 2N116 2N1117 2N1479 USA2N1479 2N1480 **USA2N1480** 2N1481 USA2N1481 2N1482 USA2N1482 2N1700 2N2033 2N2034



T0 - 375 WATT

STC5080 STC5081 STC5082 STC5083 STC5084

STC5085



PNP-11/16" HEX 85 WATT

STC5580 STC5581 STC5582

STC5583 STC5584 STC5585



PNP 10 - 53

2P389 2P389A 2P424 2P424A

CORPORATION SILICON TRANSISTOR

CARLE PLACE, L. I., N.Y.

(516) PIONEER 2-4100

TWX-516-248-9085

| | | 720 | | | | M | AX. RATII | NGS | 088 | CHA | RACTE | RISTIC | CS | |
|-----------------------|--|---------------------------------|---|--|--|--|------------------------------------|--|------------------------------------|--|--|-------------------|--------------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P c (mw) | T _i (°C) | mw/°C | V _{CEO} *V _{CBO} (v) | 1 C (ma) | hfe *hFE | ¹ CO (μα) | NF (db) | Coe *Cob (pf) | Remarks |
| | 2N1958A 2N1959A 2N2084 2N2243 2N2243A | SYL SYL AMP TI TI | npn,P,si npn,P,si pnp,PADT,ge npn,PE,si npn,PE,si | *100 *100 100 *100 *100 | 600 600 125 2800 2800 | 175 175 90 200 200 | - 1.93 16.0 16.0 | *60 *60 *40 *80 *80 | 1000 1000 10 1000 1000 | *20-60 *40-120 100 *40-*120 *40-*120 | | | *14 *14 - *12 *12 | RF, Mixer, Osc. on FM rec. |
| HF 36 | 2N2459 2N2463 2N2515 2N2516 2N2518 | 022 022 022 022 022 | npn,DP,si npn,DP,si npn, DP, si npn, DP, si npn, DP, si | *100 *100 *100 *100 *100 | 4.0 1.8 4.0 4.0 4.0 | 200 200 200 200 200 200 | 2.3 2.8 2.3 2.3 2.3 | 60 60 60 60 80 | 11111 | 30-80 30-80 40-100 80-200 40-100 | 2na 2na 5na 5na 5na | 1111 | *5 *5 *6 *6 *6 | |
| | 2N2519 2N2520 2N2521 2N2521 2N2522 2N2523 | 022 022 022 022 022 | npn, DP, si npn, DP, si npn, DP, si npn, DP, si npn, DP, si | *100 *100 *100 *100 *100 | 4. 0 4. 0 4. 0 4. 0 4. 0 | 200 200 200 200 200 200 | 2.3 2.3 2.3 2.3 2.3 | 80 60 60 60 45 | 1111 | 80-200 18-90 36-90 76-333 60-350 | Sna Sna Sna Sna Sna 2na | - - - 4 | *6 *6 *6 *6 | |
| HF 37 | 2N2524 2N2601 2N2602 2N2603 2N2604 | 022 022 022 022 022 | npn, DP, si pnp, DP, si pnp, DP, si pnp, DP, si pnp, DP, si | *100 *100 *100 *100 *100 | 4. 0 4. 0 4. 0 4. 0 4. 0 | 200 200 200 200 200 200 | 2.3 2.3 2.3 2.3 2.3 | 45 60 60 60 45 | 11011 | 150-600 18-90 36-90 76-333 60-350 | 2na 25na 25na 25na 10na | 3 - - 4 | *6 *6 *6 *6 | |
| | 2N2605 2N2800 2N2801 3N34 OC171 | SSD MO MO TI AMP | pnp. DP, si npn,PE,si npn,PE,si npn,GD,si pnp,DJ,ge | *100 *100 *100 100 100 | 4. 0 800 800 125 60 | 200 200 200 150 75 | 2.3 4.57 4.57 1 2 | 45 *50 *50 30 *20 | - - 20 5 | 150-600 *30/90 *75/225 4 | 10na 0.1 0.1 0.4 2 | 3 - 20 - | *6 *25 *25 - | tetrode |
| HF 38 | 2N1752 2N2593 2N497 2N498 2N656 | PH SSD RA RA RA | pnp,MD,ge pnp,DP,si npn,MS,si npn,MS,si npn,MS,si | 106 *110 120 120 120 | 60 4.0 4w 4w 4w | 100 200 175 175 175 | 0.8 2.3 26.5 26.5 26.5 | *12 60 60 100 60 | 50 - 500 500 500 | 250 150-275 25 25 60 | 0.8 25na 0.1 0.1 0.1 | 11111 | *1 *5 20 20 20 | NA, GE, TI, PSI NA, GE, TI, PSI NA, GE, TI, PSI |
| | 2N657 2N1023 2N1066 2N1397 2N1409 | RA RCA RCA RCA RA | npn,MS,si pnp,Dr,ge pnp,Dr,ge pnp,Dr,Ge npn,MS,si | 120 120 120 120 120 | 4w 120 120 120 120 2.8w | 175 85 85 85 150 | 26.5 | 100 40 40 *40 30 | 500 10 10 10 10 500 | 60 60 60 90 30 | 0.1 12 12 16 0.1 | 11111 | 20 - - - 20 | NA, GE, TI, PSI AMP AMP PSI |
| HF 39 | 2N1410 2N1420 2N2460 2N2464 2N2798 | RA RA SSD SSD SPR | npn,MS,si npn,DD,si npn,DP,si npn,DP,si pnp,ED,ge | 120 120 *120 *120 *120 *120 | 2.8w 2w 4.0 1.8 75 | 150 175 200 200 100 | 22.5 13.2 2.3 2.8 1.0 | 30 *60 60 60 *25 | 500 500 - 100 | 50 200 50-130 50-130 *30 | 0.1 .003 2na 2na 3 | 1111 | 20 20 *5 *5 *4 | PSI, GI PSI, TR, GI, TI, MO |
| | PT600 PT601 2N715 2N716 2N1507 | PSI PSI TI TI RA | npn,DM,si npn,DM,si npn,MS,si npn,MS,si npn,DD,si | 120 120 125 125 125 120 | 13w 13w 1.2w 1.2w 2w | 175 175 175 175 175 175 | 86.7 86.7 8 8 13.2 | 60 60 *50 *70 60 | - - - - 500 | 12 14 1 1 200 | 1 .001 .001 0.003 | 11111 | 40 40 3 3 20 | hi freq. hi pwr. hi freq. hi pwr. NA, MO NA, MO TI |
| HF 40 | 2N1785 2N1786 2N1787 2N1864 2N2188 | PH PH PH PH TI | pnp,MD,ge pnp,MD,ge pnp,MD,ge pnp,MD,ge pnp,AD,ge | 125 125 125 125 125 *** 125 | 45 45 45 60 125 | 85 85 85 100 | 0.75 .75 0.75 .8 - | *10 *10 *15 *20 40 | 50 50 50 50 50 30 | 150 250 120 60 90 | 2 2 1.5 1.5 3 | 11111 | *1.5 *1.7 *1.5 *1.6 | |
| | 2N2190 2N1748A 2N929 2N930 2N1177 | TI PH GI GI RCA | pnp,AD, ge pnp,MD,ge npn,PL,si npn,PL,si pnp,Dr,ge | **125 *132 *140 *140 140 | 125 60 1.8 w 1.8 w 80 | 100 175 175 175 71 | 0.8 3.33 3.33 | 60 *25 45 45 30 | 30 50 - - 10 | 90 70 40-120 100-300 100 | 3 1.5 3na 3na 12 | 11111 | *1.3 *5 *5 | |
| HF 41 | 2N1178 2N1179 2N2461 2N2465 3N35 | RCA RCA SSD SSD TI | pnp,Dr,ge pnp,Dr,ge npn,DP,si npn,DP,si npn,GD,si | 140 140 *140 *140 *150 | 80 80 4.0 1.8 125 | 71 71 200 200 150 | - 2.3 2.8 1 | 30 30 60 60 30 | 10 10 - - 20 | 40 80 100-180 100-180 4 | 12 12 2na 2na 0.4 | - - 14 | *5 *5 - | Tetrode |
| UE 43 | 2N728 2N729 2N1726 2N1727 2N1728 | TR TR PH PH PH | npn,JD,si npn,DJ,si pnp,MD,ge pnp,MD,ge pnp,MD,ge | 150 150 150 150 150 | 300 300 60 60 60 | 175 175 100 100 100 | - 0.8 0.8 0.8 | 15 30 *20 *20 *20 | 25 25 50 50 50 | 20 20 150 200 120 | 2.5 2.5 1.5 1.5 1.5 | 11111 | 8 8 *1.5 *1.5 *1.5 | |
| HF 42 | 2N1788 2N1789 2N1790 2N2189 2N2191 | PH PH PH TI TI | pnp,MD,ge pnp,MD,ge pnp,MD,ge pnp,AD,ge pnp,AD,ge | 150 150 150 **150 **150 | 60 60 60 125 125 | 100 100 100 - | 0.8 0.8 0.8 - - | *35 *35 *35 40 60 | 50 50 50 30 30 | 150 200 120 135 135 | 1.5 1.5 1.5 3 | 11111 | *1.5 *1.5 *1.5 - | |

May 24, 1963 T27

The high-voltage barrier to passivated PNP transistors has finally been broken
—but it took a new manufacturing process to overcome the obstacles.

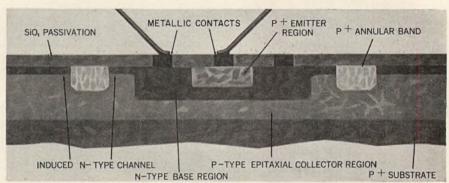
Now from MOTOROLA Epitaxial, Passivated PNP SILICON TRANSISTORS Made by the Annular* Process

Some new words are being added to the dictionary of semiconductor terms—words like Annular and Band-Guard , words that relate to a new manufacturing process which will have a strong influence on transistor design and promises to open new areas for transistor applications. The Annular manufacturing process provides a new degree of freedom from surface effects for semiconductor products.

For years, the industry had been working to design high voltage silicon PNP transistors with the low leakage currents normally associated with NPN types, surface passivated by the planar process. For PNP devices, planar techniques proved inadequate since any attempt to increase voltage ratings beyond approximately 20 volts (through increasing collector material resistivity) induced a phenomenon, called channeling, which actually increased leakage current far beyond tolerable levels.

Channeling is a condition whereby the surface portion of a transistor collector region actually changes polarity and hecomes an extension of the base region. The base-collector junction, therefore, rather than coming to the top surface where it is protected from the environment by a silicon oxide coating, extends to the unprotected edges of the transistor where it is subject to contamination and surface damage. This phenomenon circumvents the passivation advantages of planar designs and results in excessive leakage currents.

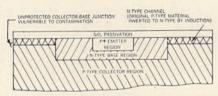
The formation of channels has been traced to effects of ionized or polarized particles on or within the passivating oxide coating which create an electrical environment that tends to alter the apparent polarity of the material directly



Cross Section of Annular Transistor

beneath the oxide—an effect which is particularly pronounced in lightly doped P-type material. The channels are random in nature and erratic in characteristics, and can be highly sensitive to radiation bombardment.

As a result of channeling, some manufacturers have reverted to earlier silicon mesa structures or have deliberately circumvented the oxide passivation in planar transistors in order to produce high voltage devices. These methods have yielded high voltage ratings but other characteristics of the resulting transistors do not compare favorably with those of surface passivated devices.



Cross Section of Planar Transistor

Now, Motorola has overcome these obstacles—but it has taken a new manufacturing process to do so. Rather than trying to eliminate the channel, Motorola, in a new series of "Band-Guard" transistors, has deliberately introduced a channel whose controlled characteristics completely overshadow the variable effects of any randomly induced channel, thus providing a high

degree of performance stability. Moreover the controlled channel is terminated close to the base region by a diffused annular band of the same polarity as the collector region but with a resistivity level impervious to channeling. The collector-base junction, therefore, is properly terminated underneath the oxide coating where it is protected against environmentally induced leakage currents. The resultant "Band-Guard" PNP silicon devices, for the first time, combine the low-leakage characteristics of passivated junctions with the high-voltage characteristics of non-passivated, or mesa structures.

And, if theoretical analysis of this process is confirmed by tests now in progress, they will prove to be more resistant to radiation, thus heralding improved performance and greater reliability of space equipment.

Though initially devised for the production of high voltage silicon PNP transistors, there are strong indications that the Annular process yields major benefits for NPN and field effect transistors and other semiconductor devices as well.

In view of these considerations, there is little doubt that the new, Motorola developed Annular process will take its place among the major milestones in the advancement of the semiconductor art.

*Patents Pending

†Trademark of Motorola Inc.

... made by the new ANNULAR PROCESS

Four new Motorola PNP silicon transistors made by the Annular process and featuring high speed . . . high voltage . . . low leakage . . . and surface passivation and stability, are now immediately available as types 2N2800, 2N2801, 2N2837, and 2N2838. Called "Band-Guard" transistors, the new devices reflect performance advantages inherent in an Annular, oxide-passivated, epitaxially fabricated transistor.

Annular Process — Provides a new degree of freedom from surface effects of adverse environments. Gives a new degree of performance stability by eliminating sub-surface leakage paths to the unprotected edges of the device. Makes possible combined high voltage and true silicon oxide passivation.

Oxide Surface Passivation — Prevents contamination of the junction by external agents. Makes possible the low collector leakage current (1/10th that of other PNP units) of Motorola's "Band-Guard" transistors.

Epitaxial Structure — Gives lower saturation voltage (% lower) and twice the frequency response (120 mc) of ordinary PNP devices.

Other types supplied as "Band-Guard" units include 2N1132, 2N1132A, 2N1132B, and 2N722.

Motorola passivated, epitaxial "Band-Guard" transistors are immediately available from your Motorola Seminconductor Distributor or District Office. For full electrical specifications write: Technical Information Center, Motorola Semiconductor Products, Inc., Box 955, Phoenix 1, Arizona.

"Band-Guard" Transistor Performance Ratings

| Characteristic | 2N2800 (TO-5 pkg) | 2N2801 (TO-5 pkg) | 2N2837 (10-18 pkg) | 2N2838 (TO-18 pkg) | Unit |
|---|----------------------|----------------------|-----------------------|-----------------------|------|
| Collector-Base Breakdown Voltage ($I_{\rm C}=10~\mu Adc, I_{\rm E}=0$) | 50 | 50 | 50 | 50 | Vdc |
| $ \begin{array}{c} \text{Collector-Emitter Breakdown Voltage} \\ (I_c = 100 \text{mAdc}, I_n = 0) \end{array} $ | 35 | 35 | 35 | 35 | Vdc |
| | 100 | 100 | 100 | 100 | nAdc |
| DC Forward Current Transfer Ratio $(I_c = 150 \text{ mAdc}, V_{c\kappa} = 10 \text{ Vdc})^{\circ}$ | 30.90 | 75-225 | 30-90 | 75-225 | _ |
| $\begin{aligned} & \text{Current-Gain} \leftarrow \text{Bandwidth Product} \\ & \text{($I_c = 50$ mAdc, $V_{c\kappa} = 10$ Vdc, $f = 100$ mc)} \end{aligned}$ | 120 | 120 | 120 | 120 | mc |

*Pulse Test: Pulse Width ≤ 300 μsec, duty cycle ≤ 2%

... also supplied as "Band-Guard" types:

| Characteristic | 2N1132 (70-5 pkg) | 2N1132A (TO-5 pkg) | 2N1132B (70-5 pkg) | 2N722 (TO-18 pkg) | Unit |
|--|----------------------|-----------------------|-----------------------|----------------------|------|
| Collector-Base Breakdown Voltage ($I_{\rm C}=100~\mu Adc,I_{\rm E}=0$) | 50 | 60 | 70 | 50 | Vdc |
| $\begin{array}{c} \text{Collector-Emitter Breakdown Voltage} \\ \text{($I_c = 100 mAdc pulsed)} \end{array}$ | 35 | 40 | 45 | 35 | Vdc |
| | 1.0 | s | 01 | 1.0 | μAdc |
| DC Forward Current Transfer Ratio (Ie = 150 mAdc, Vcg = 10 Vdc) | 30-90 | 30-90 | 30-90 | 30-90 | _ |
| Current-Gain — Bandwidth Product ($I_c = 50 \text{ mAdc}, V_{\text{ele}} = 10 \text{ Vdc}, f = 20 \text{ mc}$) | 60 | 60 | 60 | 60 | mc |



"new leader in Total Silicon Technology"

MOTOROLA Semiconductor Products Inc.

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A - 43-034

ON READER-SERVICE CARD CIRCLE 450

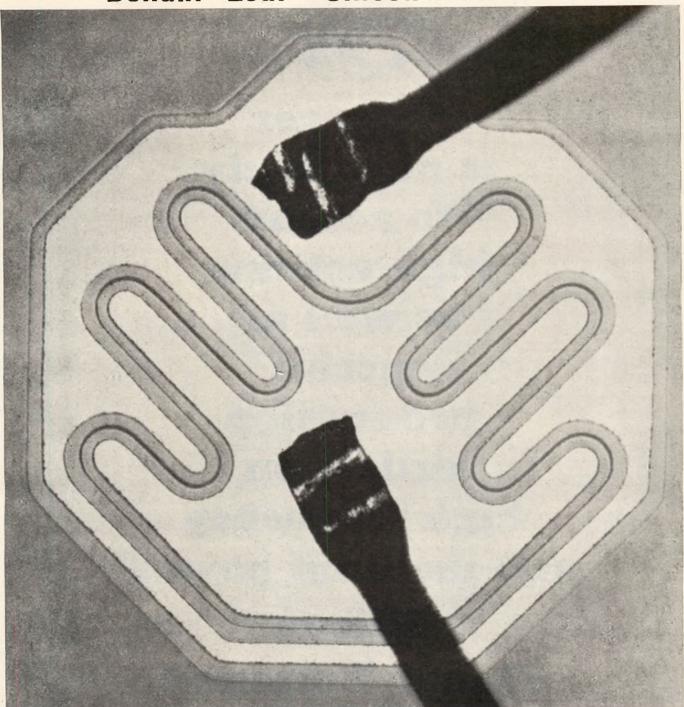
| | | | | | MAX. RATINGS | | | | CHARACTERISTICS | | | | | |
|-----------------------|--|---------------------------------|--|---|------------------------------------|--|--|--------------------------------------|-----------------------------------|--|---------------------------------------|-------------------------|---------------------------------------|---|
| Crass Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P c (mw) | T _i (°C) | mw/°C | V CEO *Y CBO (v) | 1 C (ma) | h _{fe} *hFE | ¹ CO (μα) | NF (db) | C _{oe} *C _{ob} (pf) | Remarks |
| | 2N2654 2N2797 2N1499A 2N2462 2N2466 | AMP SPR PH SSD SSD | pnp,AD,ge pnp,ED,ge pnp,MD,ge npn,DP,si npn,DP,si | 150 *150 *160 *160 *160 | 100 75 60 4.0 1.8 | 75 100°c 100 200 200 | 0.50 1.0 0.8 2.3 2.8 | *25 *20 *20 60 60 | 10 100 100 | 65 *50 *70 150-230 150-230 | | 18.8 | *3.5 *1.5 *5 *5 | |
| HF 43 | 2N1500 2N1500 2N1746 2N2207 2N2512 | PH GI PH AMP AMP | pnp,MD,ge MADT pnp,MD,ge pnp,AD,ge pnp,AD,ge | *175 , 175 175 175 175 175 | 60 60 60 260 260 | 100 100 100 75 75 | 0.8 0.8 0.8 0.25 0.25 | *15 *0.5 *20 *70 *70 | 50 10 50 50 50 | •70 70 70 200 200 | 1 5 1 - | 11111 | *1.5 3 *1.2 - | |
| | 2N1840 2N2494 2N2495 2N2496 PT886 | PSI AMP AMP AMP PSI | npn, TDP, si pnp, AD, ge pnp, AD, ge pnp, AD, ge npn, TDP, si | 180 180 180 180 180 | 2 100 100 100 1.6 | 175 85 85 85 85 175 | .013 1.67 1.67 1.67 .01 | 25 *20 *20 *20 *20 22 | 500 10 10 10 | 15 60 60 60 | .3 2.0 2.0 2.0 2.0 | 16661 | 11111 | |
| HF 44 | PT887 PT888 2N1566 2N1889 2N1890 | PSI PSI PSI PSI PSI | npn,TDP,si npn,TDP,si npn,TDP,si npn,TDP,si npn,TDP,si | 180 180 190 190 190 | 1.6 1.6 3 3 | 175 175 175 200 200 | .01 .01 .02 .017 | 45 45 80 100 100 | 50 | - 130 80 200 | .3 .01 .001 | 11111 | 11111 | |
| | 2N1342 2N1506A 2N1564 2N1565 2N1893 | PSI PSI PSI PSI PSI | npn, TDP, si npn, TDP, si npn, TDP, si npn, TDP, si npn, TDP, si | 190 190 190 190 190 | 2.8 3.5 3 3 | 175 200 175 175 200 | .018 .02 .02 .02 .02 | 150 80 80 80 120 | 300 500 50 50 50 | 12 60 30 60 80 | .01 .005 .01 .01 .001 | 11111 | 11111 | |
| HF 45 | 2N1893A 2N957 2N995 2N996 2N2318 | PSI FA FA FA GI | npn,TDP,si npn,DD,si pnp,DP,si pnp,DP,si npn,si | 190 *2 00 •200 •200 200 | 3 800 1200 1200 360 | 200 150 200 200 200 | .017 6.5 6.9 6.9 2.1 | 140 20 15 12 *1 | 500 - - - 20 | 90 *60 *60 *75 60 | .001 - 0.0002 0.0002 0.05 | 1 10 10 10 | - *7.5 *7.5 5 | |
| | 2N2319 2N2320 2N2403 2N2404 2N2618 | GI GI NA NA SYL | npn,si npn,si npn,si npn,si npn,MESA,si | 200 200 200 200 200 *200 | 300 600 8000 8000 600 | 200 200 200 200 200 250 | 1.7 3.4 45.2 45.2 | *1 *1 60 60 *60 | 20 20 0.001 0.001 750 | 60 60 20-60 40-120 *25 | 0.05 0.05 1 1 0.25 | 31111 | 5 5 25 25 •14 | |
| HF 46 | 2N2618/46 MM799 MM800 MM801 2N1506 | SYL MO MO MO PSI | npn,MESA,si npn,PE,si npn,PE,si npn,PE,si npn,MS,si | *200 *200 *200 *300 210 | 400 20w 25 w 4 w 3w | 250 175 175 175 175 175 | 133 167 26.7 0.2 | *60 *60 *60 *60 | 750 - - - - 9 | *25 *10 *10 *10 | 0.25 0.5 0.5 0.5 | 11111 | *14 - - - 8 | High freq., high power |
| | 2N2781 2N2782 2N2783 PT531 PT612 | PSI PSI PSI PSI PSI | npn,TDP,si npn,TDP,si npn,TDP,si npn,TDP,si npn,TDP,si | 210 210 210 210 210 210 | 13 13 13 13 13 | 175 175 175 175 175 | .087 .087 .087 .087 .087 | 75 100 100 75 75 | 2a 2a 2a 2a 2a 2a | 30 30 30 30 30 | .5 .5 .1 .1 | 11111 | 111111 | |
| HF 47 | PT1558 PADT28 2N1746 2N588 2N710 | PSI AMP PH PH MO | npn,TDP,si pnp,PADT,ge pnp,MD,ge npn,MD,ge pnp,MS,ge | 210 *220 235 250 250 | 4 100 60 30 300 | 200 - 100 85 100 | .023 1.7 0.8 0.75 4 | 80 *35 20 *15 *15 | 10 50 50 50 | 40 120 - - 40 | .005 - 2 1.8 .2 | - - - 3.8 - | 3 - | RF amp SPR,GI TI |
| | 2N957 2N988 2N989 2N1491 2N1837 | PSI PSI PSI RCA PSI | npn,TDP,si npn,TDP,si npn,TDP,si npn,MS,si npn,DM,si | 250 250 250 250 250 250 | .8 1 1 3w 2w | 150 175 175 175 175 | .006 .006 .006 .006 .20 .13.3 | 40 20 20 30 80 | - - 50 - | *45 70 70 50 9 | .01 .05 .05 .05 10 | 11111 | - - - - 11 | Hi freq., hi power |
| HF 48 | 2N1837A 2N1838 2N1839 2N2485 2N2486 | PSI PSI PSI CS CS | npn,DM,si npn,DM,si npn,DM,si npn,MS,si npn,MS,si | 250 250 250 *250 *250 *250 | 2.8w 2w 2w 8.7 w 8.7 w | 175 175 175 200 200 | 18.6 13.3 13.3 50 50 | 80 45 45 120 140 | - la la | 9 9 9 •10 •10 | .001 0.1 0.1 500 500 | 1111 | 11 9 9 •8 •8 | Hi freq., hi power Hi freq., hi power Hi freq., hi pwr. |
| | 2N 26 49 2N 26 50 2N 26 56 2N 27 99 PT 720 | CS CS PSI SPR PSI | npn,MS,si npn,MS,si npn,TDP,si pnp,ED,ge npn,TDP,si | *250 *250 250 *250 *250 250 | 8.7 w 8.7 w 1.2 75 1.2 | 200 200 200 100 200 | 50 50 .006 1.0 .006 | 65 140 25 •15 25 | 1 a 1 a 200 100 200 | *10 *10 50 *30 80 | 500 500 .01 3 | 11111 | *8 *8 - *4 | |
| HF 49 | SN 230 SN 234 2N 502 2N 502A 2N ! 492 | CS CS PH PH RCA | npn,MS,si npn,MS,si pnp,MD,ge pnp,MD,ge npn,MS,si | *250 *250 *260 *260 *260 275 | 18 w 18 w 60 75 3w | 175 175 85 100 175 | 120 120 1,0 1,0 20 | 65 140 *20 *30 60 | 2a 2a - - 50 | *10 *10 65 65 50 | 500 500 1 1.3 10 | - - 6 - | *25 *25 *1.0 *1.0 | SPR SPR |

| | | | | | MAX. RATINGS CHARACTERIS | | | | | RISTI | CS | | | |
|-----------------------|---|--------------------------------|---|--|--|--|-------------------------------|---------------------------------------|--|---|---|----------------------|---------------------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P c (mw) | T _i (°C) | mw/°C | УСЕО *УСВО (v) | ^{1.} C (ma) | hfe *hFE | ¹ C0 (μα) | NF (db) | C _{oe} *C _{ob} (pf) | Remarks |
| | 2N2635 2N695 2N707 2N834 2N835 | TI MO PSI GI GI | pnp, EM, ge pnp, DM, ge npn, TDP, si npn, si npn, si | *295 300 300 300 300 300 | 300 75 1 360 360 | 100 100 175 200 200 | 4.0 1 .006 2.1 21 | *30 15 56 *40 *25 | 100 50 - 10 10 | 100 40 12 40 30 | 1 0.2 .005 0.5 0.5 | 1111 | *3.5 3.5 - 4 4 | GE CL CL |
| HF 50 | 2N916 2N960 2N961 2N962 2N964 | PSI TI TI TI | npn,TDP,si pnp,EM,ge pnp,EM,ge pnp,EM,ge pnp,EM,ge | 300 *300 *300 *300 *300 | 1.2 150 150 150 150 | 200 - - - - | .006 - - - - | 45 15 12 12 15 | 150 150 150 150 | 120 *20 *20 *20 *40 | .001 3 3 3 3 | 11111 | - *4 *4 *4 | |
| | 2N965 2N966 2N985 2N1493 2N2242 | TI TI TI RCA GI | pnp, EM, ge pnp, EM, ge pnp, EM, ge npn, MS, si npn, si | *300 *300 *300 300 300 | 150 150 150 3w 360 | - - 175 200 | - - - 20 2.1 | 12 12 15 100 •40 | 150 150 200 50 10 | *40 *40 *60 50 80 | 3 3 3 10 0.1 | 11111 | *4 *4 *6 -6 | |
| HF 51 | 2N2381 2N2382 2N2795 2N2796 2N503 | MO MO SPR SPR PH | pnp,EM,ge pnp,EM,ge pnp,ED,ge pnp,ED,ge pnp,MD,ge | *300 *300 *300 *300 320 | 750 750 75 75 75 25 | 100 100°c 100°c 85 | 10 10 1.0 1.0 0.5 | *30 *45 *15 *12 *20 | 500 500 100 100 50 | *25 *25 *50 *30 4.2 | 1 1 3 3 3 | 11111 | *3.5 *3.5 *3 *4 *1.0 | SPR |
| | 2N703 2N706 2N706A 2N706B 2N706C | SYL SYL SYL SYL | npn,P,si npn,P,si npn,P,si npn,P;si npn,P,si | *320 *320 *320 *320 *320 | 300 300 300 300 300 300 | 200 200 200 200 200 200 | 1.15.1.1 | *25 *25 *25 *25 *40 | 200 200 200 200 200 200 | *40-100 *20 *20-60 *20-60 *20-60 | .5 .5 .5 .025 | 11111 | *6 - *5 *5 *5 | W |
| HF 52 | 2N706/46 2N706A/46 2N706B/46 2N706C/46 2N706/51 | SYL SYL SYL SYL | npn,P,si npn,P,si npn,P,si npn,P,si npn,P,si | *320 *320 *320 *320 *320 | 400 400 400 400 400 300 | 200 200 200 200 200 200 | | *25 *25 *25 *40 *25 | 200 200 200 200 200 200 | *20 *20-60 *20-60 *20-60 *20 | .5 .5 .5 .025 | 11111 | *6 *5 *5 *5 *6 | |
| | 2N706A/51 2N706B/51 2N706C/51 2N968 2N969 | SYL SYL SYL MO | npn,P,si npn,P,si npn,P,si pnp,DM,ge pnp,DM,ge | *320 *320 *320 *320 *320 *320 | 300 300 300 300 300 300 | 200 200 200 100 100 | - - 4 4 | *25 *25 *40 *15 *12 | 200 200 200 - | *20-60 *20-60 *20-60 35 35 | .5 .5 .025 3 | 11111 | *5 *5 *5 4.0 4.0 | RA RA |
| HF 53 | 2N970 2N971 2N972 2N973 2N974 | MO MO MO MO | pnp, DM, ge pnp, DM, ge pnp, DM, ge npn, DM, ge npn, DM, ge | *320 *320 *320 *320 *320 | 300 300 300 300 300 | 100 100 100 100 100 | 4 4 4 4 | *12 *7 *15 *12 *12 | 1 1 1 1 1 | 35 35 75 75 75 | 3 10 3 3 3 | - - 4.0 4.0 | 4.0 4.0 4.0 - | RA RA RA RA RA |
| | 2N975 2N2256 2N2257 2N2258 2N2259 | MO MO MO MO MO | npn, DM, ge npn, ME, si npn, ME, si pnp, ME, ge pnp, ME, ge | *320 *320 *320 *320 *320 *320 | 300 1000 1000 300 300 | 100 175 175 100 100 | 4 6.67 6.67 4 | *7 *7 *7 *7 *7 | 100 100 100 100 | 75 30 50 30 50 | 10 3 3 3 3 | 4.0 4 4 4 | 11111 | RA CL CL Epitaxial Epitaxial |
| HF 54 | 2N499 2N743 2N743/46 2N743/51 2N744 | PH SYL SYL SYL SYL | pnp,MD,ge npn,P,si npn,P,si npn,P,si npn,P,si | 340 *350 *350 *350 *350 | 30 300 400 300 300 | 85 200 200 200 200 200 | 9.75 - - - - | 30 *20 *20 *20 *20 *20 | 50 | 8.5 *20-60 *20-60 *20-60 *40-120 | 1.0 1.0 1.0 1.0 1.0 | 11111 | 1.3 *5 *5 *5 *5 | GI, SPR |
| | 2N744/46 2N744/51 2N784A 2N784A/46 2N784A/51 | SYL SYL SYL SYL | npn,P,si npn,P,si npn,P,si npn,P,si npn,P,si | *350 *350 *350 *350 *350 | 400 300 300 400 300 | 200 200 200 200 200 200 | 11111 | *20 *20 *40 *40 *40 | - 200 200 200 200 | *40-120 *40-120 *25-150 *25-150 *25-150 | 1.0 1.0 .025 .025 .025 | 11111 | *5 *5 *3.5 *3.5 *3.5 | |
| HF 55 | 2N914 2N915 2N984 2N1962 2N2170 | FA FA SPR SYL SPR | npn,DP,si npn,DP,si pnp,MD,ge npn,P,si pnp,MD,ge | *350 *350 *350 *350 *350 | 1200 1200 60 400 60 | 200 200 100 200 100 | 6.9 6.9 0.8 - 0.8 | *15 50 10 *40 10 | - 100 200 100 | 55* *100 *50 *20-80 *50 | 0.004 0.005 5.0 0.25 5.0 | 11111 | 4.5 *3.0 *2.5 *3.5 *3.0 | CL, MO |
| | 2N2397 2N2787 2N2788 2N2788 2N2789 2N2790 | SYL GI GI GI GI | npn,P,si npn,PE,si npn,PE,si npn,PE,si npn,PE,si | *350 *350 *350 *350 *350 | 300 3 w 3 w 3 w 1.8 w | 200 175 175 175 175 175 | 5.33 5.33 5.33 3.33 | *25 35 35 35 35 35 | 200 - - - - | *25-125 20-60 40-120 100-300 20-60 | 0.10 2na 2na 2na 2na 2na | 11111 | *5 *5 *5 *5 | |
| HF 56 | 2N2791 2N2792 2N741 2N741A 2N1407 | GI GI MO MO TI | npn,PE,si npn,PE,si pnp,MS,ge pnp,OM,ge pnp,MS,ge | *350 *350 360 360 375 | 1.8 w 1.8 w 300 300 75 | 175 175 100 100 100 | 3.33 3.33 4 4 1 | 35 35 *15 *20 30 | - 100 100 50 | 40-120 100-300 25 25 6 | 2na 2na .2 0.2 2 | 7 7 7 | *5 *5 6 6 | Amp VHF |

May 24, 1963 T31

| | | | | | MAX. RATINGS | | СНА | RACTE | RISTI | CS | | | | |
|-----------------------|--|---------------------------------|---|--|--|--|--------------------------------------|--------------------------------------|--------------------------------------|--|---|-----------------------|--|--|
| Cross Index Key | Type No. | Mfr. | Type / | fae *fT **fab (mc) | P c (mw) | T i (°C) | mw/°C | V CEO *V CBO (v) | 1 C (ma) | hfe *hFE | ¹ CO (μα) | NF (db) | Coe *Cob (pf) | Remarks |
| | 2N708 2N708/46 2N708/51 2N743 2N828A | SYL SYL SYL MO | npn,P,si npn,P,si npn,P,si npn,PE,si pnp,DJEM,ge | *400 *400 *400 *400 *400 | 300 400 300 1000 300 | 200 200 200 175 100 | - - 6.67 4 | *40 *40 *40 *25 *15 | - - 200 200 | *30 120 *30 120 *30 120 *20 *60 *40 | .025 .025 .025 .002 3 | 11111 | *6 *6 *3.5 *2.2 | |
| HF 57 | 2N829 2N916 2N947 2N2217 2N2218 | MO FA FA MO MO | pnp,DJEM,ge npn,DP,si npn,DP,si npn,DD,si npn,DD,si | *400 *400 *400 *400 *400 | 300 1200 1200 3 3 | 100 200 200 175 175 | 4 6.9 6.9 5.33 5.33 | *15 25 - *60 *60 | 200 - - - - - | *80 *80 *50 20-60 40-120 | 3 0.002 0.005 0.01 0.01 | 11111 | *2.2 *4.0 - - - | Pl. Epitaxial Pl. Epitaxial |
| | 2N2219 2N2220 2N2221 2N2222 2N2537 | MO MO MO MO | npn,DD,si npn,DD,si npn,DD,si npn,DD,si pnp,PE,si | *400 *400 *400 *400 *400 | 3 1.8 1.8 1.8 800 | 175 175 175 175 175 200 | 5.33 3.33 3.33 3.33 4.57 | *60 *60 *60 *60 *60 | 11111 | 100-300 20-60 40-120 100-300 *50/150 | 0.01 0.01 0.01 0.01 0.25 | 11111 | 8 | Pl. Epitaxial Pl. Epitaxial Pl. Epitaxial Pl. Epitaxial |
| HF 58 | 2N2538 2N2539 2N2540 MM719 2N835 | MO MO MO MO | npn PE,si npn PE,si npn PE,si npn PE,si npn P,si | *400 *400 *400 *400 *425 | 800 500 500 3 w 300 | 200 200 200 200 200 200 | 4.57 2.86 2.86 17.1 | *60 *60 *60 *60 *25 | - - - 200 | *100/300 *50/150 *100/300 *40 | 0.25 0.25 0.25 0.5 | 11111 | *8 *8 *8 - | |
| | 2N835 46 2N835 51 2N708 2N744 2N834 | SYL SYL FA TI SYL | npn,P,si npn,P,si npn,DP,si npn,PE,si npn,P,si | *425 *425 *450 *450 *450 | 400 300 1200 1000 300 | 200 200 200 175 200 | - 6.9 6.67 | *25 *25 15 *25 *40 | 200 200 - 200 200 200 | - *50 *40-*120 *25 | - 0.004 .002 0.5 | 1111 | - *5.0 *3.5 *4 | CL |
| HF 59 | 2N834/46 2N834/51 2N835 2N914 2N914/46 | 27F 27F 27F 27F 27F | npn,P,si npn,P,si npn,DDM,si npn,P,si npn,P,si | *450 *450 *450 *450 *450 | 400 300 300 300 400 | 200 200 175 200 200 | - 2 - | * 10 * 40 * 25 * 40 * 40 | 200 200 200 - - | *25 *25 40 *30-120 *30-120 | 0.5 0.5 0.5 .025 | 1111 | *4 *4 - *6 *6 | Epitaxial |
| | 2N914/51 2N982 2N983 2N1405 2N1406 | SYL SPR SPR TI | npn,P,si pnp,MD,ge pnp,MD,ge pnp,MS,ge pnp,MS,ge | *450 *450 *450 450 450 | 300 60 60 75 75 | 200 100 100 100 100 | - 0.8 0.8 1 | *40 15 15 30 30 | - 100 100 50 50 | *30-120 *70 *65 8 | .025 3.0 3.0 2 2 | - - - 5 6 | *6 *2.5 *2.5 - | |
| HF 60 | 2N2168 2N2169 2N960 2N961 2N962 | SPR SPR MO MO MO | pnp,MD,ge pnp,MD,ge pnp,DM,ge pnp,DM,ge pnp,DM,ge | *450 *450 *460 *460 *460 | 60 60 300 300 300 | 100 100 100 100 100 | 0.8 0.8 4 4 | 15 15 *15 *12 *12 | 100 100 100 100 100 | *70 *65 40 40 40 | 3. 0 3.0 0.4 0.4 0.4 | 11111 | *2.5 *2.5 2.2 2.2 2.2 | Epitaxial Epitaxial, RA Epitaxial, RA |
| | 2N963 2N964 2N964A 2N965 2N966 | MO MO MO MO | npn, DM, ge npn, DM, ge npn, DM, ge npn, DM, ge npn, DM, ge | *460 *460 *460 *460 *460 | 300 300 300 300 300 300 | 100 100 100 100 100 | 4 4 4 4 | *12 *15 *15 *12 *12 | 100 100 100 100 100 | 40 70 80 70 70 | 5 0.4 0.4 0.4 0.4 | 11111 | 2.2 2.2 2.2 2.2 2.2 2.2 | Epitaxial, RA Epitaxial, RA Epitaxial, RA Epitaxial, RA Epitaxial, RA |
| HF 61 | 2N967 2N1143 2N1561 2N1562 2N2095 | MO TI MO MO SPR | npn,DM,ge pnp,DB,ge pnp,MS,ge pnp,MS,ge pnp,ED,ge | *460 480 500 500 *500 | 300 750 3w 3w 1w | 100 100 100 100 100 | 4 10 40 40 — | *12 25 *25 *25 *30 | 100 100 500 500 300 | 70 8 10db 10db | 5 .7 1.5 1.5 0.2 | 11111 | 2.2 1.5 7 7 6.5 | Epitaxial, RA PG=22db © 200mc, MO High freq., high power High freq., high power |
| | 2N2098 2N2501 2N700 2N700A 2N709 | SPR MO MO MO SYL | pnp,ED,ge pnp,PE,si pnp,DM,ge pnp,DM,ge npn,P,si | *500 *500 600 600 *600 | 1w 360 75 75 300 | 100 200 100 100 200 | 2.06 1 1 | *30 *40 *25 *25 *15 | 300 - 50 50 - | - *50/150 10db 5db200mc *20-120 | 2 - 0.4 0.4 .005 | - 6 6 | 6.5 *4 1.1 1.1 *3 | UHF Amp. MIL |
| HF 62 | 2N709 46 2N709 51 2N1142 2N2368 2N2369 | SYL SYL TI FA FA | npn,P,si npn,P,si pnp,DB,ge npn,DP,si npn,DP,si | *600 *600 600 *650 *650 | 400 300 750 1200 1200 | 200 200 100 200 200 | - 10 6.9 6.9 | *15 *15 30 15 15 | - 100 - - | *20-120 *20-120 10 *40 *70 | .005 .005 0.7 0.1 0.1 | 1.101.1 | *3 *3 1.5 *2.5 *2.5 | PG=26db @ 200mc,MO |
| | 2N1645 2N537 2N1094 2N1141 2N1195 | WE WE TI WE | pnp,DJ,ge pnp,DG,ge pnp,DM,ge µnp,DB,ge pnp,DM,ge | 700 750 750 750 750 750 | 250 150 750 250 | 100 100 100 100 100 | 12.5 3.3 2.0 10 4.0 | *35 - *35 *30 | 300 100 40 100 50 | 50 10 13 12 13 | 1.5 2 1.2 0.7 1.2 | 11111 | 10 2.8 4 1.5 4 | U.S. MIL only U.S., MIL only PG=30db@200mc, MO TI, MO |
| HF 63 | 2N709 2N709A 2N709A '46 2N709A '51 2N917 | FA SYL SYL SYL FA | npn,DP,si npn,P,si npn,P,si npn,P,si npn,DP,si | *800 *800 *800 *800 *800 | 1000 300 400 300 300 | 200 200 200 200 200 200 | 5.0 - - - 1.71 | 6.0 *15 *15 *15 15 | 11111 | *55 *30-90 *30-90 *30-90 *50 | 0.005 .050 .050 .050 .050 0.0005 | 11111 | *2.5 *3 *3 *3 *1.0 | |

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S-19500/74C JAN-2N696M—MIL-S-19500/99B S-19500/74C USA-2N697—MIL-S-19500/99A S-19500/74C JAN-2N697M—MIL-S-19500/99B S-19500/74C USA-2N706—MIL-S-19500/120 S-19500/99A JAN-2N706M—MIL-S-19500/120A USN-2N1613—MIL-S-19500/181

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small signal and low level amplifiers

2N910 2N930 2N911 2N1973 2N912 2N1974 2N929 2N1975

general purpose amplifiers and switches

2N696 2N718 2N1420 2N697 2N718A 2N1613 2N717 2N956 2N1711

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2N706 2N708 2N914

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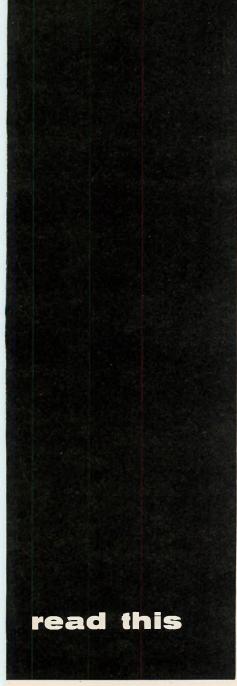
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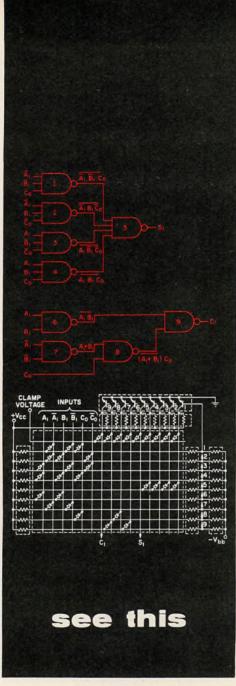
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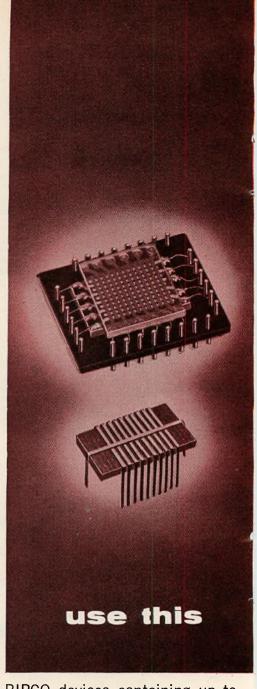
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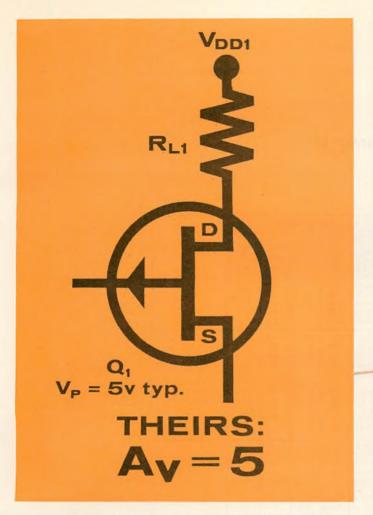


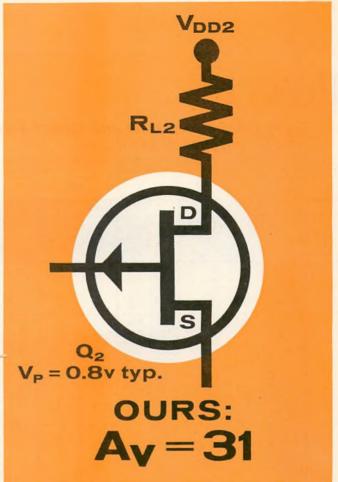
HF continued

| | | 900 | | | MAX. RATINGS CHARACTERISTIC | | | | | | | CS | | |
|-----------------------|---|--------------------------------|--|--|------------------------------------|--|------------------------------|--|---------------------------------------|---|--|--------------------|---------------------------------------|--|
| Cross Index Key | Type Na. | Mfr. | Туре | (ae *fT **fab (mc) | P c (mw) | T _i (°C) | mw/°C | VCEO *VCBO (v) | l C | h _{fe} *h _{FE} | l CO (μα) | NF (db) | C _{oe} *C _{ob} (pf) | Remarks |
| | 2N2416 2N918 2N2415 2N797 2N955 | TI FA TI TI RCA | pup, DM, ge npn, DP, si pnp, DM, ge npn, MS, ge npn, DDM, ge | *800 *900 *900 *1000 *1000 | 75 300 75 150 150 | 100 200 1 00 - 100 | 1.0 1.71 1.0 - - | *15 15 *15 7 *12 | 20 - 20 150 150 | 20 *50 30 *40 | 1 0.0005 1 1.0 0.6 | 3.4 2.4 — | *1.2 1.0 *1.2 *4 **4 | мО |
| HF 64 | 2N2808 2N2784 2N2784 46 2N2784 51 2N218 | RA SYL SYL SYL SYL | pnp,PE,si npn,P,si npn,P,si npn,P,si pnp,AJ,ge | *1000 *1200 *1200 *1200 - | 300 300 400 300 80 | 200 200 200 200 200 85 | - - - 1.3 | *30 *15 *15 *15 *15 *20 | 11111 | *5 *40-120 *40-120 *40-120 22-110 | 0.002 .005 .005 .005 50 | 7.5 - - - | *0.7 *3 *3 *3 | |
| | 2N231 2N233 2N247 2N312 2N410 | SPR SY SY SY SY | pnp,SBT,ge npn,AJ,ge pnp,Dr,ge npn,AJ,ge pnp,AJ,ge | 11111 | 9 50 80 75 50 | 55 75 100 85 75 | *0.9 1 1 - | *4.5 *10 *40 *15 *20 | 3 50 10 - | 66 10 20-175 - 22-110 | 3 50 50 60 5 | 110011 | - - 12 | GI, TI |
| HF 65 | 2N504 2N544 2N624 2N706A 2N706C | SPR SY SY GE SY | pnp,MD,ge pnp,DJ,ge pnp,DJ,ge npn,si npn,DM,si | 11111 | 30 80 100 300 360 | 85 85 100 175 200 | 1.3 1.3 - | *35 *18 *20 25 40 | 50 10 - - 50 | 16 20-175 20 2.0 20-60 | 100 4 30 0.5 .025 | 11111 | 5.0 | GI Planar, Epitaxial, RA CL, RA |
| | 2N708 2N717 2N718 2N718A 2N719 | GE GE GE GE | npn,si npn,si npn,si npn,si npn,si | 11111 | 360 0.4 0.4 0.5 0.4 | 200 175 175 200 175 | 11111 | 40 60 60 75 120 | 11111 | 3.0 - - 30 15 | 0.5 1.0 1.0 10µa 2.0 | - - 12 - | 6.0 35 35 25 20 | Planar Epitaxial CL, MO Planar Passivated, RA Planar Passivated, CL, PSI Planar Passivated, PSI Planar Passivated, PSI |
| HF 66 | 2N719A 2N720 2N720A 2N743 2N744 | GE GE SY SY | npn,si npn,si npn,si npn,MS,si npn,MS,si | 1111 | 0.5 0.4 0.5 300 300 | 200 175 200 175 175 | - - 2 2 | 120 120 120 *20 *20 | 1.0amp - - 200 200 | 15 30 30 20-60 40-120 | 10µa 2.0 - 1 1 | 111111 | 15 20 15 - | Planar Passivated, PSI Planar Passivated, PSI Planar Passivated, PSI Epitaxial, CL., GI, NA, TI, MO Epitaxial, CL., GI, NA, TI, MO |
| | 2N753 2N768 2N769 2N781 2N782 | TI SPR SPR SY SY | npn,MS,si pnp,MD,ge pnp,MD,ge pnp,MS,ge pnp,MS,ge | 11111 | 1 w 35 35 150 150 | 175 100 100 100 100 | 6.7 | 25 *12 *12 15 *12 | 50 100 100 •200 200 | - 40 55 25 20 | 0.5 1 0.3 3 | 11111 | 5 | GI, NA, GE, CL PH PH PH Epitaxial, GE Epitaxial, GE |
| HF 67 | 2N783 2N784 2N828 2N834 2N849/TI-43 | SY SY GE GE TI | npn,MS,si npn,MS,si pnp,ge npn,si npn,EP,si | 11111 | 300 300 150 300 1000 | 175 175 100 175 | 2 2 - - - | 40 30 15 40 15 | 200 200 200 200 200 30 | 20-60 25 3.0 3.5 *20-*60 | .25 .25 3.0 0.5 | 11111 | 6.0 4.0 | Epitaxial, CL, GI, MO (CL, Epitaxial), GI Mesa Epitaxial, RCA Planar Epitaxial CL |
| | 2N850/TI-43 2N851/TI-42 2N852/TI-42 2N914 2N915 | 22 TI | npn,EP,si npn,EP,si npn,EP,si npn,si npn,si | 11111 | 1000 1000 1000 360 360 | - - 200 200 | 1 | 15 12 12 40 70 | 30 200 200 - - | *40-*120 *20-*60 *40-*120 3.0 2.5 | - - 25тµа 10 | 11111 | - - 6.0 3.5 | Planar Epitaxial Planar Passivated |
| HF 68 | 2N929 2N930 2N955 2N960 2N961 | SYL SYL RCA GE GE | npn,P,si npn,P,si npn,MS,ge pnp,ge pnp,ge | 11111 | 300 300 150 150 150 | 200 200 - 100 100 | 11111 | *45 *45 12 15 12 | - 100 150 150 | - *60 20 20 | - - 3.0 3.0 | 111111 | - - 4.0 4.0 | Mesa Epitaxial, RA Mesa Epitaxial |
| HF 69 | 2N962 2N964 2N965 2N966 2N994 | GE GE GE GE | pnp,ge pnp,ge pnp,ge pnp,ge pnp,ge | 11111 | 150 150 150 150 200 | 100 100 100 100 100 150 | 11111 | 12 15 12 12 12 | 150 150 150 150 150 | 20 20 20 20 20 20 | 3.0 3.0 3.0 3.0 3.0 3.0 | 111111 | 4.0 4.0 4.0 4.0 6.0 | Mesa Epitaxial Mesa Epitaxial Mesa Epitaxial Mesa Epitaxial Mesa Epitaxial |
| nr 69 | 2N1158 2N1158A 2N1204 2N1264 2N1266 | PH PH SPR SY SY | pnp,MD,ge pnp,MD,ge pnp,MD,ge pnp,DD,ge pnp,AJ,ge | 11111 | 60 75 200 50 80 | 100 100 100 75 85 | 0.8 1 - 1 1.3 | *20 *20 *20 *20 *10 | 100 100 500 10 | 50 50 40 15 | 5 7 50 100 | 11111 | *3 *2.8 - - | PH, MO |
| HF 70 | 2N1398 2N1399 2N1400 2N1401 2N1401A | TI TI TI TI | pnp,MS,ge pnp,MS,si pnp,MS,ge pnp,MS,ge pnp,MS,ge | 11111 | 50 50 50 50 50 | 85 4 85 85 85 85 | 11111 | 30 30 30 30 30 | 10 10 10 10 10 | 2.3 2.3 1.6 2 | 10 10 10 10 10 | 5 6 1 1 - | 11111 | |
| 70 | 2N1402 2N1450 2N1494 2N1515 2N1646 | TI SY SPR AMP SY | pnp,MS,ge pnp,AJ,ge pnp,MD,ge pnp,PADT,ge pnp,MS,ge | 11111 | 50 120 400 83 150 | 85 100 100 75 100 | 1.6 - - 2 | 30 *30 *20 *20 *15 | 10 100 500 10 50 | 2.2 20 15 60 20 | 10 10 7 - 3 | 11111 | 11111 | GI PH, MO OC169 |

HF continued

| | | | | | MAX. RATINGS | | | | | СНА | RACTE | RISTIC | S | |
|-----------------------|---|----------------------------------|--|--------------------|----------------------------------|--|------------------------------------|--|--|---|-------------------------------------|------------------------|----------------------------------|--|
| Cross Index Key | Type No. | Mfr. | Type | fae *fT **fab (mc) | P c (mw) | T _i (°C) | mw/°C | V _{CEO} *V _{CBO} (√) | 1 C (ma) | hfe *hFE | ¹ CO (μα) | NF (db) | Coe *Cob (pf) | Remarks |
| | 2N1676 2N1677 2N1684 2N1711 2N1742 | PH PH SY GE PH | pnp,SAT,si pnp,SAT,si pnp,AJ,ge npn,si pnp,MD,ge | 11111 | 100 100 100 0.8 60 | 140 140 100 200 125 | - 1.3 - | *4.5 4.5 *25 75 *20 | 50 50 100 - 55 | 10.5 50 - 50 *33 | .001 0.001 5 10 0.8 | - - 8 4.9 | - - 25 - | SPR, chopper " Spr. Chopper Planar Passivated, RA |
| HF 71 | 2N1743 2N1744 2N1745 2N1747 2N1782 | PH PH PH PH SY | pnp,MD,ge pnp,MD,ge pnp,MD,ge pnp,MD,ge pnp,AJ,ge | 11111 | 60 60 60 60 100 | 125 125 100 100 100 | - 0.8 0.8 1.3 | *20 *20 *20 *20 *30 | 50 50 50 50 100 | *33 *33 *33 70 30-150 | 0.8 0.8 1 1 6 | 10 - - - - | 11111 | |
| | 2N1783 2N1784 2N1841 2N1865 2N1866 | SY SY WE PH PH | pnp,AJ,ge pnp,AJ,ge npn,DM,si pnp,MD,ge pnp,MD,ge | 11111 | 100 100 1250 60 60 | 100 100 150 100 100 | 1.3 1.3 100 0.8 0.8 | *30 *30 75 *20 *35 | 100 100 2000 50 50 | 30-90 20 30 70 70 | 5 4 .1 2 1 | 11111 | 11111 | |
| HF 72 | 2N1867 2N1868 2N1893 2N1958 2N1959 | PH PH GE SY SY | pnp,MD,ge pnp,MD,ge npn,si npn,MS,si npn,MS,si | 1111 | 60 0.8 600 600 | 100 100 200 175 175 | 0.8 0.8 - 4 4 | *35 *20 120 *60 *60 | 50 50 - 500 500 | 50 *33 30 20-60 40-120 | 1 1.5 15 0.5 0.5 | 11111 | - 15 18 18 | Planar Passivated Epitaxial Epitaxial |
| 1.0 | 2N1960 2N1961 2N1962 2N1963 2N1964 | 2Y 2Y 2Y 2Y 2Y 2Y | pnp,MS,ge pnp,MS,ge npn,MS,si npn,MS,si npn,MS,si | 11111 | 150 150 400 400 400 | 100 100 175 175 175 | 2 2 2.6 2.6 2.6 2.6 | *15 *12 *40 *30 *60 | 200 200 200 200 200 500 | 25 20 20-60 25 20-60 | 3 3 .25 .25 0.5 | 11111 | - 3 3.5 18 | Epitaxial Epitaxial Epitaxial Epitaxial Epitaxial |
| HF 73 | 2N1965 2N1969 2N2192 2N2192A 2N2193 | SY SY GE GE GE | npn,MS,si pnp,AJ,ge npn,si npn,si npn,si | 1111 | 400 150 0.8 0.8 0.8 | 175 100 200 200 200 200 | 2.6 2 - - - | *60 *30 60 60 80 | 500 400 1.0a 1.0a 1.0a | 40-120 50-200 2.5 2.5 2.5 | 0.5 5 10тµа 10тµа 10тµа | 11111 | 18 20 20 20 20 20 | Epitaxial 71 Planar Epitaxial Planar Epitaxial Planar Epitaxial |
| | 2N2193A 2N2194 2N2194A 2N2195A 2N2360 | GE GE GE GE PH | npn,si npn,si npn,si npn,si pnp,MD,ge | 11111 | 0.8 0.8 0.8 0.6 60 | 200 200 200 200 200 125 | - - - 0.75 | 80 60 60 45 *20 | 1.0a 1.0a 1.0a 1.0am 50 | 2.5 2.5 2.5 2.5 • 2.5 • 33 | 10πμα 10πμα - 100πμ 0.8 | 1111 | 20 20 - 20 - | Planar Epitaxial Planar Epitaxial Planar Epitaxial Planar Epitaxial, RA |
| HF 74 | 2N2361 2N2362 2N2363 2N2389 2N2395 | PH PH TI TI | pnp,MD,ge pnp,MD,ge pnp,MS,ge npn,PL,si npn,PL,si | 11111 | 60 60 125 2000 2000 | 125 120 - - - | 0.75 2 - - - | *20 *20 60 35 40 | 50 50 30 600 300 | *33 *33 135 *40-*120 *20-*60 | 0.8 0.8 3 - | 11111 | | |
| | 2N2396 2N2398 2N2399 2N2410 2N2411 | TI PH PH TI TI | npn,PL,si pnp,MD,ge pnp,MD,ge npn,PE,si pnp,PE,si | 11111 | 2000 60 60 2500 1000 | 100 100 - - | 2 2 | *20 *20 *20 30 20 | 300 50 50 800 100 | *40-*120 *33 *33 *30-*120 *20-*60 | 8.0 8.0 | 11111 | 1111 | |
| HF 75 | 2N2412 10B551 10B553 10B555 10B556 | TI GE GE GE GE | pnp.PE.si npn.GP.si npn.PE.si npn.PE.si npn.PE.si | 11111 | 1000 100 100 100 100 | 125 125 125 125 125 | 1.0 1.0 1.0 1.0 | 20 *40 *40 *25 *25 | 100 - - - - | *40-*120 *30-120 *30-120 20 *20-60 | 50mμa .5 .5 .5 | 11111 | 6.0 6.0 6.0 6.0 | |
| | 10C573 10C574 11B551 11B552 11B554 | GE GE GE GE | npn,P,si npn,P,si npn,P,si npn,P,si npn,P,si | 11111 | 100 100 100 100 100 | 125 125 125 125 125 125 | 1.0 1.0 1.0 1.0 1.0 | *45 *45 *60 *60 *60 | | 36-90 73-333 *20-60 *40-120 *40-120 | 0.2 0.2 .5 .5 25mµa | - - - - 12 | *8 *8 - - - *25 | |
| HF 76 | 11B555 11B556 11B560 GT1665 MA-1 | GE GE GE GI SPR | npn,P,si npn,P,si npn,P,si pnp,AJ,ge pnp,MAT,ge | 11111 | 100 100 100 150 25 | 125 125 125 100 75 | 1.0 1.0 1.0 2 | *60 *100 *100 *100 6 | - - - - 50 | *100-300 *40-120 *40-120 25 40 | 25mµa 25mµa .5 4 10 | 12 - - - - | *25 *15 - - - | Drift |
| HF 77 | MA-2 PT850 PT850A SO-1 SO-2 | SPR PSI PSI SPR SPR | pnp,MAT,ge npn,DM,si npn,DM,si pnp,SBT,ge pnp,SBT,ge | 11111 | 20 2w 2.8w 20 15 | 75 175 175 65 65 | 13.3 18.6 | 3 120 120 5 3 | 50 - - 5 5 | 40 2 2 10 10 | 10 2 2 10 10 | 11111 | - | hi freq., hi pwr. hi freq., hi pwr. |
| | SO-3 ST3031 | SPR TR | pnp,SBT,ge npn,DJ,si | - | 20 150 | 65 175 | - | 5 - | 5 - | 10 - | 10 | - | - | |





WHY DO LOW PINCH-OFF UNIFETS* GIVE HIGHER VOLTAGE AMPLIFICATION?

BECAUSE AV IS INVERSELY PROPORTIONAL TO V_P WHEN $V_{DD1} = V_{DD2}$ AND $V_{DS1} = V_{DS2} = YOU$ ALSO GET GREATER BIAS STABILITY AND WIDER DYNAMIC RANGE.

AVAILABLE NOW IN FOUR g_m VALUES AS SHOWN WRITE FOR FILE #841, THE DESCRIPTIVE PAPER ON LOW V_P UNIFET APPLICATIONS

Low Pinch-off UNIFETs *(Unipolar Field-Effect Transistors) now available:

| Typical | 2N2841 | 2N2842 | 2N2843 | 2N2844 | | | | | | | |
|---|--------|--------|--------|--------|------|--|--|--|--|--|--|
| VP | 0.8 | 0.8 | 0.8 | 0.8 | ٧ | | | | | | |
| gm | 90 | 270 | 800 | 2000 | μmho | | | | | | |
| loss | -50 | -150 | -450 | -1000 | μа | | | | | | |
| NF at 1kc | 0.5 | 0.5 | 0.5 | 0.5 | db | | | | | | |
| Pinch-off: 1.7v max.—Gate-drain breakdown: 20v min —T0-18 package | | | | | | | | | | | |

AMPLIFICATION CALCULATIONS FOR HIGH PINCH-OFF VS. LOW PINCH-OFF UNIFETS

For all UNIFETs, it can be shown that:

 $g_{mo} \dagger = \frac{2.5 \, l_{DSS} \dagger \dagger}{V_P} \text{ within about } 20\%$

When $V_{DD1} = V_{DD2} = -15v$ and $V_{DS1} = V_{DS2} = -5v$

then IDSS1 $R_{L1} = 10v$ and IDSS2 $R_{L2} = 10v$

Available voltage amplification, $A_v = g_m R_L$

From these equations, it can be shown that $A_{v1} = \frac{25}{V_{P1}}$ and $A_{v2} = \frac{25}{V_{P2}}$

since $V_{P1} = 5v$ $V_{P2} = 0.8v$

 $A_{v1} = 5$ $A_{v2} = 31$

 $\dagger g_m$ when $V_{GS} = 0$. $\dagger \dagger$ Drain-source current when $V_{GS} = 0$.



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|-----------------------|--|----------------------------------|--|------------------------------------|--|--|---------------------------------|--------------------------|---|--|--|--------------------------|-------------------------|----------------------------------|
| Crass Index Key | Type Na. | Mfr. | Туре | P _c (w) | w/°C | T _i (°C) | V CEO *V CBO (v) | l _c (a) | h _{fe} | Ι (ma) (*μα) | fae *fT (kc) | Powr. Gain (db) | Powr. Out. (w) | Remarks |
| P 1 | 2N2038 2N2039 2N2040 2N2041 2N2198 | TR TR TR TR TR | npn npn npn npn npn | 0.6 0.6 0.6 0.6 0.6 | 0.03 0.03 0.03 0.03 0.03 0.025 | 200 200 200 200 200 200 | 45 75 45 75 80 | 0.5 0.5 0.5 0.5 | 12-36 12-36 30-90 30-90 20-70 | 0.001 0.001 0.001 0.001 0.010 | 11111 | 11111 | 1111 | |
| | 2N957 2N339 2N340 2N341 2N341A | PSI TI TI TI TR | npn,TPD,si npn,GR,si npn,GR,si npn,GR,si npn,DJ,si | 0.8w 1.0 1.0 1.0 | 0.006 0.008 800.0 800.0 800.0 | 150 150 150 150 200 | 40 55 85 *125 *125 | .06 .06 .06 | 9-90 9-90 9-90 9-90 15-90 | 0.01 .001 .001 .001 | 250 6 6 6 - | 30 30 30 30 | 11111 | TR, PSI TR TR |
| P 2 | 2N342 2N342A 2N342B 2N343 2N343A | TI TI TI TI TR | npn,GR,si npn,GR,si npn,GJ,si npn,GR,si npn,DJ,si | 1.0 1.0 1.0 1.0 | 0.008 0.008 - 0.008 .008 | 150 150 - 150 150 | 60 85 85 60 *60 | .06 .06 0.6 .06 | 9-32 9-32 9-32 28-90 29-90 | .001 .001 - .001 .001 | 6 6 - 8 - | 30 30 - 30 - | 1 | TR TR TR TR |
| | 2N343B 2N497 A 2N498 A 2N656 A 2N657 A | TI BE BE BE BE BE | npn,GJ,si npn,PL,si npn,PL,si npn,PL,si npn,PI,si | 1.0 1 1 1 1 | 1 1 1 1 1 | 200 200 200 200 200 | 65 60 60 60 100 | 0.6 - - - - | 28-90 *12-36 *12-36 *30-90 *30-90 | 11111 | 11111 | 11111 | 1 - 1 - 1 | |
| P 3 | 2N706 2N707 2N709 2N988 2N989 | FA PSI FA PSI PSI | npn,DD,si npn,TDP,si npn,DP,si npn,TPD,si npn,TPD,si | 1.0 1 1.0 1 | 0.0067 .006 0.005 0.006 0.006 | 175 175 200 175 175 | *25 56 6.0 20 20 | 11111 | *45 12 *55 70 70 | *0.005 .005ma *0.005 0.05 0.05 | *400 300 *800 250 250 | 6 - 8 11 | 0.2 0.32 0.63 | МО |
| | 2N1048A 2N1206 2N1207 2N2017 2N2106 | BE TR TR GE GE | npn,DM,si npn,GR,si npn,GR,si npn,MS,si npn,MS,si | 1 1.0 1.0 1.0 1.0 | - 10 10 - - | 165 200 200 200 200 150 | 120 60 *125 60 60 | 0.5 - - - - | *12-36 15-19 15-90 30 12-36 | 1 1 10 200° | - - - - 15 | 11111 | 11111 | BE BE |
| P 4 | 2N2107 2N2108 2N2726 2N2727 7A30 | GE GE GE GE | npn,MS,SI npn,MS,si npn,DM,si npn,DM,si npn,DM,si | 1.0 1.0 1.0 1.0 1.0 | 1 | 150 150 200 200 150 | 60 60 *200 *200 *50 | 11111 | 30-90 30 *30-90 *75-150 *12-36 | 200° 200° °1.0 °1.0 °10 | 15 15 - - 15mc | 11111 | 1 - 1 - 1 | BE BE |
| | 7A31 7A32 2N708 2N869 2N914 | GE GE FA FA | npn,DM,si npn,DM,si npn,DP,si pnp,DP,si npn,DP,si | 1.0 1.0 1.2 1.2 1.2 | - 0.0069 0.0069 0.0069 | 150 150 200 200 200 200 | *50 *50 15 18 *15 | 11111 | *30-90 *75-200 *50 *50 *55 | *10 *10 *0.004 0.0001 *0.004 | 15mc 15mc *450 150 *370 | | | MO CL, MO |
| P 5 | 2N915 2N916 2N947 2N995 2N996 | FA FA FA FA | npn,DP,si npn,DP,si npn,DP,si pnp,DP,si pnp,DP,si | 1.2 1.2 1.2 1.2 1.2 | 0.0069 0.0069 0.0069 0.0069 0.0069 | 200 200 200 200 200 200 | 50 25 - 15 12 | 11111 | *100 *80 *50 *60 *75 | *0.005 *0.002 *0.005 0.0002 0.0002 | •350 •400 •400 200 200 | 61111 | | RA |
| P 6 | 2N1566 2N2368 2N2369 2N2656 PT720 | TI FA FA PSI PSI | npn,MS,si npn,DP,si npn,DP,si npn,EM,si npn,TPD,si | 1.2 1.2 1.2 1.2 1.2 | 0.0069 0.0069 0.006 0.006 | 175 200 200 200 200 200 | *80 15 15 25 25 | 50 - 200 200 | 100 •40 •70 50 80 | 1 *0.1 *0.1 0.01 5 | 50 *650 *650 250 250 | - - 10 15 | - - 0.05 0.05 | TR,NA |
| P 6 | 2N721 2N722 2N978 2N717 2N718 | TR TR TR FA FA | pnp,PL,si pnp,PL,si pnp,PL,si npn,DD,si npn,DD,si | 1.25 1.25 1.25 1.5 1.5 | .010 .010 .010 0.010 0.010 | 200 200 200 175 175 | *30 *50 *30 - | 1 1 | *20 *25 *15 *40 *80 | *1 *1 *5 *0.01 *0.01 | *50,000 *60,000 *40,000 *80 *100 | | - | RA, PSI RA, PSI |
| | 2N719 2N720 2N721 2N722 2N2786 | FA FA FA AMP | npn,DD,si npn,DD,si pnp,DD,si pnp,DD,si pnp,BB | 1.5 1.5 1.5 1.5 1.5 | 0.010 0.010 0.010 0.010 35 | 175 175 175 175 175 75 | - 35 35 *34 | - - - - 150 | *40 *65 *30 *60 *40 | *0.01 *0.01 *0.01 *0.01 | *90 *100 *70 *80 | - - - 10 | - - - 0.5 | RA, PSI RA, PSI 0.5w @80mc |
| P 7 | PT886 PT887 PT888 2N718A 2N719A | PSI PSI PSI FA FA | npn,TPD,si npn,TPD,si npn,TPD,si npn,DP,si npn,DP,si | 1.6 1.6 1.6 1.8 1.8 | 0.01 0.01 0.01 0.0103 0.0103 | 175 175 175 200 200 | 22 45 45 - 60 | 11111 | - - - •80 •40 | 0.3 0.3 0.3 •0.0003 •0.0003 | 180 180 180 *100 *80 | 6.0 4.0 - | 150 750 1000 — | PSI |

T40

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V_{CE}(sat.)

Object

V MAX.@I_c=5A

V_{BE}(sat.)

1

1

V MAX.@I_c=5A

1_{CB0}

0 1

μα@V_{CB}=60V



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|--------|-------|-------|-------|--------|
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| 2N2812 | 80 | 60 | 8 | 40-120 |
| 2N2813 | 120 | 80 | 8 | 20-60 |
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|-----------------------|--|--------------------------------|--|--|--|--|--------------------------------|---------------------------------|---|---|---|-----------------------|----------------------|--|
| Cross Index Key | Гуре No. | Mfr. | Туре | P _c (w) | w/°C | T _i (°C) | V CEO *V CBO (v) | i _c (a) | hfe *hFE | C0 (ma) (*μa) | fae *f _T (kc) | Powr. Gain (db) | Powr. Out. (w) | Remarks |
| P 8 | 2N720A 2N870 2N871 2N910 2N911 | FA FA FA FA | npn,DP,si npn,DP,si npn,DP,si npn,DP,si npn,DP,si | 1.8 1.8 1.8 1.8 1.8 | 0.0103 0.0103 0.0103 0.0103 0.0103 | 200 200 200 200 200 200 | 80 60 60 60 | 11111 | *80 *80 *200 *135 *70 | *0.0003 *0.0003 *0.0003 *0.0003 | *100 *70 *90 *80 *70 | 11111 | 11111 | PSI RA RA RA, PSI RA |
| , 0 | 2N912 2N956 2N 1890 2N696 | FA FA PSI FA | npn,DP,si npn,DP,si npn,TPD,si npn,DD,si | 1.8 1.8 1.8 2.0 | 0.0103 0.0103 0.01 0.0133 | 200 200 200 175 | 60 - 100 - | | *42 *200 200 *40 | *0.0003 *0.0003 0.001 *0.01 | *60 *100 190 *60 | 1111 | 1111 | RA PSI RA, PSI |
| | 2N697 2N699 2N1131 2N1132 2N1252 | FA FA FA FA | npn,DD,si npn,DD,si pnp,DD,si pnp,DD,si npn,DD,si | 2.0 2.0 2.0 2.0 2.0 2.0 | 0.0133 0.0133 0.0133 0.0133 0.0133 | 175 175 175 175 175 | - 35 35 | 11111 | *75 *65 *30 *60 *35 | *0.01 *0.01 *0.01 *0.01 *0.01 | *80 *100 *70 *90 *80 | 11111 | 11111 | RA, PSI RA MO RA |
| P 9 | 2 N1253 2N1420 2N1840 2N1983 2N1984 | FA FA PSI FA FA | npn,DD,si npn,DD,si npn,TPD,si npn,DD,si npn,DD,si | 2.0 2.0 2 2.0 2.0 2.0 | 0.0133 0.0133 0.013 0.016 0.016 | 175 175 175 150 150 | - 25 25 25 25 | - 500 - - | *45 *150 15 4.0 4.0 | *0.1 *0.01 0.3 *1.0 *1.0 | *110 *130 180 *10 *10 | 11111 | 11111 | RA PSI RA RA |
| | 2N1985 2N1986 2N1987 2N1988 2N1989 | FA FA FA FA | npn,DD,si npn,DD,si npn,DD,si npn,DD,si npn,DD,si | 2.0 2.0 2.0 2.0 2.0 2.0 | 0.016 0.016 0.016 0.016 0.016 | 150 150 150 150 150 | 25 25 25 45 45 | 11111 | 4.0 *100 *50 *70 *40 | *1.0 *1.0 *1.0 *1.0 *1.0 | *50 *80 *80 *80 *80 | 11111 | 11111 | RA RA RA RA |
| P 10 | 2N1990 2N1991 2N2303 2N1335 2N1336 | FA FA FA PSI PSI | npn,DD,si npn,DD,si pnp,DP,si npn,MS,si npn,MS,si | 2.0 2.0 2.0 2.8 2.8 | 0.016 0.016 0.0133 0.024 0.024 | 150 150 175 150 150 | 20 -35 .120 120 | - - .075 .075 | *40 *30 *120 13 | *1.0 *0.005 .008 | *50 *50 *90 70 70 | 11111 | 11111 | RA RA high freq. high pwr. high freq., high pwr. |
| | 2N1339 2N1340 2N1341 2N1342 2N698 | PSI PSI PSI PSI FA | npn,MS,si npn,MS,si npn,MS,si npn,TPD,si npn,DP,si | 2.8 2.8 2.8 2.8 3.0 | 0.024 0.024 0.024 0.018 0.0172 | 150 150 150 175 200 | 120 120 120 150 60 | .075 .075 .075 300 | - - 12 •40 | .008 .008 .008 0.01 •0.0003 | 70 70 70 190 •70 | - - 8 - | - - 0.7 | high freq., high pwr. high freq., high pwr. high freq., high pwr. RA, PSI |
| P 11 | 2N1505 2N1506 2N1506 A 2N1561 2N1562 | PSI PSI BE MO MO | npn,MS,si npn,MS,si npn,PL,si pnp,MS,si pnp,MS,ge | 3 3 3 3 | 0.2 0.2 - .04 .04 | 175 175 200 100 100 | 50 60 50 •25 •25 | - - .25 .25 | 7 9 •10-10 10 10 | - - 0 - .0015 | 70 70 - 500 mc 450 mc | 11111 | | high freq., high pwr., BE high freq., high pwr., BE high freq., high pwr. high freq., high pwr. |
| | 2N1564 2N1565 2N1566 2N1613 2N1613 | PSI PSI PSI TR FA | npn,TPD,si npn,TPD,si npn,TPD,si npn,PL,si npn,DP,si | 3 3 3 3 3.0 | 0.02 0.02 0.02 0.02 .017 0.0172 | 175 175 175 200 200 | 80 80 80 •75 | 50 50 50 | 30 60 130 *20 *80 | 0.01 0.01 0.01 10na *0.0003 | 190 19 0 190 •60,000 •80 | 1111 | 1111 | |
| P 12 | 2N1692 2N1693 2N1711 2N1711 2N1890 | MO MO TR FA EA | pnp,MS,ge pnp,MS,ge npn,PL,si npn,DP,si npn,DP,si | 3 3 3,0 3.0 | .04 .04 .017 0.0172 0.0172 | 100 100 200 200 200 | *25 *25 *75 - 60 | .25 .25 - - | 10 db 10 db •100 •130 •200 | .0015 .0015 10na •0.0003 •0.0003 | 500 mc -70,000 •100 •90 | 6 6 - - | 0.5 .4 - - | PSI RA |
| | 2N1893 2N1893 2N1893A 2N1893A 2N1973 2N1974 | FA PSI PSI FA FA | npn,DP,si npn,TPD,si npn,TPD,si npn,DP,si npn,DP,si | 3.0 3 3 3.0 3.0 | 0.0172 0.017 0.017 0.0172 0.0172 | 200 200 200 200 200 200 | 120 140 60 60 | 500 500 - - | - 80 90 *135 *70 | *0.0003 0.001 0.001 *0.0003 *0.0003 | *70 190 190 *80 *70 | | | RA |
| P 13 | 2N1975 2N2049 2N2224 MM719 2N1506A | AMF FA BE MO PSI | npn,DP,si npn,DP,si npn,PL,si npn,PE,si npn,TPD,si | 3.0 3.0 3 3 3 3.5 | 0.0172 0.0172 - 17.1 0.02 | 200 200 200 200 200 200 | 60 - *40 *60 80 | - - - - 500 | *42 3.0 *40-121 *40 60 | *0.0003 *0.0003 | *60 - - *400 190 | - - - 10 | - - 0.8 1.3 | DVV-U- |
| | 2N497 2N498 2N656 2N657 TAG200 | TI TI TI TI FA | npn,DJ,si npn,DJ,si npn,DJ,si npn,DJ,si npn,DP,si | 4.0 4.0 4.0 4.0 4.0 | .023 .023 .023 .023 .023 0.0228 | 200 200 200 200 200 200 | 60 100 60 100 | 200 200 200 200 200 | 12-36 12-36 30-90 30-90 *80 | 10 10 10 10 | 9 mc 9 mc 8 mc 8 mc | 11111 | 11111 | TR, FA, NA, BE, RCA TR, FA, NA, BE TR, FA, NA, BE, RCA,GE TR, FA, NA, BE, GE |
| P 14 | 2N1479 2N1480 2N1481 2N1482 2N1615 | RCA RCA RCA RCA TR | npn,DJ,si . npn,DJ,si npn,DJ,si npn,DJ,si npn,ME,si | 4 4 4 4 4 | - - - .023 | 175 175 175 175 175 200 | 60 100 60 100 *100 | 1.5 1.5 1.5 1.5 | 50 50 50 50 •25 | 10 10 10 10 •10 | 1.5 mc 1.5 mc 1.5 mc 1.5 mc 1.5 mc •25,000 | | - | TR TR TR TR |

| | 1 | | | | | TINGS | | | CHARAC | TERIST | ICS | 100 VI | | |
|----------------------|---|--------------------------------|---|--|---|--|----------------------------------|-------------------------------|--|--|---|--|----------------------|---|
| Cros Inde: Key | | Mfr. | Туре | P _c (w) | w/°c | T _i | VCEO *VCBO | ا _د (a) | h _{fe} | CO (ma) (*μa) | fae *fT (kc) | Powr. Gain (db) | Powr. Out. (w) | Remarks |
| P 1 | MHT-4401 MHT-4402 MM801 PT1588 ST4341 | MH MH MO PSI TR | npn,EP,si npn,EP,si npn,PE,si npn,TPD,si npn,ME,si | 4 4 4 4 4 | 0.023 0.023 26.7 0.023 .023 | 200 200 175 200 200 | *60 *120 *60 80 *80 | 0.5 0.5 - - | 20-120 20-120 *10 40 *15 | 0.001 0.002 *0.5 0.005 *80 | 80m 80m •300 210 •15,000 | - - 10 | - 6 1 | Vce (sat)=1v Vce (sat)=2 v |
| | 2N699B 2N1067 2N1700 2N2102 2N2270 | FA STC RCA RCA RCA | npn,BP,si npn,DJ,si npn,si npn,TDP,si npn,TDP,si | 5.0 5 5 5 5 | 0.035 28.6 - - | 200 175 - - - | - 60 *60 120 60 | - 0.5 1.0 1.0 1.0 | 35 *20 35* 35* | *0.0004 5 - - | *100 1.5 - - - | | 11111 | PSI RCA, AMF TR BE BE |
| 0.16 | 2N2297 2N121E 2N2038 2N2039 2N2040 | FA SY TR TR TR | npn,DP,si npn,AJ,ge npn,DJ,si npn,DJ,si npn,DJ,si | 5.0 6 6 6 6 | 0.0286 0.1 .03 .03 | 200 85 200 200 200 | *45 45 75 45 | 2 0.5 0.5 0.5 | *35 40-100 12-36 12-36 30-90 | *0.0004 3 .001 .001 .001 | *90 7 - - | 11111 | 1 1 1 1 1 1 | |
| P 16 | 2N2041 OC30 2N326 7F1 7F2 | TR AMP SY GE GE | npn,DJ,si pnp,PADT,ge npn,AJ,ge npn,um,si npn,MS,si | 6 6.7 7 7 | .03 75 0.11 | 200 75 85 175 175 | 75 *32 *35 *80 *80 | 0.5 1.4 2 - | 30-90 35 45 •12-36 •30-90 | .001 .012 3 *50 *50 | - 150 - - | 1111 | 11111 | |
| | 7F3 7F4 2N1172 2N1183 2N1183A | GE GE DE RCA RCA | npn, DM, si npn, DM, si pnp, AJ, ge pnp, AJ, ge pnp, AJ, ge | 7 7 7.5 7.5 7.5 7.5 | - .1 - | 175 175 100 100 100 | *120 *120 *40 45 60 | - 1.5 3 3 | *12-36 *30-90 20 20 | *50 *50 0.100 .03 .03 | - 17 500 500 | - 34 - | 11111 | driver |
| P 17 | 2N1183B 2N1184 2N1184A 2N1184B 2N1609 | RCA RCA RCA RCA DE | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 7.5 7.5 7.5 7.5 7.5 7.5 | - - - 10.0 | 100 100 100 100 100 | 80 45 60 80 60 | 3 3 3 1.5 | 20 40 40 40 *30/75 | .03 .03 .03 .03 .03 | 500 500 500 500 15 | - - - 32 | 11111 | |
| | 2N1610 2N1610 2N1612 2N2403 2N2404 | DE KF KF NA NA | pnp,A,ge pnp,AJ,ge pnp,AJ,ge npn,si npn,si | 7.5 7.5 7.5 8 8 | 10.0 .1 .1 0.045 0.045 | 100 100 100 200 200 | 60 *80 *60 60 | 1.5 1½ 1½ 1 1 | *50/125 *35 *35 20-60 40-120 | 100 *20 *20 0.001 0.001 | 15 - - 200mc 200mc | 32 - - 12 12 | - - 1.2 1.2 | |
| P 18 | 2N2485 2N2486 2N2649 2N2650 2N122 | CS CS CS TI | npn,MS,si npn,MS,si npn,MS,si npn,MS,si npn,GR,si | 8.7 8.7 8.7 8.7 8.75 | .05 .05 .05 .05 .070 | 200 200 200 200 200 150 | 120 140 65 140 120 | 1 1 1 1 140 | *10 *10 *10 *10 3 | *500 *500 *500 *500 | *250 *250 *250 *250 *250 | 7 5 5 6.5 28 | 5 3 2 4.5 | |
| P1 | 2N176 2N350 2N351 2N376 2N669 | SY SY RCA RCA MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 10 10 10 10 10 | 0.15 0.13 1 1 1.5 | 90 100 90 90 90 | *30 *40 40 40 30 | 3 3 3 3 3 | 4.5 40 65 78 90 | 0.3 - 3 3 0.3 | - 5 - - 5 | 35.5 32 33.5 35 40 | - 4 4 2 | RCA, MO, BE MO, BE MO, SY, BE MO, BE BE, CL |
| | 2N1068 2N1714 2N1715 2N1716 2N1717 | IND TI TI TI TI | npn,AJ,si npn,MS,si npn,MS,si npn,MS,si npn,MS,si | 10 10 10 10 10 | 0.133 .134 .134 .134 .134 | 175 175 175 175 175 175 | 60 60 100 60 100 | 1.5 1 1 1 1 | 38 - - - - | 0.5 .002 .002 .002 .002 | 20 mc 20 mc 20 mc 20 mc 20 mc | 11111 | 11111 | STC, RCA, AMF, BE |
| P 20 | 2N1718 2N1719 2N1720 2N1721 2N1755 | TI TI TI TI CL | npn,MS,si npn,MS,si npn,MS,si npn,MS,si pnp,AJ,ge | 10 10 10 10 10 | .134 .134 .134 .134 2.5 | 175 175 175 175 175 95 | 60 100 60 100 *40 | 1 1 1 1 3 | | .002 .002 .002 .002 .002 | 20 mc 20 mc 20 mc 20 mc 20 mc 15 | - - - - 30-75 | 11111 | RA RA RA |
| 7 20 | 2N1756 2N1757 2N1758 2N1759 2N1760 | CL CL CL CL | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 10 10 10 10 10 | 2.5 2.5 2.5 2.5 2.5 2.5 | 95 95 95 95 95 | *60 *80 *100 *40 *60 | 3 3 3 3 | - | 7 7 7 7 | 15 8 8 10 10 | 30-75 30-75 30-75 60-150 60-150 | 11111 | |
| P 21 | 2N1761 2N1762 CDT1310 CDT1311 CDT1312 | CL CL CL | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 10 10 10 10 10 | 2.5 2.5 1.5 1.5 | 95 95 95 95 95 | *80 *100 *40 *60 *80 | 3 3 5 5 5 | 11111 | 7 7 15 15 15 | 6 5 5 5 | 60-150 60-150 40-120 40-120 40-120 | 111111 | |
| | CDT1313 CST1739 CST1740 CST1741 CST1742 | CL CL CL CL | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,LA,qnq pnp,AJ,ge | 10 10 10 10 10 | 1.5 2.5 2.5 2.5 2.5 2.5 | 95 95 95 95 95 | *100 *40 *40 *40 *40 | 5 3 3 3 3 | 11111 | 15 3 3 3 3 | 5 7 7 7 7 | 40-120 28-39 28-33 32-35 34-37 | 11111 | |

May 24, 1963 T43

$P_{\text{continued}}$

| 0.13 | | 2 | 1 - | S | 6.0 | 30min 20min | 3 | 100 | 58 | 65.0 0.33 | 20 20 | ag,lA,qnq ag,lA,qnq | KE | ZN1437 ZN1326 | |
|----------------------------------|------------------------------|-------------------------------|--|--|--------------------------------------|--|----------------------------------|--------------------------------------|--------------------------------------|---|----------------------------------|--|--|--|-----------------------|
|)-10 [' KE | | 2 2 2 - | | 9 | 87.0 8.0 8.0 | 20-60 30min 30min | ~ ~ ~ ~ | 001 08* 09* 001 | 82 82 100 | 72. EE.0 EE.0 | 20 20 20 20 | 9g,lA,qnq 9g,lA,nqn 9g,lA,qnq | 2X 2X 11 | 2N1294 2N1294 2N1294 | 8 Z d |
| , кЕ , кЕ , кЕ | 38 | - - - S Z | - - - 30 52 | | £.1 87.0 87.0 87.0 | 50-60 50-60 50-60 - | | 80 90 90 52 | 001 001 06 98 | 2.0 5.1 75. 75. | 20 20 20 20 20 | 93,lA,qnq 93,lA,qnq 93,lA,qnq 93,lA,qnq 93,lA,qnq | 11 11 38 38 | 2N1043 2N1043 2N4001 2N266A | |
| | | 22-25 2 92-51 2 2 | - 52 - - | - 8 - 88 | 1°0 1°0 1°0 1 | - - - 50 50 | w w w w w | 30 12 12 80 80 | 58 58 58 58 | 0.33 2.0 2.0 0.5 2.0 | 20 20 20 20 20 20 | 98,LA,qnq 98,LA,qnq 98,LA,qnq 98,LA,qnq | A9 A9 38 38 38 | 821NS 281NS 22NS A22SNS 82SNS | 47.1 |
| | KE BE | 2 8 8 9 | 2.8 4 - - | \$ \$ 0\$Z• 0\$Z• \$\$20 | 1 2 - 200 • 200 • 200 | 50 50 10 • 10 • 10 | £ Z Z Z | 30 • 30 • 140 • 62 • 140 | 98 98 921 921 921 | 21. 21. 21. 51. 55. | 20 20 18 18 18 | iz,ZM,nqn iz,ZM,nqn iz,ZM,nqn 99,LA,qnq 98,LA,qnq | 22 22 22 22 8A | 5N129 5N122 2N534 2N535 2N531 | 7 <u>2</u> q |
| 3 | 38 | - - - 3.7 | - 33 5.7 | - S | 005 • - 05 • 05 • | 01.0 52 .30-90 .30-90 | 2 - - - | 99 •32 •150 •150 | SZT SZT SZT SZT SZT | - - \$6.0 S1. | 81 21 31 31 31 | iz,MO,nqn iz,MO,nqn iz,MO,nqn 99,LA,qnq iz,2M,nqn | CE CE CE CE CE | 762 763 764 24307A 24307A | 07 |
| | | 11111 | 11111 | 11111 | 05 • 05 • 05 • 05 • | • 15-38 • 15-38 • 15-38 • 15-39 | 11111 | 08. 08. 08. 08. | 941 941 941 941 941 | - | 12 12 12 12 12 13 | iz,MO,nqn iz,MO,nqn iz,MO,nqn iz,MO,nqn iz,MO,nqn | 30 30 30 | 703 183 194 194 | 92 d |
| 7 | | 11111 | 11111 | 11111 | 05 • 05 • 05 • 05 • 05 • 05 • | \$30-80 \$15-36 \$30-80 \$15-36 | 11111 | 08. 08. 08. 08. 08. | 921 921 921 921 921 | | 12 12 12 12 12 12 | iz,MO,nqn iz,MO,nqn iz,MO,nqn iz,MO,nqn iz,MO,nqn | 30 30 30 30 | 101 702 703 701 702 | |
| | | | 11111 | 12 - - - | 05 05* 05* 05* | 15 • 15-30 • 15-30 • 30-30 | 11111 | 021 08* 08* 021* 021* | 941 941 941 941 941 | - | 12 12 12 12 12 | iz,MQ,nqn iz,MQ,nqn iz,MQ,nqn iz,MQ,nqn iz,2M,nqn | 30 30 30 30 | 783 187 187 2022N2 5022N2 | 82 q |
| | | | 11111 | - - - - SI | 05. 05. 05. SI engl | 06-08. 06-08. 030-90 30-90 | 30 | \$150 \$150 80 80 | 941 941 941 941 941 | - | 12 12 12 12 12 12 | iz,ZM,nqn iz,ZM,nqn iz,MO,nqn iz,MO,nqn iz,MO,nqn | 30 30 30 30 | 2N 2S 03 2N 2S 05 2N 2S 01 2N 2S 01 2N 2S 03 2N 2S 03 2N 2S 03 | |
| 73¢⊬ | NZ | 3.0 8 - - | - - - 01 10 | 700 700 700 710 710 | 2. 2. 2.0 2.0 | 30-90 30-90 30 30 | 1 0.1 2 2 2 | 09. 08. 32 54 54 | 001 001 52 521 521 | 780. 780. 0.5 5.0 5.0 | 12 12 13 13 | iz,90T,nqn iz,90T,nqn 9g,lA,qnq 9g,lA,qnq 9g,lA,qnq | PSI PSI MH MH WH | PT531 PT612 2N307 2N1658 2N1659 | ₹Z d |
| freq., hi pwr. freq., hi pwr. | | - 3.2 3.2 3.2 3.5 | 2 2 2 8 qp 10 qp | \$10 \$10 \$10 \$30 \$40wc | x6m0! x6m0! č. č. | 30 30 30 - | 62.1 62.1 5 2 2 2 | 001 001 97 09 87 | \$21 \$21 \$21 \$21 \$21 | 7,38 7,38 780. 780. 780. | 13 13 13 13 | iz,MO,nqn iz,MO,nqn iz,9OT,nqn iz,9OT,nqn iz,9OT,nqn | P51 P51 P51 P51 P51 P51 | 2N2782 2N2782 2N2781 2N1710 2N1710 | |
| e (sat)=2 v | 38 | 12111 | - - - - | 80m 2 150 2 150 | 0.002 0.1 0.1 5 5 100 | 33 33 30-150 | 9 7 5.8 8 1 | 080 090 250 00 00 | 06 82 06 16 00Z | 720.0 - 5.0 - | 13 11 11 11 10 | iz,93,nqn 9g,1A,qnq 9g,TOA9,qnq. 9g,1A,qnq 9g,TOA9,qnq | HM ADA AMA YZ 9MA | MH T-4502 2N301 2N1314 2N301A 2N301A | FZ d |
| v l=(162) 9: | οΛ | 71 90 90 21 | - 52 32 22 32 30 | ф 9 ф 9 | 2 2 2 8 0.001 | 70-150 - - - - | 3 3 3 | 09. 08 02 05 00 | 00Z 06 06 98 58 | 2.0 2.0 2.0 2.0 2.0 2.0 2.0 | 10 10 10 10 10 | 9g,lA,qnq 9g,lA,qnq 9g,lA,qnq 9g,lA,qnq iz,93,nqn | אא כר כר כר כר | CTP1105 CTP1108 CTP1111 CTP1111 CTP1111 | |
| | | 1.2 | 82 35-32 28-33 58-33 38-36 | L L L L | 2 2 2 2 2 | | 5 5 5 5 | 0b 08* 08* 0b* | \$8 \$6 \$6 \$6 \$6 | 2.5 2.5 2.5 2.5 2.5 2.5 | 10 10 10 10 10 | ag,lA,qnq ag,lA,qnq ag,lA,qnq ag,lA,qnq ag,lA,qnq | 10 01 01 01 01 01 | C15110¢ C211146 C21-1140 C21-1140 C211143 | ₩ d |
| e mark s | צי | .tuO (w) | Powr. Gain (db) | (KC) +L +QG | (pm) (DD) | ajų ajų* | (o) | (^) *V CEO | (O ₀) | J₀/M | р (w) | Type | .13M | Type No. | Cross Index Key |
| | MAX. RATINGS CHARACTERISTICS | | | | | | | | | | 4 | | | | |

| | | | | | MAX. RATINGS | | | | CHARAC | TERIST | ICS | | | |
|-----------------------|--|-------------------------------|--|--|--|-----------------------------------|----------------------------------|----------------------------|---|----------------------------------|--------------------------------------|---------------------------|----------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | P _c (w) | w/°C | T _i (°C) | V CEO *V CBO (v) | l _c (a) | h _{fe} *h | CO (mo) (* μα) | fae *fT (kc) | Powr. Gain (db) | Powr. Out. (w) | Remarks |
| P 29 | 2N1438 2N1465 2N1466 2N1504 2N2552 | KF KF KF KF | e, LA, qnq e, LA, qnq e, LA, qnq e, LA, qnq eg, LA, qnq | 20 20 20 20 20 20 | 0.33 0.33 0.33 0.33 0.33 | 85 85 85 85 100 | 100 120 120 80 •40 | 3 3 3 3 | 20min 20min 20min 20min *33 | 0.5 0.5 0.5 0.5 *40 | 5 5 5 10 | 1111 | 2 2 2 2 2 | TO-10 TO-13 TO-10 |
| | 2N2553 2N2554 2N2555 2N2555 2N2556 2N2557 | KF KF KF KF | g, LA, qnq ag, LA, qnq ag, LA, qnq ag, LA, qnq ag, LA, qnq | 20 20 20 20 20 20 | .27 .27 .27 .27 .27 .27 | 100 100 100 100 100 | *60 *80 *100 *40 *60 | 1 1 1 1 1 | *33 *33 *33 *33 *33 | *40 *40 *40 *40 *40 | 10 10 10 10 10 | 11111 | | |
| P 30 | 2N2558 2N2559 2N2560 2N2561 2N2562 | KF KF KF KF | pnp,AJ,ge pnp,AJ,ge eg,LA,qnq eg,LA,qnq pnp,AJ,ge | 20 20 20 20 20 20 | .27 .27 .27 .27 .27 | 100 100 100 100 100 | *80 *100 *40 *60 *80 | 1 1 3 3 3 | *33 *33 *25 *25 *25 | *40 *40 *40 *40 | 10 10 10 10 10 | | - | |
| P 30 | 2N2563 CDT1319 CDT1320 CDT1321 CDT1322 | KF CL CL CL | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 20 20 20 20 20 20 | .27 1.5 1.5 1.5 1.5 | 100 100 100 100 100 | *100 *40 *60 *80 100 | 3 5 5 5 5 | *25 20-60 20-60 20-60 20-60 | *40 15 15 15 15 | 10 5 5 5 5 | 1 - 1 | 11111 | |
| 0.01 | CK 31 CK-312 CK-313 CK-314 CK-315 | RA RA RA RA | pnp,AJ,ge pg,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 20 20 20 20 20 20 | 0.33 0.33 0.33 0.33 0.33 | 85 85 85 85 85 | 80 100 120 150 200 | 3 3 3 3 | 11111 | 1 1 1 1 1 | 5 5 5 5 | 1 - 1 - 1 | | |
| P 31 | MM799 2N234A 2N235A 2N235B 2N236A | MO BE BE BE BE | npn,PE,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 20 25 25 25 25 25 | 133 1.2 1.2 1.2 1.2 | 175 90 90 90 95 | *60 30 40 40 40 | - 3 3 3 3 | *10 - - - - | *0.5 1 1.0 1.0 1.0 | *200 - - - - | 11111 | 12 34 36 38 35 | CL CL CL |
| P 32 | 2N285A 2N296 2N399 2N400 2N1146 | BE SY BE BE CL | pnp,AJ,ge pg,LA,qnq pg,LA,qnq pg,LA,qnq pg,LA,qnq | 25 25 25 25 25 25 | 1.2 0.33 1.2 1.2 0.7 | 95 100 90 95 95 | 40 *60 40 40 *40 | 3 2 3 3 15 | - 20 - - - | 1.0 2.0 1.5 1.3 25 | - 4 - 4 | - - 33 35 - | 39 - - 6 - | hFE 20 min., CL BE |
| F 32 | 2N1146A 2N1146B 2N1146C 2N1147 2N1147A | CL CL CL CL | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 25 25 25 25 25 25 | 0.7 0.7 0.7 0.7 | 95 95 95 95 95 | *60 *80 *100 *40 *60 | 15 15 15 15 15 | 1111 | 25 25 25 25 25 25 | 4 4 4 4 | | - | BE BE BE solder lugs, BE solder lugs, BE |
| P 33 | 2N1147B 2N1147C 2N1483 2N1484 2N1485 | CL CL RCA RCA RCA | pnp,AJ,ge pnp,AJ,ge npn,DJ,si npn,DJ,si npn,DJ,si | 25 25 25 25 25 25 | 1111 | 95 95 200 200 200 | *80 *100 60 100 | 15 15 3 3 | - 45 45 45 | 25 25 15 15 15 | 4 4 1.25mc 1.25mc 1.25mc | 111111 | 1.1.1.1.1 | solder lugs, BE solder lugs, BE STC, AMF STC, AMF STC, AMF |
| F 33 | 2N1486 B-177 B-178 B-179 CTP1500 | RCA BE BE BE CL | npn,DJ,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 25 25 25 25 25 25 | 1.2 1.2 1.2 1.2 1.0 | 200 90 90 90 90 95 | 100 30 30 40 100 | 3 3 3 3 15 | 45 - - - 30-75 | 15 1.0 1.0 1.0 | 1.25mc - - - - | - 36 30-36 25-30 | 111111 | STC, AMF |
| P 34 | CTP1503 CTP1504 CTP1508 CTP1544 CTP1545 | CT CT CT CT | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 25 25 25 25 25 25 | 1.0 1.0 1.0 1.0 1.0 | 95 95 95 95 95 | 80 60 40 60 80 | 15 15 15 25 25 | 30-75 30-75 30-75 25-75 25-75 | 8 8 8 15 15 | - - 3 3 | 11111 | 11111 | |
| 1 34 | CTP1552 CTP1553 MM800 2N236B 2N242 | CL MO BE SY | pnp,AJ,ge pnp,AJ,ge npn,PE,si pnp,AJ,ge pnp,AJ,ge | 25 25 25 30 30 | 1.0 1.0 167 - 0.33 | 95 95 175 85 100 | 40 100 *60 40 *45 | 25 25 - 3 2.0 | 25-75 25-75 *10 - | 15 15 *0.5 1.0 3.0 | 3 *200 5 | - - 37 36 | - 17 4 - | CL CL, BE, TS, SO |
| P 35 | 2N257 2N268 ST7530 ST7120 ST7130 | BE BE TR TR TR | pnp,AJ,ge pnp,AJ,ge npn,ME,si npn,ME,si npn,ME,si | 30 30 30@100 30@100 | 2.0 | 90 90 150 160 160 | 40 - 40 • 45 • 45 | 3 2 5 5 | - - *20 *20 *20 | 2 | - *8,000 *8,000 *8,000 | 1 1 | 33 35 | CL SY, CL |
| | 2N538 2N539 2N540 2N1202 2N1203 | MH MH MH MH MH | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 32 32 32 32 32 32 32 | 0.45 0.45 0.45 0.45 0.45 | 100 100 100 100 100 | *80 *80 *80 *80 *120 | 3 3.0 3.0 3 | 20-50 30-75 45-113 40-120 25-75 | 2 2 2 2 2 | 400 400 400 400 | 11111 | 1 | KF (MH, JAN2N 539), KF KF KF KF |

May 24, 1963 T45

| | | | | | MAX. RATINGS | | | - | CHARA | CTERIST | ICS | • • | | |
|-----------------------|--|----------------------------------|--|--|--------------------------------------|--|---------------------------------------|-------------------------------|--|---------------------------------|---|-----------------------|----------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | P _c (w) | w/°C | T _i (°C) | *V _{CBO} (v) | I _с (а) | hfe *hFE | CO (ma) (*μa) | fae *f T (kc) | Powr. Gain (db) | Powr. Out. (w) | Remarks |
| | 2N1261 2N1262 2N1263 2N1501 2N1502 | MH MH MH MH MH | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 32 32 32 32 32 32 | 0.45 0.45 0.45 0.45 0.45 | 100 100 100 100 100 | *80 *80 *80 *60 *40 | 3 3 3 3 3 | 20-50 30-75 45-113 25-100 25-100 | 2 2 2 2 2 2 | 400 400 400 400 400 | 11111 | 11111 | KF KF KF KF KF |
| P 36 | CA2D2 2N463 2N1011 2N256 2N307 | MH WE BE DE DE | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,A,ge pnp,A,ge | 32 35 35 37 37 | 0.45 - 0.2 2.0 2.0 | 100 100 95 100 100 | 20 60 80 •30 •35 | 3 5 3 3 | *20 60 30-75 - *20 | 4 0.1 15 3 15 | 400 4 - 5 3 | - 25 - | 11 111 | мо |
| | 2N663 2N178 2N554 2N555 2N1047 | DE MO MO MO STC | pnp,A,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,AJ,si | 37 40 40 40 40 | 2.0 1.4 1.4 1.4 0.2 | 100 90 90 90 90 200 | *50 *40 *15 *30 80 | 4 3 3 3 2 | *25/75 50 50 50 12-36 | 4 - - - .015 | 15 6 6 - | 30 35 35 - | 1 | BE BE TR, TI, BE |
| P 37 | 2N1047A 2N1047B 2N1047C 2N1048 2N1048A | TI TI BE STC TI | npn,MS,si npn,DM,si npn,DM,si npn,DJ,si npn,MSI,si | 40 40 40 40 40 | .228 - - 0.2 .228 | 200 - 165 200 200 | 80 80 80 120 120 | 0.5 0.75 8 2 0.5 | 12-36 12*-36* *12-36 12-36 12-36 | .0015 - .015 .0015 | 8 mc 90 - - 8 mc | 1111 | 1111 | TR, BE BE TR, TI, BE TR, STC, BE |
| | 2N1048B 2N1048C 2N1049 2N1049A 2N1049B | TI BE STC TI STC | npn,DM,si npn,DM,si npn,DJ,si npn,MS,si npn,D,si | 40 40 40 40 40 | - 0.2 .228 | 165 200 200 | 12 0 120 80 80 80 | 0.75 8 2 0.5 | 30°-90° *12-36 30-90 30-90 | - .015 .0015 | - - 7 mc | 11111 | 41111 | STC, BE TR, TI, BE TR, STC, BE BE |
| P 38 | 2N1049C 2N1050 2N1050A 2N1050B 2N1050C | BE STC TI, TI BE | npn,DM,si npn,DM,si npn,MS,si npn,DM,si npn,DM,si | 40 40 40 40 40 | - 0.2 .228 - - | 200 200 200 200 | 80 120 120 120 120 120 | 8 2 5 0.75 8 | *30-90 30-90 30-90 30-90 *30-90 | - .015 7 mc - - | | 1111 | 1111 | TR, TI, BE TR, STC, BE STC, BE |
| P 39 | 2N1647 2N1648 2N1649 2N1650 2N1690 | TR TR TR TR STC | is,LQ,nqn is,LQ,nqn is,LQ,nqn is,LQ,nqn is,Q,nqn | 40 40 40 40 40 | .27 .27 .27 .27 | 175 175 175 175 | *80 *120 *80 *120 | 3 3 3 - | 15-45 15-45 30-90 30-90 | .025 .025 .025 .025 | 10 mc 10 mc 10 mc 10 mc | 1111 | 11111 | BE BE BE TI |
| | 2N1691 2N1886 2N2018 2N2019 2N2020 | TI TR TR TR TR | npn,DM,si is,LD,nqn is,LD,nqn is,LD,nqn is,LD,nqn | 40 40 40 40 40 | .27 .27 .27 .27 | 175 175 175 175 175 | 120 60 *150 *200 *150 | 0.5 5 - - - | *20-*60 20-80 20-60 20-60 40-120 | .35 .01 .01 | 8 mc 10 mc 10 mc 10 mc | | 1111 | STC |
| D.40 | 2N2021 MHT-6001 2N1120 2N250 2N251 | TR MH BE TI TI | npn,DJ,si npn,DP,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 40 40 45 50 50 | .27 - 1.0 .27 .27 | 175 175 95 100 100 | *200 100 *80 30 60 | - 3 15 5 5 | 40-120 10-120 20-50 60 60 | .01 0.001 15 2 2 | 10 mc 30m - - | - - 30 30 | | Planar MO CL, BE BE, CL |
| P 40 | 2N553 2N665 2N1014 2N1069 2N1070 | DE DE RCA STC STC | pnp,AJ,ge pnp,AJ,ge is,LD,nqn is,LD,nqn is,LD,nqn | 50 50 50 50 50 | 1.5 1.5 1.0 .29 .29 | 100 100 100 175 175 | *80 *80 100 60 | 5 5 10 4 4 | - - 75 20 20 | 0.02 0.02 0.1 1 | 25 25 - 1 1 | - 26 - - | - 30 - - | BE JAN2N665 RCA, AMF, FT, BE RCA, AMF, FT, BE |
| | 2N1722 2N1724 2N1905 2N1906 2N2266 | TI TI RCA RCA MH | npn,MS,si npn,MS,si pnp,Dr,ge pnp,Dr,ge pnp,AJ,ge | 50 50 50 50 50 | .67 .67 0.7 0.7 0.5 | 175 175 - - 125 | 80 80 60 100 *100 | 7.5 7.5 10 10 5.0 | - 90 125 25-75 | 1 1 .15 .15 | 20 mc 20 mc - - 400 | 11111 | | STC |
| P 41 | 2N2267 2N1722 2N1724 2N1704 2N1657 | MH TR TR NA NA RA | pnp,AJ,ge npn,PL,si npn,PL,si npn,si npn,DB,si | 50 50@100 50@100 50-200 55 | 0.5 500 .33 | 125 175 175 175 175 200 | *120 80 80 3.3 60 | 5. 0 7.5 7.5 45 2 | 25-75 *20 *20 100 50 | 2 - 0.1 10 | 400 •10,000 •10,000 - 10 mc | 15 | 60 - | |
| P 42 | 2N419 2N639 2N639A 2N639B 2N1073 | BE BE BE BE BE | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 60 60 60 60 | 1.2 1.2 1.2 1.2 1.2 | 95 100 100 100 100 | 45 40 70 80 40 | 3 5 5 5 10 | - 15-30 15-30 15-30 20-6 | 0.5 1.0 1.0 2.2 2.0 | - - - 1.5 | 11111 | 5 - - - | CL CL |
| 16 | 2N1073A 2N1073B 2N1136 2N1136A 2N1136B | BE BE BE BE BE | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 60 60 60 60 | 1.0 1.0 1.2 1.2 1.2 | 100 100 100 100 100 | 80 120 40 70 80 | 10 10 6 6 6 | 20-6 20-6 - - - | 1.5 2.0 0.5 2 2 | 1.5 - - - | 11111 | 11111 | DE CL CL CL |

ANSISTORS

2N2875 Features remarkably high beta linearity over wide range of collector currents. Dissipates up to 15 Watts of power at 100°C case.

| Туре | DC Current Gain @ Ic= 500mA (IB) | Typical Collector Saturation Voltage @ Ic= 500mA (Volts) | Minimum Sustaining Voltage @ Ic= 50mA (Volts) | Typical Cut-Off Frequency @ Ic= 100mA (Mc) | Power Dissipation Rating @ 100°C Case (Watts) |
|--------|--|--|--|---|---|
| 2N2875 | 20-60 | 1.0 | 50 | 30 | 15 |

IN A 1/16" STUD-MOUNTED **PACKAGE**



2N2866-7

Features extremely low RCS of 0.75 Ohms Max.

Dissipates up to 20 Watts of power at 100°C case. High beta linearity.

| Туре | DC Current Gain @ Ic= 500mA (β) | Typical Collector Saturation Voltage @ Ic= 1 Amp (Volts) | Minimum Sustaining Voltage @ Ic= 50mA (Volts) | Typical Cut-Off Frequency @ Ic= 100mA (Mc) | Power Dissipation Rating @ 100°C Case (Watts) |
|--------|---|--|--|---|--|
| 2N2866 | 20-60 | 0.4 | 80 | 15 | 20 |
| 2N2867 | 40-120 | 0.4 | 80 | 15 | 20 |

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These highly reliable silicon planar power transistors are the product of the

same intensive Transitron Total Reliability Program that produced the popular $\%_6$ " NPN 2N1647-50 and 2N2018-21 series for modern military ICBM systems. Continuous lot control from ingot stage, thorough product improvement documentation, and comprehensive failure analysis have enabled Transitron Product Engineering to develop units which will satisfy the strictest requirements.

The 2N2875 and the 2N2866-7, and other complementing PNP and NPN silicon

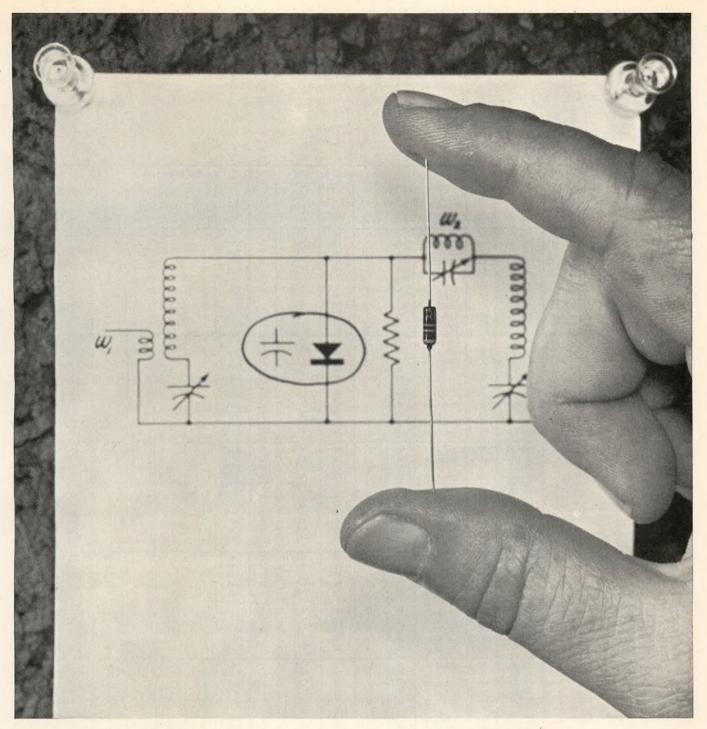
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|---------------------|---|--------|--------------------------------|--|--------------------------------------|--------------------------------------|--|---------------------------------|----------------------------|--|------------------------------------|---|-------------------------|----------------------|--|
| Cros Inde Key | | | Mfr. | Туре | P _c (w) | w/°C | T _i (°C) | V CEO *V CBO (v) | l _c (a) | hfe *hFE | l _{CO} (ma) (*μa) | fae *f _T (kc) | Powr. Gain (db) | Powr. Out. (w) | Remarks |
| | 2N1137 2N1137 2N1137 2N1138 2N1138 | A E | BE BE BE BE BE | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 60 60 60 60 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | 40 70 80 40 70 | 9 9 9 9 9 | 11111 | 0.5 2 2 0.5 2.0 | 1111 | 11111 | 11111 | CL CL CL |
| P 4 | 2N1138 2N1210 2N1211 2N1487 2N1488 | 1 | BE TR TR RCA RCA | gp,AJ,ge is,Ld,nqn np,DJ,si is,Ld,nqn si,Ld,nqn | 60 60 60 60 | 1.2 .27 .27 - | 100 175 175 175 175 | 80 *60 *80 60 100 | 6 5 5 6 | 15-75 15-75 30 30 | 2 50 50 25 25 | 15 mc 15 mc 1 mc 1 mc | | 11111 | CL STC, FN, FT STC, FN, FT STC, FT, AMF, BE STC, FT, AMF, BE |
| | 2N1489 2N1490 2N1616 2N1617 2N1618 | F 1 | RCA RCA TR TR TR | npn,DJ,si npn,DJ,si npn,DJ,si npn,DJ,si si,LO,nqn | 60 60 60 60 | - .27 .27 .27 | 175 175 175 175 175 | 60 100 60 70 80 | 6 5 5 5 | 30 30 15-75 15-75 15-75 | 25 25 50 50 50 | 1 mc 1.25mc 15 mc 15 mc 15 mc | 11111 | 1-1-1-1 | STC, FT, AMF, BE STC, FT, AMF, BE AMF, FT, STC, BE AMF, FT, STC, BE AMF, FT, STC, BE |
| P 4 | ST440 ST450 2N2137 2N2137 2N2138 | A N | TR TR MO MO MO | npn,DJ,si npn,DJ,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 60 60 62.5 62.5 62.5 | .27 .27 0.83 0.83 0.83 | 150 150 100 100 100 | 60 *60 *30 30 45 | 5 5 3 3 | 10 10 30-60 30-60 30-60 | 1 1 2 2 2 2 | - 20 20 20 | 11111 | 11111 | STC "Meg-A-Life" "Meg-A-Life" |
| | 2N2139 2N2140 2N2141 2N2142 2N2143 | N N | MO MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 62.5 62.5 62.5 62.5 62.5 | 0.83 0.83 0.83 0.83 0.83 | 100 100 100 100 100 | 60 75 90 30 45 | 30 3 3 3 3 | 30-60 30-60 30-60 50-100 50-100 | 2 2 2 2 2 | 20 20 20 20 20 20 | | 11111 | "Meg-A-Life" "Meg-A-Life" "Meg-A-Life" "Meg-A-Life" "Meg-A-Life" |
| P 4 | 2N2144 2N2145 2N2146 2N301 2N301 | M M | MO MO MO DE DE | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,A,ge pnp,A,ge | 62.5 62.5 62.5 75 75 | 0.83 0.83 0.83 1.0 1.0 | 100 100 100 100 100 | 60 75 90 • 40 • 60 | 3 3 3 3 | 50-100 50-100 50-100 •62.5 •62.5 | 2 2 2 3 3 | 20 20 20 5 5 | 11111 | 11111 | "Meg-A-Life" "Meg-A-Life" "Meg-A-Life" |
| D.44 | 2N174/ 2N1511 2N1512 2N1513 2N1514 | F | TS RCA RCA RCA RCA | npn,AJ,ge npn,si npn,si npn,si npn,si | 75-95 75 75 75 75 75 | 11111 | 95 - - | *80 60 100 60 100 | 15 6 6 6 | *37 15* *15 *25 *25 | 8 | 10 - - - | 11111 | 11111 | MO, SO, DE STC STC STC STC |
| P 46 | 2N1703 2N2101 3N45 3N46 3N47 | N N | RCA AMF MH MH MH | npn,si npn,MESA,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 75 75 75 75 75 75 | 0.5 1.0 1.0 1.0 | 200 100 100 100 | 60 *60 *60 *80 *40 | 5 3.0 12 12 12 | *15 *15-60 30-120 20-80 30-120 | *1 3.0 3.0 3 | - 1.5mc 750 450 750 | 11111 | 11111 | STC |
| | 3N48 2N424 2N389 2N389/ 2N424 | 1 1 | MH TI TI STC TI | pnp,AJ,ge npn,DJ,si npn,DJ,si npn,D,si npn,DJ,si | 75 85 85 85 85 | 1.0 .48 .48 - | 100 200 200 - 200 | *60 80 60 60 *80 | 12 2 2 - 2 | 20-80 12-60 12-60 - 12.60 | 3 10 10 - 10 | 450 6 mc 7 mc - 6 mc | 11111 | 11111 | STC, TR, RA, FT, AMF, BE, STC, TR, RA, AMF, FT, BE, AMF, BE STC, TR, RA, FN, FT |
| P4 | 2N1619 2N1660 2N1661 2N1662 2N1894 | F | TR RA RA RA | npn,DJ,si npn,DB,si npn,DB,si npn,DB,si npn,DB,si | 85 85 85 85 85 | .27 0.5 0.5 0.5 0.5 | 200 200 200 200 200 200 | 80 60 80 100 60 | 5 2 2 2 2 | 30 90 90 90 90 30 | 0.1 10 10 10 .01 | 15 mc 40 mc 40 mc 40 mc | | 11111 | |
| | 2N1895 2N1896 2N1897 2N1898 2N2383 | F | RA RA RA RA STC | npn,DB,si npn,DB,si npn,DB,si npn,DB,si npn,DJ,si | 85 85 85 85 85 | 0.5 0.5 0.5 0.5 0.5 | 200 200 200 200 200 180 | 80 60 80 100 80 | 2 2 2 2 5 | 30 90 90 90 *20-*60 | .01 .01 .01 .01 | - - - - *3.0mc | 11111 | | 5Q. Flange |
| P 4 | 2N238- 2N2526 2N252- 2N2522 2N2528 STC11 | | STC MO MO MO STC | npn,DJ,si pnip,AD,ge pnip,AD,ge pnip,AD,ge npn,DJ,si | 85 85 85 85 85 | 0.5 1 1 1 - | 180 110 110 110 200 | 80 80 120 160 60 | 5 10 10 10 6 | *20-*60 *20-50 *20-50 *20-50 10-50 | *3.0 3 3 3 .025 | *3.0mc - - - 1 mc | 1111 | - | 1 tex Stud |
| P 4 | STC11 STC11 STC11 2N176 2N255/ | 13 3 | STC STC STC DE DE | npn,DJ,si npn,DJ,si npn,DJ,si pnp,A,ge pnp,A,ge | 85 85 85 90 90 | - - - 0.8 0.8 | 200 200 200 100 100 | 100 60 100 •40 •15 | 6 6 7 5 | 10-50 25-75 25-75 *25/90 | .025 .025 .025 .025 .3 | 1 mc 1 mc 1 mc 4 | - - - 25 25 | - | |
| | 2N256/ 2N297/ 2N350/ 2N351/ 2N376/ | | DE MO MO MO MO | pnp,A,ge onp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 0.8 1.2 1.4 1.4 1.4 | 100 100 100 100 100 | *25 *60 *50 *50 *50 | 5 3 3 4 5 | 40-100 30 45 60 | 5 3 3 3 3 | 5 5 5 5 | - 33 33 35 | | DE, BE, CL BE, CL BE, CL BE, CL |



Raytheon introduces new F7 series of 63 VHF-UHF varactor diodes

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|-----------------------|--|----------------------------|---|----------------------------|--|---------------------------------|---------------------------------------|----------------------------------|--|----------------------------------|---------------------------------|------------------------|----------------------|--|
| Crass Index Key | Гуре No. | Mfr. | Type | P _c (w) | w/°C | T _i (°C) | VCEO *VCBO | l _c (a) | h _{fe} *h | l _{CO} (ma) (*μa) | fae *fT (kc) | Powr. Gain (db) | Powr. Out. (w) | Remarks |
| P 50 | 2N379 2N380 2N627 2N628 2N629 | DE DE MO MO | pnp,A,ge pnp,A,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | .8 .8 1.2 1.2 | 100 100 100 100 100 | *80 *60 *40 *60 *80 | 7 7 10 10 | *20/90 *20/90 10-30 10-30 10-30 | 8 8 4 4 4 | 3 5 5 5 | 38 38 38 38 | 1 1 1 1 | BE, CL BE, CL BE, CL |
| 1 30 | 2N630 2N677 2N677A 2N677B 2N677C | MO BE BE BE BE | gnp,AJ,ge gn,AJ,ge gn,AJ,ge gg,LA,qnq gg,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *100 50 60 90 100 | 10 15 15 15 15 | 10-30 45 45 45 45 | 4 1 1 1 | 5 - - - | 38 - - - - | 11111 | BE, CL CL CL CL CL |
| P 51 | 2N678 2N678A 2N678B 2N678C 2N1031 | BE BE BE BE BE | pnp,AJ,ge pg,LA,qnq pg,LA,qnq pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 0.8 | 100 100 100 100 100 | 150 60 90 100 30 | 15 15 15 15 15 | 75 75 75 75 75 20-60 | 1 1 1 1.0 | 1 | 1111 | 11111 | CL CL CL CL CL |
| | 2N1031A 2N1031B 2N1031C 2N1032 2N1032A | BE BE BE BE BE | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 0.8 0.8 0.8 0.8 0.8 | 100 100 100 100 100 | 40 70 80 30 40 | 15 15 15 15 15 | 20-60 20-60 20-60 50-100 50-100 | 1.0 1.0 2.0 1.0 1.0 | | 11111 | 11111 | CL CL CL CL |
| P 52 | 2N1032B 2N1032C 2N1073 2N1073A 2N1073B | BE BE DE DE DE | pnp,AJ,ge pnp,AJ,ge pnp,A,ge pnp,A,ge pnp,A,ge | 90 90 90 90 90 | 0.8 0.8 0.8 0.8 0.8 | 100 100 110 110 110 | 70 80 *40 *80 *120 | 15 15 10 10 10 | 50-100 50-100 *20/60 *20/60 *20/60 | 2.0 2 10 10 10 | - 30 30 30 30 | 11111 | 1111 | CL CL |
| 1 32 | 2N1162 2N1162A 2N1163 2N1163A 2N1164 | MO MO MO MO | gnp,AJ,ge gg,LA,qnq gg,LA,qnq gg,LA,qnq gg,LA,qnq | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | 50 *50 *50 *50 *50 *80 | 25 25 25 25 25 25 | 15-65 15-65 15-65 15-65 15-65 | 3 15 3 15 3 | 4 4 4 4 | - 1 1 1 1 | 11111 | CL, BE BE, CL CL, BE BE CL, BE |
| P 53 | 2N1164A 2N1165 2N1165A 2N1166 2N1166A | MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *80 *80 *80 *80 *100 | 25 25 25 25 25 25 | 15-65 15-65 15-65 15-65 15-65 | 15 3 15 3 15 | 4 4 4 4 | 11111 | 11111 | BE CL, BE BE CL, BE BE |
| 7 33 | 2N1167 2N1167A 2N1358M 2N1359 2N1360 | MO MO DE MO MO | pnp,AJ,ge pnp,AJ,ge pnp,A,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 0.8 1.2 1.2 | 100 100 110 100 100 | *100 *100 *80 *50 *50 | 25 25 15 3 3 | 15-65 15-65 25/50 35-90 60-140 | 3 15 4 3 3 | 4 4 5.0 7 5 | 11111 | 1 - 1 - 1 | CL, BE BE BE BE |
| | 2N1362 2N1363 2N1364 2N1365 2N1529 | MO MO MO MO MO | gnp,AJ,ge gnp,AJ,ge gnp,AJ,ge gnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *100 *100 *120 *120 *40 | 3 3 3 5 | 35-90 60-140 35-90 60-140 20-40 | 3 3 3 2 | 7 5 7 5 10 | 11111 | 11111 | BE BE BE BE CL, BE |
| P 54 | 2N1529A 2N1530 2N1530A 2N1531 2N1531A | MO MO MO MO MO | gnp,AJ,ge gn,AJ,ge gn,AJ,ge gn,AJ,ge gn,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *40 *40 *60 *80 *80 | 5 5 5 5 | 20-40 20-40 20-40 20-40 20-40 | 2 2 2 2 2 2 | 10 10 10 10 10 | 11111 | 11111 | BE CL, BE BE CL, BE BE |
| | 2N1532 2N1532A 2N1533 2N1534 2N1534A | MO MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *100 *100 *120 *40 *40 | 5 5 5 5 5 | 20-40 20-40 20-40 *35-70 35-70 | 2 2 2 2 2 | 10 10 10 8.5 8.5 | 11111 | | CL, BE BE CL, BE CL, DE, BE BE |
| P 55 | 2N1535 2N1535A 2N1536 2N1536A 2N1537 | MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *60 *60 *80 *80 100 | 5 5 5 5 5 | *35-70 35-70 *35-70 35-70 35-70 | 2 2 2 2 2 | 8.5 8.5 8.5 8.5 8.5 | | 11111 | CL, DE, BE BE CL, DE, BE BE CL, DE, BE |
| P 56 | 2N1537A 2N1538 2N1539 2N1539A 2N1540 | MO MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *100 *120 *40 *40 *60 | 5 5 5 5 | 35-70 35-70 50-100 50-100 50-100 | 2 2 2 2 2 2 | 8.5 8.5 4 4 | | 11111 | BE CL, BE CL, BE BE CL, BE |
| 1 30 | 2N1540A 2N1541 2N1541A 2N1542 2N1542A | MO MO MO MO | g,LA,qnq g,LA,qnq g,LA,qnq g,LA,qnq g,LA,qnq | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *60 *80 *80 *100 *100 | 5 5 5 5 5 | 50-100 50-100 50-100 50-100 50-100 | 2 2 2 2 2 2 | 4 4 4 4 | 1 | -11-1-1 | BE CL, BE BE CL, BE BE |

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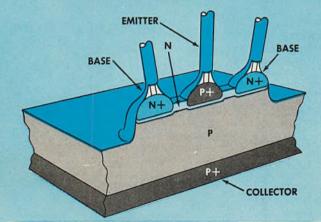
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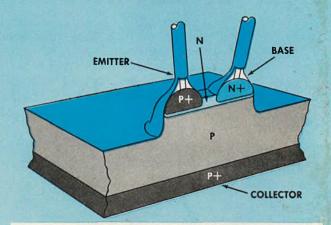


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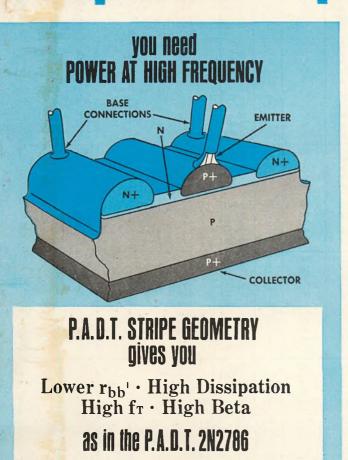
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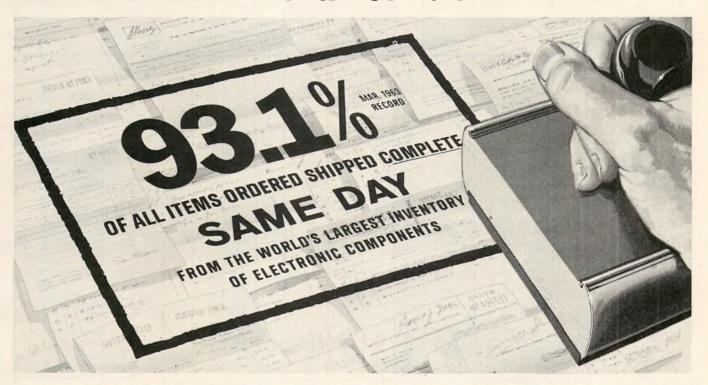
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|-----------------------|---|------------------------------|---|-------------------------------------|------------------------------------|---------------------------------------|--------------------------------------|---------------------------------|--|---------------------------------------|--|------------------------|---------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | P _c (w) | w/°C | τ _ί (ος) | V CEO *V CBO (v) | l _c (a) | h _{fe} | I _{CO} (ma) (*µa) | fae *f _T (kc) | Powr. Gain (db) | Powr. Out. (w) | Remarks |
| P 57 | 2N1543 2N1544 2N1544A 2N1545 2N1545A | MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *120 *40 *40 *60 *60 | 5 5 5 5 5 | 50-100 75-150 75-150 75-150 75-150 | 2 2 2 2 2 | 4 4 4 4 4 | 11111 | | CL, BE CL, BE BE CL, BE BE |
| | 2N1546 2N1546A 2N1547 2N1547A 2N1548 | MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *80 *80 *100 *100 *120 | 5 5 5 5 | 75-150 75-150 75-150 75-100 75-150 | 2 2 2 2 2 2 | 4 4 4 4 | 11111 | 11111 | CL, BE BE CL, BE BE CL, BE |
| P 58 | 2N1549 2N1549A 2N1550 2N1550A 2N1551 | MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *40 *40 *60 *60 *80 | 15 15 15 15 15 | 10-30 10-30 10-30 10-30 10-30 | 3 3 3 3 2 | 10 10 10 10 10 | 1111 | | CL, BE BE CL, BE BE CL, BE |
| | 2N1551A 2N1552 2N1552A 2N1553 2N1553A | MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *80 *100 *100 *40 *40 | 15 15 15 15 15 | 10-30 10-30 10-30 30-60 30-60 | 3 2 3 2 3 | 10 10 10 6 6 | 11111 | 11111 | BE CL, BE BE CL, BE BE |
| P 59 | 2N1554 2N1554A 2N1555 2N1555A 2N1556 | MO MO MO MO | ga,LA,qnq ga,LA,qnq ga,LA,qnq ga,LA,qnq ga,LA,qnq | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *60 *60 *80 *80 *100 | 15 15 15 15 15 | 30-60 30-60 30-60 30-60 30-60 | 2 3 3 3 3 3 | 9 9 9 9 | 11111 | 1111 | CL, BE BE CL, BE BE CL, BE |
| P 39 | 2N1556A 2N1557 2N1557A 2N1558 2N1558A | MO MO MO MO | ga,LA,qnq ga,LA,qnq ga,LA,qnq pnp,AJ,ge ga,LA,qnq | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *100 *40 *40 *60 *60 | 15 15 15 15 15 | 30-60 50-100 50-100 50-100 50-100 | 3 3 3 3 | 6 6 5 5 | | | BE CL, BE BE CL, BE BE |
| P 60 | 2N1559 2N1559A 2N1560 2N1560A 2N392 | MO MO MO MO DE | ge,LA,qnq ge,LA,qnq ge,LA,qnq ge,LA,qnq ge,LA,qnq | 90 90 90 90 90 | 1.2 1.2 1.2 1.2 1.2 | 100 100 100 100 100 | *80 *80 *100 *100 *60 | 15 15 15 15 15 | 50-100 50-100 50-100 50-100 | 3 3 3 0.065 | 5 5 5 5 6 | 11111 | 11111 | CL, BE BE CL, BE BE BE |
| P 60 | 2N669 2N1159 2N1160 2N1168 3N49 | DE DE DE DE MH | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 94 94 94 94 | 1.2 0.8 0.8 0.8 1.25 | 100 100 100 100 100 | *40 *80 *80 *50 *60 | 3 5 7 5 15 | - - - - 30-120 | 0.065 0.065 0.065 0.065 3 | 10 10 10 10 750 | 11111 | | BE BE BE, CL |
| | 3N50 3N51 3N52 151-04 151-07 | MH MH WH WH | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,AJ,si npn,AJ,si | 94 94 94 100 100 | 1.25 1.25 1.25 1.4 1.4 | 100 100 100 150 150 | *80 *40 *60 *80 *140 | 15 15 15 6.0 6.0 | 20-80 30-120 20-80 *11 *11 | 3 3 10ma 10ma | 450 750 450 25 25 | | | |
| P 61 | 152-04 152-05 152-08 151-05 151-06 | WH WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 100 100 100 100 100 | 1.4 1.4 1.4 1.4 1.4 | 150 150 150 150 150 | *80 *100 *160 *100 *120 | 6.0 6.0 6.0 6.0 6.0 | *18 *18 *18 *11 *11 | 10ma 10ma 10ma 10ma 10ma | 25 25 25 25 25 25 | | | |
| P 62 | 151-08 151-09 151-10 152-06 152-07 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 100 100 100 100 100 | 1.4 1.4 1.4 1.4 1.4 | 150 150 150 150 150 | *160 *180 *200 *120 *140 | 6.0 6.0 6.0 6.0 6.0 | *11 *11 *11 *18 *18 | 10ma 10ma 10ma 10ma 10ma | 25 25 25 25 25 25 25 | | | |
| P 62 | 152-09 152-10 2N 1084 2N 1085 2N 1157 A | WH WH TR TR MH | npn,AJ,si npn,AJ,si pnp,PL,si npn,ME,si pnp,AJ,ge | 100 100 5@100 5@100 100 | 1.4 1.4 .050 .050 1.43 | 150 150 200 200 200 95 | *180 *200 *60 60 *80 | 6.0 6.0 | *18 18 *20 *40 50 | 10ma 10ma *10 *15 20 | 25 25 •25,000 •15,000 75 | _ | - | |
| P 63 | 2N1206 2N1207 2N1651 2N1652 2N1653 | TR TR BE BE BE | npn,ME,si npn,ME,si pnp,DJ,ge pnp,DJ,ge pnp,DJ,ge | 3@100 3@100 100 100 100 | .030 .030 1.2 1.2 1.2 | 200 200 110 110 110 | 60 125 60 100 120 | 25 25 25 25 | 15 15 30 30 30 | *1 *1 2.0 2.0 2.0 | *30,000 *30,000 - - - | | | Sat. volt=1.0v Sat. volt=0.5v Sat. volt=0.5v |
| P 63 | 2N1675 2N1936 2N1937 2N1899 2N1900 | WE TI TI PSI PSI | npn,D, ge npn,MS,si npn,MS,si npn,DM,si npn,DM,si | 100 100 100 125 125 | 1.34 1.34 1 | 150 175 175 150 150 | 100 60 80 140 140 | 10 15 15 10 5 | 12 - - 10 10 | 0.008 20 20 20 20 20 | 50mc 7 mc 7 mc 20 20 | - - - 10 - | 100 - - 100 - | hi freq., hi power hi freq., hi power |

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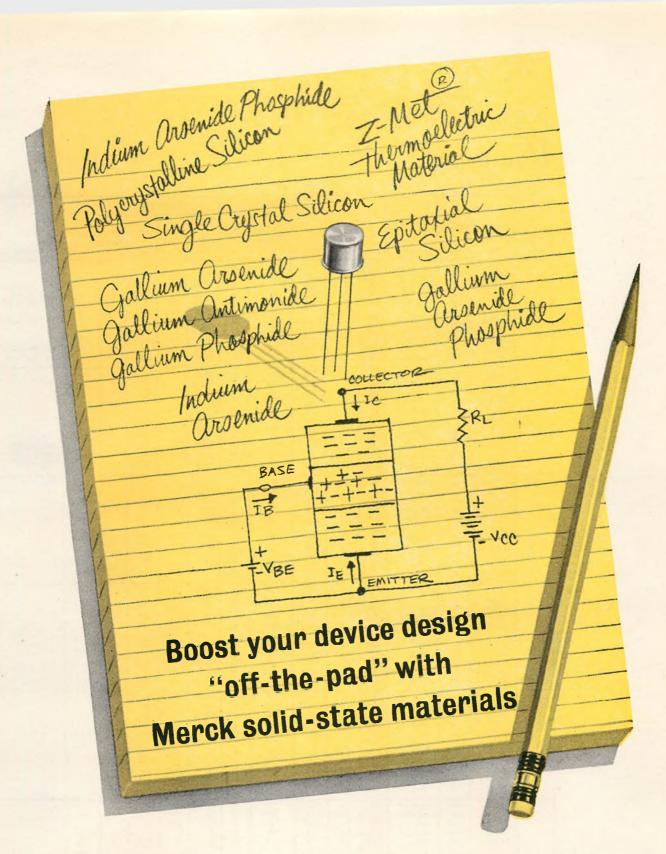


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| Cross Index Key | Type No. | Mfr. | Type | P _c (w) | w/°C | T _i (°C) | *VCBO (v) | ا _د (۵) | hfe *hFE | l _{CO} (ma) (*μa) | fae *fT (kc) | Powr. Gain (db) | Powr. Out. (w) | Remarks |
| | 2N1901 2N1902 2N1903 2N1904 PT900 | PSI PSI PSI PSI PSI | npn,DM,si npn,DM,si npn,DM,si npn,DM,si npn,DM,si | 125 125 125 125 125 125 | 1 1 1 1 | 150 150 150 150 150 | 140 140 140 140 80 | 5 10 10 10 | 10 10 10 10 3 | 20 20 20 20 20 10 | 20 20 20 20 20 20 | - 10 - 10 | - 100 - 100 | hi freq., hi pwr. hi freq., hi power |
| P 64 | 2N173 2N174 2N229 2N277 2N278 | DE DE WH DE DE | ga,LA,qnq ia,LA,qnq ag,LA,qnq ag,LA,qnq ga,LA,qnq | 150 150 150 150 150 | 0.5 0.5 2.0 0.5 0.5 | 100 100 150 100 100 | *60 *80 *200 *40 *50 | 0.5 15 10 15 15 | - *100 - - | 0.1 0.1 10ma 0.1 0.1 | 10 10 30 10 | 11 11 | 20 40 20 20 | MO, TS, TI, RCA, SO, BE TS, MO, TI, RCA, SO, BE MO, TS, TI, RCA, SO, BE MO, TS, TI, RCA, BE, SO |
| | 2N441 2N442 2N443 2N456A 2N457A | DE DE DE CL CL | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,A,ge pnp,A,ge | 150 150 150 150 150 | 0.5 0.5 0.5 0.5 | 100 100 100 100 100 | *40 *50 *60 *40 *60 | 15 15 15 7 7 | - - - *30-90 *30-90 | 0.1 0.1 0.1 *0.5 *0.5 | 10 10 10 •200 •200 | 11111 | 20 20 20 - - | MO, TS, TI, RCA, BE MO, TS, TI, RCA, BE MO, TS, TI, RCA, BE USA, Mil USA, Mil |
| P 65 | 2N458A 2N511 2N511A 2N511B 2N512 | CL TI TI TI | pnp,A,ge pnp,Al,ge pnp,Al,ge pnp,Al,ge | 150 150 150 150 150 | 0.5 2 2 2 2 | 100 100 100 100 100 | *80 40 60 80 40 | 7 25 25 25 25 25 | *30-90 20-60 20-60 20-60 20-60 | •0.5 5 5 5 5 | •200 - - - - | 11111 | 11111 | USA, Mil Sat. voll=0,2v, BE Sat. voll=0,2v, BE BE |
| | 2N512A 2N512B 2N513 2N513A 2N513B | TI TI TI TI | sg,LA,qnq sg,LA,qnq sg,LA,qnq sg,LA,qnq sg,LA,qnq | 150 150 150 150 150 | 2 2 2 2 2 | 100 100 100 100 100 | 60 80 40 60 80 | 25 25 25 25 25 25 | 20-60 20-60 20-60 20-60 20-60 | 5 5 5 5 | | 11111 | - | Sat volt=0.4v Sat volt=0.4v Sat volt=0.4v |
| P 66 | 2N514 2N514A 2N514B 2N1015 2N1015A | TI TI TI WH WH | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,AJ,si npn,AJ,si | 150 150 150 150 150 | 2 2 2 1.43 1.43 | 100 100 100 150 150 | 40 60 80 *30 •60 | 25 25 25 7.5 7.5 | 20-60 20-60 20-60 •10 •10 | 5 5 5 10 10 | - - 25 25 | | 1111 | Sat. volt=0.5v, BE Sat. volt=0.5v, BE Sat. volt=0.5v, BE STC, AMF AMF |
| | 2N1015B 2N1015C 2N1016 2N1016A 2N1016B | WH WH WH AMF AMF | is,LA,nqn npn,AJ,si npn,AJ,si npn,FJ,si npn,FJ,si | 150 150 150 150 150 | 1.43 1.43 1.43 1.4 1.4 | 150 150 150 150 150 | *100 *150 *30 60 100 | 7.5 7.5 7.5 7.5 7.5 75 | *10 *10 *10 8 8 | 10 10 10 10 10 | 25 25 30 - | 11111 | | AMF AMF |
| P 67 | 2N 1016 D 2N 1021 2N 1022 2N 1099 2N 1100 | WH TI TI DE DE | si A, lang sg, lA, nnn sg, lA, nnn sg, lA, nnn sg, lA, nnn sg, lA, nnn | 150 150 150 150 150 | 1.43 2 2 0.5 0.5 | 150 100 100 100 100 | *200 *100 *120 *80 *100 | 7.5 10 10 15 15 | *10 *30-90 *30-90 - | 10 2 2 0.1 0.1 | 30 - - 10 10 | 11111 | - - 40 40 | DE, BE DE, BE TS, MO, TI, RCA, SO, BE TS, MO, RCA, SO, BE |
| | 2N1358A 2N1412USN 2N1907 2N1908 2N1980 | DE DE TI TI | pnp,A,ge pnp,A,ge pnp,AD,ge pnp,AD,ge pnp,AJ,ge | 150 150 150 150 150 | 0.5 0.5 2 2 2 | 110 110 100 100 100 | *100 *100 100 130 *50 | 15 15 20 20 15 | *25/50 *25/50 10 10 50 | 4 4 10 10 6 | 5.0 5.0 - - | 11111 | | TS |
| P 68 | 2N1981 2N1982 2N2015 2N2016 2N2233 | TI TI RCA RCA WH | pnp,AJ,ge pnp,AJ,si npn,si npn,si npn,AJ,si | 150 150 150 150 150 | 2 2 - - 2.0 | 100 100 - - 150 | *70 *90 100 130 *200 | 15 15 10 10 10 | 50 50 10 *15 •400 | 6 6 *15 — 10ma | - - - - 35 | | 1111 | TS TS |
| | 2N2226 2N2227 2N2228 2N2231 2N2230 | WH WH WH WH | npn,F,si npn,F,si npn,F,si npn,F,si npn,F,si | 150 150 150 150 150 | 2 2 2 2 2 | 150 150 150 150 150 | *50 *100 *150 *100 *50 | 10 10 10 10 10 | 100 100 100 400 400 | 10 10 10 10 10 | 11 11 11 11 11 | 11111 | 11111 | |
| P 69 | 2N2232 2N2330 2N2331 2N2580 2N2581 | WH MO MO DE DE | npn,F,si npn,DDP,si npn,DDP,si npn,D,si npn,D,si | 150 150 150 150 150 | 2 0.8 0.5 0.7 0.7 | 150 175 175 150 150 | *150 5.33 3.33 400 400 | 10 *30 *30 10 | 400 - - *10/40 *25/65 | 10 50 50 5 5 | 11 0.1 0.1 50 50 | 1111 | 7 7 ~ | Epitaxial Epitaxial |
| | 2N2582 2N2583 2N2075 2N2075A 2N2076 | DE DE MO MO | npn,D,si npn,D,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 150 150 170 170 170 | 0.7 0.7 2 2 2 | 150 150 110 110 110 | 500 500 80 80 70 | 10 10 15 15 15 | *10/40 *25/65 25-100 25-100 25-100 | 5 5 4.0 4.0 4.0 | 50 50 10 10 | 11111 | 11111 | SO "Meg-A-Life" SO, "Meg-A-Life" |
| P 70 | 2N2077 2N2078 2N2079 2N2080 2N2081 | MO MO MO MO MO | ag, LA, qnq ag, LA, qnq ag, LA, qnq ag, LA, qnq ag, LA, qnq | 170 170 170 170 170 | 2 2 2 2 2 2 | 110 110 110 110 110 | 50 40 80 70 50 | 15 15 15 15 15 | 25-100 25-100 40-160 40-160 40-160 | 4.0 4.0 4.0 4.0 4.0 | 10 10 10 10 10 |) 1 1 1 1 | | SO, "Meg-A-Life" SO, "Meg-A-Life" SO, "Meg-A-Life" SO, "Meg-A-Life" SO, "Meg-A-Life" |



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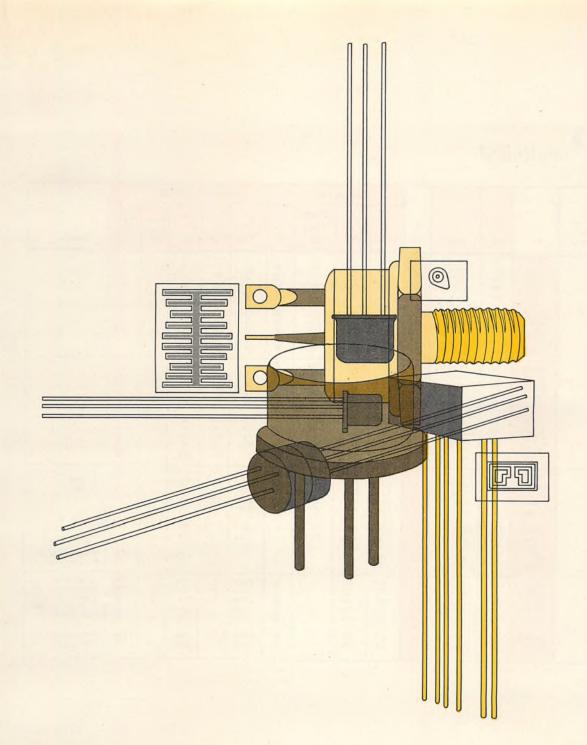
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| | Cross Index Key | Гуре No. | Mfr. | Туре | P _c (w) | w/°c | T _i (°C) | VCEO *VCBO | l _c (a) | h _{fe} *h _{FE} | Ι (ma) (* μα) | fae *f _T (kc) | Pawr. Gain (db) | Pawr. Out. (w) | Remarks |
| | P 71 | 2N2082 2N2082A 2N2152 2N2152A 2N2153 | MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 170 170 170 170 170 | 2 2 2 2 2 2 | 110 110 110 110 110 | *40 *40 45 45 60 | 15 15 30 30 30 | *70 *70 50-100 50-100 50-100 | 4 4.0 4.0 4.0 | 10 10 2.7 2.7 2.7 | 11111 | 11111 | SO, "Meg-A-Life" "Meg-A-Life" SO, "Meg-A-Life" |
| | | 2N2154 2N2155 2N2156 2N2157 2N2158 | MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 170 170 170 170 170 | 2 2 2 2 2 2 | 110 110 110 110 110 | 75 90 45 60 75 | 30 30 30 30 30 | 50-100 50-100 80-160 80-160 30-160 | 4.0 4.0 4.0 4.0 4.0 | 2.7 2.7 2.7 2.7 2.7 2.7 | 11111 | | SO, "Meg-A-Life" SO SO, "Meg-A-Life" SO, "Meg-A-Life" SO, "Meg-A-Life" |
| | P 72 | 2N2490 2N2491 2N2492 2N2493 2N2728 | MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 170 170 170 170 170 | 2 2 2 2 2 2 | 110 110 110 110 110 | *70 *60 *80 *100 *15 | 15 15 15 15 15 50 | *20-40 *25-50 *25-50 *25-50 *40-130 | 3 3 2 3 *30 | 10 10 10 10 | 11111 | 1111 | |
| | 1 72 | MP500 MP500A MP501 MP502 MP504 | MO MO MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 170 170 170 170 170 | 2 2 2 2 2 2 | 110 110 110 110 110 | 45 45 60 75 45 | 60 60 60 60 | 30-60 30-60 30-60 30-60 50-100 | 4.0 4.0 4.0 4.0 4.0 | 3.6 3.6 3.6 3.6 3.6 | 11111 | 11111 | "Meg-A-Life" "Meg-A-Life" "Meg-A-Life" "Meg-A-Life" |
| | P 73 | MP505 MP506 2N574 2N574A 2N575 | MO MO MH MH MH | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 170 170 187 187 187 | 2 2 2.5 2.5 2.5 2.5 | 110 110 100 100 100 | 60 75 *60 *80 *60 | 60 60 10 10 25 | 50-100 50-100 9-22 9-22 19-42 | 4.0 4.0 7 20 7 | 3.6 3.6 100 100 150 | 11111 | | "Meg-A-Life" "Meg-A-Life" USA USA |
| | F /3 | 2N575A 2N1157 DA3F3 2N2739 2N2740 | MH MH MH WH WH | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,AJ,si npn,AJ,si | 187 187 187 200 200 | 2.5 2.5 2.5 2.0 2.0 | 100 100 100 175 175 | *80 *60 *60 *50 *200 | 25 40 25 20 20 | 19-42 38-84 35 •10 •10 | 20 7 20 15ma 15ma | 150 200 175 14 14 | 111 | - | |
| | | 2N2741 2N2742 2N2745 2N2746 2N2747 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si np,AJ,si npn,AJ,si | 200 200 200 200 200 200 | 2.0 2.0 2.0 2.0 2.0 2.0 | 175 175 175 175 175 175 | *150 *200 *50 *100 *150 | 20 20 20 20 20 20 | *10 *10 *10 *10 *10 | 15ma 15ma 15ma 15ma 15ma | 14 14 14.5 14.5 14.5 | | | |
| | P 74 | 2N2748 2N2751 2N2752 2N2753 2N2754 | WH WH WH WH WH | is, LA, nqn is, LA, nqn is, LA, nqn is, LA, nqn is, LA, nqn | 200 200 200 200 200 200 | 2.0 2.0 2.0 2.0 2.0 2.0 | 175 175 175 175 175 175 | *200 *50 *100 *150 *200 | 20 20 20 20 20 20 | *10 *10 *10 *10 *10 | 15ma 15ma 15ma 15ma 15ma | 14.5 16 16 16 16 | | | |
| | | 2N2757 2N2758 2N2759 2N2760 2N2761 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 200 200 200 200 200 200 | 2.0 2.0 2.0 2.0 2.0 2.0 | 175 175 175 175 175 175 | *50 *100 *150 *200 *250 | 30 30 30 30 30 30 | *10 *10 *10 *10 *10 | 15ma 15ma 15ma 15ma 15ma | 14 14 14 14 14 | | | |
| | P 75 | 2N2763 2N2764 2N2765 2N2766 2N2769 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 200 200 200 200 200 200 | 2.0 2:0 2.0 2.0 2.0 2.0 | 175 175 175 175 175 | *50 *100 *150 *200 *50 | 30 30 30 30 30 | *10 *10 *10 *10 *10 *10 | 15ma 15ma 15ma 15ma 15ma | 14.5 14.5 14.5 14.5 16 | | | |
| | P 76 | 2N2771 2N2772 2N2776 2N1809 2N1810 | WH WH WH WH | is, LA, nqn is, LA, nqn is, LA, nqn is, LA, nqn is, LA, nqn | 200 200 200 250 250 | 2.0 2.0 2.0 2.22 2.22 | 175 175 175 175 175 175 | *150 *200 *100 *50 *100 | 30 30 30 30 30 30 | *10 *10 *10 10 | 15ma 15ma 15ma 15 15 | 16 16 16 17 17 | | | |
| | 70 | 2N1811 2N1812 2N1813 2N1814 2N1816 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,FJ,si npn,FJ,si npn,AJ,si | 250 250 250 250 250 250 | 2.22 2.22 2.22 2.22 2.22 2.22 | 175 175 175 175 175 | *150 *200 *250 *300 *50 | 30 30 30 30 30 30 | 10 10 10 10 10 | 15 15 15 15 15 | 17 17 - - 18 | 111111 | 11111 | |
| | P 77 | 2N1817 2N1818 2N1819 2N1823 2N1824 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 250 250 250 250 250 250 | 2.22 2.22 2.22 2.22 2.22 2.22 | 175 175 175 175 175 | *100 *150 *200 *50 *100 | 30 30 30 30 30 30 | 10 10 10 10 10 | 15 15 15 15 15 | 18 18 18 19 19 | 11111 | 11111 | |
| | F // | 2N 1825 2N 1826 2N 1830 2N 1831 2N 1832 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 250 250 250 250 250 250 | 2.22 2.22 2.22 2.22 2.22 2.22 | 175 175 175 175 175 | *150 *200 *50 *100 *150 | 30 30 30 30 30 30 | 10 10 •10 •10 •10 | 15 15 5ma 5ma 5ma | 19 19 14 14 14 | = | - | |



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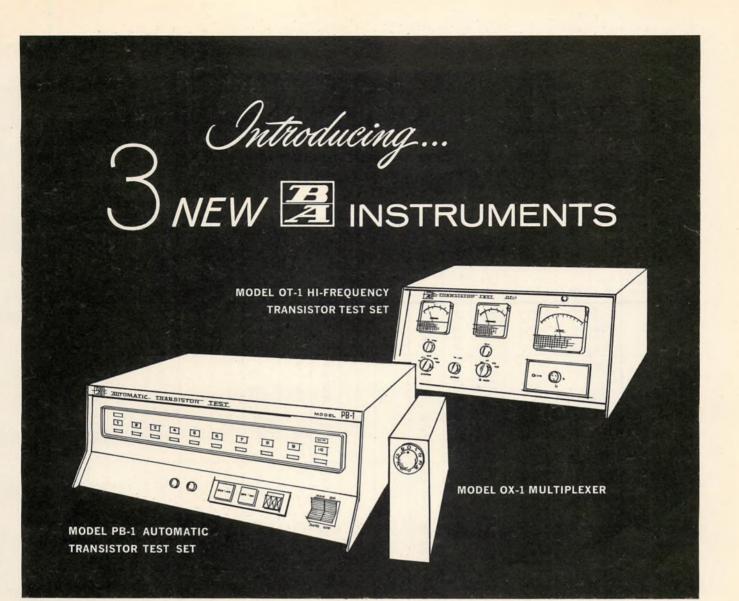
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|-----------------------|---|----------------------------|--|--|--|--|-------------------------------------|----------------------------------|--|--|--------------------------------------|-----------------------|----------------------------------|--|
| Cross Index Key | Гуре Na. | Mfr. | Туре | P _c (w) | w/°C | T _i (°C) | VCED *VCBO (v) | ا _د (۵) | hfe *hFE | l _{CO} (πα) (*μα) | fae *fT (kc) | Powr. Gain (db) | Powr. Out. (w) | Remarks |
| | 2N 1833 2N 2109 2N 2110 2N 2111 2N 2112 | WH WH WH WH | npn,AJ,si npn,FJ,si npn,FJ,si, npn,FJ,si npn,FJ,si | 250 250 2 50 2 50 250 250 | 2.22 2.22 2.22 2.22 2.22 2.22 | 175 175 175 175 175 175 | *200 *50 *100 *150 *200 | 30 30 30 30 30 30 | *10 10 10 10 10 | 5ma 15 15 15 15 | 14 14 14 14 14 | 1111 | 1111 | |
| P 78 | 2N2113 2N2114 2N2116 2N2117 2N2118 | WH WH WH WH WH | npn,FJ,si npn,FJ,si npn,FJ,si npn,FJ,si npn,FJ,si | 250 250 250 250 250 250 | 2.22 2.22 2.22 2.22 2.22 2.22 | 175 175 175 175 175 175 | *250 *300 *50 *100 *150 | 30 30 30 30 30 | 10 10 10 10 10 | 15 15 15 15 15 | - 14.5 14.5 14.5 | 11111 | | |
| P 79 | 2N2119 2N2123 2N2124 2N2125 2N2126 | WH WH WH WH | npn,FJ,si npn,FJ,si npn,FJ,si npn,FJ,si npn,FJ,si | 250 250 250 250 250 250 | 2.22 2.22 2.22 2.22 2.22 2.22 | 175 175 175 175 175 175 | *200 *50 *100 *150 *200 | 30 30 30 30 30 | 10 10 10 10 | 15 15 15 15 15 | 14.5 16 16 16 16 | 11111 | 11111 | |
| F /3 | 2N2130 2N2131 2N2132 2N2133 2N1620 | WH WH WH WH TR | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn | 250 250 250 250 250 | 2.22 2.22 2.22 2.22 0.4 | 175 175 175 175 175 200°C | *50 *100 *150 *200 *100 | 30 30 30 30 5 | *10 *10 *10 *10 | 5ma 5ma 5ma 5ma 10 | 14 14 14 14 800 | - | 60 | |
| | 2N2032 SN-101 SN-102 ST5060 ST5061 | TR CS CS TR TR | npn npn,MS,si npn,MS,si npn npn | 11111 | 0.9 8.7 8.7 0.025 0.025 | 200°C 200 200 200 200 200 | *45 - - 40 70 | 5 140 120 | 12 1 1 9-36 9-36 | 40 40 0.005 0.005 | 1200 0.5 0.5 - - | 11111 | 45 *3 *5 - | *at 200mc *at 100mc |
| P 80 | ST6510 ST6511 ST6512 2N914 2N916 | TR TR TR GE GE | npn npn npn npn,si npn,si | 11111 | 0.088 0.088 0.088 360 360 | 200 200 200 200 200 200 | 20 *40 *40 - - | - - - 40 45 | 20min 20-60 40-120 - - | 0.005 0.005 0.005 3.0 3.0 | 10K 10K 10K 25mµ 10mµ | | - - 6.0 6.0 | Planar Epitaxial, RA Planar Passivated , RA |
| | 2N2192 2N2192A 2N2193 2N2193A 2N2194 | GE GE GE GE | npn,si npn,si npn,si npn,si npn,si | 11111 | 0.8 0.8 0.8 0.8 0.8 | 200 200 200 200 200 200 | 1 1 1 1 | 60 60 80 80 60 | 1.0amp 1.0amp 1.0amp 1.0amp 1.0amp | 2.5 2.5 2.5 2.5 2.5 2.5 | 10mµ 10mµ 10mµ 10mµ 10mµ | | 20 20 20 20 20 20 | Planar Epitaxial, RA Planar Epitaxial, RA Planar Epitaxial, RA Planar Epitaxial, RA Planar Epitaxial, RA |
| P 81 | 2N2194A 2N2195 | GE GE | npn,si npn,si | - | 0.8 0.6 | 200 200 | - | 60 45 | 1.0amp 1.0amp | 2.5 2.5 | 10mµ 100mµ | - | 20 20 | Planar Epitaxial, RA Planar Epitaxial, RA |

T60 ELECTRONIC DESIGN



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- MODEL OX-1 MULTIPLEXER A solid state unit utilizing a cold cathode GS10K Dekatron tube for the switching function. The instrument is a programmable 10-channel device with single pole switching; several units can be cascaded to obtain multiple channel input. Sampling rate: d.c. to 10,000/sec. Signal range: ±10 v.

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| | | | | | 108 | MAX | . RATING | S | 1302 | CHAR | ACTERIS | TICS | SV | ITCHING | | |
|-----------------------|--|--------------------------------|---|-----------------------------------|--|--|---------------------------------|-------------------------------|--|--------------------------------|-----------------------------------|---------------------------------------|--|---|-------------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | fae *!T **fab (mc) | P _c (mw) | τ _i (°c) | mw/°C | VCEO VCBO (v) | l C (ma) | hfe *hFE | l _{C0} (μο) | C _{oe} *C _{ob} (pf) | t _r (μsec) *ton (nsec) | † _s (μsec) *†off (nsec) | V _{ce(sat)} | Remarks |
| LL 1 | 2N1034 2N1275 2N1037 2N329A 2N1035 | RA RA RA CT RA | pnp,FA,si pnp,FA,si pnp,FA,ge pnp,AJ,si pnp,FA,si | 0.2 0.2 0.25 0.3 0.3 | 250 250 250 250 250 250 | 160 160 160 160 | - .54 - 3 - | *40 80 *35 35 *35 | 50 100 50 50 50 | 15 15 30 28 30 | 5 .005 5 .005 5 | 70 60 70 70 70 | 11111 | 1111 | | SSD, NA, KF KF SSD, NA, KF SSD, NA, KF, AMP |
| | 2N1036 2N1640 C301 2N328A 2N329A | RA CT CT CT SSD | pnp,FA,si pnp,AJ,si si,LA,qnq is,LA,qnq is,LA,qnq | 0.4 0.4 0.4 0.5 **0.5 | 250 250 250 250 250 385 | 160 160 160 160 | - 2 2 3 2.85 | *30 20 70 30 30 | 50 50 50 50 50 | 60 11 4 60 *88 | 5 .001 5 .005 0.1 | 70 50 50 70 70 | | 11111 | 11111 | SSD, NA, KF KF KF KF, RA |
| LL 2 | 2N1057 2N327A 2N670 2N2670 2N1234 | GE WT PH PH HU | pnp,AJ,ge pnp,AJ,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,si | 0.5 0.7 0.7 ••0.7 0.8 | 240 300 -300 400 | 100 200 85 85 160 | 4 3 5.0 - 3 | 45 .3 40 •40 110 | 300 200 2a 2a 100 | 15 200 • 100 21 | 300 100 20 20 0.1 | 40 70 - - 95 | 1111 | 11111 | 0,08 - 0,3 0.3 - | RA, KF, SD Pulse Amp. Pulse Amp TO-5 Package, KF |
| | 2N1244 2N1641 C302 2N327A 2N328A | HU CT CT HU HU | is, LA, qnq is, LA, qnq is, LA, qnq is, LA, qnq is, LA, qnq | 0.8 0.8 0.8 1.0 | 1000 250 250 385 385 | 160 160 160 160 160 | 7.4 2 2 2 3 3 | 110 10 8 50 50 | 200 50 50 100 | 20 15 12 14 25 | 0.1 .001 .2 0.1 0.1 | 95 50 50 95 95 | 11111 | 11111 | 1 1 1 1 | Coaxial package RA, SSD, KF WT, RA, SSD, JA, KF |
| LL 3 | 2N329A 2N331 2N1056 2N2370 2N2371 | HU RCA GE NA NA | pnp,AJ,si pnp,AJ,ge pnp,AJ,ge pnp,si pnp,si | 1.0 1.0 1.0 1.0 1.0 | 385 200 240 200 200 | 160 85 100 200 200 | 3 3 4 1.4 1.4 | 50 *30 50 15 15 | 100 200 300 50 50 | 50 - 25 15 20 | 10 16 25 0.005 0.005 | 95 - 40 15 15 | 11111 | - | - 0.09 - | WT, RA, SSD, NA, KF BE, US, MO Neon indicator 2.5db NF 2.5 db NF |
| | 2N2372 2N2373 TS605 TS606 2N1228 | NA NA TS TS | pnp,si pnp,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,si | 1.0 1.0 **1.0 **1.0 | 150 150 150 150 150 400 | 200 200 100 100 160 | 0.86 0.86 - - 3 | 15 15 12 20 *15 | 50 50 400 400 100 | 15 20 *15 *15 20 | 0.005 0.005 10 10 0.1 | 15 15 - - 95 | 11111 | 1 - 1 - 1 | 1 1 1 1 | 2.5 db NF 2.5 db NF WT,KF, SSD |
| LL 4 | 2N1229 2N1230 2N1231 2N1232 2N1233 | HU HU HU HU | pnp,AJ,si pnp,FJ,si pnp,FJ,si pnp,FJ,si pnp,FJ,si | 1.2 1.2 1.2 1.2 1.2 | 400 400 400 400 400 | 160 200 200 200 200 200 | 3 | 15 *35 *35 65 65 | 100 500 500 500 500 | 36 14 24 14 24 | 0.1 0.1 0.1 0.1 0.1 | 95 100 100 100 100 | 1111 | | - - - - | WT, NA, KF.AMP, SSD WT, NA, KF. SSD, AMP WT, NA, KF. SSD, AMP WT, NA, KF. SSD, AMP WT, NA, KF.SSD, AMP |
| | 2N1234 2N1238 2N1239 2N1240 2N1241 | HU HU HU HU | pnp,FJ,si pnp,AJ,si pnp,AJ,si pnp,AJ,si pnp,AJ,si | 1.2 1.2 1.2 1.2 1.2 | 400 1000 1000 1000 1000 | 200 160 160 160 160 | 7.4 7.4 7.4 7.4 7.4 | 110 15 15 35 35 | 500 200 200 200 200 200 | 14 20 36 20 36 | 0.1 0.1 0.1 0.1 0.1 | 100 95 95 95 95 | 11111 | | 11111 | WT, NA, KF, SSD Coaxial package Coaxial package Coaxial package Coaxial package |
| LL 5 | 2N1242 2N1243 2N1642 C106 OC122 | HU HU CT CT AMP | pnp,AJ,si pnp,AJ,si pnp,AJ,si pnp,AJ,si pnp,AJ,ge | 1.2 1.2 1.2 1.2 1.3 | 1000 1000 250 250 300 | 160 160 160 160 90 | 7.4 7.4 2 2 4.5 | 60 60 6 10 *32 | 200 200 50 50 50 | 20 36 23 50 180 | 0.1 0.1 .005 50 | 95 95 50 | 11111 | 11111 | 11111 | Coaxial package Coaxial package Field effect |
| | 2N312 2N519 2N519A B1154 B1154A | SY IND IND BE BE | npn,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 1.5 1.5 1.5 1.5 1.5 | 100 150 150 400 400 | 85 85 85 100 100 | 1.66 2.5 2.5 .15 | 15 15 25 40 60 | 200 200 200 300 300 | - 25 25 - - | 15 2 1 10 15 | - 14 14 20 20 | 1.5 - 1.3 1.5 1.5 | 2 - 0.7 - - | 0.075 - - .25 .25 | US, KF, TI US, KF |
| LL 6 | OC123 2N328A 2N536 2N679 2N1220 | AMP SZD PH SY SZD | pnp,AJ,ge pnp,FA,si pnp,AJ,ge npn,AJ,ge pnp,AJ,si | 1.5 2 ** 2 2 ** 2 | 300 385 50 150 250 | 90 160 85 85 175 | 4.5 2.85 - 2.5 1.7 | *50 40 *20 20 25 | 500 50 30 200 100 | 160 30 50 - *9 | - 5 4.0 25 0.1 | 70 - 18 | - - - 5 - | - - 5 - | - 0.07 0.3 - | KF |
| | 2N1222 2N1223 2N1446 OC80 2N438 | SSD SSD IND AMP SY | pnp,AJ,si pnp,AJ,si pnp,AJ,ge pnp,PADT,ge npn,AJ,ge | **2 **2 2 2 2.5 | 250 250 200 550 100 | 175 175 85 75 85 | 1.7 1.7 3.33 - 1.6 | 25 40 45 *32 30 | 100 100 400 600 | 10 6 30 85 20 | .005 0.1 5 10 10 | *18 15 - | - - 0.7 | 1.1.1.1 | 1 1 1 1 | - |
| LL 7 | 2N817 2N818 2N356 2N356A 2N520 | RA RA SY GI KF | npn,AJ,ge npn,AJ,ge npn,AJ,ge npn,AJ,ge pnp,AJ,ge | 2.5 2.5 3 3 | 75 75 100 150 150 | 85 85 85 100 100 | 1.25 1.25 1.6 2 | 30 30 20 30 20 | 400 400 500 500 | 20 20 - 60 20(min) | 10 10 25 3 25 | 20 20 - 14 - | - 1.0 1.5 | - 0.3 0.3 - | - 0.6 0.18 | Submin Submin Gl SY, TI TI |

LL continued

| | | | | | | MAX | RATING | S | | CHAR | ACTERIS | TICS | SI | WITCHING | ; | |
|-----------------------|--|-----------------------------------|---|-----------------------------------|----------------------------------|--------------------------------------|--|--|--|------------------------------------|---------------------------------|----------------------------------|--|---|------------------------------|---|
| Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P c (mw) | T _i | mw/°C | V _{CEO} *V _{CBO} (v) | l C (ma) | h _{fe} *h | l _{CO} (μα) | Coe *Cab (pf) | t _r (μsec) *ton (nsec) | † _s (μsec) *†off (nsec) | V _{ce(sat)} | Remarks |
| | 2N801 2N802 2N1051 2N1302 2N1447 | RA RA WE TI IND | pnp,AJ,ge pnp,AJ,ge npn,D,si npn,AJ,ge pnp,AJ,ge | 3 3 **3 3 | 75 75 250 150 200 | 85 85 150 - 85 | 1.25 1.25 4.0 - 3.33 | 30 30 40 25 45 | 400 400 100 300 400 | 30 30 30 *20 45 | 4 4 0.1 6 5 | 20 20 7.0 *20 | 11111 | 11111 | - - - 0.4 - | Submin Submin |
| LL 8 | 2N1993 2N1353 2N385A 2N404A 2N425 | TI IND SY RCA SY | npn,A.ge pnp,AJ,ge npn,AJ,ge pnp,AJ,ge pnp,AJ,ge | 3.5 4 4 4 | 300 200 150 150 150 | 100 85 100 100 85 | 4.0 3.33 2 - 2.5 | *30 15 *40 40 20 | 300 200 200 150 400 | *120 70 30-110 30 | 4 2.5 40 5 2.0 | *13 12 - 20 14 | 0.2 .6 - - 1.0 | 0.7 .4 - - 0.3 | 0.07 0.1 - - 0.2 | KF, US GI, TI GI,IND,TS,KF, TI RA, IND, TS, US, KF, GI |
| | 2N799 2N800 2N824 2N1027 2N1028 | RA RA RA SSD SSD | ag, LA, qnq ag, LA, qnq ag, LA, qqn iz, LA, qnq iz, LA, qnq | 4 4 4 **4 **4 | 75 75 75 250 250 | 85 85 85 176 175 | 1.25 1.25 1.25 1.7 1.7 | 25 25 25 •18 •10 | 150 150 100 100 100 | 30 20 40 18 9 | 5 5 .025 .025 | 20 20 20 7 7 | 11111 | 11111 | 11111 | Submin Submin Submin NA, SSD, KF NA, KF |
| LL 9 | 2N1404 2N1448 2N1605A 2N1780 2N1781 | IT DAI Y2 Y2 Y2 Y2 | pnp,A,ge pnp,AJ,ge npn,AJ,ge npn,AJ,ge gg,LA,nqn | **4 4 4 4 | 300 200 200 100 100 | 100 85 100 100 100 | 4.0 3.33 2.6 1.3 1.3 | *25 45 40 25 25 | 300 400 200 100 100 | *90 65 40 30-110 40 | 3 5 10 10 5 | *13 20 20 20 20 | 0.18 - - - - | 0.8 | 0.08 - - - - | GI, RCA |
| | 2N 1808 2N 2000 2N 395 2N 520 2N 520 A | TI TI GE IND IND | npn, A, ge pnp, AJ, ge pnp, AJ, ge pnp, AJ, ge pnp, AJ, ge | ** 4 4 ** 4.5 4.5 4.5 | 300 300 500 150 150 | 85 100 100 85 85 | 5.0 4 6.67 2.5 2.5 | *25 50 *30 15 25 | 300 750 200 200 200 200 | *120 *100 40 100 | 3 8 6 1 | *13 30 *14 14 14 | 0.2 - 0.55 - 0.9 | 0.7 - 0.5 - 0.7 | 0.07 0.6 - | TI, KF, PH US, KF US, KF, TI |
| LL 10 | 2N1169 2N1170 2N1302 2N1303 2N1354 | SY SY TI TI IND | ag,LA,nqn ag,LA,nqn ag,LA,nqn ag,LA,qnq ag,LA,qnq | 4.5 4.5 4.5 4.5 4.5 | 120 120 150 150 200 | 85 85 85 85 85 | 2 2 2.5 2.5 3.33 | 25 25 25 • 30 30 | 400 400 300 300 200 | 20 20 - - 70 | 50 50 5 3 2.5 | 20 20 11 16 12 | - .70 .40 | - .50 .90 | - .1v .1v 0.1 | RCA RCA TO-5, SY, GI, RCA GI, KF, AMP KF, US |
| | 2N123 2N315 2N315A 2N388A 2N396A | SY GI GI RCA SY | pnp,AJ,ge ge,LA,qnq ge,LA,nqn ge,LA,nqn | \$ 5 5 5 5 | 100 100 150 150 150 | 85 85 100 100 100 | 1.66 2 2 - 2 | 15 *20 *30 *40 30 | 125 500 500 200 200 | 30-150 - 70 •30 30-150 | 0.6 1 1 5 6 | 14 14 20 | 1.0 0.9 1 | 0.2 0.4 0.7 | 0.2 0.12 0.12 - | KF, IND, US IND, US, KF TS,KF,GE,GI,RCA |
| LL 11 | 2N414 2N439 2N450 2N576 2N578 | SY SY GE SY RCA | onp,AJ,ge npn,AJ,ge pnp,AJ,ge npn,AJ,ge pnp,AJ,ge | 5 5 5 5 | 150 100 150 200 120 | 85 85 85 100 71 | 2.5 1.66 2.5 2.6 | *30 *20 12 20 20 | 200 - 125 400 400 | 30-90 - - 15 | 5 10 6 20 | - 20 - | 0.5 - 2 0.85 | 0.7 1 0.33 | 0.25 0.2 0.4 0.2 | KF, GI, US, TS TI IND,US,KF,GI |
| | 2N585 2N658 2N803 2N804 2N815 | RCA RA RA RA RA | npn,AJ,ge pnp,FA,ge pnp,AJ,ge pnp,AJ,ge npn,AJ,ge | 5 5 5 5 5 | 120 150 75 75 75 | 71 85 85 85 85 | 1.25 1.25 1.25 1.25 | 25 16 30 30 25 | 200 1a 400 400 200 | 40 40 40 60 | 3 2.5 4 4 10 | 12 20 20 20 20 | 0.35 | 0.25 | 0.1 0.25 - - | SY, GI, TI KF Submin Submin Submin |
| LL 12 | 2N816 2N819 2N820 2N825 2N826 | RA RA RA RA | npn,AJ,ge npn,AJ,ge npn,AJ,ge pnp,AJ,ge pnp,AJ,ge | 5 5 5 5 | 75 75 75 75 75 75 | 85 85 85 85 85 | 1.25 1.25 1.25 1.25 1.25 1.25 | 25 30 30 30 30 30 | 200 400 400 200 200 | 60 30 30 30 30 | 10 10 10 6 6 | 20 20 20 20 20 20 | 11111 | 11111 | 11111 | Submin Submin Submin Submin |
| 11.12 | 2N1012 2N1219 2N1221 2N1348 2N1449 | GI SSD SSD IND IND | npn,AJ,ge pnp,AJ,si pnp,AJ,si pnp,AJ,ge pnp,AJ,ge | 5 **5 **5 5 | 150 250 250 200 200 | 100 175 175 175 85 85 | 2 1.7 1.7 3.33 3.33 | *40 25 25 40 45 | 100 100 400 400 | *18 20 95 80 | 5 0.1 .005 5 5 | 10 15 *15 12 | 0.1 | 0.1 | 0.1 | KF, TI |
| LL 13 | 2N1994 GT1658 KGS1005 2N357 2N357A | TI GI KF SY GI | ge,LA,nqn ge,LA,nqn ge,LA,nqn ge,LA,nqn | 5 5 6 6 | 150 150 200 100 150 | 85 100 85 85 100 | 2.5 2 5.2 1.6 2 | 30 *30 30 *15 30 | 300 - 400 500 500 | 50 40 - 90 | 5 3 12 25 3 | 11 10 - - 14 | 1.1 - 1.2 0.5 | 1.5 - .7 0.5 | - - .20 0.18 | GI, TI SY, TI |
| LL 14 | 2N377 2N426 2N789 2N902 2N1319 | SY SY RA RA RCA | npn,AJ,ge pnp,AJ,ge npn,DB,si npn,DB,si pnp,AJ,ge | 6 6 6 | 150 150 - - 120 | 100 85 - 71 | 2 2.5 1.4 - | *20 *20 45 45 20 | 200 400 25 25 400 | - 15 15 30 | 10 2 .002 .002 2.5 | 14 5 5 | 2.5 1.0 - - 20 | 0.7 0.3 - - | - 0.22 - - - | GE, GLTI RA, TS, GI, US, TI, KF Submin Submin TI |
| CC 14 | 2N1343 2N1997 2N2181 2N2182 2N2183 | IND TI PH PH PH | pnp,AJ,ge npn,AJ,ge pnp,SAT,si pnp,SAT,si pnp,SAT,si | 6 6 *6 *6 | 150 250 150 150 150 | 85 100 140 140 140 | 2.5 3.3 1.3 1.3 | 20 45 •25 •25 •15 | 400 50 50 50 | 40 4 10 10 10 | 3 15 0.01 0.01 0.01 | 12 - •12 •12 •12 | 1.0 | 11111 | 11-11 | Chopper 2N2181 Chopper |

May 24, 1963 T63

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| TYPE | Ma | Maximum Ratings | | | | | Charac | teristics | | | |
|----------------------------|--------------------------|------------------------|-----------------------|-----------------------------|-------------------------|-------------------------------------|--------|----------------------------|-----------------------------|------------------------------|-------------------------------|
| | T _S °C. | V _{CB} volts | P _T @25°C. | I _{CBO} max. μa | h _{FE} min. | V _{CE} (SAT) max. volts | min. | C _{ob} max. pf | t _s max. nsec | t _{on} max. nsec | t _{off} max. nsec |
| 2N709 | 300 | 15 | 300 | 0.05 | 20 | 0.30 | 600 | 3 | 6 | 15 | 15 |
| T-2877 *T0-18 case—collect | 300 for internally co | 15 nnected to case. | 300 | 0.05 | 20 | 0.30 | 500 | 3 | 8 | 17 | 17 |

| CORE | DRIVER | C/DIII CE | AMDII | FIEDS |
|------|--------|-----------|-------|-------|

| TYPE* | V _{CB} max. volts | f _T @ 50 ma mc | h _{FE} @ 150 ma |
|----------------------------------|-------------------------------|---------------------------------|-----------------------------|
| 2N1893 | 120 | 50 | 40 |
| 2N1613 *TO-5 case—collector inte | 75 | 60 | 40 |

100 mc LOW-NOISE AMPLIFIER

Industry's Newest Silicon Amplifier Standard

| TYPE | Power | Maximum | Minimum |
|---------|----------------|--------------|-------------------|
| | Gain | Noise Figure | BV _{CEO} |
| T-2857* | 15-22db@100 mc | 5db@100 mc | 20 volts |

The new Philco T-2857 is industry's first silicon amplifier transistor to be functionally tested at 100 mc for fixed-matched, fixed neutralized, and fixed-bias performance. This insures interchangeability in practical communications circuits.

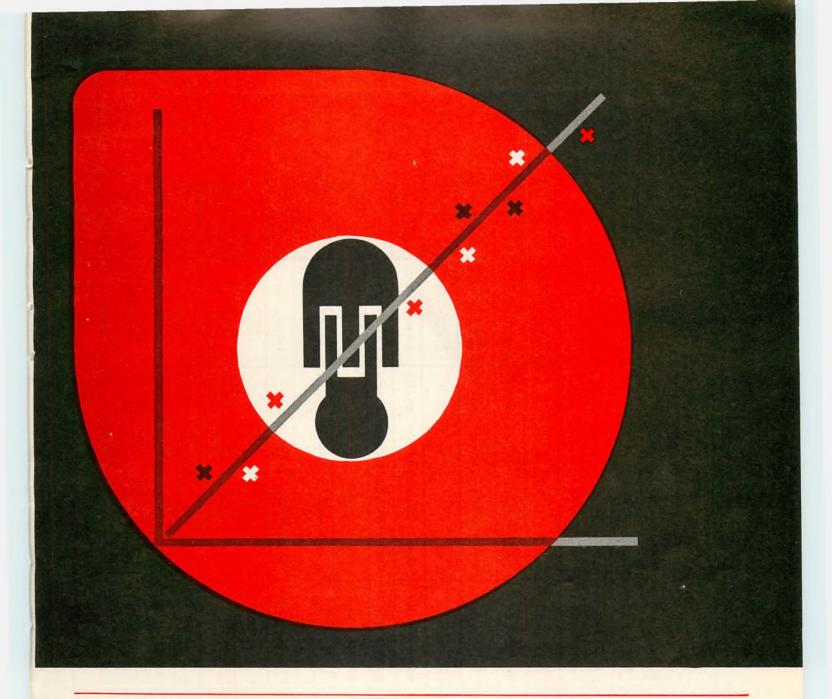
*TO-18 case with 4 leads—collector isolated from case:



Whatever your silicon transistor application, evaluate Philco Planar Transistors.

For complete data, and new Reliability report, write Dept. ED52463.

ON READER-SERVICE CARD CIRCLE 464



VERY HIGH SPEED SWITCHES

These Philco Types Feature Industry's Best Combination of Voltage, Switching Speed, and Beta.

| TYPE | | M | aximum | Ratings | | Characteristics | | | | | | | | | | | |
|--------|--------------------|------------------------|------------------------|----------------------------------|-------------------|-----------------------------|-------------------------|-------------------------------------|---------------------------|-------------------------|-----------------------------|------------------------------|-------------------------------|--|--|--|--|
| 71 | T _S °C. | V _{CBO} volts | V _{CEO} volts | P _T @ 25° C. mw | I _C ma | l _{CBO} max. μa | h _{FE} min. | V _{CE} (SAT) max. volts | f _T min. mc | C _{ob} max. pf | t _s max. nsec | t _{on} max. nsec | t _{off} max. nsec | | | | |
| 2N2710 | 300 | 40 | 20 | 360 | 500 | 0.03 | 40 | 0.25 | 500 | 4 | 15 | 20 | 35 | | | | |
| 2N2651 | 300 | 40 | 20 | 360 | 500 | 0.03 | 25 | 0.25 | 350 | 4 | 25 | 35 | 75 | | | | |
| 2N914 | 300 | 40 | 15 | 360 | 500 | 0.025 | 30 | 0.25 | 300 | 6 | 20 | 40 @ 200 ma | 40 @ 200 ma | | | | |
| 2N834 | 175 | 40 | 30** | 300 | 200 | 0.50 | 25 | 0.25 | 350 | 4 | 25 | 35 | 75 | | | | |
| 2N784A | 300 | 40 | 15 | 350 | 200 | 0.025 | 25 | 0.19 | 300 | 3.5 | 15 | 20 | 40 | | | | |
| 2N708 | 300 | 40 | 15 | 360 | | 0.025 | 30 | 0.40 | 300 | 6 | 25 | | | | | | |
| 2N706 | 175 | 25 | 20* | 300 | 50 | 0.5 | 20 | 0.60 | 200 | 6 | 60 | | | | | | |

*VCER **VCES † TO-18 case—collector internally connected to case.



LANSDALE DIVISION, LANSDALE, PA.



LL continued

| | | | | | | MAX. | RATINGS | | 1 | CHARACTERISTICS | | SW | ITCHING | | | |
|-----------------------|--|--------------------------------|---|--------------------------------|--|--|--------------------------------------|-------------------------------|---------------------------------|-------------------------------|--|----------------------------------|--|---|---------------------------------------|---|
| Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P _c (mw) | τ _ί (°c) | mw/°C | VCEO | I C | hfe *hFE | _{CO} (μα) | Coe *Cob (pf) | t _r (μsec) *ton (nsec) | t _s (μsec) *toff (nsec) | V _{ce(sat)} | Remarks |
| | 2N2184 2N2274 2N2275 2N2276 2N2277 | PH PH PH PH PH | pnp,SAT,si pnp,SP,si pnp,SP,si pnp,SP,si pnp,SP,si | *6 *6 *6 *6 | 150 150 150 150 150 | 140 140 140 140 140 | 1.3 1.3 1.3 1.3 1.3 | • 15 25 25 15 15 | 50 50 50 50 50 | *15 10 10 10 10 | 0.0003 0.045 0.045 0.003 0.003 | *12 9 9 9 | 11111 | 11111 | 1111 | Pair 2N2183 Chopper 2N2274 chopper 2N2276 |
| LL 15 | 2N2185 2N2186 2N2187 2N100 2N1090 | PH PH PH SY RCA | pnp,SP,si pnp,SP,si pnp,SP,si npn,AJ,ge npn,AJ,ge | *6.5 *6.5 *6.5 7 7 | 150 150 150 150 150 120 | 140 140 140 100 85 | 1.3 1.3 1.3 2 | 30 30 30 40 25 | 50 50 50 - 400 | - - 25(min) 50 | 0.001 0.001 0.001 15 4 | 9 9 - | - - - 0.25 | - - - 0.20 | 1 - 1 1 | chopper M. Pair 2N2185 Gl |
| | 2N1114 2N1995 GT123 2N2278 2N2279 | SY TI GI PH PH | npn,AJ,ge npn,AJ,ge pnp,AJ,ge pnp,SAT,si pnp,SAT,si | 7 7 7 *7.6 *7.6 | 150 150 150 150 150 | 100 85 150 140 140 | 2 2.5 2 1.3 1.3 | *15 25 *25 15 15 | 200 300 - 50 50 | - 40 - | 30 5 3 0.001 0.001 | - 11 15 9 9 | - 0,9 - | - 0.5 - - | - 0.1 - - | TI Chopper 2N2278 |
| LL 16 | 2N123 2N388 2N396 2N396A 2N576A | GE GI GE PH SY | pnp,AJ,ge npn,AJ,ge pnp,AJ,ge pnp,AJ,ge npn,AJ,ge | 8 8 8 **8 | 150 150 200 500 200 | 85 100 100 100 100 | 2,5 2 3.3 6.67 2,6 | 15 *25 20 *30 40 | 125 500 200 200 400 | 0.987 - - •100 - | 6 5 6 40 | 15 10 12 •14 | 0.45 0.6 0.4 .2 2 | 0.90 0.4 0.6 .25 | 0.15 0.08 .15 0.4 | SY SY, GE, RA, TI – TI, GI, SY, KF |
| | 2N579 2N581 2N583 2N597 2N598 | RCA RCA RCA PH PH | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 8 8 **8 8 | 120 150 120 250 250 | 71 85 - 85 100 100 | - - 3.3 3.3 | 20 18 18 *45 *35 | 400 100 100 500 500 | 30 30 30 •70 125• | 3 3 3.5 3 | 12 12 •15 •15 | 0.36 0.20 0.20 - - | 0.33 0.20 0.20 - | 0.2 0.35 0.35 0.085 0.085 | INO, US, KF, GI US,IND,GI,KF,TI KF-MIL |
| LL 17 | 2N600 2N662 2N714 2N790 2N792 | PH RA RCA RA RA | pnp, AJ, ge pnp, FA, ge pnp, AJ, ge npn, DB, si npn, DB, si | *8 8 8 8 | 750 150 150 - | 100 85 85 - | 10 - - 1.4 1.4 | *35 11 30 45 45 | 500 1a 200 25 25 | *125 - 80 30 60 | 3 2.5 2 .002 | *15 12 11 8 5 | 11111 | 11111 | 0.085 0.25 - - - | MIL KF Submin Submin |
| | 2N903 2N905 2N1280 2N1284 2N1304 | RA RA IND IND TI | npn,DB,si npn,DB,si pnp,AJ,ge pnp,AJ,ge npn,AJ,ge | 8 8 8 8 | - 200 150 150 | 85 85 85 85 | 3.33 2.5 2.5 | 45 45 16 20 •25 | 25 25 400 400 300 | 30 80 60 90 110 | .002 .002 5 2 | 20 20 10 15 16 | - .10 .45 .45 | - - .9 .50 | - - 15 .1v | Submin Submin TO-5, GI, SY, GE, AMP |
| LL 18 | 2N1305 2N1347 2N1350 2N1351 2N1355 | T1 IND IND IND IND | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 8 8 8 8 | 150 150 200 200 200 | 85 85 85 85 85 | 2.5 2.5 3.33 3.33 3.33 | *30 20 50 40 30 | 300 200 400 400 200 | 100 80 95 65 80 | 3 2.5 10 5 2.5 | 11 12 12 12 12 12 | .28 - - .4 | .80 - - - - .6 | .1v - - - 0.08 | TO-5, KF, GI, AMP KF KF US |
| | 2N1356 2N1478 2N1685 2N2001 2N2177 | IND PH SY TI SSD | pnp,AJ,ge pnp,AJ,ge npn,AJ,ge pnp,AJ,ge si,LA,qnq | 8 **8 8 8 | 200 250 100 300 100 | 100 100 100 100 100 175 | 2.66 3.3 1.3 4 0.7 | 30 *30 25 30 6 | 200 500 200 750 50 | 80 •70 40 - •95 | 2.5 3.5 10 5 *0.5 | 12 *15 20 30 10 | .A | .6 - - - | 0.08 .085 - - - | us |
| LL 19 | 2N2178 2N167 2N358 2N358A 2N394 | SSD GE GI SY GE | np,AJ,si np,GJ,ge np,AJ,ge np,AJ,ge np,AJ,ge | **8 9 9 | 100 65 100 150 150 | 175 85 85 100 85 | 0.7 1.1 2 2 2.5 | 6 30 20 •30 10 | 50 75 500 500 200 | •95 0,985 60 25-75 | *0.5 1.5 3 5 | 10 2.5 14 14 12 | 0.4 0.4 - | 0.7 0.5 - | 0.35 0.18 - 0.04 | USAF2N167-MIL SY, TI GI KF |
| | 2N823 2N1198 2N2274 2N2275 2N2276 | RA GE PH PH PH | npn,AJ,ge npn,RG,ge pnp,SP,si pnp,SP,si pnp,SP,si | 9 *9 *9 | 75 65 150 150 150 | 85 85 140 140 140 | 1.25 1.1 1.3 1.3 1.3 | 25 25 •25 •25 •15 | 100 75 50 50 50 | 40 - *15 *15 *15 | 5 1.5 .003 .003 .003 | 20 2.5 *6 *6 *6 | 0,4 - - - | 0.7 - - - | - 0.35 - - - | Submin Chopper pair 2N2274 chopper |
| LL 20 | 2N2277 2N397 2N440 2N518 2N521 | PH RCA SY GE IND | pnp,SP,si pnp,AJ,ge npn,AJ,ge pnp,AJ,ge pnp,AJ,ge | *9 10 10 10 10 | 15 0 150 100 150 150 | 140 85 85 85 85 | 1.3 - 1.66 2.5 2.5 | *15 30 *15 12 15 | 50 200 - 125 200 | 10 • 40 — — 70 | 0.003 6 10 6 1 | *9 *20 - 12 14 | - 0.3 0.8 - | - 0.7 0.9 - | - 0.2 0.25 0.15 | pair 2N2276 GI,TI US, KF |
| LL 21 | 2N521A 2N600 2N659 2N745 2N805 | IND PH RA RA RA | pnp,AJ,ge pnp,AJ,ge pnp,FA,ge npn,MS,si pnp,AJ,ge | 10 10 10 10 10 | 150 750 150 150 75 | 85 100 85 175 85 | 2.5 10 - 0.75 1.25 | 25 35 14 45 30 | 200 500 1a 50 400 | 150 - - 22 60 | 1 10 2.5 10 4 | 14 15 12 3 20 | 0,2 - - - - | 0.5 - - - - | 0.085 0.25 - - | US, KF KF, GI Submin Submin |
| LL 21 | 2N806 2N821 2N822 2N1281 2N1349 | RA RA RA IND IND | pnp,AJ,ge npn,AJ,ge npn,AJ,ge pnp,AJ,ge pnp,AJ,ge | 10 10 10 10 10 | 75 75 75 200 200 | 85 85 85 85 85 | 1.25 1.25 1.25 3.33 3.33 | 30 30 30 16 40 | 400 400 400 400 400 | 60 40 40 90 110 | 10 10 5 5 | 20 20 20 10 12 | - - - .9 - | - | - | Submin Submin Submin |

ELECTRONIC DESIGN



Obsoletes the Silicon Alloy Transistor

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Epitaxial Junction PNP Silicon Transistors

Featuring -

HIGH V_{eb}
ULTRA LOW LEAKAGE

LOW OFFSET VOLTAGE
HIGH FREQUENCY

RELIABILITY

These transistors are available in TO-5, TO-18, TO-46 and Molytab packages.

| Characteristic | | n | |
|---|---------|---------|---------|
| | C9001 | C9002 | C9003 |
| V_{cb} and V_{eb} ($I_b = 10^{-10}$ a) | 15v | 25v | 40v |
| V _{ce} | 10v | 20v | 35v |
| I _{cbo} and I _{ebo} (100°C) | 3nA | 3nA | 3nA |
| $V_0 (I_b = 200 \mu a; I_e = 0)$ | 0.3mV | 0.5mV | 0.8mV |
| Beta at 1mc ($I_c = 1$ ma; $V_{ce} = 6v$) | 30 | 20 | 10 |
| Dissipation (case temp. =25°C) | 2 watts | 2 watts | 2 watts |
| Max. Operating Temperature | 200°C | 200°C | 200°C |
| Package | TO-46 | TO-46 | TO-46 |

In addition, virtually all present PNP types can be supplied in this new construction in quantities and at competitive prices for direct replacement in existing circuits.

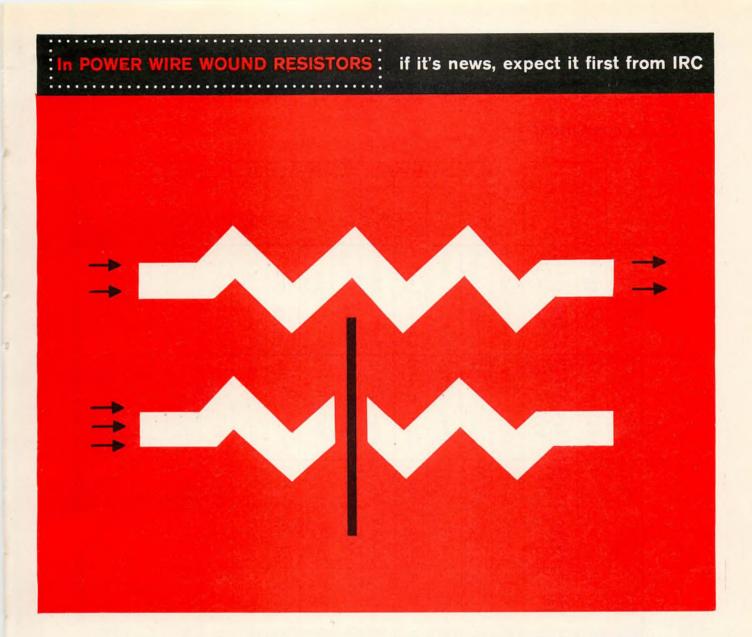
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ON READER-SERVICE CARD CIRCLE 465

LL continued

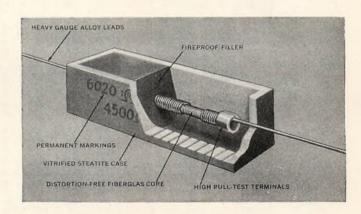
| Γ | | | | | | | MAX | . RATING | TINGS CHARACTERISTICS SWITCHING | | | | ING | | | | |
|---|-----------------------|---|--------------------------------|---|----------------------------------|--|-----------------------------------|--------------------------------------|----------------------------------|---------------------------------|--|-----------------------------------|----------------------------------|-----------------------------------|---|--------------------------------------|---|
| | Cross Index Key | Type No. | Mfr. | Type | fae *fT **fab (mc) | P c (mw) | T ((°c) | mw/°C | VCEO *VCBO (v) | l C (ma) | hfe *hFE | lco (μο) | Coe *Cob (pf) | (μsec) *ton (nsec) | t _s (μsec) *toff (nsec) | V _{ce(sat)} (v) | Remarks |
| | | 2N1996 2N1998 2N2185 2N2186 2N2187 | TI TI PH PH PH | npn,AJ,ge pnp,AJ,ge pnp,SP,si pnp,SP,si pnp,SP,si | 10 10 10 10 10 | 150 250 150 150 150 | 85 100 140 140 140 | 2.5 3.3 1.3 1.3 1.3 | 20 35 *30 *30 *30 | 300 400 50 50 50 | 11111 | 5 4 0.001 0.001 0.001 | 11 15 •6 •9 •6 | 11111 | 1111 | | Chopper Chopper Pair 2 N2185 |
| | LL 22 | 2N2648 R212 2N427 2N791 2N904 | GI TS GI RA RA | pnp, AJ, ge pnp, AJ, ge pnp, AJ, ge npn, DB, si npn, DB, si | **10 **10. 11 11 11 | 250 0- 150 - - | 100 85 100 - | 3.3 - 2 1.4 | *35 30 *30 45 45 | 1 a 400 - 25 25 | *80-500 *20 - 60 60 | 3 - 2 .002 | *18 *200 14 5 20 | .12 5 0.43 - - | .6 *20 0.3 - - | 0.105 | KF, TS, TI, IND, RA, US Submin Submin |
| | | 2N316 2N316A 2N397 2N404 2N428A | GI GE RCA GI | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,ge | 12 12 12 12 12 12 | 100 150 200 120 150 | 85 100 100 85 100 | 2 2 3.3 - 2 | *20 *30 15 *25 *0.25 | 500 500 200 100 10 | 130 - - 100 | 1 6 5 5 | 14 14 12 - 20 | 0.4 0.4 0.3 0.17 0.43 | 0.4 0.4 0.7 0.20 0.3 | 0.14 0.14 0.07 0.12 0.22 | KF IND, US, KF TI, KF US,GE,RA,GI,SY,KF, PH, TI, AMP |
| | LL 23 | 2N635 2N1306 2N1307 2N1313 2N1344 | GE TI TI IND IND | npn,AJ,ge npn,AJ,ge pnp,AJ,ge pnp,AJ,ge | 12 12 12 12 12 | 150 150 150 175 175 | 85 85 85 85 85 | 2.5 2.5 2.5 - 2.5 | 20 *25 *30 *30 15 | 300 300 300 400 400 | - 110 110 80 90 | 5 5 3 - 5 | 16 11 14 12 | .22 .20 - 0.7 | - .50 .80 - 0.3 | .lv .lv - | TO-5,GI,SY,GE,AMP TO-5,GI, KF,AMP KF, TI KF |
| | | 2N1345 2N1346 2N1357 2N2278 2N2279 | IND IND IND PH PH | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,SAT,si pnp,SAT,si | 12 12 12 •12 •12 | 150 150 200 150 150 | 85 85 85 140 140 | 2.5 2.5 3.33 1.3 1.3 | 10 12 30 •15 •15 | 400 400 200 50 50 | 60 125 85 - | 3 2.5 2.5 0.001 0.001 | 14 14 12 •6 •6 | .3 .3 - | .4 .4 .7 - | - .10 0.07 - - | KF KF Chopper Pair 2 N2278 |
| | LL 24 | 2N269 2N793 2N906 2N1091 2N582 | RCA RA RA RCA SY | pnp,AJ,ge npn,DB,si npn,DB,si npn,AJ,ge pnp,AJ,ge | 13 13 13 13 14 | 120 - - 120 120 | 85 - 85 71 | 1,4 - - 2,6 | 25 45 45 25 *25 | 100 25 25 400 100 | 40 150 150 70 40(min) | 2 .002 .002 4 5 | 5 20 - | 0.17 - 0.20 - | 0.20 - 0.17 - | 0.12 - - - - | Submin Submin GI KF, RCA, TI |
| | | 2N584 2N807 2N808 2N858 2N859 | RCA RA RA PH PH | ga,LA,qnq ga,LA,qnq pnp,AJ,ge pnp,SP,si qnq,SP,si | **14 14 14 14 14 | 120 75 75 150 150 | 85 85 85 140 140 | 1.25 1.25 1.3 1.3 | 25 25 25 •40 •40 | 100 100 100 50 50 | 60 40 40 33 65 | 2 5 5 .1 .1 | 12 20 20 5 5 | 0.15 - - - - | 0.17 - - - - | 0.2 - - - - | US Submin Submin SPR SPR |
| | LL 25 | 2N860 2N862 2N580 2N636A 2N660 | PH PH RCA SY RA | pnp,SA,si pnp,SP,si pnp,AJ,ge npn,AJ,ge pnp,FA,ge | 14 14 15 15 | 150 150 120 150 150 | 140 140 71 100 85 | 1.3 1.3 - 2 | *25 *15 20 *25 11 | 50 50 400 300 1a | 33 33 45 100-300 | .1 .1 3 6 2.5 | 5 5 - 20 12 | 0.16 - - | - 0.29 - - | 0.2 - 0.25 | SPR SPR GI,IND.US,TS,KF TI KF, TI |
| | | 2N1282 2N1316 2N1317 2N1318 2N1999 | IND IND IND IND TI | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 15 15 15 15 15 | 200 200 200 200 200 250 | 85 85 85 85 100 | 3.33 3.33 3.33 3.33 3.33 | 16 30 20 10 30 | 400 400 400 400 400 | 100 100 95 85 | 5 2 3 4 4 | 10 14 14 14 14 15 | .8 - - - | | - | KF KF |
| | LL 26 | 2N388A 2N599 2N601 2N2280 2N2281 | T1 PH PH PH PH | npn,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,SAT,si pnp,SAT,si | **16 *16 16 *16 *16 | 150 250 750 150 150 | 100 100 140 140 | 3.3 10.0 1.3 1.3 | 40 *30 *30 10 | 200 500 500 50 50 | *60-*180 *175 *175 - - | 5 3.5 3.5 0.003 0.003 | *20 *15 *15 10 | - - - - 10 | | - 0.07 *0.07 - - | MIL Chopper 2N2280 |
| | | 2N428 2N636 2N522 2N522A 2N582 | GI GE IND IND RCA | pnp,AJ,ge npn,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 17 17 18 18 18 | 150 150 150 150 150 | 100 85 85 85 85 85 | 2 2.5 2.5 2.5 2.5 | *30 *20 15 *25 25 | - 300 200 200 100 | - 120 200 60 | 2 5. 1 1 5 | 14 - 14 14 - | 0.43 - - 0.2 0.15 | 0.3 - - 0.5 0.17 | 0.22 - - - 0.2 | SY, RA, IND, US, PH, TS, TI, KF, GE TI US,KF US,KF,TI TS,GI,IND,SY,KF |
| | LL 27 | 2N584 2N1308 2N1309 2N2165 2N2166 | RCA TI TI SPR SPR | pnp,AJ,ge npn,AJ,ge pnp,AJ,ge pnp,SP,si pnp,SP,si | 18 18 18 *18 *18 | 120 150 150 150 150 | 85 85 85 - | 2.5 2.5 1.3 1.3 | 25 *25 *30 *30 *15 | 100 300 300 - - | 60 200 210 2.5-4.5 2.5-4.5 | 2 5 3 0.02 0.02 | 12 15 11 *10 *10 | 0.15 - - - - | 0.17 - - - - | 0.2 - - - - | US TO-5,SY,GE,AMP TO-5, KF, GI, AMP |
| | | 2N2377 2N317 2N317A 2N337 2N417 | SPR GI GI TI IND | pnp,SP,si pnp,AJ,ge pnp,AJ,ge npn,GD,si pnp,AJ,ge | 18 20 20 20 20 20 | 150 100 150 125 200 | 140 85 100 150 85 | 1.3 2 2 .001 3 | *25 *30 *30 *45 *30 | 50 500 500 20 20 | 20 - 180 19 140 | .002 1 1 1 2 | 14 14 14 - | 0.3 0.3 0.05 | 0.4 0.4 0.02 | - 0.18 0.18 1.5 | TO-18 US, IND, KF IND, US, KF, PH TR, RA, GE, AMP KF, US, TI |
| | LL 28 | 2N 496 2N661 2N7 46 2N 1008 2N 1008 A | PH RA RA BE BE | pnp,SAT,si pnp,FA,ge npn,MS,si pnp,AJ,ge pnp,AJ,ge | 20 20 20 20 20 20 | 150 150 150 400 400 | 140 85 175 85 85 | 1.3 - 0.75 6.6 6.6 | *10 9 45 20 40 | 50 1a 50 300 300 | *25 - 45 100 100 | .001 2.5 10 10 10 | *6 12 3 - | | | .06 0.25 - 0.25 0.25 | MIL KF, TI Submin |



Transistor circuits and low power applications need this safety feature!

IRC PW Resistors are available with special resistance windings, designed to act as a standard resistor at normal operating wattages and fuse at some specific overload condition. They can also provide positive temperature compensation to offset transistor high temperature avalanching. Thus they offer a standard circuit resistor that can provide fusing or temperature compensating characteristics in one unit at a cost as low as 5 cents each.

These triple-duty resistors come in seven sizes—2, 3, 5, 7, 10, 15 and 20 watts. Write for Bulletin P-7: International Resistance Co., 401 N. Broad Street, Philadelphia 8, Pa.





| | | | | | | MAX | . RATING | S | | CHAR | ACTERIS | TICS | SW | ITCHING | | |
|-----------------------|--|------------------------------|--|-------------------------------------|---------------------------------------|--|--|--|---------------------------------|--|---------------------------------------|-----------------------------------|--|---|------------------------------------|---|
| Cross Index Key | Type No. | Mfr. | Туре | fae *fT **(ab (mc) | P c (mw) | т _і | mw/°C | V CEO *V CBO (v) | 1 C (ma) | h _{fe} *h | Ι _{CO} (μο) | Cae *Cab (pf) | t _τ (μsec) *ton (nsec) | t _s (μsec) *toff (nsec) | V _{ce(sat)} (v) | Remarks |
| | 2N1008B 2N1017 2N1119 2N2162 2N2163 | BE US PH SPR SPR | pnp,AJ,ge pnp,FA,ge pnp,SAT,si pnp,SP,si pnp,SP,si | 20 20 •20 •20 •20 | 400 150 150 150 150 | 85 85 140 — — | 6.6 - 1.3 1.3 1.3 | 60 10 *10 *30 *15 | 300 400 50 - | 100 *25 3.5-35 3.5-35 | 10 2 .001 0.01 0.01 | 12 6.0 *10 *10 | 0.25 - - - | 11111 | 0.25 0.25 .06 - | KF SPR-MIL |
| LL 29 | CK419 CK420 CK421 CK474 CK475 | RA RA RA RA RA | npn,FA,si npn,FA,si npn,FA,si npn,DB,si npn,DB,si | 20 20 20 20 20 20 | 385 385 385 250 250 | 160 160 160 180 180 | - - 1.9 1.9 | 4Q 35 30 40 35 | 50 50 50 50 50 | 15 30 60 15 30 | .005 .005 .005 .005 | 35 - 20 20 20 | 11111 | 11111 | 11111 | |
| 11. 20 | CK476 CK477 TMT1543 2N861 2N863 | RA RA TR PH PH | npn,DB,si npn,DB,si npn,MS pnp,SP,si pnp,SP,si | 20 20 20 22 22 22 | 250 250 30 150 150 | 180 180 150 140 140 | 1.9 1.9 - 1.3 1.3 | 30 30 6 •25 •15 | 50 50 - 50 50 | 60 65 15 65 65 | .005 .005 0.01 0.1 .1 | 20 20 5 5 | 11111 | 11111 | 11111 | Low noise, low level unil SPR SPR |
| LL 30 | 2N864 2N523 2N523A 2N523A 2N2280 2N2281 | PH IND IND PH PH | pnp,SP,si pnp,AJ,ge pnp,AJ,ge pnp,SP,si pnp,SP,si | 22 24 24 •24 •24 •24 | 150 150 150 150 150 | 140 85 85 140 140 | 1.3 2.5 2.5 1.3 1.3 | *6 15 20 *10 *10 | 50 200 200 50 50 | 65 200 300 - - | .1 1 1 3 3 | 14 14 •7 •7 | - 0.1 - - | - 0.4 - | - - .05 .05 | SPR US, KF US, KF Chopper Pair 2 N2280 |
| | 2N747 2N748 2N338 2N643 2N645 | RA RA TI RCA RCA | npn,MS,si npn,MS,si npn,GD,si pnp,DR,ge pnp,Dr,ge | 25 25 30 30° •• 30 | 150 150 125 120 120 | 175 175 150 71 85 | 0.75 0.75 .001 - | 25 30 • 45 30 30 | 50 50 20 100 100 | 30 10 39 45 45 | 10 6 1 3 | 6 - 2 2 | - .06 0.03 0.01 | - .02 0.006 0.002 | 1.5 - | Submin TR, RA, NA, GE, AMP *gain-bandwidth, Gi *gain bandwidth, Gi |
| LL 31 | 2N907 2N1060 2N1276 KGS1004 2N2167 | RA WE TI KF SPR | npn,DB,si npn,D,ge npn,MS,si pnp,AJ,ge pnp,SP,se | 30 30 **30 32 *36 | 250 150 200 150 | 150 - 85 - | 2.0 - 3 1.3 | 45 40 40 10 •12 | 25 50 25 400 | 35 20 9-22 120 4–9 | .002 0.1 - 12 0.02 | 20 5 - *10 | 1, 1 1 1 1 | 11111 | - •200 - - | Submin |
| | 2N842 2N2 164 TMT842 TMT840 TMT839 | TR SPR TR TR TR | npn,GJ,si pnp,SP,si npn,DJ,si npn,MS npn,MS | 44 +44 44 45 45 | 300 150 150 150 150 | 175 - 175 175 175 | 1.3 - - - | *45 *12 *45 *45 *45 *45 | 25 - 25 - - | 20 6.0-40 20 40-90 20-45 | 0.1 0.02 .1 1 max 1 max | 6 *10 6 15 max 15 max | 11111 | 1111 | - 2 max 2 max | NA |
| LL 32 | 2N908 2N337 A 2N644 2N2349 2N2677 | RA GE- RCA GE GE | npn,DB,si npn,GD,si pnp,DR,ge npn,GD,si npn,GD,si | 45 **50 *50 **50 **50 | 500 120 150 250 | 175 71 200 | 3,33 - 1.66 | 45 *45 30 *40 *45 | 25 20 100 25 25 | 75 *55 45 *250 120 | .002 0.001 3 1.0 | 20 •2 - •4 •3 | | - .09 0,004 - .09 | - - 1.5 0.8 | Submin •gain bandwidth, Gl |
| | ST3030 TMT1131 TNT842 TNT843 2N865 | TR TR TR TR PH | npn,DJ,si pnp,MS npn,MESA,si npn,MESA,si pnp,SP,si | 50 50 *50 *50 52 | 100 150 100 100 150 | 150 200 175 175 140 | 0.8 - 0.66 0.66 1.3 | 15 *50 45 45 45 *10 | - 50 50 50 | *15-45 *20 *45 150 | 50 1 max 0.1 0.1 .1 | 4 45max *6 *6 | .04 - 0.04 0.04 - | .07 - 0.01 0.01 - | 40 1.5 max 0.05 0.05 — | SPR |
| LL 33 | 2N1254 2N1256 2N1258 2N1427 2N1779 | HU HU UH PH SY | pnp,MS,si pnp,MS,si pnp,MS,si pnp,MA,ge npn,A'J,ge | 55 55 55 60 60 | 250 250 250 250 25 100 | 160 160 160 85 100 | 1.8 1.8 1.8 - 1.3 | 30 40 30 •6 25 | - - 50 100 | 25 25 25 120 25 | 0.2 0.2 0.2 .5 10 | 8 8 8 •3.5 | 11111 | .015 - - - | .015 .1 | TO-5 package TO-5 package TO-5 package |
| 11.21 | 2N2244 2N2245 2N2246 2N2247 2N2248 | NA NA NA NA | npn,si npn,si npn,si npn,si npn,si | 60 60 60 60 | 500 500 500 500 500 | 200 200 200 200 200 200 | 2.85 2.85 2.85 2.85 2.85 2.85 | 200 20 20 45 45 | 100 100 100 100 100 | 40-120 80-250 150-450 40-120 80-250 | 0.01 0.01 0.01 0.01 0.01 | 8 8 8 8 | . 11111 | 1111 | - | |
| LL 34 | 2N2249 2N2250 2N2251 2N2252 2N2253 | NA NA NA NA | npn,si npn,si npn,si npn,si npn,si | 60 60 60 60 | 500 500 500 500 500 | 200 200 200 200 200 200 | 2.85 2.85 2.85 2.85 2.85 2.85 | 45 20 20 20 20 45 | 100 100 100 100 100 | 150-450 40-120 80-250 150-450 40-120 | 0.01 0.01 0.01 0.01 0.01 | 8 8 8 8 | 11111 | 11111 | | 4db NF 4db NF 4db NF 4db NF |
| 11.25 | 2N2254 2N2255 2N2693 2N2694 TMT1132 | NA NA TI TI TR | npn,si npn,si npn,PE,si npn,PE,si pnp,MS | 60 60 •60 •60 60 | 500 500 600 600 150 | 200 200 175 175 200 | 2.85 2.85 4.0 4.0 | 45 45 30 20 *50 | 100 100 30 30 - | 80-250 150-450 *60 *30 *30-90 | 0.01 0.01 .001 .001 1 max | 8 8 *3.4 *3.4 45 max | - 0.7 0.7 - | 0.6 1.0 | 0.1 0.1 1.5 max | 4db NF 4db NF For 100 ua Switching For 100 ua Switching |
| LL 35 | 2N843 TMT843 TMT841 2N560 2N645 | TR TR TR WE RCA | npn,DJ,si npn,DJ,si npn,MS npn,DD,si pnp,DR,ge | 64 64 65 70 70 | 300 150 150 500 120 | 175 175 175 150 85 | - - - 4.0 | *45 *45 *45 60 30 | 25 25 - 100 100 | 40 40 80-330 20 45 | .1 1 max 0.1 3 | 6 6 15max 8 2 | - 0.06 0.01 | - - 0.05 0.002 | - 2 max .5 | US, NA Gain band width, Gl |

HITACHI TRANSISTORS

SPECIFY "MESA" TYPE TRANSISTORS FOR HIGH FREQUENCY USE

2SA233, 2SA234, 2SA235

Hitachi PNP germanium diffused "Mesa" type transistors provide outstanding high frequency characteristics compared with conventional alloy junction or drift transistors.

Exclusive "Mesa" type transistors are indispensable for FM receivers used in tuner circuits and intermediate frequency amplifiers and also in TV receivers in intermediate

frequency amplifiers. They can be used effectively in short-wave converters, medium wave converters and all high frequency applications.

For superior performance, specify Hitachi "Mesa" type transistors . . . another engineering achievement from one of the world leaders in electronics.

Maximum Ratings (Ta=25°C)

| Ítems | Symbol | Unit | 2SA233 | 2SA234 | 2SA235 |
|-----------------------|--------|------|--------|--------------|--------|
| Collector Voltage | Vсво | V | -20 | - 20 | - 20 |
| Emitter Voltage | VEBO | ٧ | - 0.5 | - 0.5 | - 0.5 |
| Collector Current | Ic | mA | -10 | — 10 | - 10 |
| Emitter Current | IE | mA | 10 | 10 | 10 |
| Junction Temperature | Ti | °C | 85 | 85 | 85 |
| Collector Dissipation | Pc | mW | 80 | 80 | 80 |
| Ambient Temperature | TA | °C | 60 | 60 | 60 |

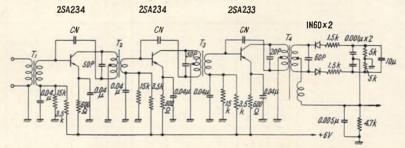
Characteristics (Ta=25°C)

| Items | Symbol | Conditions for measurement | Unit | 2SA233 | 2SA234 | 2SA235 |
|---------------------------------|--------|---|------|--------|--------|--------|
| Max. Collector Cut-off-Current | Ісво | V _C =-20V I _E =0 | μΑ | -30 | -30 | -30 |
| Max. Emitter Cut-off-Current | IEBO | V _E = -0.5V 1 _C = 0 | μΑ | -50 | - 50 | - 50 |
| Current Amplification Factor | hfe | $V_C = -6V$ $I_E = 1 mA$ | | 50 | 60 | 80 |
| Alpha Cut-off Frequency | fаь | VC=-6V IE=1mA | Мс | 90 | 110 | 125 |

Typical Operation (Ta=25°C)

| Items | Conditions for Measurement | Unit | 2SA233 | 2SA234 | 2SA235 |
|--------------------|------------------------------------|------|--------|--------|--------|
| Power Gain at | Vc=-6V | | | | |
| FM Radio Frequency | fs = 100Mc/s | db | _ | _ | 12 |
| | $R_g = 75\Omega$ $R_L = 2k\Omega$ | | | | |
| Mixer Gain at | Vc=-6V | | | | |
| FM Radio Frequency | fs = 100Mc/s fosc = 110.7Mc | db | _ | _ | 13 |
| | $R_g = 3k\Omega$ $R_L = 15k\Omega$ | | | | |

10.7 Mc Intermediate Frequency Amplifier Circuit



Hitachi New York, Ltd.
666, 5th Avenue, New York 19, N.Y., U.S.A.,
Sole Agent:
International Importer Inc.
2242 South Western Avenue, Chicago 8, Illinois, U.S.A.



| | | | | | | MAX | . RATING | S | | CHAR | ACTERIS | TICS | SV | ITCHING | ; | |
|-----------------------|---|-------------------------------|---|--------------------------------------|-----------------------------------|---------------------------------|-----------------------------------|----------------------------------|---------------------------------|---|-----------------------------------|---|--|---|--------------------------------------|---|
| Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P _c (mw) | т _і | mw/°C | **CEO **CBO (*) | 1 C (ma) | hfe *hFE | ¹ CO (μα) | C _{oe} *C _{ob} (pf) | t _r (μsec) *ton (nsec) | t _s (μsec) *t _{off} (nsec) | V _{ce(sat)} | Remarks |
| | 2N1411 2N2180 2N1255 OC46 2N1257 | PH PH HU AMP HU | pnp,MA,ge pnp,MA,ge pnp,MS,si pnp,PADT,ge pnp,MS,si | *70 *70 75 73 75 | 50 50 250 83 250 | 100 100 160 75 160 | 0.67 0.67 1.8 - 1.8 | 15 15 15 •20 30 | 50 50 - 125 | 100 100 30 80 40 | 1.0 1.0 0.2 3 0.2 | 3.0 3.0 8 - | 75 75 - - | 1111 | 80.0 - - - | TO-5 Package TO-5 Package |
| LL 36 | OC139 OC140 2N1259 OC47 2N706 | AMP AMP HU AMP FA | npn,PADT,ge npn,PADT,ge pnp,MS,si pnp,PADT,ge npn,DP,si | 73.5 74.5 75 75.5 *80 | 100 100 250 83 1w | 75 75 160 75 175 | - 1.8 - 6.7 | *20 *20 50 *20 20 | 250 250 - 125 | 45 75 50 ⊘200 45 | 0.8 0.8 0.2 <3 0.005 | - 8 - 5 | - - - 0.02 | 1111 | - % - - | TO-5 Package IND, TI, RCA, PH, CL, MO |
| | TMT696 2N702 2N2800 2N2801 TMT697 | TR TI MO MO TR | npn,MS npn,DJ,si pnp, PE,si pnp, PE,si npn,MS | 80 100 •100 •100 100 | 150 150 800 800 150 | 200 175 200 200 200 | - .002 4.57 4.57 | *60 20 *50 *50 60 | - 50 - - - | *20-60 15-45 *30/90 *75/225 *40-120 | 1max .5 0.01 0.1 1max | 35max - *25 *25 35max | 25 25 25 | - 100 100 | 1.5max .6 0.4 0.4 1.5max | FA, NA, GI |
| LL 37 | 2N1507 2N2188 2N2190 2N703 2N1139 | RA TI TI TI TR | npn,DD,si pnp,AD,ge pnp,AD,ge npn,MS,si npn,GR,si | 120 **125 **125 *150 150 | 1w 125 125 600 500 | 175 - - - 175 | 13.2 - - - - | 60 40 60 25 15 | 500 30 30 50 25 | 200 90 90 •40-•120 20 | .003 3 3 - .25 | 20 - - - 8 | 80 - - 12 | 600 - - - 10 | .07 - - 0.5 0.7 | JI |
| | 2N2189 2N2191 2N2330 2N2331 2N501 | TI TI MO MO PH | pnp, AD, ge pnp, AD, ge npn, DDP, si npn, DDP, si pnp, MD, ge | **150 **150 150 150 175 | 125 125 800 500 60 | - 175 175 100 | 5.33 3.33 0.8 | 40 60 *30 *30 *15 | 30 30 - - 50 | 135 135 50 50 | 3 3 0.1 0.1 1.0 | - 7 7 1.75 | - - - 0.013 | - - - 0.007 | - - - - 0.08 | SPR, GI |
| LL 38 | 2N501A 2N7 6 8 2N2411 2N 2086 2N2087 | PH PH TI PH PH | pnp,MD,ge pnp,MD,ge pnp,PE,si npn,MS,si npn,MS,si | 175 *175 200 *225 *225 | 175 35 1000 600 600 | 60 100 200 175 175 | 0.8 0.46 5.71 4.0 4.0 | *15 12 20 *120 *120 | 50 100 100 500 500 | - 40 •20-60 •70 •65 | 1.0 1 .001 2.0 2.0 | 1.1 1.6 *4 *7.4 *7.4 | 0.013 - .008 0.06 0.055 | 0.007 - .050 0.085 0.065 | 1.0 0.09 0.1 0.43 0.39 | SPR, GI |
| | 2N 240C 2N 1495 2N 1495 2N 1496 2N 2048 | PH PH PH PH PH | pnp,MD,ge pnp,MD,ge pnp,MD,ge pnp,MD,ge pnp,MD,ge | 225° *240 *240 *240 *240 250° | 150 250 250 500 150 | 100 100 100 100 100 | 2.0 3.3 3.3 6.67 2.0 | *12 *40 40 40 *20 | 100 500 500 500 100 | *60 *60 60 60 125 | 3 7 4 4 1.0 | *2.2 *4.0 4.0 4.0 *1.5 | 0.03 30 30 0.035 | 0.1 - - - - | 0.13 0.18 0.18 0.18 0.18 | MO MO |
| LL 39 | 2N2380 2N2380A 2N2478 2N559 2N705 | PH PH PH WE TI | npn,MS,si npn,MS,si npn,MS,si pnp,DG,ge pnp,AJ,ge | *270 *270 *275 300 300 | 600 600 2000 150 300 | 175 175 175 100 100 | 4.0 4.0 4 4.0 4 | *80 *80 *120 *15 *15 | 500 500 500 50 50 | 70 70 •70 25 6 | 4 4 2 3 .3 | *7.4 *7.4 *7.4 - 5 | 0.06 0.06 .055 0.002 0.03 | 0.06 0.06 .065 0.003 0.075 | 0.6 0.4 .45 .3 0.2 | MO,SY,GE,RA, AMP |
| | 2N708 2N710 2N711 2N711A 2N711B | PH TI TI TI | npn,PL,si pnp,MS,ge pnp,MS,ge pnp,MS,ge pnp,MS,ge | *300 300 300 *300 *300 | 1200 100 300 150 150 | 200 300 100 - | 2.1 4 - - - | *40 *15 *12 7 | 50 50 100 100 | *120 6 6 *25.*150 *30.*150 | .025 .3 0.3 1.5 1.5 | *6 5 5 *6 | - .06 .07 | .025 .075 0.1 - | .4 80 90 0.5 0.45 | SY,MO,RCA,GE,RA, AMP MO,SY,RCA,GE,RA, AMP MO MO |
| LL 40 | 2N784A 2N960 2N961 2N962 2N964 | PH TI TI TI | npn,PL,si pnp,EM,ge pnp,EM,ge pnp,EM,ge pnp,EM,ge | *300 *300 *300 *300 *300 | 1000 150 150 150 150 | 175 - - - - - | 6.85 - - - - | *40 15 12 12 15 | 200 150 150 150 150 | *150 *20 *20 *20 *20 *40 | .025 3 3 3 3 | *3.5 *4 *4 *4 *4 | 11111 | .015 - - - - | .19 0.5 0.5 0.5 0.5 | |
| | 2N965 2N966 2N985 2N1992 2N2401 | TI TI TI WE PH | pnp,EM,ge pnp,EM,ge pnp,EM,ge npn,D,si pnp,MD,ge | *300 *300 *300 300 *300 | 150 150 150 350 150 | - - 200 100 | - - 2.0 2.0 | 12 12 15 15 15 | 150 150 200 50 100 | *40 *40 *60 30 *90 | 3 3 3 0.5 1.5 | 4 *4 *6 5 *2.2 | - | - - 20ns 0.09 | 0.5 0.5 0.6 0.25 0.12 | |
| LL 41 | 2N2717 2N2381 2N2382 2N2256 2N2257 | AMP MO MO MO MO | pnp,AD,ge pnp,EM,ge pnp,EM,ge npn,ME,si npn,ME,si | 300 *300 *300 320 320 | 275 750 750 1000 1000 | 75 100 100 175 175 | 0.50 10 10 6.67 6.67 | *-15 *30 *45 *7 *7 | 300 500 500 100 100 | 50 •25 •25 •25 30 50 | - 1 1 3 3 | - *3.5 *3.5 4 4 | .020 8 8 3 3 | .040 20 20 4 4 | - 0.25 0.25 - - | |
| | 2N2258 2N2259 2N2402 2N707A 2N537 | MO MO PH MO WE | pnp,ME,ge pnp,ME,ge pnp,MD,ge npn,DM,si pnp,D,ge | 320 320 *325 350 400 | 300 300 150 1w 250 | 100 100 100 175 100 | 4 4 2.0 6.7 3.3 | *7 *7 *18 *70 *30 | 100 100 100 - 100 | 30 50 170 30 9 | 3 3 1.5 .01 0.1 | 4 4 *2.2 4 - | 4 4 - - | 3 3 0.075 - | - 0.11 - | Epitaxial Epitaxial Epitaxial, GI |
| LL 42 | 2N706A 2N706B 2N828 2N828 2N828A 2N829 | MO MO MO MO MO | npn,DM,si npn,DM,si pnp,DM,si pnp,DJEM,ge pnp,DJEM,ge | 400 400 400 •400 •400 | 1w 1w 500 300 300 | 175 175 175 100 100 | 6.7 6.7 4 4 | *25 *25 *15 *15 *15 | 200 200 200 200 | 4 4 4 •40 •80 | .005 .005 .4 3 | 4.5 4.5 3.5 *2.2 *2.2 | .018 .018 - - | .016 .016 - 30 30 | - - 0.11 0.11 | MO,SY,TI,NA,HU,GI,TI,PH,CL,DP MO,SY,PSI,TI,HU,NA,GI,CL,DP Epitaxial, SY, RA |

| | | | | | | MAX | . RATING | S | | CHAR | ACTERIS | TICS | S | WITCHING | ; | |
|-----------------------|--|-------------------------------|---|--------------------------------------|------------------------------------|------------------------------------|-------------------------------|---------------------------------------|---------------------------------------|--|-----------------------------------|------------------------------------|--------------------------------|-----------------------------------|-------------------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (mc) | P _c (mw) | т _і | mw/°C | VCE0 *VCB0 (v) | 1 C (ma) | hfe *hFE | lCO (μο) | Coe *Cob (pf) | tr (μsec) *ton (nsec) | t _s (μsec) *toff | V _{ce(sat)} | Remarks |
| LL 43 | 2N1195 2N1204 2N1204A 2N1494A 2N2096 | WE PH PH PH SPR | pnp,D,ge pnp,MD,ge pnp,MD,ge pnp,MD,ge pnp,ED,ge | 400 *400 *400 *400 *400 | 300 200 200 400 750 | 100 100 100 100 100 | 4.0 2.67 2.67 5.3 | *30 *20 *20 *20 *20 25 | 50 500 50 0 500 500 | 25 30 45 *45 *40 | 5 4 4 4 12 | 2.5 *5.0 *5.0 *5.0 *20 | 0.015 0.015 0.015 35 | - - - 70 | 03 0.3 0.3 0.6 | |
| LL 43 | 2N2097 2N2099 2N2100 2N2537 2N2538 | SPR SPR SPR MO MO | pnp,ED,ge pnp,ED,ge pnp,ED,ge npn, PE,si npn, PE,si | *400 *400 *400 *400 *400 | 750 750 750 800 800 | 100 100 100 200 200 | - - 4.57 4.57 | 40 25 40 *60 *60 | 500 500 500 - - | *50 *40 *50 *50/150 *100/300 | 12 12 12 0.25 0.25 | *20 *20 *20 *8 *8 | 20 35 20 *40 *40 | 50 70 50 *40 *40 | 0.5 0.6 0.5 0.25 0.45 | |
| | 2N2539 2N2540 NS345 2N744 2N779A | MO MO NA TI PH | npn, PE,si npn, PE,si npn, DM,si npn, PE,si pnp,MD,ge | *400 *400 400 450 450 | 500 500 500 1000 60 | 200 200 175 175 100 | 2.86 2.86 2.8 6.67 | *6 0 *60 30 12 *15 | 200 50 | *50/150 *100/300 80-200 *40-120 | 0.25 025 .002 1 | *8 5 *3.5 1.9 | *40 *40 .003 | *40 *40 - .009 | 0.45 0.45 - 0.2 | SPR |
| LL 44 | 2N779B 2N835 2N846A 2N834 2N2501 | PH MO PH MO MO | pnp,MD,ge npn,DDM,si pnp,MD,ge npn,DM,si pnp, PE,si | *450 450 450 500 *500 | 150 300 60 1w 360 | 100 175 100 175 200 | 2.0 2 .8 6.7 2.06 | 15 *25 *15 *40 *40 | 100 200 50 200 | 125 40 5 *50/150 | 0.5 0.5 1 .01 | 1.4 - 1.9 2.8 •4 | 13 - .015 | .016 | 0.09 0.3 - - 0.2 | Epitaxial SPR SY,PH,CL,DP, GI |
| | 2N2651 2N1094 2N559 2N2710 2N1385 | PH WE WE PH TI | npn,PL,si pnp,D,ge pnp,DG,ge npn,PL,si pnp,MS,ge | *600 600 750 *650 750 | 1200 150 150 1200 750 | 200 100 100 200 100 | 2.1 2.0 0.5 2.1 8 | *40 30 15 *40 25 | 500 40 50 500 100 | *50 25 25 *65 30 | .012 5.0 5 .012 5 | *2.85 2.5 - *2.85 1.3 | - 0.002 - .001 | .007 - 0.003 .015 | .2 - - .2 4 | US, MIL only TO-5, non saturated |
| LL 45 | 2N768 2N769 2N918 2N976 2N797 | PH PH FA PH TI | pnp,MD,ge pnp,MD,ge npn,DP,si pnp,MD,ge npn,MS,ge | *900 900 *900 *900 *1000 | 35 35 300 100 150 | 100 100 200 100 | 0.46 0.46 1.71 1.33 | *12 *12 15 *15 7 | 100 100 — 100 150 | *40 55 *50 *80 *40 | 1 0.3 0.0003 3 1.0 | *1.6 1.5 *1.0 *1.5 *4 | - 0.007 | 11111 | 0.09 0.13 0.3 0.12 0.44 | SPR MO |
| | 2N2205 2N2206 2N167A 2N240 2N269 | RCA RCA GE PH RCA | npn,AJ,ge pnp,SBT,ge pnp,AJ,ge | 1000 1000 - - - | - 65 25 120 | - 85 85 85 | 25 25 - 0.82 | 200 - 30 *6 *25 | *20 *40 75 15 100 | - 30 30 *50 | - 0.6 0.5 5 | - - *4 - | 0.035 - - - | 0.025 - - - | - - 0.15 | TO-18 SPR-MIL |
| LL 46 | 2N335B 2N336A 2N377A 2N388A 2N398 | GE GE SY SY RCA | npn,GJ,si npn,GJ,si npn,AJ,ge npn,AJ,ge pnp,AJ,ge | ****** | 500 500 150 150 50 | 175 175 100 100 55 | - 2 2 | 60 45 * 40 25 * 105 | 25 25 200 200 100 | 52 75 20-60 60-180 60 | 1 1 40 40 6 | - 11 - | | !.5usGC (max) | - ax) - | GI, TI GI GL KF, MO, TI |
| | 2N399A 2N438A 2N439A 2N440A 2N496 | GE SY SY SY PH | pnp,AJ,ge npn,AJ,ge npn,AJ,ge npn,AJ,ge pnp,SB,si | 11111 | 150 150 150 200 150 | 100 85 85 85 85 140 | 2.5 2.5 3.3 1.3 | 15 *25 *25 *25 10 | 200 200 200 200 200 50 | 70 15(min) 30(min) 40 5.0 | 2 10 10 10 10 | - - - 6 | 0.7 0.5 0.3 | 11111 | - - - - 0.08 | GI, TI GI, TI GI, TI |
| LL 47 | 2N556 2N557 2N558 2N586 2N587 | SY SY SY RCA SY | npn,AJ,ge npn,AJ,ge npn,AJ,ge pnp,AJ,ge npn,AJ,ge | 11111 | 100 100 100 250 150 | 85 85 85 85 85 | 1.66 1.66 1.66 - | 20 20 15 45 • 40 | 200 200 200 250 200 | - - - 55 20 | 25 25 15 8 10 | - - - 30 | 3.5 6.5 3.5 | 2 2.5 2 - | 0.5 0.5 0.75 0.25 | t≥=3.5 ns max TI |
| | 2N597 2N634A 2N635A 2N636A 2N705A | PH GE GE GE RA | pnp,AJ,ge npn,AJ,ge npn,AJ,ge npn,AJ,ge pnp,EM,ge | 11111 | 250 150 150 150 150 | 100 85 - 85 100 | 3.3 - 85 - - | 45 20 20 15 15 | 400 300 300 300 100 | - 55 100 190 *40 | 5 6 6 6 3.0 | 15 - - 8.0 | 111111 | - - - - 50 | 0.085 - - - 0.20 | TI TI |
| LL 48 | 2N706 2N707 2N708 2N709 2N710A | FA FA SY AI RA | npn,PL,si npn,DP,si npn,DP,si npn,P,si pnp,EM,ge | | 1200 1w 360 - 0.3w 150 | 175 175 200 - 100 | 6.7 6.7 2.0 | *25 28 *40 *15 | 50 - - - 50 | 20 12 15 •75 •34 | - .005 0.025 .001 3.0 | *5 5 6 *3.0 8.0 | .02 .02 - - | - 25 - 50 | 0.6 - 0.40 - 0.50 | GI,TR,SY,NA,IND,TI,RCA,CL,PH (Epitaxial, MO), GI, CL Epitaxial, CL |
| | 2N711A 2N725 2N781 2N782 2N784A | RA SY RA RA SY | pnp,EM,ge pnp,DM,ge pnp,EM,ge pnp,EM,ge npn,DP,si | 11111 | 150 - - 360 | 100 100 100 100 200 | - 2 - - 2.0 | 15 15 15 12 40 | 100 50 200 200 200 200 | *25-*150 20 *25 *20 25 | 1.5 3 3.0 30 0.025 | 6.0 | 0,1 - - 20 | 120 20 35 15 | 0.55 | GE Epitaxial |
| LL 49 | 2N794 2N795 2N835 | RCA RCA CL | pnp,DM,ge pnp,DM,ge npn,DP,si | - | 150 150 1.2w | 85 85 175 | 2.5 2.5 6.7 | 13 13 25 | 100 100 200 | 50 50 20 | 1 1 0.5 | 8 8 4 | - 0.02 | - 0.035 | - | |
| | 2N849/ T/431 2N850/ T/431 | TI TI | npn,EP,si npn,EP,si | - | 1000 1000 | - | - | 15 15 | 30 30 | *20-*60 *40-*120 | - | - | - | - | 0.6 0.6 | |

May 24, 1963 T73

| | | 200 | 100000000000000000000000000000000000000 | | | ,,,,, | BATHE | | | CULT | CTEALS | TICC | E LIEVA | UTCHING | | |
|-----------------------|---|-------------------------------|---|---|--|---|--|----------------------------------|-----------------------------------|---|--------------------------------------|--------------------------------|--|---------------------------------|----------------------------------|--|
| | 6.11 | - 11/4 | | | | MAX | . RATING | 2 | | CHARA | ACTERIS | LICS | SW | ITCHING | | |
| Cross Index Key | Type No. | Mfr. | Туре | fae *f _T **f _{ab} (mc) | P _c (mw) | т _і (°с) | mw/°C | VCEO *VCBO | C (mo) | hfe *hFE | (μ ₀) | Coe *Cob (pf) | t _r (μsec) *ton (nsec) | ts (µsec) *toff (nsec) | V _{ce(sat)} | Remarks |
| LL 50 | 2N914 2N917 2N1119 2N1122 2N1122A | SY AI PH PH PH | npn,DP,si npn,P,si pnp,SAT,si pnp,MA,ge pnp,MA,ge | 1111 | 360 0.3w 150 25 25 | 200 - 140 85 85 | 2.0 - 1.3 0.63 0.63 | *40 *30 10 12 15 | - 50 50 50 | 30 *35 5.0 8 | 0.025 .0001 .001 5.0 5.0 | 6 *1.7 6.0 6.0 6.0 | 40 - - - - | 20 - - - - | 0.7 - - 0.1 0.1 | Epitaxial, CL SPR SPR, GI SPR, GI |
| LL 30 | 2N1175 2N1175A 2N1213 2N1214 2N1215 | GE GE RCA RCA RCA | pnp,AJ,ge pnp,MESA,ge pnp,MESA,ge pnp,MESA,ge | 11111 | 200 200 75 75 75 | 85 85 85 85 85 | | 25 25 25 25 25 25 | 200 200 100 100 100 | 80 80 - - - | 6 6 3 3 3 3 | 11111 | - .015 .015 .015 | - .05 .05 | | MO, TI TI |
| LL 51 | 2N1216 2N1217 2N1252 2N1253 2N1277 | RCA GE AI AI GE | pnp,MESA,ge npn,AJ,ge npn,P,si npn,P,si npn,GJ,si | 1111 | 75 75 2w 2w 150 | 85 85 - - 150 | 1 - 1 - 1 | 25 20 •30 •30 •30 | 100 25 - - 25 | - 40 *35 *45 20 | 3 .6 .10 .10 | - *20 *20 - | .015 - - - - | .05 - - - - | 1111 | ті |
| EE 31 | 2N1278 2N1279 2N1288 2N1289 2N1289 | GE GE GE SY | npn,GJ,si npn,BG,ge npn,MB,ge npn,AJ,ge | 11111 | 150 150 75 75 150 | 150 150 85 85 100 | - - - 2 | *30 *30 10 15 40 | 25 25 50 100 200 | 33 80 50 50 35-110 | .001 .001 2 2 0.1 | 11111 | - - - Rise + I | - - - all time = | - - - 1.5 usGC | TI TI |
| 11.50 | 2N1300 2N1301 2N1384 2N1404 2N1411 | RCA RCA RCA TI PH | pnp,DM,ge pnp,DM,ge pnp,DR,ge pnp,AJ,ge pnp,MA,ge | 11111 | 150 150 240 150 25 | 85 85 85 85 85 | 2,5 2,5 4 2.5 | 13 13 30 25 *5 | 100 100 500 300 50 | 50 50 50 - *75 | 1 1 4 3 0.3 | 8 8 - 16 •3.0 | 11111 | 1111 | 11111 | TI TI MIL |
| LL 52 | 2N1413 2N1414 2N1450 2N1473 2N1499 | GE GE RCA SY PH | pnp,AJ,ge pnp,AJ,ge pnp,DR,ge npn,AJ,ge pnp,MD,ge | 11111 | 200 200 120 200 30 | 85 85 85 75 85 | - - 4 .75 | 25 25 30 40 *30 | 200 200 100 400 50 | 36 52 20 25-80 8.5 | 8 8 10 100 | - - - - •1.3 | 11111 | 11111 | 11111 | TI MO, TI GI MIL |
| | 2N1614 2N1683 2N1694 2N1708 2N1754 | GE RCA GE RCA PH | pnp,AJ,ge pnp,DM,ge npn,AJ,ge pnp,MD,ge | 11111 | 240 150 75 1000 50 | 85 85 85 - 85 | 2.5 - - .83 | 40 13 20 25 *13 | 300 100 25 200 100 | 32 75 30 •20 | 25 1 0.6 - 1 | 8 - - 1.5 | 11111 | 0.025 | 11111 | TI GI, SPR |
| LL 53 | 2N1808 2N1954 2N1955 2N1955 2N1957 | TI RA RA RA | npn,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 11111 | 150 375 375 375 375 375 | 85 100 100 100 100 | 2.5 0.2 0.2 0.2 0.2 0.2 | 25 60 60 60 60 | 300 1a 1a 1a 1a | 90 100 90 90 | 5 10 10 - 10 | 11 | 11111 | 11111 | 11111 | |
| | 2N2002 2N2003 2N2004 2N2005 2N2006 | NA NA NA NA | pnp,AJ,si pnp,AJ,si pnp,AJ,si pnp,AJ,si pnp,AJ,si | 11111 | 250 250 250 250 250 250 | 175 175 175 175 175 | 1.67 1.67 1.67 1.67 1.67 | 30 30 50 50 60 | 100 100 100 100 100 | 1111 | .001 .001 .003 .0015 | 8 8 8 8 | (*11) | 11111 | 11111 | |
| LL 54 | 2N2007 2N2175 2N2176 2N2282 2N2283 | NA SSD SSD BE BE | pnp,AJ,si pnp,AJ,si pnp,AJ,si pnp,DAP,ge pnp,DAP,ge | 11111 | 250 100 100 5 5 | 175 175 175 175 11 0 110 | 1.67 0.7 0.7 67 67 | 60 6 6 60 100 | 100 50 50 3a 3a | - *80 *80 60 | *0.2 *0.2 *0.2 50 50 | 8 10 10 75pf 75pf | - - 2.5 2.5 | - - 1.5 1.5 | - - 0.2 0.2 | |
| | 2N2284 2N2368 2N2369 2N2378 2N2713 | BE A1 A1 SPR GE | pnp,DAP,ge npn,P,si npn,P,si pnp,SP,si npn,PE,si | | 5 1.2w 1.2w 150 200 | 110 - - 140 100 | 67 - - 1.3 2.67 | 200 *40 *40 *10 *18 | 3a - - 50 200 | 60 *40 *75 5.0 *30-90 | 50 .01 .01 0.001 0.5 | 75pf *2.5 *2.5 6.0 | 2.5 - - - 85 | 1.5 - - - 85 | 0.2 - - - 0.30 | T0-18 |
| LL 55 | 2N2714 4D20 4D21 4D22 4D24 | GE GE GE GE GE | npn,PE,si npn,GD,si npn,GD,si npn,GD,si npn,GD,si | 11111 | 200 - | 100 150 150 150 150 125 | 2.67 1.5 1.5 1.5 1.5 | *18 *40 *40 *40 *40 | 200 25 25 25 25 25 | 75-225 •15-50 •40-135 •120-250 •15-50 | 0.5 1 1 1 1 | - *4 4 *4 *4 | 85 0.1 0.1 0.1 | 85 0.1 0.1 0.1 - | 0.30 1.5 1.5 1.5 1.5 | |
| | 4D25 4D26 10B551 10B553 10B555 | GE GE GE GE | npn,GD,si npn,GD,si npn,PE,si npn,PE,si npn,PE,si | | - 100 100 100 | 125 125 125 125 125 125 | 1.25 1.25 1.0 1.0 1.0 | *40 *40 *40 *40 *25 | 25 25 - - | *40-135 *120-250 *30-120 *30-120 *20 | 1 1 50 0.5 0.5 | *4 *6 *6 | - - 45 - - | - - 25 60 25 | - - 0.25 0.4 0.6 | |
| LL 56 | 108556 SST610 | GE SSE | npn,PE,si npn | 1.1 | 100 500 | 125 | 1.0 0,25 | *25 14v | 500 | *20-60 10,000 | 0.5 | *6 35pf | 1 1 | 25 | 0.6 1.5v | TO5 Package |



These P-channel diffused silicon transistors embody all the desirable characteristics inherent in the field effect design—low input capacitance and high impedance. Use of an S-shaped gate configuration contributes to the exceptionally low capacitance Tung-Sol's wide application experience with injection transistors and vacuum tubes—features of which are combined in the field effect transistor—is an important consideration for anyone seeking a competent source of this advanced semiconductor device Write for complete technical information. Tung-Sol Electric Inc., Newark 4, N. J. TWX: 201-621-7977

| | TYPIC | AL ELECTRI | CAL CHARACTERISTICS | (25°C) | | | |
|--------|---|-------------------------------------|---|-------------|------|-----------|------------|
| | TEST | SYMBOL | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| 2N2386 | Drain Current Forward Trans- admittance | I _{DSS} Y _{FS} | $V_{DS} = -10V, V_{GS} = 0$ $V_{DS} = -10V, V_{GS} = 0$ f = 1Kc | 1000 | 3.0 | 3000 | mA μmho |
| 2N2794 | Drain Current Forward Trans- admittance | I _{DSS} Y _{FS} | $V_{DS} = -10V, V_{GS} = 0$ $V_{DS} = -10V, V_{GS} = 0$ $f = 1Kc$ | 1.5 1000 | | 5 3000 | mA μmho |



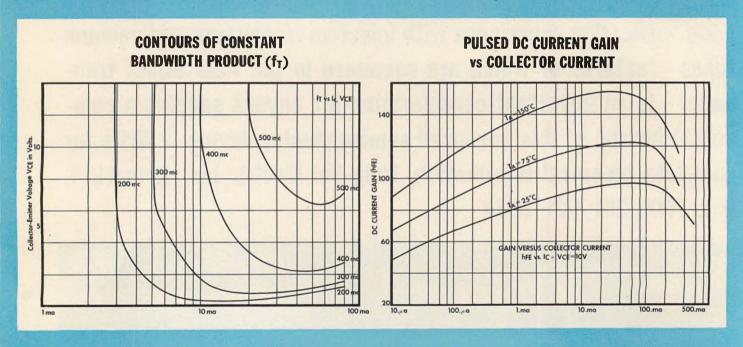
0.5 AMP INTERDIGITATED PASSIVATED SILICON PLANAR EPITAXIAL TRANSISTORS

2N2217 2N2218 2N2219

2N2220 2N2221 2N2222

(TO-5)

(TO-18)



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| | | | | , | | MA | X. RATI | NGS | | | CHARAC | TERISTI | CS | | SWITCH | ING | |
|-----------------------|---|------------------------------|---|--|--|--|--|--------------------------------------|----------------------------------|--|--------------------------------------|-----------------------|---------------------------------|---------------------------------|---|--------------------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | fae *fT **fab (kc) | P _c (w) | T _i (°C) | w/°C | VCEO *VCBO | l _C (a) | hfe *hFE | 1 _{C0} (ma) (*μa) | Powr, Gain (db) | Powr. Out (w) | t, (μsec) | t _s (μsec) | V _{ce} (sat) (μα) | Remarks |
| HL 1 | 2N1830 2N1831 2N1832 2N1833 2N2109 | WH WH WH WH | is, LA, nqn is, LA, nqn is, LA, nqn is, LA, nqn is, LA, nqn | 0.014 0.014 0.014 0.014 0.014 | 250 250 250 250 250 250 | 175 175 175 175 175 175 | 2.22 2.22 2.22 2.22 2.22 2.22 | *50 *100 *150 *200 *50 | 30 30 30 30 30 30 | *10 *10 *10 *10 *10 | 5 5 5 5 | | 8 8 8 8 | 3.0 3.0 3.0 3.0 1.3 | 0.87 0.87 0.87 0.87 0.4 | 0.4 | |
| | 2N2110 2N2111 2N2112 2N2113 2N2114 | WH WH WH WH | is,LA,nqn is,LA,nqn is,LA,nqn is,LA,nqn is,LA,nqn | 0.014 0.014 0.014 0.014 0.014 | 250 250 250 250 250 250 | 175 175 175 175 175 175 | 2.22 2.22 2.22 2.22 2.22 2.22 | *100 *150 *200 *250 *300 | 30 30 30 30 30 30 | *10 *10 *10 *10 *10 | 5 5 5 5 | 11111 | 4 4 4 4 | 1.3 1.3 1.3 1.3 | 0.4 0.4 0.4 0.4 0.4 | 0.4 0.4 0.4 0.4 0.4 | |
| HL 2 | 2N2130 2N2131 2N2132 2N2133 2N2116 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 0.014 0.014 0.014 0.014 0.0145 | 250 250 250 250 250 250 | 175 175 175 175 175 175 | 2.22 2.22 2.22 2.22 2.22 2.22 | *50 *1 00 *150 *200 *50 | 30 30 30 30 30 30 | *10 *10 *10 *10 *10 | 5 5 5 5 | 11111 | 8 8 8 8 5.6 | 3.0 3.0 3.0 3.0 1.4 | 0.87 0.87 0.87 0.87 087 0.63 | 1.4 | |
| | 2N2117 2N2118 2N2119 2N2123 2N2124 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 0.0145 0.0145 0.0145 0.016 0.016 | 250 250 250 250 250 250 | 175 175 175 175 175 175 | 2.22 2.22 2.22 2.22 2.22 2.22 | *100 *150 *200 *50 *100 | 30 30 30 30 30 30 | *10 *10 *10 *10 *10 | 5 5 5 5 | 11111 | 5.6 5.6 5.6 6.4 6.4 | 1.4 1.4 1.4 1.5 1.5 | 0.63 0.63 0.63 0.74 0.74 | 0.63 0.63 0.63 0.74 0.74 | |
| HL 3 | 2N2125 2N2126 2N1238 2N1239 2N1240 | ₩H ₩H HU HU | npn,AJ,si npn,AJ,si pnp,FJ,si pnp,FJ,si pnp,FJ,si | 0.016 0.016 0.8 0.8 1.0 | 250 250 1.0 1.0 | 175 175 200 200 200 | 2.22 2.22 - - - | *150 *200 15 15 35 | 30 30 0.5 0.5 0.5 | *10 *10 14 32 14 | 5 5 0.1 0.1 0.1 | 11111 | 6.4 6.4 - - | 1.5 1.5 | 0.74 0.74 - - | 0.74 0.74 - | |
| | 2N1241 2N1242 2N1243 2N1244 2N1073 | HU HU HU HU BE | pnp,FJ,si pnp,FJ,si pnp,FJ,si pnp,FJ,si pnp,DJ,ge | 1.0 1.0 1.0 1.2 1.5 | 1.0 1.0 1.0 1.0 35 | 200 200 200 200 200 100 | - - - 1.5 | 35 65 65 110 *40 | 0.5 0.5 0.5 0.5 10 | 24 14 24 14 *20-6 | 0.1 0.1 0.1 0.1 2.0 | | 11111 | 11111 | 111111 | - - - 1.0 | DE |
| HL 4 | 2N 1073 A 2N 1073 B B-1085 OC22 OC23 | BE BE BE AMP AMP | pnp,DJ,ge pnp,DJ,ge pnp,DJ,ge pnp,PADT,ge pnp,PADT,ge | 1.5 1.5 1.5 2.5 2.5 | 35 35 60 10 | 100 100 100 75 75 | 1.5 1.5 1.0 - | *80 *120 120 *32 *40 | 10 10 10 1 | *20-6 *20-6 5a 150 150 | 2.0 2.0 2.0 30 30 | 111111 | 11111 | 11111 | 11111 | 1.0 1.0 0.75 | DE DE |
| | OC24 2N1518 2N1519 2N1520 2N1521 | AMP DE DE DE DE | pnp,PADT,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 2.5 4 4 4 4 | 10 70 70 70 70 | 75 100 100 100 100 | 1.2 1.2 1.2 1.2 | *32 *50 *80 *50 *80 | 1 25 25 35 35 35 | 150 15-60 15-60 17-18 25-100 | 30 100 100 100 100 | 11111 | 40 40 40 40 | 20 20 20 20 20 | - 7 7 7 | 0.3 0.3 0.3 0.3 | \$0 \$0 |
| HL 5 | 2N1522 2N1523 2N297 2N297 A 2N618 | DE DE BE CL CL | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 4 4 5 5 5 | 70 70 35 12 14 | 100 100 90 95 90 | 1.2 1.2 1.5 2.0 1.5 | *50 *80 50 *60 *80 | 50 50 5 5 3 | 25-100 25-100 - - | 100 100 3 3 3 | 11111 | 40 40 - - | 20 20 - - | 7 7 - - | 0.3 0.3 1.02 1.0 0.8 | SO SO BE, DE, MO, SO MO, BE |
| | 2N375 2N378 2N379 2N380 2N458 | CL TS CL TS | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 7 7 7 7 | 50 5 50 50 | 95 100 85 100 95 | - 1.2 0.3 0.8 0.72 | *80 20 80 30 80 | 3 5 3 5 5 | 30 - - - | 3 0.5 5 0.5 1 | 11111 | 11111 | - - - 12 | 12.5 | 1.0 - 1 - 0.24 | MO,BE BE TS, BE BE, CL CL, BE |
| HL 6 | 2N459 2N1011 2N2230 2N2231 2N2232 | TS DE WH WH | pnp,AJ,ge pnp,AJ,ge si,LA,mn is,LA,nnn is,LA,nnn | 7 7 7 7 7 | 50 70 150 150 150 | 100 100 2.0 150 150 | 0.8 0.1 *50 2.0 2.0 | 60 *80 10 *100 *150 | 5 5 •400 10 | - 10 •400 •400 | 0.5 100 - 10 10 | 1111 | - 12 - - | 5 3.5 12 12 | 2 2.2 3.5 3.5 | 0.3 2.2 2.2 | BE, CL 2N1011 Sig. C., MO, BE, CL |
| ш. 2 | 2N2233 2N456 A 2N457 A 2N458 A 2N1038 | WH DE DE DE TI | npn,AJ,si pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 7 10 10 10 10 | 150 94 94 94 20 | 150 100 100 100 100 | 2.0 1.2 1.2 1.2 0.27 | *200 *40 *60 *80 40 | 10 7 0.065 7 3 | *400 - - - 33 | 1 0 0.065 0.065 0.065 50 | 1 | 14111 | 12 10 10 10 | 3.5 5 5 5 | 2.2 | TI, BE, CL TI, BE, CL TI, BE, CL BE, KF |
| HL 7 | 2N1039 2N1040 2N1358 2N1412 2N1970 | TI TI DE DE DE | pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge pnp,AJ,ge | 10 10 10 10 10 | 20 20 150 150 150 | 100 100 100 100 100 | 0.27 0.27 2 2 2 | 60 80 *80 *100 *100 | 3 15 15 15 | 33 33 - - | 50 50 0.1 100 0.1 | 11111 | - 40 40 - | - 15 15 10 | 5 5 5 | 0.3 0.3 | BE, KF BE, KF TS, TI, RCA, MO, SO, BE TS, RCA, MO, SO, BE SO, MO |

| | | N. S. | | fae | | MA | X. RATI | NGS | 49 | | CHARAC | TERISTIC | CS | | SWITCHI | NG | |
|-----------------------|--|----------------------------|--|--|--|--|--|--------------------------------------|--|--|----------------------------------|-----------------------|--------------------------|-----------------------------------|---------------------------------|--------------------------------------|----------------------------------|
| Cross Index Key | Type No. | Mfr. | Туре | *f T **f ab (kc) | P c (w) | T _i (°C) | w/°C | VCEO | I _С (а) | h _{fe} *hFE | l _{CO} (ma) (*μa) | Powr. Gain (db) | Powr. Out (w) | t, (μsec) | †ς (μsec) | V _{ce} (sat) (μα) | Remarks |
| | 2N2226 2N2227 2N2228 2N2564 2N2565 | WH WH WH KF KF | ia, LA, nqn npn, AJ, si npn, AJ, si ng, LA, qnq gg, LA, qnq gg, LA, qnq | 10 10 10 10 10 | 150 150 150 20 20 | 150 150 150 100 100 | 2.0 2.0 2.0 2.7 .27 | *50 *100 *150 *40 *60 | 10 10 10 3 3 | *100 *100 *100 *25 *25 | 10 10 10 *40 *40 | 11111 | 11111 | 8 8 | 3 3 - - | 2.2 2.2 2.2 2.5 .5 | |
| . HL 8 | 2N2566 2N2567 2N1809 2N1810 2N1811 | KF KF WH WH | eg, LA, qnq eg, LA, qnq iz, LA, nqn iz, LA, nqn iz, LA, nqn | 10 10 14 14 14 | 20 20 250 250 250 250 | 100 100 175 175 175 | .27 .27 2.22 2.22 2.22 2.22 | *80 *100 *50 *100 *150 | 3 3 30 30 30 | *25 *25 *10 *10 *10 | *40 *40 5 5 | 1111 | 11111 | - 4 4 4 | - 1.3 1.3 1.3 | .5 .5 0.4 0.4 | |
| 0 | 2N1812 2N1813 2N1814 2N2739 2N2740 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 14 14 14 14 14 | 250 250 250 200 200 | 175 175 175 175 175 | 2.22 2.22 2.22 2.0 2.0 | *200 *250 *300 *50 *100 | 30 30 30 20 20 | *10 *10 *10 *10 *10 | 5 5 5 15 15 | 11111 | 11111 | 4 4 4 9 9 | 1.3 1.3 1.3 2 | 0.4 0.4 0.4 0.4 0.4 | |
| HL 9 | 2N2741 2N2742 2N2757 2N2758 2N2759 | WH WH WH WH | n pn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 14 14 14 14 14 | 200 200 200 200 200 200 | 175 175 175 175 175 | 2.0 2.0 2.0 210 2.0 | *150 *200 *50 *100 *150 | 20 20 30 30 30 30 | *10 *10 *10 *10 *10 | 15 15 15 15 15 | | | 9 9 9 9 | 2 2 2 2 2 2 | 0.4 0.4 0.4 0.4 0.4 | |
| | 2N2760 2N2761 2N1816 2N1817 2N1818 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 14 14 14.5 14.5 14.5 | 200 200 250 250 250 250 | 175 175 175 175 175 | 2.0 2.0 2.22 2.22 2.22 2.22 | *200 *250 *50 *100 *150 | 30 30 30 30 30 30 | *10 *10 *10 *10 *10 | 15 15 5 5 5 | 11111 | 11111 | 9 9 5.6 5.6 5.6 | 2 2 1.4 1.4 1.4 | 0.4 0.4 0.63 0.63 0.63 | |
| HL 10 | 2N 18 19 2N 27 45 2N 27 46 2N 27 47 2N 27 48 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 14.5 14.5 14.5 14.5 14.5 | 250 200 200 200 200 200 | 175 175 175 175 175 175 | 2.22 20 2.0 2.0 2.0 2.0 | *200 *50 *100 *150 *200 | 30 20 20 20 20 20 | *10 *10 *10 *10 *10 | 5 15 15 15 15 | | 11111 | 5.6 12 12 12 12 12 | 1.4 1.3 1.3 1.3 1.3 | 0.63 0.63 0.63 0.63 0.63 | |
| | 2N2763 2N2764 2N2765 2N2766 2N1046 | WH WH WH WH T1 | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si pnp,AD,ge | 14.5 14.5 14.5 14.5 15 | 200 200 200 200 200 150 | 175 175 175 175 175 100 | 2.0 2.0 2.0 2.0 2.0 | *50 *100 *150 *200 100 | 30 30 30 30 30 | *10 *10 *10 *10 *10 | 15 15 15 15 15 | 11111 | 11111 | 12 12 12 12 12 | 1.3 1.3 1.3 1.3 | 0.63 0.63 0.63 0.63 1.0 | |
| HL 11 | 2N1046A 2N1046B 2N1823 2N1824 2N1825 | TI TI WH WH WH | pnp,AD,ge pnp,AD,ge npn,AJ,si npn,AJ,si npn,AJ,si | 15 15 16 16 16 | 150 150 250 250 250 | 100 100 175 175 175 | 2 2 2.22 2.22 2.22 2.22 | 130 130 •50 •100 •150 | 10 10 30 30 30 | 20 10 •10 •10 •10 | 10 10 5 5 5 | 11111 | 111111 | 6.4 6.4 6.4 | 1.5 1.5 1.5 1.5 | 0.74 0.74 0.74 | |
| W 12 | 2N 1826 2N 27 51 2N 27 52 2N 27 53 2N 27 54 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 16 16 16 16 16 | 250 200 200 200 200 200 | 175 175 175 175 175 175 | 2.22 2.0 2.0 2.0 2.0 2.6 | *200 *50 *100 *150 *200 | 30 20 20 20 20 20 | *10 *10 *10 *10 *10 *10 | 5 15 15 15 15 | 11111 | 11111 | 6.4 16 16 16 | 1.5 1.5 1.5 1.5 1.5 | 0.74 0.74 0.74 0.74 0.74 | |
| HL 12 | 2N2769 2N2770 2N2771 2N2772 2N1611 | WH WH WH DE | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si pnp,AJ,ge | 16 16 16 16 17 | 200 200 200 200 200 7.5 | 175 175 175 175 175 100 | 2.0 2.0 2.0 2.0 0.1 | *50 *100 *150 *200 *60 | 30 30 30 30 1.5 | *10 *10 *10 *10 *10 | 15 15 15 15 10 | 1111 | - - - - 0.4w | - 16 16 16 3 | - 1.5 1.5 1.5 1 | 0.74 0.74 0.74 0.74 0.3 | |
| HL 13 | 2N1612 2N1015 2N1015A 2N1015B 2N1015C | DE WH WH WH | pnp,AJ,ge npn,FJ,si npn,FJ,si npn,FJ,si npn,FJ,si | 17 25 25 25 25 25 | 7.5 150 150 150 150 | 100 150 150 150 150 | 0.1 1.4 1.4 1.4 1.4 | *60 *30 *60 *100 150 | 1.5 7.5 7.5 7.5 7.5 7.5 | 8 8 8 8 | 10 10 10 10 10 | 11111 | 0.4w - - - - | 3 5 5 5 5 | 1 1 1 1 1 | 0.3 1.5 1.5 1.5 1.5 | AMF |
| 112 13 | 2N1015D 2N1015E 2N1016 2N1016A 2N1016B | WH WH WH WH | npn,FJ,si npn,FJ,si npn,FJ,si npn,FJ,si npn,FJ,si | 25 25 25 25 25 25 | 150 150 150 150 150 | 150 150 150 150 150 | 1.4 1.4 1.4 1.4 1.4 | *200 *250 30 60 100 | 7.5 7.5 7.5 7.5 7.5 | 8 8 8 8 | 10 10 10 10 10 | - | | 5 5 5 5 | 1 1 1 1 | 1.5 - 2.5 25 2.5 | STC, AMF STC, AMF STC, AMF |
| HL 14 | 2N1016C 2N1016D 2N1016E 2N1971 151-04 | WH WH DE WH | npn,FJ,si npn,FJ,si npn,FJ,si pnp,AJ,ge npn,AJ,si | 25 25 25 25 25 25 25 | 150 150 150 50 100 | 150 150 150 100 150 | 1.4 1.4 1.4 0.7 1.4 | 150 *200 *250 *80 *80 | 7.5 7.5 7.5 4 6.0 | 8 8 8 - *11 | 10 10 10 0.02 10 | 11111 | 1111 | 5 5 5 8 | 1 1 - 2 2 | 2.5 2.5 - 0.6 | AMF |
| 17 | 151-05 151-06 151-07 151-08 151-09 | WH WH WH WH | npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si npn,AJ,si | 25 25 25 25 25 25 | 100 100 100 100 100 | 150 150 150 150 150 150 | 1.4 1.4 1.4 1.4 1.4 | *100 *120 *140 *160 *180 | 6.0 6.0 6.0 6.0 6.0 | *11 *11 *11 *11 *11 | 10 10 10 10 10 | 1 1 1 1 1 | - | 8 8 8 8 | 2 2 2 2 2 2 | 0.6 0.6 0.6 0.6 0.6 | |

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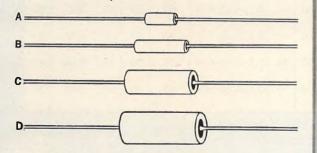
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Metals • Semiconductor Silicon • Silicon Monoxide • KEMET Barium
Getters and Solid Tantalum Capacitors
(Request Technical Data)

0.1 to 2.7 Microfarads

Temperature Range: 100v at 85°C. • 67v at 125°C.

KEMET was first to bring you high-voltage solid tantalums -50, 60, and 75 volts - three big contributions in $2\frac{1}{2}$ years!

Now KEMET pioneers with true quantity production of 100-volt units—in hermetically sealed A and B case sizes conforming to Style CS12 and Style CS13 in MIL-C-26655A.

These new 100-volt capacitors show the same resistance to shock and vibration, the same stability of electrical parameters with temperature change, and the same low levels of leakage current as the lower-voltage J-Series units. Also, the maximum dissipation factor has been reduced to 3%—the lowest ever—or one-half the usual J-Series m.d.f.

Today's total J-Series provides microfarad values from .0047 to 330; working voltages of 6, 10, 15, 20, 35, 50, 60, 75, and 100 volts—offering standard E.I.A. values with ± 5 , 10, and 20% tolerances.

KEMET is your assurance of maximum reliability, since KEMET controls the characteristics of tantalum powder from mine to finished product! For technical data on any member of the J-Series, write to:

"THE SPECIALIST IN SOLID TANTALUM CAPACITORS"

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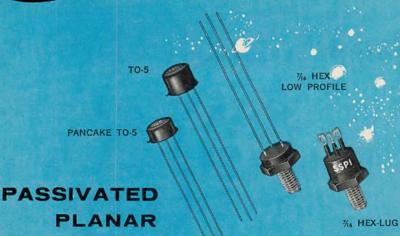
KEMET DEPARTMENT

LINDE COMPANY



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HIGH RELIABILITY

WIDE RANGE PERFORMANCE

CIRCUIT MINIATURIZATION

SILICON NPN POWER TRANSISTORS

A NEW GENERATION OF MINIATURE SILICON POWER TRANSISTORS FROM SSPI OFFERING SIGNIFICANTLY IMPROVED PERFORMANCE, "DESIGNED IN" RELIABILITY, AND REDUCED SIZE . . . AT COMPETITIVE PRICES.

| | | Power | Volta Ratin | _ | Operating | | | | | | Typical | | Switc | I Saturate hing Time oseconds | |
|--------|---------|--------------|----------------|-------|-----------|-------------|-------|-------|-----|--------------------------|---------|-------|-------|-------------------------------------|------|
| | 100 | Dissipation | | VCEO | Current | | Minii | mum h | 1FE | Maximum | fŧ | Ic= | 1A la | $=1_{B2}=100$ |)mA |
| Type | Package | (Case Temp.) | Vcso | (Sus) | Range | VcE(sat)@Ic | 50mA | 1A | 5A | Ісво@Vсв | Мс | Delay | Rise | Storage | Fall |
| 2N2849 | | 5W @ 125°C | 100 | 80 | Up to 5A | 0.4V @ 1A | 50 | 100 | _ | 0.1μA @ 80V | 80 | 20 | 40 | 350 | 50 |
| 2N2850 | | 5W @ 125°C | 100 | 80 | " | 0.25V @ 1A | 25 | 40 | - | 0.1 _μ A @ 80V | 60 | 20 | 50 | 200 | 50 |
| 2N2851 | 2 | 5W @ 125°C | 100 | 80 | " | 0.4V @ 1A | 25 | 40 | - | 0.1μA @ 80V | 60 | 20 | 50 | 200 | 50 |
| 2N2852 | 10.5 | 5W @ 125°C | 100 | 80 | " | 0.4V @ 1A | 15 | 20 | _ | 0.1μA @ 80V | 40 | 20 | 60 | 150 | 50 |
| 2N2853 | PANCAKE | 5W @ 125°C | 60 | 40 | " | 1.5V @ 5A | _ | 40 | 20 | 0.1μA @ 40V | 60 | 20 | 50 | 250 | 50 |
| 2N2854 | PAN | 5W @ 125°C | 60 | 40 | " | 0.4V @ 1A | 50 | 100 | _ | 0.1μA @ 40V | 80 | 20 | 40 | 350 | 50 |
| 2N2855 | | 5W @ 125°C | 60 | 40 | " | 0.4V @ 1A | 25 | 40 | _ | 0.1μΑ @ 40V | 60 | 20 | 50 | 200 | 50 |
| 2N2856 | | 5W @ 125°C | 60 | 40 | " | 0.4V @ 1A | 15 | 20 | _ | 0.1μA @ 40V | 40 | 20 | 60 | 150 | 50 |
| 2N2657 | TO-5 | 4W @ 100°C | 80 | 50 | " | 0.5V @ 1A | _ | 40 | 15 | 0.1μA @ 60V | 40 | 20 | 50 | 600 | 90 |
| 2N2658 | TO-5 | 4W @ 100°C | 100 | 70 | | 0.5V @ 1A | - | 40 | 15 | 0.1μΑ @ 60V | 40 | 20 | 50 | 600 | 90 |

All of the above types optionally available in any of the 4 packages shown.

In addition to the above Preferred Types, the following Types are also available from SSPI:

2N497, 2N498 • 2N545, 2N546, 2N547, 2N548, 2N549, 2N551 • 2N656, 2N657 • 2N1052, 2N1054, 2N1055 2N1116, 2N1117 • 2N1714, 2N1715, 2N1716, 2N1717, 2N1718 2N1719, 2N1720, 2N1721





| | | | | fae | | MA | X. RAT | INGS | | | CHARAC | TERISTI | CS | | SWITCH | ING | |
|-----------------------|--|---------------------------------|--|--|----------------------------------|--|--|--|---------------------------------|--|---------------------------------------|-----------------------|---------------------|-----------------------------|------------------------------------|---|--|
| Cross Index Key | Type No. | Mfr. | Туре | *fT **fab (kc) | P _c (w) | T _i (°C) | w/°C | VCEO *VCBO (v) | 1 _C (a) | h _{fe} | l CO (ma) (*μa) | Pawr. Gain (db) | Powr. Out (w) | † _r (μsec) | t _s (μsec) | V _{ce(sat)} (μα) | Remarks |
| HL 15 | 151-10 152-04 152-05 152-06 152-07 | WH WH WH WH | npn,AJ,si npn,AJ,si si,LA,m,n npn,AJ,si npn,AJ,si | 25 25 25 25 25 25 | 100 100 100 100 100 | 150 150 150 150 150 | 1.4 1.4 1.4 1.4 1.4 | *200 *80 *100 *120 *140 | 6.0 6.0 6.0 6.0 | *11 *18 *18 *18 *18 | 10 10 10 10 10 | 11111 | 1111111 | 8 8 8 8 | 2 2 2 2 2 2 | 0.6 0.9 0.9 0.9 0.9 | |
| 112 13 | 152-08 152-09 152-10 2N2310 2N2311 | WH WH WH RA RA | npn,AJ,si npn,AJ,si npn,AJ,si npn,DD,si npn,DD,si | 25 25 25 50 50 | 100 100 100 3 3 | 150 150 150 175 175 | 1.4 1.4 1.4 0.02 0.02 | *160 *180 *200 60 100 | 60 6.0 6.0 0.5 0.5 | *18 *18 *18 20 20 | 10 10 10 - | 111111 | 11111 | 8 8 - | 2 2 2 - | 0_9 0_9 0_9 - | Microbloc TO-46 Microbloc |
| HL 16 | 2N2312 2N2313 2N2314 2N2243 2N2243A | RA RA RA TI TI | npn,DD,si npn,DD,si npn,DD,si npn,PE,si npn,PE,si | 60 60 80 100 100 | 3 3 3 2800 2800 | 175 175 175 200 200 | 0.02 0.02 0.02 16.0 16.0 | 60 100 60 80 80 | 0.5 0.5 0.5 1 | 60 60 40 *40-120 | - 0.003 .001 .001 | 11,10 | 117111 | - - .040 .040 | - - .100 .100 | - 0.2 0.2 | Microbloc Microbloc Microbloc |
| HE 16 | RT697M RT699M RT1613M RT1420M 2N1015D | RA RA RA WH | npn,DD,si npn,DD,si npn,DD,si npn,DD,si npn,DD,si | 100 100 100 130 150 | 3 3 3 3 1.43 | 175 175 175 175 175 150 | 0.02 0.02 0.02 0.02 0.02 *200 | 60 120 75 60 7.5 | 0.5 0.5 0.5 0.5 *10 | 70 65 45 175 10ma | 0.003 0.01 0.001 0.003 25 | | 1444 | 11111 | 11111 | 11111 | Microblac Microblac Microblac Microblac |
| 111 17 | 2N1016A 2N1016B 2N1016C 2N1667 2N1668 | WH WH WH AMP | npn,AJ,si npn,AJ,si npn,AJ,si pnp,PADT,ge pnp,PADT,ge | 150 150 150 200 200 | 1.43 1.43 1.43 30 30 | 150 150 150 90 90 | *60 *100 *150 - | 7.5 7.5 7.5 - | *10 *10 *10 6 | 10ma 10ma 10ma 90 50 | 30 30 30 0.1 | 111111 | - | 1.1 | | | AMP AMP |
| HL 17 | 2N1669 OC28 OC29 OC35 OC36 | AMP AMP AMP AMP AMP | pnp,PADT,ge pnp,PADT,ge pnp,PADT,ge pnp,PADT,ge pnp,PADT,ge | 200 200 200 200 200 200 | 30 13 13 13 13 | 90 90 90 90 90 | | *80 *60 *60 *80 | 6 6 6 | 70 32 90 50 70 | 0,1 <100 <100 <100 <100 | 111111 | 111111 | 11111 | 11111 | 11111 | AMP |
| | 2N418 2N420 2N420A 2N637 2N637 A | BE BE BE BE | eg,LA,qnq eg,LA,qnq eg,LA,qnq eg,LA,qnq eg,LA,qnq | 400 400 400 400 400 | 60 60 60 60 | 100 100 100 100 100 | 1.2 1.2 1.2 1.2 1.2 | 100 65 90 60 90 | 4 4 15 6 | 60 60 60 45 45 | 1.0 1.0 1.0 1.0 | 11111 | 11111 | 15 - - | 11111 | 0.5 1.7 0.5 0.7 0.7 | CL CL CL CL |
| HL 18 | 2N637B 2N638 2N638A 2N638B 2N456 | BE BE BE TI | eg,LA,qnq eg,LA,qnq eg,LA,qnq eg,LA,qnq eg,LA,qnq | 400 400 400 400 430 | 60 60 60 60 50 | 100 100 100 100 100 | 1.2 1.2 1.2 1.2 1.2 0.67 | 100 60 90 100 40 | 6 6 6 5 | 45 30 30 30 30 30-90 | 1.0 1.0 1.0 1.0 | 11111 | . 1.1.1.1. | - - - 12 | - - - 12.5 | 0.7 0.7 0.7 0.7 0.7 0.24 | CL CL CL CL RCA, BE, CL |
| | 2N457 2N671 2N2350 2N2350A 2N2467 | TI PH GE GE KF | pnp,AJ,ge pnp,AJ,ge npn,PE,si npn,PE,si pnp,AJ,ge | 430 700 - - - | 50 1 5 5 5 | 100 85 200 200 110 | 0.67 0.017 28.5 28.5 .07 | 60 40 *60 *60 *60 | 5 2 1.0 1.0 .5 | 30-90 100 2.5 2.5 *45 | 0.6 20 10myza 10myza *40 | 11111 | 11111 | 12 | 12.5 | 0.24 0.35 0.25 | RCA, BE, CL Infinite heat sink |
| HL 19 | 2N2468 2N2469 2N2526 2N2527 2N2527 2N2528 2N2728 | KF KF MO MO MO | pnp,AJ,ge pnp,AJ,ge pnp,AD,ge pnp,AD,ge pnp,AD,ge pnp,AJ,ge | 1 11 11 1 | 5 5 85 85 85 170 | 110 110 110 110 110 110 | .07 .07 1 1 1 2 | *100 *200 *80 *120 *160 *15 | .5 5 10 10 10 50 | *45 *45 *20/50 *20/50 *20/50 | *40 *40 3 3 3 *30 | 1111111 | 111111 | - 5.5 5.5 5.5 7 | - 1,2 1.2 1,2 1,2 8 | .1 0.5 0.5 0.5 0.5 0.75 | |

| | | | | , | | MA | X. RAT | NGS | | | CHARAC | TERISTIC | cs | | SWITCHI | NG | |
|-----------------------|---|--------------------------------|--|--|----------------------------------|--|--|--|---------------------------|---|---|-----------------------------|---------------------|--------------------------------|-------------------------------|-------------------------------|--|
| Cross Index Key | Type No. | Mfr. | Туре | 'ae *f T **f ab (mc) | P _c (w) | T _i (°C) | w/°C | V _{CE0} *V _{C80} (v) | I _C (a) | h _{fe} *h | l CO (ma) (*μa) | Powr. Gain (db) | Powr. Out (w) | t _r (μsec) | t _s (μsec) | V _{ce(sat)} (μg) | Remarks |
| | STC1103 STC1104 2N673 2N424A 2N1620 | STC STC PH STC STC | npn,DJ,si npn,DJ,si pnp,AJ,ge npn,DM,si npn,DM,si | 1.0 1.0 *1.1 2 | 85 85 1.0 85 85 | 200 200 85 200 200 | 0.425 0.425 - 0.4 0.425 | 60 100 •40 60 100 | 6 2 3 5 | 25-75 25-75 *100 12-60 15-75 | 0.025 0.025 *20 10 | 11111 | 11/11 | 11.131.1 | 1111 | - 0.3 - | Infinite heat sink AMF AMF |
| HL 20 | 2N1701 2N1702 2N1768 2N1769 2N551 | STC STC STC STC TR | npn,DM,si npn,DM,si npn,DM,si npn,DM,si npn,DJ,si | 2 2 2 2 2 3 | 25 75 40 40 3 | 200 200 200 200 200 200 | 0.125 0.375 0.2 0.2 0.5 | 60 60 80 100 60 | 2.5 5 3 3 | 20-80 15-60 35-100 35-100 20-80 | 0.1 0.2 .015 .015 | 111111 | 11111 | - - - 1.2 | - - - 0.3 | - - - - 0.9 | AMF |
| | 2N552 2N1055 2N547 2N548 2N549 | TR TR TR TR TR | s, LO, nqn is, LO, nqn is, LO, nqn is, LO, nqn is, LO, nqn | 3 3 4 4 4 | 3 3 5 5 | 200 200 200 200 200 200 | 0.5 0.045 0.5 0.5 0.5 | 30 100 60 30 60 | 11111 | 20-80 20-80 20-80 20-80 20-80 | 1.2 0.001 1.2 0.5 0.5 | 11111 | 1111 | 1.2 - 0.7 0.7 0.7 | 0.3 - 0.2 0.2 0.2 | 0.9 - 3.0 2.0 1.5 | |
| HL 21 | 2N550 2N1117 2N1116 2N1173 ST402 | TR TR TR WE TR | npn,DJ,si npn,DJ,si npn,DJ,si npn,AJ,ge npn,DJ,si | 4 4 6 6 6 | 5 5 5 - 50 | 200 200 200 100 200 | 0.5 0.5 0.5 3.33 0.33 | 30 60 60 *35 *60 | - - 0.2 3 | 20-80 40 40 80 30 | 0.5 0.04 1.2 0.004 20 | 111111 | 11111 | 0.7 0.7 0.7 - 0.25 | 0.2 0.2 0.2 - 0.5 | 1.5 1.5 3.0 - 6 | |
| | ST403 2N1174 2N545 2N546 2N1052 | TR WE TR TR TR | npn,DJ,si pnp,AJ,ge npn,DJ,si npn,DJ,si npn,DJ,si | 6 7 8 8 8 | 50 - 5 5 5 | 200 100 200 200 200 200 | 0.33 3.33 0.5 0.5 0.5 | *45 *35 60 30 *60 | 3 0.2 - - | 30 85 15 15 | 20 0.005 1.2 0.5 0.001 | 11111 | 11111 | 0.25 - 0.3 0.3 | 0.5 0.15 0.15 | 5 - 3.0 2.0 - | |
| HL 22 | 2N1212 2N2229 2N1054 2N1208 2N1209 | TR WH TR TR TR | npn,DJ,si is,LA,nqn npn,DJ,si npn,DJ,si npn,DJ,si | 10 *10 12 12 12 | 85 150 5 85 85 | 200 150 200 200 200 | 0.27 2.0 .045 0.27 0.27 | *60 *200 *125 *60 *45 | 3000 10 - 5 5 | 12-60 *100 20-80 15 20 | 1000 10 .0004 1.0 2.0 | 11111 | 11.1.1 | 8 - 0.25 0.25 | 3 - | 3.5 2.2 - 3 3 | STC STC |
| | 2N1250 ST401 2N1907 2N1908 2N1072 | TR TR TI TI WE | npn,DJ,si npn,DJ,si pnp,AD,ge pnp,AD,ge npn,DD,si | 12 12 *20 *20 *20 30 | 85 85 150 150 12 | 200 200 - - 150 | 0.27 0.27 - - 65 | 60 **45 100 130 75 | 5 5 20 20 1 | 15 20 *10 *10 13 | 1.0 2.0 0.3 0.3 0.1 | 11111 | 11111 | 0.25 0.25 - - 0.05 | - - - 0.05 | 3 3 1.7 1.7 | STC US, MIL only |
| HL 23 | 2N1041 2N498 2N978 2N1893 2N1984 | TI FA FA FA | npn,AJ,ge npn,DP,si pnp,DD,si npn,DP,si npn,DM,si | 33 *50 *50 *50 *50 | 20 4.0 1.75 3 2 | 100 200 150 200 150 | 0.27 22.8 0.010 17.2 16.0 | 100 100 20 25 | 3 - - - | 33 *27 *40 - 40 | 50 *0.0004 *0.1 .0003 1.0 | E1-1-1 | 11111 | - (11111 | 111111 | 91111 | BE, KF GI, TI RA |
| | 2N1985 2N1986 2N1987 2N1988 2N1989 | FA FA FA FA | npn,DM,si npn,DM,si npn,DD,si npn,DM,si npn,DM,si | *50 *50 *50 *50 *50 *50 | 2 2.0 2.0 2 2 | 150 150 150 150 150 | 16.0 16.0 16.0 16.0 16.0 | 25 25 25 45 60 | 1111 | 4.0 100 50* 70 40 | 1.0 1.0 1.0 1.0 1.0 | 11-11 | | 11.11.11 | 1111 | 1, 1, 1, 1 | RA RA GI, RA |
| HL 24 | 2N1991 2N656 2N657 2N912 2N1975 | FA FA FA FA | pnp,DM, si pnp,DP,si npn,DP,si npn,DP,si npn,DP,si | *50 *60 *60 *60 *60 | 2.0 4.0 4.0 1.8 3 | 150 200 200 200 200 200 | 16.0 0.0228 0.0228 10.3 17.2 | *30 60 60 60 | - 100 - - | 40 *60 - 42 42 | .005* *0.004 *60 .0003µа .003µа | - - *0.0004 - - | | 1,111 | 1 | - - - - .24 | TR Microbloc |
| | 2N1978 2N2102 2N2270 RT5202 RT5230 | FA RCA RCA RA RA | npn,DP,si npn,PL,si npn,PL,si npn,DD,si npn,DD,si | *60 *60 *60 60 | 30 5 5 5 2 | 200 - - 175 175 | 0.17 - 0.033 0.013 | 40 120 60 175 30 | 10 10 0.5 0.5 | 40 *20 *35 50 50 | *0.001 - - 0.001 - | 11111 | | 111111 | 11111 | 1111 | |
| HL 25 | TA6200 2N526 2N1925 2N698 2N721 | FA SY GE FA FA | npn,DP,si pnp,AJ,ge pnp,AJ,ge npn,DP,si mp,DP,si | *60 64 64 *70 *70 | 4.0 225 225 3.0 1.5 | 200 100 85 200 175 | 0.0228 3 - 22.8 10.0 | - *45 40 *60 35 | 500 500 - - | *80 10 4 40 30 | - - .0003 *0.01 | | 3 - - | 0.08 | - | - | GE, TS, MO, TI MO, TI TR, NA, GI, TI |
| | 2N870 2N911 2N1131 2N1409 2N1410 | FA FA FA PSI PSI | npn,DP,si npn,DP,si pnp,DP,si npn,MS,si npn,MS,si | *70 *70 *70 70 70 | 1.8 1.8 2 2.8 2.8 | 200 2 00 175 150 150 | 10.3 10.3 13.3 0.024 0.024 | 60 60 *50 30 45 | - - 0.5 0.5 | 80 *70 *30 30 60 | 0.0003 *0.0003 *0.01 10 | - - 7 7 | - - 1 1 | - 0.08 0.06 0.042 | - - 0.1 0.17 | - - 0.8 0.8 | TI HU, TI, TR Power gain F=70mc RA RA, GI |
| HL 26 | 2N1889 2N1974 2N1987 2N696 2N717 | FA FA FA FA | npn,DP,si npn,DP,si npn,DM,si npn,DP, si npn,DP,si | *70 *70 *70 *80 *80 | 3 3 2 2 1.5 | 200 200 150 175 175 | 17.2 17.2 0.0016 13.3 10 | 60 60 40 *60 *60 | | *60 *70 50 *40 *40 | *0.0003 *0.0003 - 0.01 0.01 | | | - - 0.08 0.08 | - - 0.03 - | | TI GI, RA TR, SY, NA, TI, MH GI, PSI, NA, RA,MH, TI, TR |

| | | | | - | | M | AX. RATI | NGS | | | CHARACT | ERISTI | CS | | SWITCH | ING | |
|-----------------------|---|-----------------------------|---|--------------------------------------|---------------------------------|--|--|--|---------------------------------|--|--|------------------------|---------------------|------------------------------|---------------------------|------------------------------|---|
| Cross Index Key | Type No. | Mfr. | Туре | * T ** f ab (mc) | P _c (w) | T _i (°C) | w/°C | V _{CEO} *V _{CBO} (v) | I _C (a) | h _{fe} | 1 _{C0} (ma) (*μa) | Pawr Gain (db) | Powr. Out (w) | † _r (μsec) | † _s (μsec) | V _{ce(sat)} (μα) | Remarks |
| | 2N719 2N719A 2N722 2N1132 2N1252 | FA FA FA FA | npn,DP,si npn,DP,si pnp,DP,si pnp,DP,si npn,DP,si | *80 *80 *80 *80 *80 | 1.5 1.8 1.5 2 | 175 200 175 175 175 | 10 10.3 10 13.3 13.3 | *60 60 35 *50 | | *40 *40 *60 *60 *35 | 0.01 *0.0003 *0.01 0.01 *0.1 | 7 1 1 1 1 | | 0.08 - - - 0.08 | - - - 0.05 | 1111 | PSI, RA, GI, MH, TI, TR GI, TI TI HU, TI, TR TR, IND, PSI, TI, RA |
| HL 27 | 2N1613 RT482 RT483 RT484 RT698M | FA RA RA RA | npn,DP,si npn,DD,si npn,DD,si npn,DD,si npn,DD,si | *80 80 80 80 80 | 3 2 2 2 2 3 | 200 175 175 175 175 175 | 17.2 0.0134 0.0134 0.0134 0.02 | 50 20 40 40 120 | 0.5 0.5 0.5 0.5 | 80 50 40 70 40 | 0.0004 0.02 0.02 0.02 0.02 0.01 | 17 - - - - | - 1 1 1 1 | 0.08 | 11111 | 11111 | RA, GI, TI, PSI |
| | RT5151 RT5152 RT5203 RT5204 RT5212 | RA RA RA RA | npn,DD,si npn,DD,si npn,DD,si npn,DD,si npn,DD,si | 80 80 80 80 80 | 2 2 2 2 2 2 | 175 175 175 175 175 175 | 0.013 0.013 0.013 0.013 0.013 | 45 45 40 30 60 | 0.5 0.5 0.5 0.5 0.5 | 60 60 - 70 70 | 11111 | 11111 | 1-1-1-1-1 | 11111 | 111111 | 11111 | |
| HL 28 | 2N699 2N718 2N718A 2N720 2N720A | FA FA FA FA | npn,DP,si npn,DP,si npn,DP,si npn,DP,si npn,DP,si | *100 *100 *100 *100 *100 | 2 1.5 1.8 1.5 1.8 | 175 175 200 175 200 | 13.3 10 - 0.01 10 0.01 | 80 40 50 80 100 | 1111 | 65 75 80 65 80 | 0.01 0.01 *0.0004 0.01 *0.0004 | 1 1 1 1 1 | 311311 | 0.08 0.08 - 0.08 | 111111 | 11111 | NA, TR, PSI, RA, US NA, GI, PSI, RA, TI, TR TI, RA PSI, RA, NA, GI, TI, TR GI, RA |
| | 2N730 2N731 2N871 2N909 2N910 | TI TI FA FA FA | npn,MS,si npn,MS,si npn,DP,si npn,DM,si npn,DM,si | 100 100 *100 *100 *100 | 1.5 1.5 1.8 1.5 1.8 | 175 175 200 175 200 | 0.01 0.01 0.01 0.01 0.01 | 60 60 80 30 80 | 11111 | 30 60 130 150 100 | 0.01 0.01 0.0004 *0.01 0.005 | 11111 | 11111 | 0.11 0.11 - - | 0.14 0.14 - - | 0.9 0.9 - - | FA FA TI TR RA |
| HL 29 | 2N1060 2N1253 2N1420 2N1444 2N1711 | WE FA FA WE FA | npn,MS,si npn,DP,si npn,DP,si npn,DM,si npn,DP,si | 100 *100 100 100 *100 | - 2 2w - 3 | 150 175 175 150 200 | 2 13.3 13.3 4 0.017 | 40 20 30 60 50 | 0.05 - 0.25 | 40 45 130 25 130 | *0.001 0.01 0.1 *0.002 *0.0004 | 111111 | 20 | - 80.0 - | 0,05 - - | 11 11 | TR, IND, PSi, RA, NA, GI, TI GI, TI, RA |
| | 2N 1890 2N 1972 2N 1973 2N 1983 2N 2315 | FA FA FA RA | npn, DP, si npn, DM, si npn, DP, si npn, DM, si npn, DD, si | *100 *100 *100 *100 *100 | 3 2 3 2 3 | 200 175 200 150 175 | 0.017 0.013 0.017 0.0016 0.02 | 80 30 80 35 60 | - - - 0.5 | 130 150 100 140 70 | *0.000 *0.01 *0.005 - 0.003 | 11111 | 11111 | 11110 | 11111 | 11111 | TI, RA RA Microbloc, RA |
| HL 30 | 2N2316 2N2317 2N869 2N915 2N916 | RA RA FA FA | npn,DD,si npn,DD,si pnp,DP,si npn,DP,si npn,DP,si | 100 100 *150 *400 *400 | 3 3 1.2 1.2 1.2 | 175 175 200 200 200 | 0.02 0.02 0.007 0.007 6.9 | 120 75 25 60 25 | 0.5 0.5 - - - | 65 45 45 70 80* | 0.01 0.001 *0.0008 0.0003 0.002* | 11111 | 11111 | 111111 | 111111 | 11111 | Microbloc, RA Microbloc, RA CL, Epitaxial, RA |
| | 2N947 2N2217 2N2218 2N2219 2N2220 | FA MO MO MO MO | npn,DP,si npn,DDPL,si n pn,DDPL,si npn,DDPL,si n pn,DDPL,si | *400 400 400 400 400 | 1.2 3 3 3 1.8 | 200 175 175 175 175 175 | 0.0069 5.33 5.33mw 5.33mw 3.33mw | *60 *60 *60 *60 | 11111 | *50 20-60 40-120 100 20-60 | *0.005 0.01 0.01 0.01 0.01 | 11111 | 11111 | 11111 | 11111 | 11111 | Epitaxial Epitaxial Epitaxial Epitaxial |
| HL 31 | 2N2221 2N2222 2N2787 2N2788 2N2789 | MO MO GI GI GI | npn,DDPL,si npn,DDPL,si npn,PE,si npn,PE,si npn,PE,si | 400 400 *400 *400 *400 | 1.8 1.8 3 3 | 175 175 175 175 175 | 3.33mw 3.33mw 5.33 5.33 5.33 | *60 *60 35 35 35 | 11111 | 40-120 100-300 *20-60 *40-120 *100-300 | 0.01 0.01 2na 2na 2na 2na | 111111 | 111111 | 20ns 20ns 20ns 20ns | - 40ns 40ns 40ns | - .2 .2 .2 | Epitaxial Epitaxial |
| HL 32 | 2N2790 2N2791 2N2792 2N708 2N914 | GI GI GI FA FA | npn,PE,si npn,PE,si npn,PE,si npn,DP,si npn,DP,si | *400 *400 *400 *450 *450 | 1.8 1.8 1.8 1.2 1.2 | 175 175 175 200 200 | 3.33 3.33 3.33 6.9 0.007 | 35 35 35 15 20 | 11111 | *20-60 *40-120 *100-300 *50 | 2na 2na 2na *0.004 0.0004 | 11111 | 11111 | 20ns 20ns 20ns - | 40ns 40ns 40ns - | .2 .2 .2 - | GI, CL, MO CL, Epitaxial, MO |
| 111. 32 | 2N2368 2N2369 2N1645 2N709 2N917 | FA FA WE FA FA | npn,DP,si npn,DP,si pnp,D,ge npn,DP,si npn,DP,si | *650 *650 700 *800 *800 | 1.2 1.2 6.0 1.0 0.3 | 200 200 100 200 200 | 0.0069 0.0069 80.0 0.005 0.00171 | 15 15 35 6.0 15 | 0.3 | *40 *70 20 *55 *50 | *0.1 *0.1 0.015 *.005 *0.0003 | 11,11 | 11,11 | 11,11 | 11,11 | 11,11 | |
| HL 33 | 2N918 2N268A 2N497A 2N498A 2N656A | F.A CL GE GE GE | npn,DP,si pnp,AJ,ge npn,MS,si npn,DM,si npn,DM,si | *900 - - - - | 0.3 14 1 1 | 200 90 200 200 200 200 | 0.00171 1.5 - - - | 15 80 60 100 60 | 3 | *50 - 12 12 30 | *0.0003 2 10 10 | 1111 | 11111 | 11111 | 111111 | 11111 | MO BE, 20639A TI NA, TI NA, TI |
| IIL 33 | 2N657A 2N720A 2N1751 2N1813 2N1814 | GE TI BE WH WH | npn,DM,si npn,PL,si pnp,DAP,ge npn,FJ,si npn,FJ,si | 11111 | 1 1.8 - 250 250 | 200 - 110 175 175 | - 1250 2.22 2.22 | 100 120 80 *250 *300 | 25 30 30 | 30 *40.*120 50 10 | 10 5 15 15 | - 7 - | - 4 - | - 0.5 - | 11111 | 5.0 - 1.5 1.5 | NA, TI |

May 24, 1963 T83

| | | | | , | | MA | XX. RATI | NGS | | | CHARAC | TERISTI | CS | | SWITCHI | NG | |
|-----------------------|--|-------------------------------|---|-----------------|----------------------------------|---------------------------------|--|-----------------------------------|---------------------------------|---|---|-------------------------|------------------------|---------------------------------|--------------------------|---------------------------------|---------------------------------|
| Cross Index Key | Type No. | Mfr. | Type | *f T **fab (mc) | P (*) | T _i (°C) | w/°C | VCEO *VCBO (v) | ار (ه) | h _{fe} *hFE | 1 CO (ma) (*μα) | Powr Gain (db) | Powr. Out (w) | † _r (μsec) | t _s (µsec) | V _{ce(sat)} (μα) | Remarks |
| | 2N1837 2N1837 A 2N1841 2N1990 2N2243 | GE GE WE FA GE | npn,P,si npn,P,si npn,D,si npn,DM,si npn, PE,si | 1111 | 2 2.8 100 2 2.8 | 175 175 150 150 200 | 13.3 18.6 100 0.0016 16.0 | *80 *80 60 - 80 | 2.0 | *120 *120 25 40 2.5 | - 0.0001 - | | | | | 0.8 0.3 - - 0.35 | GI, RA |
| HL 34 | 2N2243A 2N2285 2N2286 2N2287 2N2288 | GE BE BE BE BE | npn,PE,si pnp,DAP,ge pnp,DAP,ge pnp,DAP,ge pn pDAP,ge | 11111 | 2.8 | 200 110 110 110 110 | 16.0 1250 1250 1250 1250 | 80 60 100 120 40 | 25 25 25 25 10 | 2.5 50 50 50 50 | 5 5 5 5 | - 7 7 7 | - 4 4 4 4 | - 0.4 0.4 0.4 0.5 | | 0.16 - - - - | |
| | 2N2289 2N2290 2N2291 2N2292 2N2293 | BE BE BE BE | pnp,DAP,ge pnp,DAP,ge pnp,DAP,ge pnp,DAP,ge pnp,DAP,ge | 11111 | | 110 110 110 110 110 | 1250 1250 1250 1250 1250 1250 | 80 120 40 80 120 | 10 10 10 10 10 | 50 50 75 75 75 | 5 5 5 5 | 7 7 7 7 7 | 4 4 4 4 4 | 0.5 0.5 0.5 0.5 0.5 | 1111 | 11111 | |
| HL 35 | 2N2294 2N2295 2N2296 2N2357 2N2358 | BE BE BE BE BE | pnp,DAP,ge pnp,DAP,ge pnp,DAP,ge pnp,DAP,ge pnp,DAP,ge | 11111 | 11111 | 110 110 110 110 110 | 1250 1250 1250 2000 2000 | 4 0 80 120 17 0 17 0 | 10 10 10 50 50 | 75 75 75 50 50 | 5 5 5 5 | 7 7 7 7 | 4 4 4 4 | 0.5 0.5 0.5 0.5 0.5 | 11111 | 11111 | |
| | 2N2359 2N2389 2N2390 2N2393 2N2394 | BE TI TI TI | pnp,DAP,ge npn,PL,si npn,PL,si pnp,PL,si pn pPL,si | 11111 | 2.0 2.0 1.2 2.0 | 110 - - - - | 2000 - - - | 170 35 35 35 35 35 | 50 0.6 0.6 0.3 0.3 | 50 *;0.*120 *100.*300 *20.*45 *30.*90 | 5 | 7 - - - - | 4 | 0.5 | | 1.5 1.5 1.5 1.5 | |
| HL 36 | 2N2395 2N2396 2N2397 2N2410 2N2455 | TI TI SY TI SY | npn, PL,si n pn, PL,si npn, EP,si npn, PE,si pnp, EP,ge | 111111 | 2.0 2.0 300 2.5 150 | 200 - 100 | - 1.7 - 2.0 | 40 40 35 30 15 | 0.3 0.3 200 0.8 200 | *20.*60 *40.*120 25 *30.*120 40 | - 0.10 - 2.0 | - 2.5 - 3.5 | 25 - 30 | 20 - 60 | - 0.3 - 0.19 | 1.0 1.0 - 0.45 - | TO-51 co-planar |
| | 2N2456 PADT50 RT5401 RT5402 RT5403 | SY AMP RA RA RA | pnp,EP,ge pnp,PADT,ge npn,si npn,si npn,si | 11111 | 150 16.5 0.7 0.7 0.7 | 100 75 200 200 200 | 2.0 - - - - | 15 75 30 30 60 | 200 0.75 - - - | 40 - 6.0 6.0 5.5 | 2.0 - 0.1 0.1 0.1 | 3.0 - - - - | 15 - - - - | 65 - - - - | 0.19 - - - - | 2.5 2.0 3.0 | ft = 1000 mc |
| HL 37 | RT5404 ST8014 TN51 TN52 TN61 | RA TR SSP SSP SSP | npn,si pnp,DM,si npn,PE,si npn,PE,si npn,PE,si | 111111 | 0.7 0.6 5 5 | 200 175 200 200 200 | - - - 0.004 | 60 20 60 60 60 | - 5 5 5 | 5.5 85 45 80 45 | 0.1 0.001 0.00002 0.00002 0.00002 | | - | - 0.08 - - | 0.3 0.3 0.3 | 2.0 1.5 0.5 0.5 0.5 | 7/16 Hex 7/16 Hex Pancake |
| HL 38 | TN62 TN71 TN72 | SSP SSP SSP | npn,PE,si npn,PE,si npn,PE,si | 1111 | 5 5 5 | 200 200 200 | 0.004 0.005 0.005 | 60 60 60 | 5 5 5 | 80 45 80 | 0.00002 0.00002 0.00002 | - | | | 0.3 0.3 0.3 | 0.5 0.5 0.5 | Pancake T0-5 T0-5 |

T84

FIELD EFFECT

In order of transconductance.

| | | | | | | | С | BV DGO | |
|-----------------------|--|--------------------------------|--|--|----------------------------------|---|-----------------------------|------------------------------------|-----------------|
| Cross Index Key | Type No. | Mfr. | Channel & Construction | g m (µmhos) | V p (v) | DSS (ma) | or *C DG | *BV _{DGS} | NF (db) |
| FE 1 | 18A1 C620 C622 C624 2N2841 | GE CT CT CT SI | p,GD,si n,A,si n,A,si n,A,si p,DP,si | 30 min 75 75 75 75 90 | 1 10 10 10 0.8 | 0.05 0.1 0.1 0.1 -50 | 5 35 35 35 4 | -10 10 10 10 •20 | - - 1.5 |
| | 18 A2 C621 C623 C625 2N2606 | GE CT CT CT SI | p,GD,si n,A,si n,A,si n,A,si p,DP,si | 100 min 100 100 100 100 175 | 1 10 10 10 2 | 0.25 0.35 0.35 0.35 -0.17 | 5 35 35 35 4 | -10 10 10 10 10 •30 | - - 1.5 |
| FE 2 | C632 C633 C631 U-110 C610 | CT CT SI CT | n,A,si n,A,si n,A,si p,DP,si n,A,si | 175 175 200 200 250 | 250 350 150 3 40 | 1.0 1.0 1.0 -0.31 0.6 | 23 23 23 4 35 | 250 350 150 •20 40 | 111 |
| 122 | C614 2N2842 C611 18A3 XF600 | CT SI CT GE SIG | n,A,si p,DP,si n,A,si p,GD,si pn,DP,si | 250 270 400 500 min 500 | 40 0.8 40 1 2-3 | 0.6 -150 3.0 0.75 0.5 | 35 7 35 5 | 40 *20 40 -10 30 | 1.5 |
| FE 3 | 2N2607 FE200 C612 C615 2N2843 | SI AI CT CT SI | p,DP,si n,DP,si n,A,si n,A,si p,DP,si | 525 600 650 750 800 | 2 10 40 40 0.8 | - 052 1.0 3.0 1.5 -450 | 7 •1.5 35 35 12 | *30 50 40 40 *20 | 1.5 - 1.5 |
| 123 | 2N2386 2N2497 2N2500 2N2794 18A4 | TI, TS TI TI TS GE | p,DP,si p,DP,si p,DP,si p,DP,si p,GD,si | 1000 min 1000 min 1000 min 1000 min 1000 min | 8 5 6 - 2 | -3 max -6 max 0.01 2.0 | 50 32 32 6 5 | 20 20 20 20 20 -10 | - |
| FE 4 | C613 FG34 FG35 FG36 FG37 | CT AI AI AI | n,A,si n,DP,si n,DP,si n,DP,si n,DP,si | 1000 1000 1000 1000 1000 | 40 20 20 20 20 20 | 3.0 10 | 35 | 40 50 100 150 200 | - |
| 124 | XF601 FE300 2N2498 18A5 2N2608 | SIG AI TI GE SI | pn,DP,si n,DP,si p,DP,si p,GD,si p,DP,si | 1000 1250 1500 min 1500 min 1600 | 2-3 1 0 6 2 2 | 1.0 3.0 -6 max 5.0 -1.60 | - *1.5 32 5 12 | 30 50 20 -10 •30 | 1.5 |
| FE 5 | U-112 2N2844 18A6 C640 2N2499 | SI SI GE CT | p,DP,si p,DP,si p,GD,si n,A,si p,DP,si | 1900 2000 2000 min 2000 2500 min | 3 0.8 2 35 8 | -3.0 -1000 12.0 4. 0 -15 max | 12 25 5 35 32 | *20 *20 -10 35 20 | 1.5 |
| 163 | MM763 MM764 MM765 2N2609 C641 | MO MO MO SI CT | n,P,si n,P,si n,P,si p,DP,si n,A,si | 3000 3200 3500 3600 4000 | 2 3 6.5 2 35 | 2 4 10 -3.60 8.0 | 50 50 50 25 35 | 25 25 25 *30 35 | 1.5 |
| FE 6 | C642 C643 C644 C650 C651 | CT CT CT CT | n,A,si n,A,si n,A,si n,A,si n,A,si | 6000 9000 12000 — | 35 35 35 45 35 | 12.0 18.0 24.0 | 35 35 35 - | 35 35 35 45 35 | |
| LEO | C652 C653 | CT CT | n,A,si n,A,si | - | 25 15 | = | - | 25 15 | - |





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atlee corporation

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ON READER-SERVICE CARD CIRCLE 472

UNIJUNCTION

Listed by type number.

| Cross Index Key | Type No. | Mfr. | Type | R BBO (K) | η (max) | ί ΕΟ (μα) | p (μα) | V E (sat) | V _{EB2} | V 0B1 (v) | Remarks |
|-----------------------|---|----------------------------|--|---|-------------------------------------|----------------------------------|---------------------------|-------------------------------|----------------------------|------------------|----------------------------|
| UNJ 1 | 2N489 2N489A 2N489B 2N490 2N490A | GE GE GE GE | n,si n,si n,si n,si n,si | 6.8 6.8 6.8 9.1 9.1 | .62 .62 .62 .62 .62 | 12 12 0.20 120 120 | 20 15 6 20 15 | 5 4 4 5 4 | 60 60 60 60 | 3 3 3 3 | T! T! T! T! T! |
| ORS 1 | 2N490B 2N490C 2N491 2N491A 2N491B | GE GE GE GE | n,si n,si n,si n,si n,si | 9.1 9.1 6.8 6.8 6.8 | .62 .62 .68 .68 | 0.20 0.02 12 12 0.20 | 6 2 20 15 6 | 4 4 5 4.3 4.3 | 60 60 60 60 | 3 3 3 3 | TI TI TI |
| UNJ 2 | 2N 492 2N 492A 2N 492B 2N 492C 2N 493 | GE GE GE GE | n,si n,si n,si n,si n,si | 9.1 9.1 9.1 9.1 6.8 | .68 .68 .68 .68 | 12 12 .20 0.02 12 | 20 15 6 2 20 | 5 4.3 4.3 4.3 5 | 60 60 60 60 | 3 3 3 3 3 | TI TI TI |
| ONJ Z | 2N493A 2N493B 2N494 2N494A 2N494B | GE GE GE GE | n,si n,si n,si n,si n,si | 6.8 6.8 9.1 9.1 | .75 .75 .75 .75 .75 | 1 2 0.20 12 12 0.20 | 15 6 20 15 6 | 4.6 4.6 5 4.6 4.6 | 60 60 60 60 60 | 3 3 3 3 | TI TI TI TI TI |
| UNJ 3 | 2N494C 2N2646 2N2647 2N2840 2N2160 | GE GE GE GE | n,si n,si n,si n,si n,si | 9.1 9.1 9.1 9.1 12 | .75 .75 .75 - 80 | 0.02 12 12 1 1 12 | 2 25 25 10 25 | 4.6 2 2 | 60 30 30 30 60 | 3 6 - 3 | |
| 0143 3 | 2N2417 2N2417 A 2N2417 B 2N2418 2N2418A | GE GE GE GE | n,si n,si n,si n,si n,si | 6.8 6.8 6.8 9.1 9.1 | .62 .62 .62 .62 .62 | 12 12 0.20 12 12 | 20 15 6 25 15 | 5 4 4 5 4 | 60 60 60 60 60 | 3 3 - 3 | |
| UNJ 4 | 2N2418B 2N2419 2N2419A 2N2419B 2N2420 | GE GE GE GE GE | n,si n,si n,si n,si n,si | 9.1 6.8 6.8 6.8 9.1 | .62 .68 .68 .68 | 0.20 12 12 0.20 12 | 6 25 15 6 25 | 4 5 4.3 4.3 5 | 60 60 60 60 | 3 3 - | |
| 4 170 | 2N242OA 2N242OB 2N2421 2N2421A 2N2421B | GE GE GE GE | n,si n,si n,si n,si n,si | 9.1 9.1 6.8 6.8 6.8 | .68 .68 .75 .75 .75 | 12 0.20 12 12 0.2 | 15 6 25 15 6 | 4.3 4.3 5 4.6 4.6 | 60 60 60 60 | 3 - 3 3 | |
| 1411.5 | 2N2422 2N2422A 2N2422B 2N1671 2N1671A | GE GE GE TI | n,si n,si n,si pn,GJ,si pn,GJ,si | 9.1 9.1 9.1 4.7-9.1 4.7-9.1 | .75 .75 .75 .4762 .4762 | 12 12 0.2 -12 -12 | 25 15 6 25 25 | 5 4.6 4.6 5.0 5.0 | 60 60 60 - | 3 3 - - | |
| 5 LNN | 2N1671B 2N2160 | TI TI | pn,GJ,si pn,GJ,si | 4.7-9.1 4.0-12.0 | .4762 .4780 | -0.2 -12 | 6 25 | 5.0 - | - | - | |



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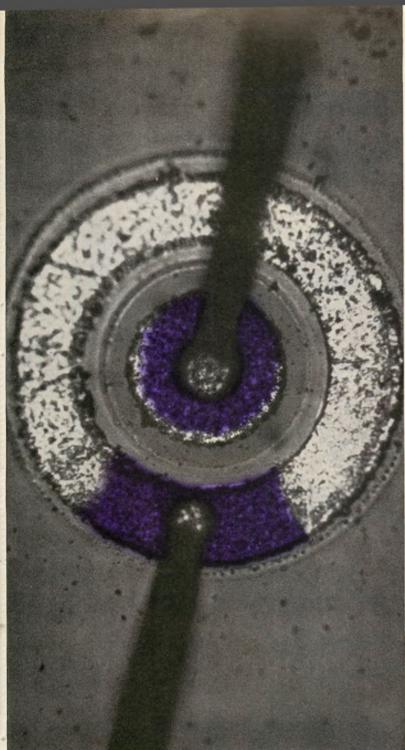
HOW TO USE THE CROSS INDEX

Types are listed in numerical sequence. EIA-registered types come first, followed by house-numbered types. The code following each type identifies its application category and the block of 10 types in which it is located. A3, for example, means the type can be found in the third block of the Audio section. Key to the letter codes is: A = audio and general purpose, P = power, HF = high frequency, LL = low-level switching, HL = high-level switching, FE = field effect, UNJ = unijunction.

| | | | | | | | | | | | | 2N66) LL.28 |
|----------|----------|----------|------------------------------|----------|---------------|-----------|-----------------|---------|------------|---------|-----------------|---------------------------|
| 5 M 3 6 | A12 | 2N241 | A25, 31 | 2N343A | P2 | ZN 426 | LL14 | 2N498A | P3, HL33 | 2N574 | P73 | 2N662 LL 17 |
| 2N35 | A12 | 2N247 | P34 | | P3 | 2N427 | LLZZ | 29,199 | HES4 | | P71 | |
| 2N43 | A20 | 2N243 | A3 | 2N 343B | | | | 411.133 | 111-01 | 2N 574A | | 7N663 P 37 |
| 2N43A | A23 | | | 2N344 | HF22 | 2N428 | LL27 | 2N501 | LL38 | 2N575 | P73 | 2N665 P40 |
| | | 2N244 | A13 | 2N345 | HF22 | 2N428A | LL23 | 2NS01A | LL 38 | 2N575A | P73 | 2N669 P19,60 |
| 2N44 . | A[1 | 2N247 | HF65 | 2N346 | HF30 | 2N438 | NF4, LL7 | 2N502 | HF49 | 2N576 | LLII | 2N670 LL2 |
| 2N 44A | A15 | 2N250 | P40 | | | 2N438A | HF4, LL 47 | | HF49 | | | |
| 2N78 | A43 | 2N251 | P40 | 2N3() | A2 | | | 2N502A | HF51 | 2N576A | LL 16 | 2N671 HL19 |
| 2N78A | A43 | | | 2N348 | A2 | 2N439 | LL11,HF7,8 | 2N503 | | 2N578 | LLII | 2N673 HL 20 |
| | | 2N255 | P 77 | 2N 349 | A) | 2N139A | HF7, LL47 | 2N 50 4 | HF65 | 2N579 | LL17 | 2N677 P50 |
| 2N94 | HF2 | 2N255A | P27, 49 | 2N 350 | PIB | 28440 | HF11,1L20 | 2N 508 | P41 | 2N580 | 11.25 | 2N677A P50 |
| 2N94A | HF6 | 2N256 | P27, 36 | | | 2N440A | HFILLL47 | 2N511 | P65 | | | |
| 2N100 | LL15 | | | 2N350A | P49 | | P65 | | | 2N581 | HF9, LE 17 | 2N677B P50 |
| | | 2N 256 A | P28, 49 | 2N351 | P19 | 2N41L | | 2N511A | P65 | 2N582 | HF15, L1,24, 27 | 2N677C P50 |
| 2N102/13 | A4 | 2N257 | P35 | 2N351A | P49 | 2N442 | P65 | 2N511B | P65 | 2N583 | LL17 | 2N678 P51 |
| 2N1C4 | A20 | 2N 265 | A41 | | | 28443 | P65 | 2N512 | P65 | | | |
| 2N 109 | A26, 31 | 2N268 | P35, HL33 | 2N 356 | HF4,LL7 | 2N414A | HF1 | | P66 | 2N 58 4 | LL25, 27 | 2N678A P51 |
| 2N L L 7 | A3 | 2N268A | | 2N356A | LL7 | | HF4 | 2N512A | | 2NS85 | LLII | 2N678B P51 |
| | | | HL33 | 2N357 | HF7, LL 13 | 2N445A | | 2N512B | P66 | 2N 586 | L147 | 2N678C P51 |
| 2N118 | A7 | 2N269 | LL 24, 46 | 2N 357 A | LL11 | 2N446A | HF7 | 2N513 | P66 | 2N587 | LL47 | 2N679 LL6 |
| 2N118A | HF12 | 2N270 | A25 | | | 2N447A | HFII | 2N513A | P66 | | | |
| 2N119 | A)7 | 2N274 | HF17 | 2N 358 | LL19, HF10 | 2N448 | HF7 | | | 2N588 | H.F47 | 2N695 HF50 |
| 2N120 | A33 | | | 2N358A | L1.19 | | | 2N513B | P66 | 2N591 | A30 | 2N696 HF31, P8, HL26 |
| | | 28/277 | P64 | 2N359 | A63 | 2N449 | HF9 | 2NS14 | P66 | 2N592 | AI1 | 2N697 HF32, P9 |
| 2N122 | P18 | 2N Z7 8 | P64 | 2N 360 | A 39 | 2N450 | LLII | 2N514A | P66 | 201594 | Al3 | 2N698 HF31, P11, NL25 |
| 2N 123 | LL,11,16 | 2N279 | A13 | | | 2N456 | HL18 | 2N514B | P66 | | | |
| 2W128 | HF28 | 2N280 | A22 | 2 N 36 1 | A 30, 32 | | | | | 2N595 | A20 | 2N699 HF31, P9, HL28 |
| | A8 | | | 2N 36? | A38 | 2N456A | P65, HL7 | 2N515 | HF3 | 2N596 | A27 | 2N6998 P15 |
| 2N129 | | 2N281 | A30 | 2N3£3 | A23 | 2N457 | HL 19 | 2N516 | HF3 | 2N597 | LL17, 48 | 2N700 HF62 |
| 2N 1 29 | HF2,8 | 2N 282 | A30 | | HF17 | 2N457A | P65, HL7 | 2M517 | HF3 | | | |
| 2N 140 | HF10 | 2N 284 | A5 | 2N370 | | 2N458 | HL6 | 2N518 | LL 20 | 2N598 | LLI7 | 2N700A H F62 |
| 28144/13 | A4 | 2N784A | A5 | 2N371 | HF18 | | P65, HL7 | | | 2N 599 | L L 26 | 2N702 HF33, LL37 |
| 2N155 | P2) | | | 28372 | HF18 | 2N458A | | 2N519 | .LL6 | 2N600 | LL17,21 | 2N703 HF33,52,LL37 |
| | | 2N 285 | A5 | 26/373 | HE18 | 2N459 | HLG | 2N519A | HF3, LL6 | 2N601 | LL 25 | 2N705 LL 39 |
| 2N156 | P 27 | 2N 285A | P32 | | HF18 | 2N460 | All | 2N520 | LL7, 10 | | HF I6 | |
| 2N158 | P27 | 2N292 | HF6 | 2N 374 | | 2N 46 I | A46 | 2N520A | HF7. LL 10 | 2NE02 | | 2N705A LL48 |
| 2N 158 A | P27 | 2N293 | HF9 | 2N375 | HL6 | | P36 | | | 2N602A | MF14 | 2N706 HF31, 52, P3, |
| 2N160 | A1 | | | 2N 376 | P19 | 2N 46 3 | | 2N521 | LL20 | 2N603 | H F 20 | LL36.48 |
| | | 2N296 | P32 | 2N376A | P49 | 2N 46 4 | A12 | 2N521A | HF10, LL21 | 2N603A | H F20 | 2N706A HF52,65, LL42 |
| 2N 160A | A1 | 2N 297 | HL5 | 28/377 | HF7, LL I4 | 2N465 | A20 | 2N522 | LL 27 | 2N604 | HF22 | |
| 2N161 | A1 | 2N 297 A | P49, HL5 | | | 2N466 | A36 | 2N522A | HF15.LL27 | | | 2N706B HF52, LL42 |
| 2N 16 LA | A1 | 2N298 | P49. HL 5 | 2N317A | L L 16 | | All | | | 2N604A | HF27 | 2N106C HF52,65 |
| | | | | 2N378 | HLF | 2N467 | | 2N523 | LL 30 | 2NE09 | A | 2N706/46 HF52 |
| 2N 163 | A2 | 2N301 | P23, 45 | 2N379 | P50, HLE | 2N 470 | A3 | 2N523A | HF17, LL30 | 2N610 | A | 2N706A/46 HF52 |
| 2N163A | A2 | 2N301A | P23, 45 | 2N 38 0 | P50, HL6 | 2N471 | A3 | 2N524 | AL3 | 2N618 | HLS | |
| 2N167. | LL 19 | 2N 306 | A12 | | | 2N471A | HF9 | 2N524A | A12 | | | 2N106B/46 HF52 |
| 2N167A | LL46 | 2N307 | P24 35 | 2N 38 1 | All | | | | | 2N624 | HF65 | 2N706C/46 HF52 |
| | | | | 2N382 | A19 | 201472 | A3 | 2N525 | A20 | 2N627 | P50 | 2N706/51 HF52 |
| 2N 168 | HF9 | 2N307A | P26 | 2N 383 | A17 | 2N472A | HF9, A4 | 2N525A | A15 | 2N628 | P50 | |
| 2N168A | HF9 | 2N312 | H F65, L L 6 | | HF32 | 2N473 | HELI | 2N526 | A26. HL25 | | P50 | |
| 2N 169 | HF9 | 2N315 | LLII | 2N 384 | | | HEII | | | 2N629 | | 2N706B/51 MF53 |
| 2N 169A | A44 | | | 2N 385 | HF6 | 28474 | | 2N527 | A34, 36 | 2N630 | P50 | 2N706C/51 HF53 |
| | | 2N 31 5A | LLII | 2N 385A | LL8 | 2N474A | HF12 | 2N527A | A31 | 2N631 | A43 | 2N707 HF1, S0, P3, LL48 |
| 2N173 | P64 | 2N316 | LL23 | 2N 388 | LLIG.HF9 | 2N475 | HF12 | 2N529 | AE | 2N6 32 | 82A | |
| 2N174 | P64 | 2N316A | 11.23 | | | 2N475A | A9 | 2N530 | A10 | | | 2N707A LL 42 |
| 2N 174A | P46 | 2N317 | LL28 | 2N 388A | LL11, 26, 46, | | HF15 | | | 2N633 | A28 | 2N708 HF57, 59, 66, P5, |
| 2N 175 | A29 | | | | HF6,15 | 2N 17b | | 2N531 | A12 | 2N634 | HF7 | LL40, 48, HL32 |
| | | 2N317A | LL28 | 2N 389 | P47 | 2N477 | HF15 | 2N532 | A15 | 2N634A | LL48 | 2N708-46 MF57 |
| 2N176 | P19,49 | 2N 319 | A15 | 2N 389 A | P47 | 2N 42P | HF12 | 2N533` | A18 | 2N635 | LL23 | |
| 2N178 | P17 | 2N 320 | A23 | 2N193 | HE27 | 2N479 | HF12 | 2N534 | A38 | | | 2N7C8/51 HF57 |
| 2N 186 A | A10 | 2N321 | A25, 34 | 4 | | | HF12 | | | 2N635A | LL 48 | 2N709 HF62, 63, P3, |
| 2N187A | A17 | | | 2N394 | LL 19 | 2N479A | | 2N535 | A38 | 2N636 | LL27 | LL 48, HL 32 |
| | | 2N 322 | A20 | 2N 39 5 | LL10, HF6 | 2M480 | HF12 | 2N535A | A38 | 2N63GA | LL25, 48 | 2N109/46 HF62 |
| 2N188A | A26 | 2N 323 | A26, 30 | 2N 396 | LLIG, NF9 | 2N480A | A19 | 2N535B | A38 | 2N637 | HL18 | |
| 2N 189 | A10 | 2N324 | A36 | | | 2N481 | HF4 | 2N536 | LL6 | | | 2N109/51 HF62 |
| 2N190 | A17 | 2N32E | P16 | 2N 396A | LL 11, 16 | | | | | 2N637A | HL I8 | 2N7C9A NF63 |
| 2N191 | A26 | | | 2N397 | LL20,23,HF13 | 2N482 | HF5 | 2N537 | LL42, HF63 | 2N637B | ML18 | 2N709A/46 HF63 |
| | | 2N327A | LL2, 3 | 2N 39B | LL46 | 2N 48 3 | HF7 | 2NS38 | P35 | 2N638 | HL 18 | 2N709A/51 HF63 |
| 2N192 | A31 | 2N328A | LL 2, 3, 6 | 2N 39BA | A29. | 2N484 | HF12 | 2N539 | P35 | 2N638A | HL18 | |
| 2N 193 | HF? | 2N 329 | LL1.23 | | P32 | 2N485 | H F8 | | P35 | | | 2N710 HF47, LL40 |
| 2N194 | HE3 | 2N 329 A | LL1,23 | 2N 399 | | | HE13 | 2N540 | | 2N638B | HL18 | 7N710A LL 48 |
| 2N194A | HF3 | | | 2N399A | LL47 | 2N186 | | 2M541 | HF14 | 2N639 | P47 | 2N711 LL40 |
| | | 2N 330 A | A11 | 2N+00 | P32 | 2N489 | LIND | 2N542 | HF14 | 2N639A | P42 | 2N711A LL40, 49 |
| 2N 207 | A37 | 2N 331 | A14, 23, LL3 | 5M401 | P28 | 2N 489 A | UNJI | 2N542A | HF14 | 2N639 B | P42 | |
| 2N207A | A38 | 2N322 | A3 | 2N404 | LL 23 | 2N4898 | UNJI | 2N543 | HE14 | 2N640 | HF20 | 2N711B LL40 |
| 2N207 B | A38 | 2N332A | A3 | 2N+04A | LL8 | 28490 | UNII | | A36 | | | 2N714 LL17 |
| 2N211 | HF3 | 2N 333 | A2 | | AI5 | | | 2N543A | | 2N641 | H F 20 | 2N715 MF40 |
| 2N212 | NF6 | | | 2N405 | | 2N490A | ILIND | 7N544 | HF65 | 2N642 | HF21 | 2N716 HF40 |
| | | 2N 333A | A3 | 2N 106 | A10, 16 | 2N490B | UNII | 2N545 | HL22 | 2NG13 | LL31 | 2N717 HF66 P6 HL26 |
| 2N213 | A31 | 2N 334 | 8A | 2N407 | A29 | 2N490C | UN31 | 2N 546 | HL22 | 28644 | LL37 | |
| 2N213A | A46 | 2N334A | A7 | 2N 408 | A25, 29 | 2N 49 I | UNII | 2N547 | HL21 | 2N645 | LL31, 35 | 2N718 HF66, P6, HL 28 |
| 2N214 | A25 | 2N335 | A)7 | 2N 409 | H F8 | | UNJ) | | | | | 2N718A HF66, P7, HL28 |
| 2N215 | A20 | | | | | 2N491A | | 2N548 | HL21 | 2N647 | A30 | 2N719 HF66, P7, HL27 |
| | | 2N335A | A17 | 2M410 | MF8,65 | ZN4918 | UNJ1 | 2N549 | KL21 | 2N649 | A29 | 2N719A HF66, P7, HL27 |
| 2M217 | A26, 31 | 2N335B | LL46 | 2N 411 | HFIL | 2N492 | UNJ2 | 2N 550 | HL21 | 2N650 | AZZ | |
| 2N218 | HF8,64 | 2N 336 | A33 | 2N413 | HFI | 2N492A | UNJ2 | 2N551 | HL 20 | 2N650A | A22 | 2N770 HF66, P7, HL 28 |
| 2N219 | HF11 | 2N 336A | A34, LL46 | 2N413A | HEI | 2N492B | UNJ? | | HL21 | | | 2N720A HF66, P8, HL28, 33 |
| 2N220 | A78 | | | | | | | 2N552 | | 28651 | A34 | 2N721 P6, HL25 |
| | | 2N 337 | LL78 | 2N414 | LL31, HF8 | 2N 49 2 C | UNJ2 | 2N553 | P40 | 2N651A | A34 | 2N722 P6, HL 27 |
| 2N 228 | A25 | 2N 337 A | LL 32 | 2N414A | HF6 | 2N493 | UNJ2 | 2N554 | P37 | 2N652 | A42 | |
| 2N 229 | A11, P64 | 2N 338 | LL31 | 2N414B | HEIL | 2N493A | UNJ2 | 2N555 | P37 | 2N652A | A42 | 2N725 LL49 |
| 2N231 | HF65 | 2N 3.29 | P2 | 2N416 | HEIL | 2N493B | UNJ2 | 2N556 | LL47 | | | 2N726 A11 |
| 2N232 | HF15 | | A5 | | | | | | | 2N653 | A22 | 2N727 A14 |
| | | 2N 339 A | | 2N417 | LL28, HEIS | 2N494 | UN12 | 2N557 | LL47 | 2N654 | A34 | 2N778 HF42 |
| 2N233 | NF65 | 2N 340 | P2 | 2N418 | HEIS | 2N49:A | UNJ2 | 2N 558 | LL47 | 28655 | A42 | |
| 2N233A | HF] | 2N340A | A5 | SH419 | P42 | 2N494B | UN13 | 2N559 | LL39, 45 | 2N656 | HF38, P14, HL24 | 2N729 HF42 |
| 2N234A | P31 | 2N341 | P2 | 2N420 | HL18 | | | | | | | 2N730 HL 29 |
| 2N235A | P31 | | A5.P2 | | | 2N494C | UNJ3 | 2N560 | LL35 | 7N656A | P3,HL33 | 2N731 HL29 |
| | | 2N341A | | 2N420A | HL18 | 2N495 | HF17 | 2N564 | All | 2N657 | HF39, P14, HL24 | 2N734 A16 |
| 2N235B | P3) | 2N 342 | P2 | 2N422 | A23 | 2N 496 | L L 28. 87 | 2N566 | A27 | 2N657A | P3, HL33 | |
| 2N 236 A | P31 | 2N342A | P2 | 2N 424 | P17 | 2N497 | HF38, P14 | 2N568 | A38 | 2N658 | . F3,RE33 | 2N735 A30 |
| 2N736B | P34 | 7N342B | P2 | 2N424A | HL 20 | | P1 HL 33 | | | | | 2N735A HF33 |
| 2N 240 | LL 46 | 2N342B | P2 | | | 2N497A | | 2M570 | A13 | 2 N659 | LL21 | 2N7 36 A 39 |
| (H 24U | E L 46 | 7N343 | PZ | 2N425 | LLE | 2N 49B | HF38, P14, HL23 | 2N 57 2 | A44 | 2N660 | LL25 | 2N736A A36 |
| | | - | | - | | | | | | - | | A30 |
| | | | | | | | | | | | | |

| 2N736B HF33 | 2N915 HFSS, 68, PS, HL30 | 2N1046A HL11 | ZNI183A PI7 | 2N1357 LL24 | 2N1529A P54 | 2N1670 AB |
|--|--|------------------------------------|---|---|---------------------------------------|--|
| 2N738 A16, H F22 2N739 A30, H F22 | 2N916 HF2, 50, 57. | 2N1046B HL11 | 2N1183B P17 | 2N1358 HL7 | 2N1530 P54 | 2N1671 UNJ5 |
| 2N739 A30, HF22 2N739A HF33 | P 5, 80, HL 30 2N917 A23, H F63, | 2N1047 P37 2N1047A P37 | 2N1184 P17 2N1184A P17 | 2N1358A P68 2N1358M P53 | 2N153GA P54 2N1531 P54 | 2N1671A UNJS 2N1671B UNJS |
| 2N740 A39, HF22 | LL 50, HL 32 | 2N1047B P37 | 2N1184B P17 | 2N1359 P53 | 2N1531A P54 | 2N1672 A32 |
| 7N740A HF33 | 2N918 A23, HF64, | 2N1047C P37 | 2N1185 A45 | 2N1360 P53 | 2N1532 P55 | 2N1675 P63 |
| 2N741 HF56 2N741A HF56 | LL 45, LL 33 2N920 HF33 | 2N1048 P37 2N1048A P4, 37 | 2N1186 A22 2N1187 A35 | 2H1362 P54 2N1363 P54 | 2N1532A P55 2N1533 P55 | 2N1676 MF71 2N1677 HF17,71 |
| 2H742 A18 | 2N921 HF34 | 2N1048B P38 | 2N1188 A42 | 2N1363 P54 2N1364 P54 | 2N1534 P55 | 2N1677 HF17,71 2N1678 A18 |
| 2N743 HF54, 57, 66 | 2N922 HF34 | 2N1048C P38 | 2N1190 A18 | 2N1365 P54 | 2N1534A P55 | 2N1683 LL53 |
| 2N743/46 HF54 2N743/51 HF54 | 2N923 A8 2N924 A21 | 2N1049 P38 2N1049A P38 | 2N1192 A32 2N1193 A44 | 2N1370 A35 2N1371 A35 | 2N1535 P55 2N1535A P55 | 2N1684 HF71 2N1685 LL19 |
| 2N744 HF54, 59, | 2N925 A6 | 2N1049B P38 | 2M1194 A45 | 2N1371 A35 2N1372 A14.70 | 2N1535 P55 | 2N1685 LL 19 2N1690 P.39 |
| 66,LL44 | 2N926 A16 | 2N1049C P38 | 2N1195 HF63, LL43 | 2N1373 A14, 20 | 2N1536A P55 | 2N1691 P39 |
| 2N744/46 HF55 2N744/51 HF55 | 2N927 AS 2N928 A16 | 2N1050 P38 | 2N1196 HF21 2N1194 HF27 | 2N1374 A26, 35 | 2N1537 P55 2N1537A P56 | 2N1592 P12 |
| 2h745 LL21 | 2N928 A19, HF28, 41, 68 | 2N1050A P38 2N1050B P38 | 2N1194 HF27 2N1198 LL20 | 2N1375 A26, 35 2N1376 A33, 37 | 2N153/A P56 2N1538 P56 | 2N1693 P17 2N1694 LLS3 |
| 2N746 LL28 | 2N929A HF34 | 7N1050C P38 | 2N1202 P35 | 2N1377 A37 | 2N 1539 P 56 | 2N1700 P15 |
| 2N747 LL31 | 2N930 A40, HF28, 41, 68 | 2N1051 A8, LL8 | 2N1203 P35 | 2N1378 A44 | 2N1S39A P56 | 2N1701 H1.20 |
| 2N748 LL31 2N750 HF20 | 2N930A HF34 2N934 HF20 | 2N1052 HL22 2N1054 HL22 | 2N1204 HF69, LL43 2N1204A LL43 | 2N1379 A45 2N1380 A15, 39 | 2N1540 P56 2N1540A P56 | 2N1702 HL20 2N1703 P46 |
| 2N751 HF13 | 2N935 A4 | 2N1055 HL21 | 2N1206 P4.63 | 2N1381 A15, 39 | 2M1541 P56 | 2N1704 P41 |
| 2N753 HF67 | 2N936 A13 | 2N1056 LL3 | 2N1207 P4,63 | 2N1382 A35 | 2N1541A P56 | 2N1705 A41 |
| 2N754 HF21 2N755 HF21 | 2N937 A28 | 2NIQS) LL2 | 2N1208 HL22 | 2N1383 A24 | 2N1542 P56 2N1542A P56 | 2N 1706 A37 |
| 2N756 A4 | 2N938 A5 2N935 A13 | 2N1058 HF6 2N1059 A25 | 2N1209 HL22 2N1210 P43 | 2N1384 LL52 2N1385 LL45 | 2N1542A P56 2N1543 P57 | 2N1707 A37 2N1708 LL53 |
| 2N756A A4, 6 | 7N910 A28 | 2N1060 LL31, HL79 | 2N1211 P43 | 2N1395 HF18 | 2N1544 P57 | 2N1709 H F18, P23 |
| 2N757 A7 2N757A A7, 13 | 2N941 A23 2N942 A23 | 2N1065 HF17 2N1066 HF39 | 2N1212 HL22 2N1213 LL50 | 2N1396 HF35 2N1397 HF39 | 2N1544A P57 2N1545 P57 | 2N1710 HF18, P23 2N1711 HF71, P12, HL29 |
| 2N758 A8 | 2N943 A46 | 2N10G6 HF39 2N10G7 P15 | 2N1214 LL50 | 2N1397 HF33 2N1398 HF70 | 2N1545A P57 | 2N1714 P19 |
| 2N758A A8, 26 | 2N944 A46 | 2N1068 P19 | 2N1215 LL50 | 2N1399 HF70 | 2N1546 P57 | 2N1715 P19 |
| 2N758B HF33 2N759 A17, HF23 | 2N945 A46 2N946 A46 | 2N1059 P40 | 2N1216 LL51 | 2N1400 HF70 | 2N1546A P57 2N1547 P57 | 2N1716 P19 |
| 2N759A A17,29 | 2N947 HF57, P5, HL31 | 2N1070 P40 2N1072 HL23 | 2N1217 LL51 2N1218 P16 | 2N1401 HF70 2N1401A HF70 | 2N1547A P57 | 2N1717 P19 2N1718 P20 |
| 2N759B HF33 | 2N955 HF64,68 | 2N1073 P42, 52, HL 4 | 2NI219 LLI3 | 2N1402 HF50 | 2N1548 P57 | 2N1719 P20 |
| 2N760 A34, HF23 | 2N956 HF23 | 2N1073A P42,52,HL4 | 2N1220 LL6 | 2N1404 LL9,52 | 2N1549 P58 | 2N1720 P20 |
| 2N760A A34, HF23 2N760B HF33 | 2N957 A28, HF9, 45, 48, P2 2N960 HF50, 60, | 2N10738 P42, 52, HL4 2N1084 P62 | 2N1221 LL13 2N1222 LL7 | 2N1405 HF60 2N1406 HF60 | 2N1549A P58 2N1550 P58 | 2N1721 P20 2N1727 P41 |
| 2N761 A9 | 68, LL40 | 2N 1085 P62 | 2N1223 LL7 | 2N140) NFS6 | 2N 1550A P58 | 2N1723 P41 |
| 2N762 A22 | 2N961 MF50,60. | 2N1086 HF10 | 2N1224 HF18, 34 | 2N1409 HF39, HL26 | 2N1551 P58 | 2N1724 P41 |
| 2N768 HF67, LL38, 45 2N769 HF67, LL45 | 68, LL40 2N962 HF50, 60, | 2N1086A HF10 2N1087 HF10 | 2N1225 HF35 2N1226 HF18,34 | 2N1410 HF39, HL26 2N1411 LL36, 52 | 2NISSIA P58 2NISS2 P58 | 2N1726 HF42 2N1727 HF42 |
| 2N779A LL44 | 69, LL 40 | 2N1090 HF8,LL15 | 2N1228 LL4 | 2N1412 HL7 | 2N1552A P57 | 2N1728 HF42 |
| 2N779B LL44 | 2N963 H FE 1 | 2N1091 HF14, LL24 | 2N1229 LL4 | 2N1412USN P68 | 2N1553 P58 | 2N1742 HF71 |
| 2N780 A34 2N781 HF67, LL-19 | 2N964 HF50,61, 69,LL40 | 2N1094 H F63, LL 45 2N1095 A2 | 2N1230 LL4 2N1231 LL4 | 2N1413 LL57 2N1414 LL52 | 2N1553A P.58 2N1554 P.59 | 2N1743 HF71 2N1744 HF71 |
| 2N782 HF67, L.L.49 | 2N964A HF61 | 2N1096 A2 | 2N1232 LL4 | 2N1417 HF12 | 2N1554A P59 | 2N1745 HF71 |
| 2N783 MF67 2N784 MF67 | 2N965 HF51,61, | 2N1097 A27 | 2N1233 LL4 | 2N1418 HF13 | 2N1555 P59 2N1555A P59 | 2N1746 HF43 |
| 2N784A HF54, LL40 | 69, LL41 2N966 MF51,61, | 2N1058 A21 2N1099 P67 | 2N1234 LL2, 5 2N1238 LL5, HL2 | 2N1420 HF35, 39, P9, HL29 | 2N1556 P59 | 2N1747 HF47,71 2N1748 HF35 |
| 2N784A/46 HF54 | 69, LL41 | 2N1100 P67 | 2N1239 LL5. HL3 | 2N1425 HF19 | 2N1556A P59 | 2N1748A HF35,41 |
| 2N784A/\$1 HF54 | 2N967 HF61 | 2N1101 A12 | ZNIZ40 LL5, HL3 | 2N1426 HF19 | 2N1557 P59 | 2N1749 HF35 |
| 2N789 LL14 2N790 LL17 | 2N568 HF53 2N969 HF53 | 2N1102 A12 2N1114 LL16 | 2N1241 LLS, HL4 2N1242 LLS, HL4 | 2M1427 HF35, LL33 2M1428 HF17 | 2N1557A P59 2N1558 P59 | 2N1750 HF18 2N1751 HL33 |
| 2N791 LLZ2 | 2N970 NF53 | 2N1115 HL21 | 2N1243 LL5, HL4 | 2N1429 HF17 | 2N1558A P59 | 2N1752 HF38 |
| 2N792 LL17 2N793 LL24 | 2N971 HF53 | 2N1117 HL21 | 2N1244 LL3, HL4 | 2N1431 A33 | 2N1559 P60 2N1559A P60 | 2N1754 LL53 |
| 2N794 LL 19 | 2N972 HF53 2N973 HF53 | 2N1118 HF15 2N1118A HF15 | 2N1247 A5,36 2N1248 A8,42 | 2N1432 A15 2N1437 P28 | 2N1559A P60 2N1560 P60 | 2N1755 P20 2N1756 P20 |
| 2N795 LL49 | 2N974 NF53 | 2N1119 LL29,50 | ZN1249 A5 | 2N1438 P29 | 2N1560A P60 | 2N1757 P20 |
| 2N797 HF64, LL45 | 7N975 HF54 | 2N1120 P40 | 2N1250 HL23 | 2N1439 A4 | 2N1561 HF61, P11 | 2N1758 P20 |
| 2N799 LL9 2N800 LL9 | 2N976 LL45 2N978 P6, HL23 | 2N1121 HF10 2N1122 LL50 | 2N1251 A31 2N1252 HF31, P9, | 2N1440 A5 2N1441 A11 | 2N1562 WF61, P11 2N1564 A16, HF5, | 2N1759 P20 2N1260 P20 |
| 2NB01 1.L8 | 2N979 HF34 | 2N1122A LL50 | LL51, HL27 | 2N1442 A21 | 24, 45, P12 | 2N1761 P21 |
| 2N802 LL8 | 2N980 HF34 | 2N1131 P9, HL 26 | 2N1253 HF35, P9. | 2N1443 A32 | 2N 1565 A31, HF5. | 2N1762 P21 |
| 2NB03 LL12 2NB04 LL12 | 2N982 HF60 2N983 HF60 | 2N1132 P9, HL 27 2N1136 P42 | 2N1254 LL33 | 2N1441 HL29 2N1446 A13, LL7 | 24, 45, P12 2N1566 A2, 18, HF5, | 2N1768 HL20 2N1769 HL20 |
| 7N805 LL21 | 2A984 HF55 | 2N1135A P42 | 2N1755 LL36 | 2N1447 A21, LL8 | 24, 45, P6, 12 | 2N1779 LL33 |
| 2N807 LL25 | 2N985 HF51, LL41 | 2N1136B P42 | 2N1756 LL33 | 2N1448 A29, L1.9 | 2N1566A A36 | 2N1780 LL9 |
| 2N808 LL 25 2N815 LL 12 | 2N987 MF34 2N988 HF1, P3 | 2N1137 P43 2N1137A P43 | 2N1257 LL 36 2N1258 LL 33 | 2N1449 A35, LL13 2N1450 HF70, LL52 | 2N1572 A16, HF24 2N1573 A31, HF24 | 2N1781 LL9 2N1782 HF71 |
| 2N016 LL12 | 2N989 HF1. 48, P3 | 2N1137B P43 | 2N1259 LL36 | 2N1451 A21 | 2N1574 A39, HF24 | 2N1783 HF72 |
| 2N817 LL7 | 2N990 HF28 | 2N1138 P43 | 2M1261 P36 | 2N1452 A29 | 2N1584 A7 | 2N1784 HF72 |
| 2N818 LL7 2N819 LL12 | 2N991 HF28 2N992 HF28 | 2N1138A P43 2N1138B P43 | 2N1262 P36 2N1263 P36 | 2N1465 P29 2N1466 P29 | 2N1586 A7 2N1587 A7 | 2N1785 HF40 2N1786 HF40 |
| 2N870 LL12 | 2N993 MF30 | 2N1139 LL.37 | 2N1264 HF69 | 2N1469 HF4 | 2N1588 A7 | 2N1787 HF40 |
| 2N821 LL21 | 2N994 HF69 | 2N1141 HF63 | 2N1265 P11 | 2N1471 A43 | 2N I 589 A24 | 2N1788 HF42 |
| 2N822 LL21 2N823 LL20 | 2N995 HF45, P5 2N996 HF45, P5 | 2N1142 HF62 2N1143 HF61 | 2N1266 HF69 2N1273 A24 | 2N1473 LL52 2N1474 A12 | 2N1590 A24 2N1591 A24 | 2N1789 HF42 2N1790 HF42 |
| 2N824 LL9 | 2N998 HF23 | 2N1141 A27 | 2N1274 A24 | 7N1474A A13 | 2N1592 A43 | 2N1808 LL10,53 |
| 2N825 LL12 2N826 LL12 | 2H1008 A4, LL28 2N100EA LL28 | 2N1145 A21 2N1146 P32 | 2N1215 LL1 2N1276 LL31 | 2N1475 A28 | 2N1593 A13 2N1594 A43 | 2N1809 P76.HL8 |
| 2NB28 HF67, LL42 | 2N1008B 1L29 | 2N1146A P32 | 2H1277 A7, LLS1 | 2N1476 A30 2N1477 A21 | 2N1605 LL9 | 2N1810 P76, HL8 2N1811 P76, HL8 |
| 7N878A HF57, LL 42 | 2N1009 A17 | 2N1146B P32 | 2N1278 A18, LL51 | 2N1478 HF10, LL19 | 2N1605A LL9 | 2N1812 P76, HL9 |
| 2N829 HF57, LL42 2N834 HF50, 59. | 2N1010 A16 2N1011 P36, NL6 | 2N1146C P32 2N1147 P32 | 2N1279 A33, LL51 2N1280 LL18 | 2N1479 P14 2N1480 P14 | 7N1609 P17 2N1610 P17 | 2N1813 P76, HL9, 33 |
| 2N834 HF30, 39, 67, LL44 | 2N1012 LL13 | 2N1147A P32 | 2N1281 LL21 | 5N1480 P14 | 2N1611 HL12 | 2N1814 P76, HL9, 33 2N1816 P76, HL10 |
| 2N834:46 HF59 | 2N1014 P40 | 2N1147E P33 | 2N1282 LL26 | 2N1482 P14 | 2N1612 P18, HL13 | 2N1817 P77, HL LO |
| 2NB34.'51 HF59 2NB35 HF50, 58, 59, | 2N1015 P66, HL13 2N1015A P66, HL13 | 2N1147C P33 2N1149 A3 | 2N1284 LL18 2N1288 LL51 | 2N1463 P33 2N1484 P33 | 2N1613 HF35, P12, HL27 2N1614 LL53 | 2N1818 P77, HL 10 2N1819 P77, HL 10 |
| LL 44, 45 | 2N1015B P67, HL 13 | 2N1150 AB, 10 | 2N1289 LL51 | 2N1485 P33 | 2N1615 P14 | 2N1823 P77, HL11 |
| 2N835/46 H F59 2N835/51 H F59 | 2N1015C P67, HL13 2N1015D HL13, 16 | 2N1151 AB 2N1152 A17 | 2N1294 P28 2N1295 P28 | 2N1486 P33 | 2N1616 P44 | 2M1824 P27, HL11 |
| 2N839 HF21 | SW1012E HE 13, 16 | 2N1152 A17 2N1153 A34 | 2N1295 P21 2N1299 LL51 | 2N1487 P43 2N1488 P43 | 2N1618 P44 2N1619 P47 | 2N1825 P77, HL11 2N1826 P77, HL12 |
| 2N810 HF21 | 2N1016 P67, ML13 | 2N1154 A2 | 2N1300 LL52 | 2N1489 P44 | 2N1620 P79, HL20 | 7N1830 P77, HLI |
| 2N841 H F Z8 2N842 LL 32 | 2N1016A P67, HL 13, 17 2N1016B P67, HL 13, 17 | 2N1155 A2 2N1156 A3 | 2N1301 LL52 2N1302 HF4, LL0, 10 | 2N1490 P44 2N1491 HF48 | 2N1623 A6 2N1624 HF10 | 2N1831 P77, HL 1 2N1832 P77, HL I |
| 2NB43 LL35 | 2N1016C HL14,17 | 2N1157 P73 | 2N1303 LL10 | 2N1492 HF49 | 2N1631 HF21 | 2N1833 P78, HL1 |
| 2N844 HF32 | 2N1016D P67, HL 14 | 2N1157A P62 | 2N1304 LL18 | 2N1493 HF51 | 2N1632 HF?1 | 2N1837 HF40, HL34 |
| 2N845 HF32 2N846A LL44 | 2N1016E HL 14 2N1017 LL 29 | 2N1158 NF69 2N1158A HF69 | 2N1305 LL18 2N1306 LL23 | 2N1494 HF70 | 2N1633 HF20 2N1634 HF20 | 2N1837A H F 48, H L 34 |
| 2N849-11-430 HF67, LLL49 | 2N1017 ELEG 2N1018 A41 | 2N1158A HF69 2N1159 P60 | 2N1305 LL23 | 2N1494A LL43 2N1495 LL39 | 2N1634 HF20 2N1535 HF21 | 2N1838 HF18 2N1839 HF48 |
| 7NES T1-431 MF68, LL 49 | 2N1021 P67 | 2N1160 P60 | 2N1308 LL27 | 2N1496 LL39 | 2N1636 HF72 | 2N1840 HF4, 44 |
| 2N851/TI-422 HF68 2N852/TI-423 HF68 | 2N1022 P67 2N1023 HF39 | 2N1162 P52 2N1167A P52 | 2N1309 LL27 2N1313 LL23 | 2N1499 LL52 2N1499A HF30, 43 | 2N1637 HF22 2N1638 HF20 | 2N1841 HF72, HL34 2N1864 HF40 |
| 2NB58 LL25 | 2N1024 HF1 | 2N1162A P52 2N1163 P52 | 2N1313 EL23 2N1314 P23 | 2N1499A HF30, 43 2N1500 HF43 | 2N1639 HF22 | 2N1864 HF40 2N1865 HF72 |
| 2MB59 LL25 | 2N1025 HF2 | 2N1163A P52 | 2N1316 LL26 | 2N1501 P36 | 2N1640 LL2 | 2N 1866 M F72 |
| 2N860 LL25 2N861 LL30 | 2N1076 HF3 2N1027 HF6,LL9 | 2N1164 P52 2N1164A P53 | 2N1317 LL26 2N1318 LL26 | 2N1502 P36 | 2N3641 LL3 2N3642 LL5 | 2N1867 HF72 |
| 2H862 LL25 | 2N1028 LL9 | 2N1165 P53 | 2N1319 LL14 | 2N1504 P29 2N1505 NF29, P11 | 2N1645 HF63, HL 32 | 2N 1868 H F7 2 2N 1886 P 39 |
| 7NB63 LL30 | 2N1031 P51 | 2N1165A P53 | 2N1326 P28 | 2N1506 HF29, 46, P11 | 2N1646 HF70 | 2N1893A HF5, 45, P13 |
| 2N864 LL30 2N865 LL33 | 2N1031A P51 2N1031B P51 | 2N1166 P53 2N1166A P53 | 2N1335 HF28, P10 2N1336 HF28, P10 | 2N1506A HF5, 45, P11, 13 2N1502 ME40 LL 37 | 2N1647 P39 2N1648 P39 | 2N1894 P47 |
| 7N869 PS, HL 30 | 2N1031C P51 | 2N1166A P53 2N1167 P53 | 2N1336 HF28, P10 2N1337 HF29 | 2N1507 HF40, LL37 2N1511 P46 | 2N1648 P39 2N1649 P39 | 2N1895 P48 2N1896 P48 |
| 2N870 HF23, P8, HL26 | 2N1032 P52 | 2N1167A P53 | 2N1339 HF29, P11 | 2N1512 P46 | 2N1650 P39 | 2N1897 P48 |
| 2N871 HF23, P8, HL29 2N902 LL14 | 2N1032A P51 2N1032B P52 | 2N1168 P60 2N1169 LL10 | 2N1340 HF29, P11 2N1341 HF29, P11 | 2N1513 P46 | 2N1651 P63 | 2N 1898 P48 |
| 2N903 LL 18 | 2N 1032C P52 | 2N1169 LL10 2N1170 LL10 | 2N1341 HF25, P11 2N1342 HF4, 45, P11 | 2NIS14 P46 2NIS15 HF70 | 2N1652 P63 2N1653 P63 | 2N1899 HF15, P63 2N1900 HF17, P64 |
| 5M901 LL22 | 2N1034 LLI | 2N1172 P17 | 2N1344 LL14, 23 | 2NIS16 HF29 | 2N1654 A14 | 2N1901 HF17, P64 |
| 7H905 LL18 7H906 LL74 | 2N1035 LL1 2N1036 LL2 | 2N1173 A23, HL21 | 2N1345 LL24 | 2N1517A HF29 | 2N1655 A6 | 2N1902 HF16 |
| 2N907 LL31 | 2N1036 LL2 2N1037 LL1 | 2N1174 A24.HL22 2N1175 LL50 | 2N1346 LL24 2N1347 LL18 | 2NIS18 HLS 2NIS19 HLS | 2N1656 A14 2N1657 P41 | 2N1903 HF16 2N1904 HF16 |
| 2N908 LL32 | 2N 1038 HL7 | 2N1175A LL50 | 2N1348 LL13 | 2N1520 HL5 | 2N1658 P24 | 2N1905 P41 |
| 2N909 HL29 2N910 HF23, P8, HL29 | 2N1039 HL7 2N1040 HL7 | 2N1176 A18 | 2N1349 LL21 | 2N1521 HLS | 2N1659 P24 | 2N1906 P41 |
| 2N911 HF23, P8, HL26 | 2N1041 HL23 | 2N1176A A18 2N1176B A18 | 2N1350 LL18 2N1351 + LL18 | 2N1522 HLS 2N1523 HLS | 2N1660 P47 2N1661 P47 | 2N1907 HF16, P68, HL23 2N1908 HF16, P68, HL23 |
| 2M912 HF23, P8, HL24 | 2N1047 P.78 | 2NE177 HF41 | 2N1352 A30 | 2N1524 HF19 | 2N1662 P47 | 2N 1917 A21 |
| 2N914 HF55,59,68,PB0 2N914446 HF59, | 2N1013 P28 2N1014 P28 | 2N1178 HF41 2N1179 HF41 | 2N1353 LL0 2N1354 LL10 | 2N1525 . HF19 | 2N1666 P23 | 2N1918 A24 |
| LL50, ML37 | 2M LO45 P28 | 2N1179 HF41 2N1180 HF34 | 2N1354 LL10 2N1355 LL18 | 2N1526 HF19 2N1527 HF19 | 2N1667 HL 17 2N1668 HL 17 | 2N1919 A46 2N1920 A46 |
| 2N914/51 HF60 | 2N1046 HL11 | 7N1183 P17 | 2N1356 LL19 | 2N1529 P54 | 2N1669 HL17 | 2N1921 A46 |

May 24, 1963





How Sylvania checked "purple plague" and boosted reliability

What you see above represents a victory over an insidious cause of semiconductor device failure - a problem faced by the whole industry-the "purple plague."

On the left, the blotches are a goldaluminum-silicon alloy formed by reaction between the gold wires and aluminum base areas of the chip. Accelerated by high temperatures, this reaction increases series resistance and weakens the leads bad news when reliability is essential.

Sylvania engineers departed from standard industry practice and developed a technique of bonding aluminum wires to aluminum, illustrated at the right. After long testing at worse-than-actual conditions, the clean Sylvania junctions confirm: no chemical reaction, no purple plague at the chip-a big step forward that means greater system reliability.

All Sylvania epitaxial planar devices now benefit from this victory. The broad, integrated capabilities that made it possible are being applied constantly to the improvement of Sylvania semiconductors.

Semiconductor Division, Sylvania Electric Products Inc., Woburn, Massachusetts.

SYLVANIA

GENERAL TELEPHONE & ELECTRONICS





NEW PHELPS DODGE ELECTRONIC ALLOY

PD-135 is Phelps Dodge's new copper base alloy with high conductivity, excellent ductility, and retention of high strength at elevated temperatures. Developed with an oxygen free copper base, PD-135 is controlled by Phelps Dodge throughout every step of casting, and fabrication into rod, bar, wire, and strip forms.

Heat-treatable PD-135 is particularly suited for applications requiring extensive cold working and upsetting.

PD-135 is completely free-flowing, and cold forms to truest tolerances. A heat-treatable alloy, PD-135 does not lose its high strength characteristics after exposure to high temperatures.

PD-135 is sold in minimum mill quantities of 500 lbs. per size. For complete information, including performance data, on this noteworthy new alloy, send for Brochure K. Just write Phelps Dodge at the address below.

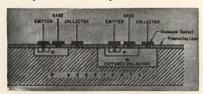
COPPER PRODUCTS CORPORATION 300 Park Avenue, New York 22, N.Y. ON READER-SERVICE CARD CIRCLE 475



Transistors and allied products have been included for your convenience in the Transistor Data Chart section of the magazine. The Reader-Service numbers for the products can be circled on either the Reader-Service card in the main section or the special one in the back of this Data Chart.

Paired Transistors

Experimental products



Saturation voltage for model XT999, a monolithic NPN and PNP pair, is 0.3 v for $I_c\!=\!10$ ma and $I_b\!=\!1$ ma. An FET pair, model X-600, provides gms of approximately 1000 μ mhos and has a pinch-off voltage of 2-3 v.

P&A: \$84-\$95; 4 weeks. Mfr: Signetics Corp.

ON READER-SERVICE CARD CIRCLE 500

Transistors

Silicon planar

Eighty-one types are manufactured in the Leaf configuration. Collector saturation voltage is 0.2 v at $I_{\rm C}=150$ ma dc, $I_{\rm B}=15$ ma dc. Beta linearity is $h_{\rm FE}=65$ at $I_{\rm C}=0.5$ amp dc and 30 at 1 amp dc.

Price: \$1.05-\$25.50 (100-999).

Mfr: Bendix Corp., Semiconductor Div.

ON READER-SERVICE CARD CIRCLE 501

Silicon Transistors

Diffused mesa



High-collector voltages, low-saturation voltages, fast-switching speeds and relatively fast betas are claimed for types 2N389, 2N424, 2N1015, etc. Diffused-mesa construction is said to have improved a present line of 41 silicon power transistors.

Price: \$1.05-\$25.50 (100-999).

Mfr: Bendix Corp., Semiconductor Div.

ON READER-SERVICE CARD CIRCLE 502

Photo-Transistors

High sensitivity



Sensitivity radiation system range is 50-200 μ a/mw/cm² for type 2N2452. Sensitivity illumination system range is 2.6-10.3 μ a/ft-c. Unit is designed as a companion to type 2N986.

P&A: \$27 (1-99); 4 weeks.

Mfr: Fairchild Semiconductor.
ON READER-SERVICE CARD CIRCLE 503

Power Transistors

150-w dissipation

A tight two-to-one $h_{\rm FE}$ ratio (50-100 at 3 amps) makes types 2N1539 through 2N1543 useful for power amplifier applications with critical stability requirements. The 150-w dissipation rating is said to be the highest available in the TO-3 diamond package.

P&A: \$2.10-\$10.40 (1-99); stock.

Mfr: Texas Instruments Inc., Semiconductor-Components Div.

ON READER-SERVICE CARD CIRCLE 504

Silicon Transistors

Interdigitated "I" geometry

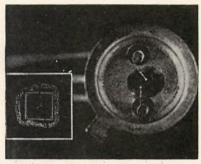


Collector breakdown voltages of 75 v min and typical total switching time of < 90 nsec are available in types 2N2787-2N2792. Noise levels as low as 0.5 db are offered in types 2N929 and 2N930, which are available singly, or as duals and matched duals.

Mfr: General Instruments Corp.
ON READER-SERVICE CARD CIRCLE 505

FETs

Planar-diffused silicon



P-channel UNIFETS have two different geometries with a 1.1 to 1 ratio of g_m to I_{DSS} and 6 v max pinch-off voltage. Storage temperature range is -65 to +200 C. Maximum gate-drain breakdown voltage of 20 v is guaranteed at $I_G=1~\mu a$.

Price: \$9.50-\$11.50 (over 100).

Mfr: Siliconix, Inc.

ON READER-SERVICE CARD CIRCLE 506

Silicon Transistor

Planar epitaxial

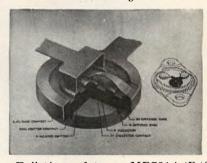
The 1.6 Gc type 2N2808 has an ac current gain of 5 at 200 Mc. It can be used as an rf amplifier to 500 Mc and as an oscillator to 1.6 Gc. Power gain is 20 db measured at 200 Mc; collector-to emitter voltage is 6 v, and collector current is 2 ma.

Mfr: Raytheon Co., Semiconductor Div.

ON READER-SERVICE CARD CIRCLE 507

Power Transistors

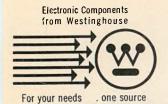
Breakdown voltage to 100 v



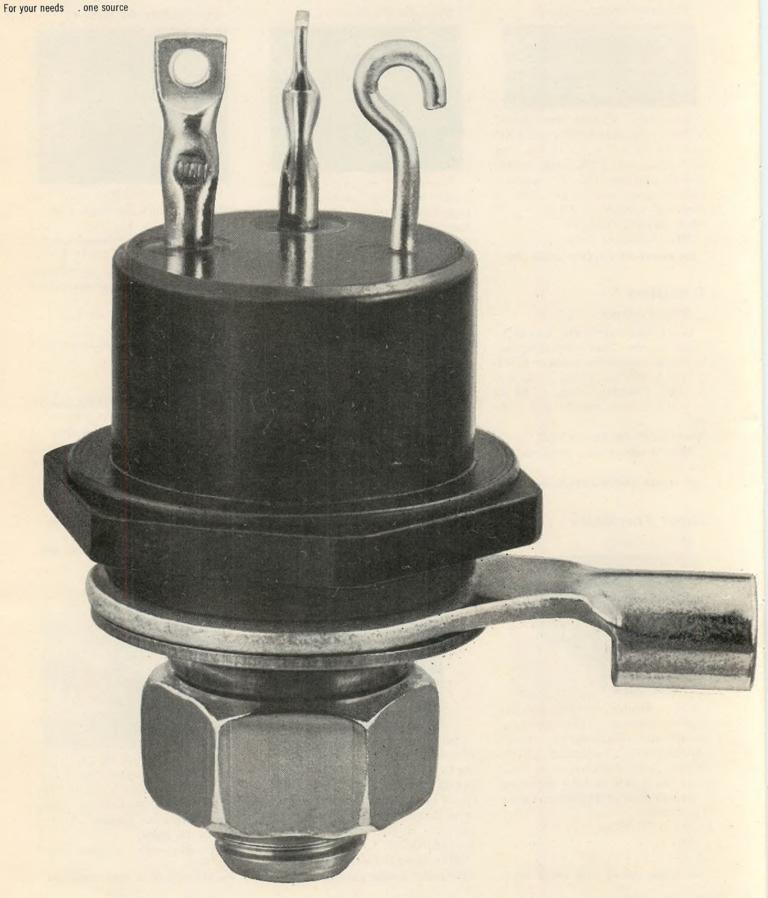
Fall time of types MP721A/B/C is 0.7 μ sec at 8 amps collector current for TV flyback circuits. The epitaxial-base germanium units have a saturation voltage of 0.3 v, max, at 10 amps.

Mfr: Motorola Semiconductor, Inc.

ON READER-SERVICE CARD CIRCLE 508



THE NEW CASE FOR RELIABILITY



The industry's standard for silicon power transistors— now in a double ended case!

In response to customer demand, Westinghouse nowmakes available its field-proven silicon power transistor in a new double-ended case. Performance, reliability and construction features are the same as have been successfully used in Westinghouse military type transistors for the last-three years. Over 5 megawatts of 30 ampere transistors are now serving in military and industrial applications.

The new double-ended transistor, 2N2757 series, comes in voltage ratings to 250 volts, current ratings to 30 amperes, and a variety of gain classes.



Rock top transistor for highest power ratings

The 250 watt, 300 volt 2N1809-2N2109 series in the rugged "rock top" case features the highest power dissipation ratings available in silicon transistors.



Conventional case for convenient mounting

The 2N2739-2N2754 series (formerly Type 109) offers the convenience of a low mounting profile. Dissipation ratings to 200 watts, currents to 20 amperes.

New procurement specifications

Procurement specifications on each of the above units are available in military format for designers and reliability engineers. These specifications outline electrical and environmental capabilities under standard Mil-spec conditions. Write for a free copy today on your company letterhead: Westinghouse Semiconductor Division, Youngwood, Pa. You can be sure...if it's Westinghouse.

We never forget how much you rely on

Westinghouse

On reader-service card circle 476 May $24,\ 1963$

Power Transistors

Meet MIL-S-19500/102

Ratings of 150 w and 7.5 amp are available for these silicon devices. Type USN 2N1016Bm is rated at 100 v, and type USN 2N1016CM is rated at 150 v.

Guide: Insert bold-italic line **P&A:** \$32.55-\$43.35 (100 or more).

Mfr: Westinghouse Electric Corp., Semiconductor Div.

ON READER-SERVICE CARD CIRCLE 509

Transistor Tester

Pulse testing



Test parameters up to 500 v and 25 amps are provided by the TACT unit. Pulse duration can be varied from 100-500 μ sec and 1-5 msec, and repetition rate from 2-100 pps. Test conditions are determined in a digital manner by prepunched and

Mfr: Texas Instruments Inc.
ON READER-SERVICE CARD CIRCLE 510

UHF Transistor

Low noise

Noise figure of the TA-2333 at 450 Mc is 4 db. Rf amplifier gain is 15 db, typical. Collector-to-base voltage is 30 v, min; collector-to-emitter, 20 v, min; total dissipation at 25 C free air, 200 mw.

P&A: \$35 (1-99); stock.

Mfr: Radio Corp. of America.
ON READER-SERVICE CARD CIRCLE 511

Power Transistors

Vhf units

Power outputs up to 5 w at 200 Mc are provided by the 70 and 140 v series 100. In the 200 series, model SN230 features power outputs of 5 w at 130 Mc, and model SN231 features 10 w at 130 Mc.

Price: \$95-\$145 (1-49).

Mfr: National Semiconductor Corp.

ON READER-SERVICE CARD CIRCLE 512

Silicon Transistors

90-nsec switching

Interdigitated "I" geometry is featured in these diffused-silicoa devices. Types 2N2787-89 are available in the TO-5 case, and types 2N2790-92 are available in the TO-18 case. Collector breakdown voltages are specified at 75 v min; collector-to-emitter ratings exceed 35 v. Typical frequencies exceed 300 Mc.

Mfr: General Instruments Corp., Semiconductor Div.

ON READER-SERVICE CARD CIRCLE 513

Heat Sink

Printed-circuit board



Natural convection unit is said to provide the maximum ratio of heat dissipation to volume occupied. It is claimed that the model 2704 substantially increases transistor performance by optimizing the effect of heat transfer coefficient available in free convection. Both the TO-5 and TO-9 transistor ca cases can be accommodated.

Mfr: Astro Dynamics, Inc.
ON READER-SERVICE CARD CIRCLE 514

Switching Transistors

25-amp

Diffused alloy power types 2N2636-38 switch clamped inductive loads in microseconds at peak powers of 100, 1500 and 2000 w. Switching times range from 1-5 μ sec. Units can switch 25 amps at collector-emitter voltages of 40, 60 and 80 v.

P&A: \$26.25-\$38.25; stock.

Mfr: Bendix Corp., Semiconductor Div.

ON READER-SERVICE CARD CIRCLE 515

Silicon Transistors

Medium-power vhf

Power output is 3.2 w, min, at 125 Mc. Types 2N2781, 2N2782 and 2N2783 can be used as drivers to reactive multiplier chains to achieve up to 2-1/2 w power in the Kc range.

P&A: \$39.90-\$75; stock.

Mfr: TRW Electronics.

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ALgonquin 4-9000

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ON READER-SERVICE CARD CIRCLE 477

Transistor Holder

Teflon insulated



The component is mounted on the shoulder of the Teflon bushing in model RTC-304T. It has a major diameter of 0.325 in. and a minor diameter of 0.290 in. Three through-hole lugs are provided on a 0.200 in. pitch circle for TO-5 type JETEC headers.

Mfr: Sealectro Corp.
ON READER-SERVICE CARD CIRCLE 517

Voltage Tester

3 µsec current duration

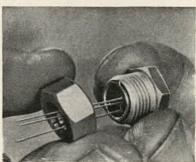
The time factor of the test, rather than the amount of current applied, is limited by model 1901A voltage breakdown tester. The duration of current avalanche through the test specimen is limited to 3 μ sec. Selector switches on the front panel determine the range (1 or 4 Kv) and the amount of ohmic current flow (10 μ a, 100 μ a or 1 ma).

Mfr: Microdot, Inc.

ON READER-SERVICE CARD CIRCLE 518

Transistor Heat Sink

TO-5 and TO-9 packages

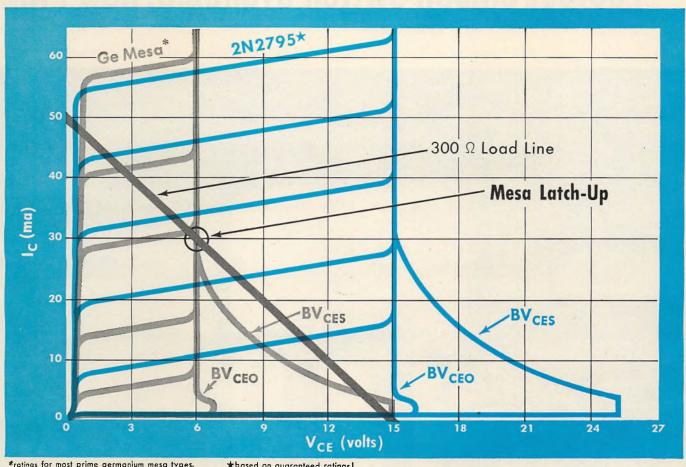


Conduction-cooled 1103 series is available in three finishes: uninsulated, electrically insulated and black anodized. Threaded two-piece construction tightens to grip both sides of transistor weld flange.

Mfr: Thermalloy Co.

ON READER-SERVICE CARD CIRCLE 519

SPRAGUE LOGIC TRANSISTORS GIVE SUPERIOR LATCH-UP PROTECTION!



*based on guaranteed ratings!

For Guaranteed High Voltage Operation at High Speeds, **Investigate Sprague ECDC® and MADT® Transistors**

| वि | Type No. | ft (typical) | BVCES (minimum) | BVCEO (minimum) |
|-------|-------------|-----------------|--------------------|--------------------|
| | 2N2795 | 450 mc | 25 volts | 15 volts |
| | 2N2796 | 450 mc | 20 volts | 12 volts |
| | 2N984 | 350 mc | 15 volts | 10 volts |
| | 2N979 | 150 mc | 20 volts | 15 volts |
| TO-18 | 2N980 | 150 mc | 20 volts | 12 volts |
| CASE | 2N2048† | 250 mc | 20 volts | 15 volts |

(†TO-9 Case)

For additional information on Sprague High Voltage Logic Transistors, write to the Technical Literature Service, Sprague Electric Company, 347 Marshall Street, North Adams, Massachusetts.

Trademark, Philco Corp.

SPRAGUE COMPONENTS

TRANSISTORS CAPACITORS MAGNETIC COMPONENTS RESISTORS MICROCIRCUITS

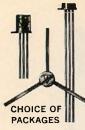
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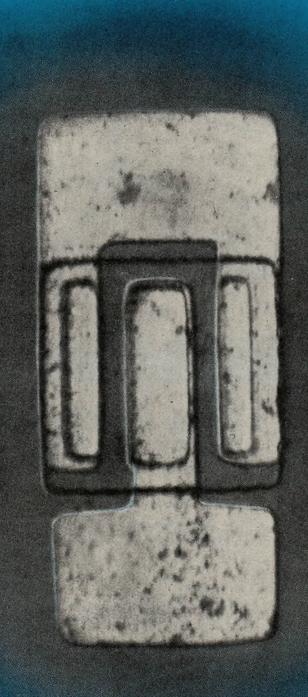


This is the micropower transistor—a new silicon epitaxial planar device that offers higher efficiency at microwatts or milliwatts. As a switch, or as an amplifier, the type 2N2784 offers capabilities beyond any now available! Typical: 1 KMC bandwidth—higher beta level at

microamperes, with reduced falloff beyond 10 milliamperes.

This performance stems from advanced device design and refined photolithographic techniques plus Sylvania's exclusive skills in epitaxial technology. Unusually small

Fastest silicon switch available: new 1 KMC



Epitaxial construction, new 3-stripe configuration, and small size, produce new high switching speed (T_{on} +T_{off} = 12 nanoseconds) with low saturation voltages (typically 0.2 volts).

junction sizes and spacings, low capacitances, result in improved frequency response for both switching and applifier applications.

The Sylvania 2N2784 and the 2N709 and 2N709A, which are members of the 2N2784 family, are all avail-

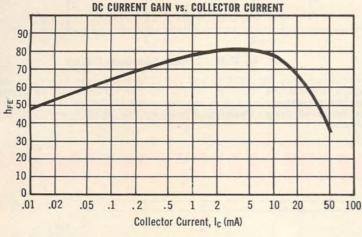
able in your choice of three packages—the TO-18, TO-46 "pancake," and the new TO-51 co-planar package.

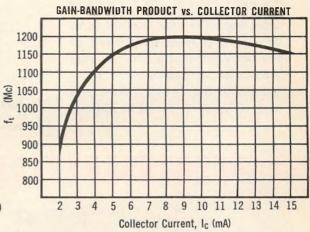
For more information, see your Sylvania salesman or write to Semiconductor Division, Sylvania Electric Products Inc., Woburn, Mass.

Sylvania epitaxial planar transistor 2N2784

ON READER-SERVICE CARD CIRCLE 479

| | SYMBOL | CHARACTERISTICS | 2N Min | 12784 Max | 2i Min | N709 Max | 2N Min | 709A Max | TEST C | ONDITIONS |
|-----|--------------------------|---|-----------|--------------|-----------|-------------|-----------|-------------|----------------------|---|
| | hFE | DC Current Gain | 40 | 120 | 20 | 120 | 30 | 90 | Ic=10mA | V _{CE} = 0.5V |
| | hre | DC Current Gain | 20 | | 15 | | 15 | | lc = 30mA | V _{CE} = 1.0V |
| | hfE (-55°C) | DC Current Gain | 10 .70 | | 10 | | 10 | | I _c =10mA | V _{CE} =0.5V |
| | V _{BE} (sat) | Base Saturation Voltage | .70 | .85 V | .70 | .85 V | .70 | .85 V | Ic = 3.0mA | $I_8 = 0.15 \text{mA}$ |
| - 1 | V _{CE} (sat) | Collector Saturation | | | | | | | | |
| | • | Voltage | | .26 V | | .30 V | | .30 V | lc=3_0mA | $I_B = 0.15 \text{mA}$ |
| | Cop | Output Capacitance | | 3.0 pf | | 3.0 pf | | 3.0 pf | IE=0 | $V_{CB} = 5.0V$ |
| | CTE | Emitter Transition | | 20 1 | | 00 1 | | | | |
| | 1 | Capacitance Collector Cutoff Current | | 2.0 pf | | 2.0 pf | | 2.0 pf | lc=0 | VEB=0.5V |
| | I _{CBO} (150°C) | Collector Cutoff Current | | 5mμA | | 50mμA | | 5mμA | I _E =0 | V _{CB} =5.0V |
| | BV _{CBO} | Collector to Base Break- | | 5.0 μA | | 5.0 μA | | 5.0 μA | I _E =0 | $V_{CB} = 5.0V$ |
| | DACRO | down Voltage | 15 | | 15 | ٧ | 15 | V | L-10 A | 10 |
| | V _{CEO} (sust) | Collector to Emitter | 15 | V | 13 | | 13 | ٧ | I _C =10μA | 1E=0 |
| 1 | . (50 (9231) | Sustaining Voltage | 6.0 | V | 6.0 | ٧ | 6.0 | ٧ | I _c =10mA | I ₈ =0 |
| | | Cootaming voltage | 0.0 | ٧ | 0.0 | | 0.0 | • | (pulsed) | 1g – U |
| | BVEBO . | Emitter to Base Break- | 51 | | | | | | (purseu) | |
| | | down Voltage | 4.0 | V | 4.0 | V | 4.0 | V | l _c =0 | I _E =10µA |
| | Ts | Charge Storage Time | 7.0 | • | | | | | | |
| | | Constant | | 5.0 ns | | 6.0 ns | | 6.0 ns | Ic= 81= 82 | =5.0mA |
| | $t_d + ,$ | Turn-on Time | | 0.0 113 | | | | | | |
| | | $(V_{BE(0)} = -1.0V)$ | | 9 ns | | 15 ns | | 15 ns | I _c =10mA | i _{B1} =2rnA |
| | $t_s + \varepsilon$ | Turn-off Time | | 9 ns | | 15 ns | | 15 ns | I _c =10mA | i ₈₁ =I ₈₂ =1.0mA |
| 1 | 11 | Gain-Bandwidth Product | 1000 | mc | 600 | mc | 800 | mc | Ic=5.0mA | V _{CE} =4.0V |





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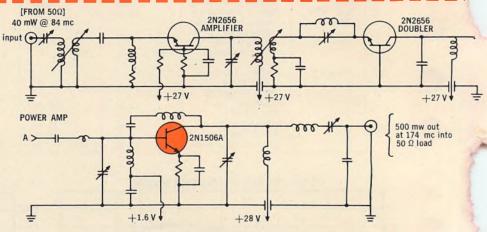
How to design transistorized communications equipment

MEDIUM POWER VHF TRANSISTORS

2N1506A

• 1 watt • 70mc @ 28V • 10db gain

Ideal transistors for application in drivers and final amplifiers of telemetry transmitters to 2W, final amplifiers for mobile radio applications in the 140mc range, and as multipliers from 40 to 200mc.



1/2 Watt - 174mc Sonobuoy Circuit

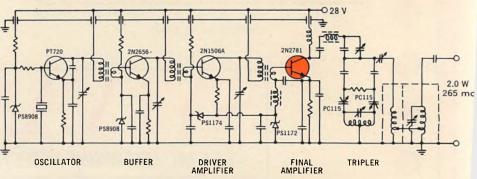
This circuit employs PSI 2N2656 and 2N1506A transistors to achieve high power for Sonobuoy applications. Outputs to 2 watts can be obtained by adding additional stages; the oscillator circuit is at the designer's discretion. This circuit is indicative of the increased design flexibility offered by PSI 2N2656 and 2N1506A silicon RF transistors.

HIGH POWER VHF TRANSISTORS

2N2781

• 5 watts • 30mc @ 28V • 12db gain

Use this series as final amplifiers in communications equipment, 2 to 5W telemetry equipment and mobile radio designs.



2 Watt - 265mc Telemetry Circuit

Originally designed and engineered at PSI, this circuit applies a PSI PT720 as an oscillator, 2N2656 as a buffer, 2N1506A for the driver stage and a 2N2781 for the final, to deliver a conservative 2 watts at 265mc. This application is one of the first telemetry designs available using low cost, off-the-shelf units instead of state-of-theart devices.

New PSI RF transistor application notes and bulletins:

• Summary of the State of the Art in the practical use of Communications Transistors • Citizens Band Transmitter • VHF Transistor Oscillator • Radio Frequency Applications, Types PT900 and 2N1900 • 50W, 30mc Amplifier • Class C—100 Watt—20 Megacycle Power Amplifier • Class C—100 Watt—10 Megacycle Power Amplifier • Class C—100 Watt—3 Megacycle Power Amplifier • 1W, 1Kmc Transmitter • 240mc PCM Transmitter • 5W, 30mc Power Gain Test Circuit • Inverter Design • Switching Application, Types PT900, 2N1899, 2N1901 • Pulse Driver for Inductive Elements and Magnetic Memories, Types PT900, 2N1899, 2N1901 • 3W, 125mc Amplifier • ½W Citizens Band Transmitter • 100W, 100mc Amplifier • 5W, 70mc Amplifier • 10W, 100mc Oscillator

NEW RF TRANSISTOR APPLICATION LITERATURE

... Application ENGINEERING Assistance!

It is now possible to design all solid state communications equipment at costs comparable to, or below, vacuum designs . . . this new PSI application literature will help show you how! If you don't find literature listed on the back of this card covering your specific field of interest, contact your nearest PSI sales office and discuss your specific communications equipment design problem with one of our sales engineers. Let our experienced application engineering section show you the reliability, economy, equipment size reductions and ruggedness you can obtain when you SPECIFY PSI for all your RF transistor needs.

(If the postal return card has been removed from your copy of this publication, write on your company letterhead. The application literature listing has been repeated on the back of this card for your convenience. PSI SERVES THE COMPLETE COMMUNICATIONS SPECTRUM... From low-level, low-noise oscillators and amplifiers to advanced high-power, high-frequency devices, PSI has the communications transistor your designs require.

For the past five years, PSI has dedicated the major part of its transistor development and engineering efforts towards optimizing capabilities of silicon transistors in all communications equipment. Today PSI is a leading producer of RF transistors for high reliability space communications equipment in such projects as Mariner, OAO, Ranger, Relay, and Explorer. Realizing that component cost is a major factor in communications equipment design, PSI has had, as an early objective, the pricing of high performance RF devices at levels which will hasten the era of all-transistorized communications systems in many new fields.

Call PSI today to discuss your particular communications equipment design problems. Let PSI application engineering show you how you can design transistorized communications equipment on a vacuum tube budget through lower overall component costs due to lower voltage operation, lack of heater equipment, smaller power supplies, and greater efficiencies.

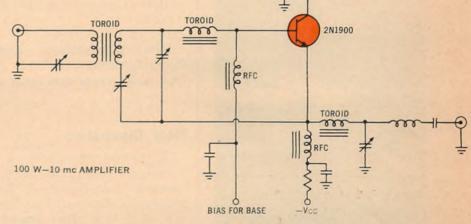
on a vacuum tube budget!

HIGH POWER
HF TRANSISTORS

2N1900

• 100 watts • 10mc @ 60V • 10db gain

The PSI 2N1900 series is ideal for commercial, marine, and military PRC and VRC designs from 2 to 12mc, as 10 amp switchers in power conversion applications, and amplifiers in VLF transmitters up to 5KW.



100 Watt-10mc Amplifier for PRC, VRC and Marine Radio

This economical design employs optimum heat sinking to provide a substantial reduction in size over 100 watt tube amplifiers. This design employs a PSI 2N1900 in a reliable, cold-welded package to deliver 100 watts out at 10mc with greater than 10db gain.

LOW POWER/LOW NOISE UHF TRANSISTORS

2N2656

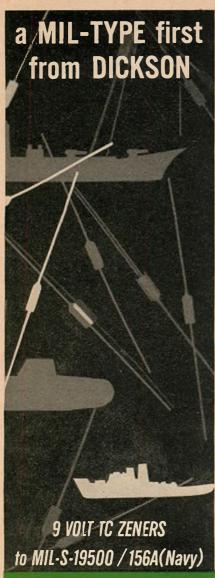
• 50mW • 100mc @ 10V • 10db gain

Apply these low noise figure units to your oscillator designs up to 50mW. These transistors also provide optimum performance in low to medium-level class A and B buffer amplifiers by delivering up to 200mW RF power with over 50% efficiency.



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ON READER-SERVICE CARD CIRCLE 480



Bickson is the first to offer 9 voit, 500 mm, silicon difficed-junction temperature compensated zener reference diodes to meet the requirements of MIL-2-23500/156A (Narc). USN Types 19935B, 19937B, 1993BB, and 19939B offer temperature coefficients of .01, .002, .001. and .0005% °C. Modest quantities are immediately available for your critical military applications.

Dickson also offers the industry's broadest line of standard temperature compensated zener reference diodes. The following types are presently available from steck, to JEDEC specifications:

 INH29
 1N1530-30A
 1N2765-70A

 1N821-27A
 1N1735-42A
 1N3154-57A

 1N935-39B
 1N2163-71A
 1N3580-84B

 1N941-45B
 1N2620-24B
 1N4057-85A

For complete information contact your authorized Dickson Representative, or write, wire or phone Mr. Jack Nancarrow, Dickson Electronics, P. O. Box 1387, Scottsdale, Arizona. Phone code 602, 946-5357.



248 Wells Fargo Avenue, Scottsdale, Ariz.

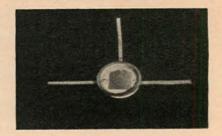
Transistor Package

Integral beryllia base

Packages of 5/8 in. and 3/4 in. diam, for devices in the 12-20 amp range, with two, three or four leads are included in this line. Glass-to-metal seals are said to be eliminated by the package, whose lower beryllia surface provides a direct path from the semiconductor material to a chassis or heat sink.

Mfr: National Beryllia Corp.

ON READER-SERVICE CARD CIRCLE 520



Silicon Transistors

6000 w peak

NPN silicon power units have voltage ratings of 50-200 v. Typical saturation resistance of series 2N1830 and 2N2130 is 0.035 ohms. Minute gain is 10 at 25 amps collector current. Dissipation is 250 w; peak power capability is 6000 w. Operating temp range is -65 to +175 C.

Price: \$105-\$198 (100+).

Mfr: Westinghouse Electric Corp., Semiconductor Div.

ON READER-SERVICE CARD CIRCLE 521



Heat Dissipators

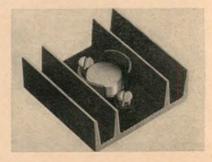
Horizontal or vertical

Designed for TO-8 or studmounted semiconductors, Series 9021 units dissipate heat at the rate of 6 C/w. They employ an extruded parallel fin design and may be used in either a vertical or horizontal position.

P&A: \$0.50-\$0.95; stock.

Mfr: Augat Inc.

ON READER-SERVICE CARD CIRCLE 522



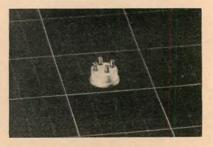
Transistor Holder

Teflon-insulated

Providing 4 connections on a 0.200-in. diam pitch circle, the RTC-400T-L2 features lugs extending 0.070 in. below the Teflon body for circuitry connections. The major diameter is 0.325 in. and the minor diameter is 0.290 in. Over-all socket height is 0.225 in. and unit may be used on chassis thicknesses up to 0.093 in.

Mfr: Sealectro Corp.

ON READER-SERVICE CARD CIRCLE 523



Transistors

Power switching

Switching up to 1200 w in μ secs is afforded by these 10-amp, diffused alloy, power transistors. They feature a high cutoff frequency, $f_{ab}=1.5$ Mc; and low saturation voltage, $V_{ces}=-0.5$ v dc, max at $I_c=5$ amp, $I_B=-0.5$ amp. Series 2N2288-2290 are germanium pnp type units.

Mfr: Bendix Semiconductor.

ON READER-SERVICE CARD CIRCLE 524

Industrial Transistor

Mesa construction

Germanium epitaxial type TIX-316 has an h_{fe} of 35 min at 1 Kc, h_{fe} of 4.0 at 100 Mc; $R_b{'}C_c$ is 15 psec, max; C_{ob} is 3.0 pf, max; and NF is 4.5 db max at 200 Mc.

The device is packaged in a four-lead TO-18 case.

P&A: \$2.93; 3 weeks.

Mfr: Texas Instruments Inc., Semiconductor-Components Div.

ON READER-SERVICE CARD CIRCLE 525

Transistors

Silicon unijunction

Useful in oscillators and timing circuits, types 2N2646 and 2N2647 feature maximum peak point emitter current of 25 μa (inter-base voltage = 25 v) and maximum valley point current of 18 ma (interbase voltage = 20 v, R_{B2} = 100 ohms) at 25 C.

Mfr: General Electric Semiconductor Products Dept.

ON READER-SERVICE CARD CIRCLE 526

Germanium Transistors

Diffused-alloy

PNP types 2N2285 through 2N-2287 feature collector-emitter breakdown voltages of -30 to -80 v dc, min. Saturation voltage $(V_{\text{CE(S)}})$ is -0.65 v dc, max. Units are capable of switching up to 1600 w in 1-5 μ sec.

Mfr: Bendix Corp., Semiconductor Div.

ON READER-SERVICE CARD CIRCLE 527

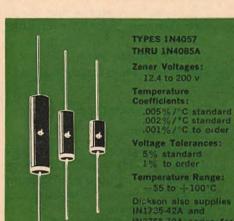


12.4 to 200 volt temperature

compensated zeners

DICKSON

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This Dickson TC zener series, the broadest ever developed for high valtage circuits, represents an ideal combination of performance, size, stability, and reliability. The rugged DURAPAK* high temperature, vacuum-molded package, exclusive with Dickson, provides a hermetic seal of the highest quality. Units meet or exceed environmental requirements of MIL-S·19500 and have passed 1000 hour storage lifetests at temperatures of 150°C.

Economical, too! Lower voltage units cost about 40% less than conventional devices. Higher voltage units offer substantial savings over small devices used "in series".

They are available from your nearby Dickson distributor. Callhim, today, for immediate delivery

FOR COMPLETE TECHNICAL INFORMA-FIGN, write: Mr. Frank Malley, Dickson Electronics, P.O. Box 1387, Scottsdale, Arizona.

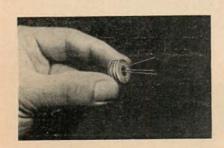
* trademark of Dickson Electronics Corp.



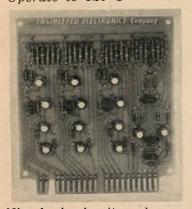
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248 Wells Fargo Avenue, Scottsdale, Ariz.





Digital Modules Operate to 120 C



Nine basic circuit cards are offered in 1 and 10 Mc versions. Power required is ± 12 v dc. Logic levels are 0 and 6 v dc. Card dimensions are 4-1/4 x 5 x 1/16 in.

Mfr: Engineered Electronics.

ON READER-SERVICE CARD CIRCLE 531

Transistor Heat Sink

Beryllium copper

For use with the TO-8 transistor, models 211, 213 and 215 feature a featherweight cooler which is said to provide rigid contact of large areas. Special tapered installation tools are available.

Mfr: Wakefield Engineering, Inc.

ON READER-SERVICE CARD CIRCLE 528

Silicon Transistors

High-power vhf

Two 50-Mc power devices, types MM800 amd MM799, have a guaranteed power gain of 7 db at 15 w output. Model MM801 is a medium power amplifier/driver with a power gain of 10 db for a 3.5 w power output at 50 Mc.

Mfr: Motorola Semiconductor Products, Inc.

ON READER-SERVICE CARD CIRCLE 529

Transistor Heat Sink

Convection cooled

Model 2211 dissipates approx 1 w at 150 C. It fits all TO-5 and TO-9 cases, regardless of case diameter. Dimensions are 5/8 in. in diameter by 5/16 in. high; total weight is 0.056 oz.

Price: \$0.18 ea (+100), \$0.10 ea (+1000).

Mfr: Thermalloy Co.

ON READER-SERVICE CARD CIRCLE 530

Planar Transistors

15-pf collector capacitance

A minimum current transfer ratio of up to 3 is available with types 2N910-912 and 2N1973-74. The series is designed for use in high frequency amplifier circuits.

Mfr: General Electric Semiconductor Products Dept.

ON READER-SERVICE CARD CIRCLE 532

Silicon Transistors

Npn planar

Minimum current transfer ratio of types 2N1189 and 2N1890 is up to 3.0 at 25 C. Units are designed for high frequency amplifier and oscillator circuits.

Mfr: General Electric Semiconductor Products Dept.

ON READER-SERVICE CARD CIRCLE 533

Transistors

Planar passivated

TO-5 size differential amplifiers, types 2N2480/80A offer maximum voltage differentials of 5-10 mv. At 25 C, the collector-to-emitter voltage is 5 v and the collector currents are $100~\mu a$ and 1 ma.

Mfr: General Electric Semiconductor Products Dept.

ON READER-SERVICE CARD CIRCLE 534

Chopper Transistors

Double-emitter types

Breakdown voltage of types 3N74 through 3N79 is $BV_{\text{E1E2}} \pm 18 \text{ v}$ min at $I_{\text{E}} \pm 10 \ \mu\text{a}$). Emitter currents are as low as 2 na at $\pm 15 \ \text{v}$ and offset voltages are $\pm 50 \ \mu\text{v}$ for specified conditions with temperatures from $-25 \ \text{to} + 100 \ \text{C}$.

Mfr: Texas Instruments Inc., Semiconductor-Components Div.

ON READER-SERVICE CARD CIRCLE 535

Kovar Tab Transistor

Npn silicon planar

Maximum collector leakage current for types 11B554-556 is 25 μ a at 25 C. Units are silicon planar versions of TO-5 types 2N1613, 2N1711 and 2N1893.

Mfr: General Electric Semiconductor Products Dept.

ON READER-SERVICE CARD CIRCLE 536

Silicon Transistor

High frequency

Interdigitated epitaxial planar device, type 2N2865, has a neutralized power gain of 18 db; oscillator output is 55 Mw at 500 Mc. Specifications include an NF of 4.5 db max at 200 Mc and an $R_{\rm b}'$ $C_{\rm c}$ of 15 psec max.

Mfr: Texas Instruments Inc., Semiconductor-Components Div.

ON READER-SERVICE CARD CIRCLE 537

Chopper Transistors

Five-terminal devices

Planar epitaxial passivated types 2N2356/56A feature a collector leakage and emitter leakage current of 10 μ a, max. At 25 C, either collector-to-base voltage is 25 v.

Mfr: General Electric Semiconductor Products Dept.

ON READER-SERVICE CARD CIRCLE 538

ELECTRONIC DESIGN'S TRANSISTOR READER-SERVICE CARD

Reprints Available

| Electronic Design's Eleventh Annual Transistor Data Chart (1963) | 549 |
|--|-----|
| "Designing A Bootstrap Emitter-Follower Amplifier" | 546 |
| "Generating Linear Waveforms With Field Effect Transistors" | 547 |
| "Four Ways to Pair Field-Effect With Conventional Transistors" | 548 |

Manufacturers' Specification Sheets and Application Notes

| Amelco | 400 | Fairchild | 408 | National | 416 | Solid State Products | 425 |
|--------------|-----|--------------------|-----|-------------------------|-----|----------------------|-----|
| AMF-Leland | 401 | General Electric | 409 | PSI | 417 | Sperry | 426 |
| Amperex | 402 | General Instrument | 410 | Philco | 418 | Sprague | 427 |
| Bendix | 403 | Honeywell | 411 | RCA | 419 | Sylvania | 428 |
| Clark | 404 | Hughes | 412 | Raytheon | 421 | Texas Instruments | 429 |
| Clevite | 405 | Industro | 413 | Silicon Transistor | 422 | Transitron | 430 |
| Crystalonics | 406 | Kearfott | 414 | Siliconix | 423 | Tung-Sol | 431 |
| Delco | 407 | Motorola | 415 | Solid State Electronics | 424 | Westinghouse | 433 |

Transistor and Allied Product Information

| 434 | 435 | 436 | 437 | 438 | 439 | 440 | 441 | 442 | 443 | 444 | 445 | 446 | 447 | 448 | 449 | 450 | 451 |
|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| 452 | 453 | 454 | 455 | 456 | 457 | 458 | 459 | 460 | 461 | 462 | 463 | 464 | 465 | 466 | 467 | 468 | 469 |
| | 474 | 470 | | | | | | _ | | | _ | _ | _ | | | | |
| 470 | 4/1 | 412 | 473 | 474 | 475 | 476 | 477 | 478 | 479 | 480 | 481 | 482 | 483 | 484 | 485 | 486 | 487 |
| 488 | 489 | 490 | 491 | 492 | 493 | 494 | 495 | 496 | 497 | 498 | 499 | 500 | 501 | 502 | 503 | 504 | 505 |
| 506 | 507 | 508 | 509 | 510 | 511 | 512 | 513 | 514 | 515 | 516 | 517 | 518 | 519 | 520 | 521 | 522 | 523 |
| 524 | 525 | 526 | 527 | 528 | 529 | 530 | 531 | 532 | 533 | 534 | 535 | 536 | 537 | 538 | 539 | 540 | 541 |

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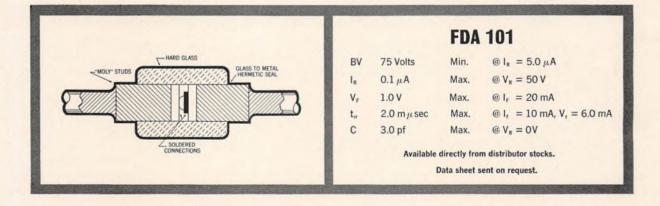
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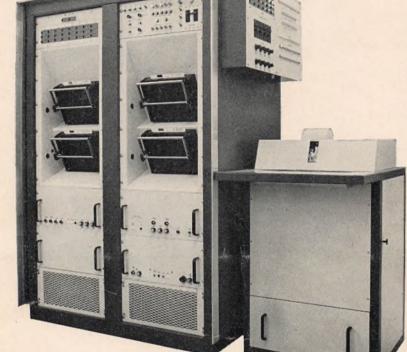
- SMALL sandwich construction no whisker.
- STRONG true hermetic seal. No pressure contacts.
- MECHANICAL STRENGTH stud-to-cathode and stud-to-anode solder-down.
- VERSATILE replacement type for any of 276 silicon diodes.





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AUTOMATIC TRANSISTOR TESTER/SORTER



FAIRCHILD SERIES 200

- Pulse testing for high current tests
- Completely programmed with four plastic punched cards
- Tests 1500 transistors per hour 24 tests per device
- Tests may be programmed in any order

The high-speed, automatic classification and sorting capabilities of the Series 200 give this tester a wide variety of applications for both users and producers of transistors. It performs any combination of 24 standard tests—or a single test up to 24 times—on a go/no-go basis. The tests may be programmed in any order through an easy-to-use punch card system. Test rate: 1500 transistors per hour!

Pulse testing techniques eliminate junction heating effects to ensure accurate high current tests. Each tested transistor is automatically placed in the appropriate sort bin. The Series 200 also features automatic detection of incorrect programming and performs an equipment self-check test during each test sequence. Write for data sheet and free demonstration. Fairchild offers the widest selection of equipment in the industry.

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